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INDEX VOLUME 23, 1987

Author index

A

Aanandan, C.K., Jose, K.A., and Nair, K.G. see Jose, K.A.
Aanandan, C.K., and Nair, K.G. Compact broadband microstrip antenna e306
Abdel Wahab, H.M.S., and Fairhurst, M.C. see Fairhurst, M.C.
Abe, Y., Sugimoto, H., Matsui, T., and Ogata, H. see Sugimoto, H.
Abeles, J.H., Chan, W.K., Cox, H.M., and Kelty, S.P. see Chan, W.K.
Abeles, J.H., Chan, W.K., Kastalsky, A., Harbison, J.P., Florez, L.T., and Bhat, R. Guided-wave GaAs/AlGaAs FET optical modulator based on free-carrier-induced bleaching p1302
Abeles, J.H., Chan, W.K., Shokoohi, F.K., Bhat, R., and Koza, M.A. Integration of GaAs MESFET drivers with GaAs directional-coupler electro-optic modulators p1037
Abidi, A.A., and Colleran, W.T. see Colleran, W.T.
Aboelsaad, M., and Shafai, L. DC ionised field quantities as influenced by coronating conductor surface gradient p162
Aboul-Saoud, A.K., Kheirallah, H.N., and Rashwan, H.M. see Kheirallah, H.N.
Aboul-Saoud, A.K., Rashwan, H.M., and Kheirallah, H.N. see Rashwan, H.M.
Abraham, M., Welch, D.F., DeVito, M., Cardinal, M., Kung, H., Harnagel, G., Cross, P., Scifres, D., and Streifer, W. see Welch, D.F.
Abramov, A.A., Bogatyrjov, V.A., Bubnov, M.M., and Dianov, E.M. Simple method for detecting water penetration into optical fibre cables p957
Abrokwah, J.K., Arch, D.K., Vold, P.J., Fraasch, A.M., Grung, B.L., and Cirillo, N.C. see Arch, D.K.
Abu-Zeid, M.M., and de Jong, G.G. MOSFET model continuous from weak to strong inversion p1299
Ackerman, D.A., Olsson, N.A., Johnson, B.H., Lee, H.J., Henry, C.H., Kazarinov, R.F., and Anthony, P.J. see Olsson, N.A.
Ackley, D.E. Equivalent circuit modelling and derivative characterisation of 1·3 μm injection lasers p1354
Acosta, R., Lee, R.Q., and Lee, K.F. see Lee, R.Q.
Adachi, F., and Ohno, K. see Ohno, K.
Adachi, T., and Harada, I. see Harada, I.
Adams, A.R., Greene, P.D., Prins, A.D., and Dunstan, D.J. see Greene, P.D.
Adams, A.R., Heasman, K.C., Greene, P.D., and Henshall, G.D. see Heasman, K.C.
Adams, A.R., Heasman, K.C., and Plumb, R.G. see Heasman, K.C.
Adams, M.J., and Westbrook, L.D. see Westbrook, L.D.
Adrian, A., and Schaubert, D.H. Dual aperture-coupled microstrip antenna for dual or circular polarisation p1226
Ageno, S.K., Jones, W.L., and Sato, T.Y. see Jones, W.L.
Agranat, A., and Yariv, A. Semiparallel microelectronic implementation of neural network models using CCD technology p580
Agrawal, G.P. Amplifier-induced crosstalk in multichannel coherent lightwave systems p1175
Agrawal, G.P. Evaluation of crosstalk penalty in multichannel ASK heterodyne optical communication systems p906
Aguila, T., Wolny, M., Deconinck, P., Moroni, D., and Andre, J.P. see Wolny, M.
Ahmad, M.M., Hua, Y.L., Petty, M.C., Roberts, G.G., Yates, H.M., Maung, N.J., and Williams, J.O. see Hua, Y.L.
Ahmadpanah, M., Baudrand, H., and Kaddour, M. see Baudrand, H.
Ahmed, H., Armistead, C.J., Butler, B.R., Clements, S.J., Collar, A.J., Moule, D.J., Wheeler, S.A., and Fice, M.J. see Armistead, C.J.
Ahmed, H., Fice, M.J., and Clements, S. see Fice, M.J.
Ahmed, H., Kirk, E.C.G., and Cleaver, J.R.A. see Kirk, E.C.G.
Ahn, B.C., Kishk, A.A., and Auda, H.A. see Kishk, A.A.
Ahrens, R.E., Lu, C.Y., Riffe, P.C., Tsai, N.S., and Banak, M.A. see Lu, C.Y.
Aihara, K., Miyahara, K., and Hohkawa, K. Josephson vortex timing circuit p545
Ainslie, B.J., Girdlestone, H.P., and Cotter, D. Semiconductor-doped fibre waveguides exhibiting picosecond optical nonlinearity p405
Ainslie, B.J., Gouveia-Neto, A.S., Gomes, A.S.L., Taylor, J.R., and Craig, S.P. see Gouveia-Neto, A.S.
Ainslie, B.J., Liu, K., Digonnet, M., Shaw, H.J., and Craig, S.P. see Liu, K.
Ainslie, B.J., Millar, C.A., Miller, I.D., Craig, S.P., and Armitage, J.R. see Millar, C.A.
Ajisawa, A., Fujiwara, M., Shimizu, J., Sugimoto, M., Uchida, M., and Ohta, Y. Monolithically integrated optical gate 2 × 2 matrix switch using GaAs/AlGaAs multiple quantum well structure p1121
Akiba, S., Matsushima, Y., Usami, M., and Utaka, K. Spectral behaviour of aged 1·55 μm λ/4-shifted DFB lasers p316
Al-Jalili, Y.O., Lockhart, G.B., Bayes, T., and Mehdi, A.A.A. see Lockhart, G.B.
Al-Kabbani, A.S.S., and Bowron, P. Behaviour of actively compensated bandpass filters at higher signal levels p1108
Al-Mudares, M., Lee, K.Y., Beaumont, S.P., Wilkinson, C.D.W., Frost, J., and Stanley, C.R. see Lee, K.Y.
Al-Shukri, S.M., Duffy, J.F., and De La Rue, R.M. see Duffy, J.F.
Alabedra, R., Peransin, J.M., and Rigaud, D. see Peransin, J.M.
Alard, F., Francois, P.L., and Monerie, M. see Francois, P.L.
Alard, F., and Monerie, M. see Monerie, M.
Albares, D.J., Garcia, G.A., Chang, C.T., and Reedy, R.E. Optoelectronic time division multiplexing p327
Albert, J., and Yip, G.L. Stress-induced index change for K^+–Na^+ ion exchange in glass p737
Alferness, R.C., Eisenstein, G., Tucker, R.S., Korotky, S.K., Raybon, G., Veselka, J.J., Buhl, L.L., Gnauck, A.H., and Kasper, B.L. see Eisenstein, G.
Alferness, R.C., Gnauck, A.H., Linke, R.A., Kasper, B.L., Pollock, K.J., Reichmann, K.C., and Valenzuela, R. see Gnauck, A.H.
Alferness, R.C., Heismann, F., and Buhl, L.L. see Heismann, F.
Alferness, R.C., Tucker, R.S., Eisenstein, G., Korotky, S.K., Buhl, L.L., Veselka, J.J., Raybon, G., and Kasper, B.L. see Tucker, R.S.
Alferness, R.C., Tucker, R.S., Eisenstein, G., Korotky, S.K., Koren, U., Raybon, G., Veselka, J.J., Buhl, L.L., and Kasper, B.L. see Tucker, R.S.
Allan, D.A., Gilbert, M.J., and O'Sullivan, P.J. New tungsten silicide thin-film resistor technology applied to GaAs integrated circuits p1216
Allan, L.E., Antar, Y.M.M., and Holt, A.R. see Antar, Y.M.M.
Allen, L., Glavas, E., Townsend, P.D., Droungas, G., Dorey, M., and Wong, K.K. see Glavas, E.
Allen, R., Kintz, G.J., and Esterowitz, L. see Kintz, G.J.
Allovon, M., Renaud, J.C., N'Guyen, L., Heliot, F., Lugiez, F., and Scavennec, A. see Renaud, J.C.
Alonso-Pardo, A., Camacho-Peñalosa, C., and Mariscal-Rico, L. see Camacho-Peñalosa, C.
Alping, A., Wu, X.S., and Coldren, L.A. Wavelength dependence of high-performance AlGaAs/GaAs waveguide phase modulators p93
Alping, A., and Andrekson, P.A. see Andrekson, P.A.
Altintas, A., Snyder, A.W., and Ankiewicz, A. see Snyder, A.W.
Amann, M.-C. Analysis of a PIN photodiode with integrated waveguide p895
Amon, J.M., Poole, C.D., Bergano, N.S., Schulte, H.J., Wagner, R.E., Nathu, V.P., and Rosenberg, R.L. see Poole, C.D.
Anand, Y., Thompson, P., Dietrich, H., Higgins, V., and Hillson, J. see Thompson, P.
Anand, Y., and Christou, A. GaAs monolithic Schottky junction pairs for W-band crossbar mixers p727
Anastassiou, D., and Tsividis, Y.P. see Tsividis, Y.P.
Anderson, A.P., Kerbyson, P., and Bennett, J.C. see Kerbyson, P.
Anderson, A.P., and Sali, S. see Sali, S.
Anderson, W.T., Morgan, D.V., Thomas, H., Thompson, P., Christou, A., and Diskett, D.J. see Morgan, D.V.
Andonovic, I., Shabeer, M., and Culshaw, B. see Shabeer, M.
Andre, J.P., Wolny, M., Aguila, T., Deconinck, P., and Moroni, D. see Wolny, M.
Andreasen, S.B. New bending loss formula explaining bends on loss curve p1138
Andrekson, P.A., and Alping, A. Novel all-electrical scheme for dynamic semiconductor laser-to-fibre coupling control p1275
Andres, M.V., Foulds, K.W.H., and Tudor, M.J. Nonlinear vibrations and hysteresis of micromachined silicon resonators designed as frequency-out sensors p952
Andres, M.V., Tudor, M.J., and Foulds, K.W.H. Analysis of an interferometric optical fibre detection technique applied to silicon vibrating sensors p774
Ang, A.L., and Yeo, S.P. see Yeo, S.P.
Ankiewicz, A., Snyder, A.W., and Altintas, A. see Snyder, A.W.
Ankiewicz, A., and Snyder, A.W. see Snyder, A.W.
Ansari, R., and Cetin, A.E. see Cetin, A.E.
Ansari, R., and Lau, C.-L. Two-dimensional IIR filters for exact reconstruction in tree-structured sub-band decomposition p633
Antar, Y.M.M., Allan, L.E., and Holt, A.R. Backscattering matrix of dielectric objects at 9·6 GHz p996
Anthony, P.J., Olsson, N.A., Johnson, B.H., Lee, H.J., Henry, C.H., Kazarinov, R.F., and Ackerman, D.A. see Olsson, N.A.
Antweiler, M., and Bömer, L. see Bömer, L.
Aoki, A., Miyoshi, S., and Shirafuji, J. Effect of photochemical etching on interface state density of $Ga_{0.47}In_{0.53}As$ metal/insulator/semiconductor diodes p891
Aoyagi, T., Hinata, S., Shigihara, K., Seiwa, Y., Ikeda, K., and Susaki, W. High-power operation of long-cavity phase-locked laser arrays p1396
Aoyama, T., Kondo, M., Ohta, Y., Tanisawa, Y., and Ishikawa, R. see Kondo, M.
Appel, R.K., Sheard, S.J., and Somekh, M.G. see Sheard, S.J.
Arch, D.K., Abrokwah, J.K., Vold, P.J., Fraasch, A.M., Grung, B.L., and Cirillo, N.C. Static random-access memory based on self-aligned-gate (Al, Ga)As/n^+-GaAs superlattice modulation-doped FETs p87
Archer, M.J. Scattering of arbitrarily polarised, arbitrarily directed incident plane waves by frequency-selective surfaces p660
Arita, T., Suzuki, S., Yabusaki, M., and Ishino, F. see Suzuki, S.
Armistead, C.J., Butler, B.R., Clements, S.J., Collar, A.J., Moule, D.J., Wheeler, S.A., Fice, M.J., and Ahmed, H. DFB ridge waveguide lasers at $\lambda = 1{\cdot}5\,\mu m$ with first-order gratings fabricated using electron beam lithography p592
Armitage, J.R., Millar, C.A., Miller, I.D., Ainslie, B.J., and Craig, S.P. see Millar, C.A.
Arnaud, J. Role of Petermann's K-factor in semiconductor laser oscillators—a further note p450
Arnaud, J., and El Mashade, M.B. see El Mashade, M.B.
Arndt, F., Uher, J., and Bornemann, J. see Uher, J.
Asahi, H., Kawamura, Y., Wakita, K., and Oe, K. see Kawamura, Y.
Asahi, H., Tanaka, H., and Kawamura, Y. see Tanaka, H.
Asai, M., Imanaka, K., Imamoto, H., Sato, F., and Shimura, M. see Imanaka, K.
Asano, K., Suzuki, A., Itoh, T., Terakado, T., Kasahara, K., Inomoto, Y., Ishihara, H., Torikai, T., and Fujita, S. see Suzuki, A.
Ash, E.A., and Yeatman, E. see Yeatman, E.
Ashley, T., Elliott, C.T., White, A.M., Crimes, G.J., and Harker, A.T. Near-ambient-temperature bipolar transistor in cadmium mercury telluride p1280
Askins, C., Mermelstein, M.D., and Dandridge, A. see Mermelstein, M.D.
Assanto, G., Gabel, A., Seaton, C.T., Stegeman, G.I., Ironside, C.N., and Cullen, T.J. All-optical switching in prism coupling to semiconductor-doped glass waveguides p484
Atkins, R.A., Lee, C.-E., and Taylor, H.F. see Lee, C.-E.
Atlas, D.A., Elrefaie, A.F., Wagner, R.E., and Daut, D.G. see Elrefaie, A.F.
Auda, H.A., Kishk, A.A., and Ahn, B.C. see Kishk, A.A.
Auld, B.A., Majidi-Ahy, R., Weingarten, K.J., Riaziat, M., and Bloom, D.M. see Majidi-Ahy, R.
Auld, B.A., Riaziat, M., Feng, I.J., and Majidi-Ahy, R. see Riaziat, M.
Auld, B.A., Rodwell, M.J.W., and Bloom, D.M. see Rodwell, M.J.W.
Austin, B.A., and Fourie, A.P.C. see Fourie, A.P.C.
Austin, J., Lau, W.H., and Vilar, E. see Lau, W.H.
Auvergne, D., Deschacht, D., and Robert, M. Explicit formulation of delays in CMOS VLSI p741
Avanic, B., and Gonzalez, G. see Gonzalez, G.

Bødtker, E., Kan, J.X., and Jacobsen, G. see Kan, J.X.

Bäcklin, L. Photoelectrochemical laser interference etching for fabrication of 235 nm diffraction gratings on *n*-InP p657

Baba, T., Kokubun, Y., Sakaki, T., and Iga, K. see Kokubun, Y.

Bahl, I.J., Geissberger, A.E., Sadler, R.A., Griffin, E.L., and Balzan, M.L. see Geissberger, A.E.

Baier, S.M., Lee, G.Y., Chung, H.K., Fure, B.J., and Cirillo, N.C. Ion-implanted *P*-channel GaAs MESFET using Schottky barrier height tailoring p223

Baker, P.W. Fast computation of $A * B$ modulo N p794

Balabanova, A., Borissov, M., Spassov, L., Yosiffov, E., and Radeva, E. see Borissov, M.

Balakrishnan, N., Jha, R.M., and Sudhakar, V. see Jha, R.M.

Balestra, F., and Brini, J. SOI MOSFET in weak inversion and weak accumulation p211

Ball, E., and Tomlinson, G.H. see Tomlinson, G.H.

Ballance, J.W., Stern, J.R., Faulkner, D.W., Hornung, S., Payne, D.B., and Oakley, K. see Stern, J.R.

Ballantyne, J.M., Wojtczuk, S.J., Chen, Y.K., and Wanuga, S. see Wojtczuk, S.J.

Balzan, M.L., Geissberger, A.E., Sadler, R.A., Griffin, E.L., and Bahl, I.J. see Geissberger, A.E.

Banak, M.A., Lu, C.Y., Riffe, P.C., Tsai, N.S., and Ahrens, R.E. see Lu, C.Y.

Bando, K., Utsumi, K., Tezuka, A., Nishii, K., Inoue, K., and Onuma, T. see Utsumi, K.

Bar-Joseph, I., Koren, U., Miller, B.I., Tucker, R.S., Eisenstein, G., Miller, D.A.B., and Chemla, D.S. see Koren, U.

Barlow, K.J., Taylor, S., Eccleston, W., and Kiermasz, A. see Taylor, S.

Barraud, A., Holcroft, B., Roberts, G.G., and Richard, J. see Holcroft, B.

Barriga, A., Huertas, J.L., and Sánchez-Gómez, G. see Huertas, J.L.

Barry, P.J., and Williamson, A.G. Radiowave propagation into and within a building at 927 MHz p248

Barton, T.M., Snowden, C.M., Richardson, J.R., and Ladbrooke, P.H. Narrow pulse measurement of drain characteristics of GaAs MESFETs p686

Bartosiński, B., and Zielonko, R. New classes of complementary signals p433 e867

Bartsch, H., Skorupa, W., Kreissig, U., and Hensel, E. see Skorupa, W.

Basu, N., and Bhat, K.N. see Bhat, K.N.

Batarseh, I., and Lee, C.Q. see Lee, C.Q.

Bates, R.H.T., and Murch, A.R. Deterministic-chaotic variably coloured noise p995

Bates, R.N., and Evans, D.H. see Evans, D.H.

Bates, R.N., and Feeney, S. Novel varactor-tuned millimetre-wave Gunn oscillator p714

Baudrand, H., Kaddour, M., and Ahmadpanah, M. Bias-variable characteristics of coupled coplanar waveguide on GaAs substrate p171

Baur, G., Luy, J.-F., and Kasper, E. see Luy, J.-F.

Bayes, T., Lockhart, G.B., Mehdi, A.A.A., and Al-Jalili, Y.O. see Lockhart, G.B.

Beamont, S.P., Cheung, R., Thoms, S., Doughty, G., Law, V., and Wilkinson, C.D.W. see Cheung, R.

Beaumont, S.P., Lee, K.Y., Al-Mudares, M., Wilkinson, C.D.W., Frost, J., and Stanley, C.R. see Lee, K.Y.

Bedair, S.M., Humphreys, T.P., Das, K., Wortman, J.J., Parikh, N., Chu, W.K., El-Masry, N., and Tarn, J.C.L. see Humphreys, T.P.

Bedi, J.S., and Chaudhry, G.M. see Chaudhry, G.M.

Beebe, E.D., Osinski, J.S., Zah, C.E., Bhat, R., Contolini, R.J., Lee, T.P., Cummings, K.D., and Harriott, L.R. see Osinski, J.S.

Beha, H., Blacha, A., Clauberg, R., and Seitz, H.K. see Blacha, A.

Beltram, F., Capasso, F., Sen, S., and Cho, A.Y. see Capasso, F.

Benalla, A., and Gupta, K.C. Transmission-line model for two-port rectangular microstrip patches with ports at the nonradiating edges p882

Beneking, H., Fernholz, G., Westphalen, R., and Lange, W. see Fernholz, G.

Beneking, H., Gruhle, A., and Vescan, L. see Gruhle, A.

Beneking, H., Werres, C., and Vescan, L. see Werres, C.

Beneking, H., and Emeis, N. see Emeis, N.

Bennett, J.C., Kerbyson, P., and Anderson, A.P. see Kerbyson, P.

Bennion, I., Cush, R., Trundle, C., and Kirkby, C.J.G. see Cush, R.

Benoit, J., Brosson, P., Fernier, B., Simon, J.C., and Landousies, B. see Brosson, P.

Benoit, J., Brosson, P., Joullie, A., and Sermage, B. see Brosson, P.

Bensahel, D., Regolini, J.L., Dutartre, D., Karapiperis, L., Garry, G., and Dieumegard, D. see Regolini, J.L.

Bergano, N.S., Poole, C.D., Schulte, H.J., Wagner, R.E., Nathu, V.P., Amon, J.M., and Rosenberg, R.L. see Poole, C.D.

Berger, J., Welch, D.F., Scifres, D.R., Streifer, W., and Cross, P.S. 370 mW, 1·06 μm, CW TEM_{00} output from an Nd : YAG laser rod end-pumped by a monolithic diode array p669

Berthou, H., and Falco, L. Switching characteristics of a piezoelectrical actuated evanescent-wave directional coupler p469

Besombes, C., Daoud-Ketata, K., Dubon-Chevallier, C., Bresse, J.F., and Henoc, P. see Daoud-Ketata, K.

Betti, S., De Marchis, G., Iannone, E., and Martellucci, A. Effect of the non-Lorentzian lineshape of semiconductor laser on a PSK coherent heterodyne optical receiver p1366

Betts, A.K., Taylor, J.T., and Haigh, D.G. Clocking schemes for switched-capacitor FIR decimators p1323

Bhargava, V.K., and Wang, Q. see Wang, Q.

Bhat, K.N., and Basu, N. High-pressure thermal oxidation of gallium arsenide at 250°C p1329

Bhat, R., Abeles, J.H., Chan, W.K., Kastalsky, A., Harbison, J.P., and Florez, L.T. see Abeles, J.H.

Bhat, R., Abeles, J.H., Chan, W.K., Shokoohi, F.K., and Koza, M.A. see Abeles, J.H.

Bhat, R., Hayes, J.R., Schumacher, H., and Koza, M. see Hayes, J.R.

Bhat, R., Osinski, J.S., Zah, C.E., Contolini, R.J., Beebe, E.D., Lee, T.P., Cummings, K.D., and Harriott, L.R. see Osinski, J.S.

Bhattacharya, P.K., Seo, K.S., and Gleason, K.R. see Seo, K.S.

Bigalli, O., and Pirri, F. see Pirri, F.

Bigler, E., Theobald, G., and Hauden, D. SAW quartz cuts with low stress and temperature sensitivity p514

Bilodeau, F., Hill, K.O., Johnson, D.C., and Faucher, S. see Hill, K.O.

Bilodeau, F., Johnson, D.C., Hill, K.O., and Faucher, S. see Johnson, D.C.

Bingkun, Zhou, Hanyi, Zhang, Yuanxiang, Wu, Jianying, Zhou, Jian, Li, and Zhenwu, Pan 24 h frequency stabilisation of an SLM external-cavity semiconductor laser p194

Birch, R.D. Fabrication and characterisation of circularly birefringent helical fibres p50

Bird, T.S. Mutual coupling in finite coplanar rectangular waveguide arrays p1199

Biswas, N.N., and Srinivas, S. Novel reconfigurable tree machine p1144

Blaauw, C., Houston, P.A., Margittai, A., Svilans, M.N., Puetz, N., Day, D.J., Shepherd, F.R., and Springthorpe, A.J. see Houston, P.A.

Blacha, A., Clauberg, R., Seitz, H.K., and Beha, H. 17 ps rise-time measurement by photoemission sampling p249

Black, A., Courville, C., Schultheis, G., and Heinrich, H. Optical sampling of GHz charge density modulation in silicon bipolar junction transistors p783

Black, J.G., Chen, C.L., Mahoney, L.J., Doran, S.P., Courtney, W.E., Ehrlich, D.J., and Murphy, R.A. see Chen, C.L.

Blackman, M.V., Charlton, D.E., Jenner, M.D., Purdy, D.R., Wotherspoon, J.T.M., Elliott, C.T., and White, A.M. Type conversion in $Cd_xHg_{1-x}Te$ by ion beam treatment p978

Blair, D.G., and Jones, S.K. see Jones, S.K.

Blake, C.D. Narrow-aperture SAW filter with both transducers finger-length-weighted p1248

Blanc, A.M., Blondy, J.M., Clapeau, M., and Facq, P. see Blondy, J.M.

Blank, L.C., Bryant, E.G., Lord, A., Boggis, J.M., and Stallard, W.A. 150 km optical fibre transmission network experiment with 2 Gbit/s throughput p977

Blondy, J.M., Blanc, A.M., Clapeau, M., and Facq, P. Azimuthal filtering technique for effective LP_{11} cutoff wavelength measurement in optical fibres p522

Bloom, D.M., Majidi-Ahy, R., Weingarten, K.J., Riaziat, M., and Auld, B.A. see Majidi-Ahy, R.

Bloom, D.M., Rodwell, M.J.W., and Auld, B.A. see Rodwell, M.J.W.

Bloor, D., Kolinsky, P.V., Chad, R.J., Jones, R.J., Hall, S.R., Norman, P.A., and Obhi, J.S. see Kolinsky, P.V.

Blumenthal, D.J., Prucnal, P.R., Thylen, L., and Granestrand, P. Performance of an 8×8 $LiNbO_3$ switch matrix as a gigahertz self-routing switching node p1359

Blumenthal, D.J., Prucnal, P.R., and Santoro, M.A. see Prucnal, P.R.

Böck, A.M., and Gallois, A.P. see Gallois, A.P.

Bömer, L., and Antweiler, M. Perfect binary arrays with 36 elements p730

Bobinchak, J., Lee, R.Q., and Lee, K.F. see Lee, R.Q.

Bogatyrjov, V.A., Abramov, A.A., Bubnov, M.M., and Dianov, E.M. see Abramov, A.A.

Bogert, G.A. Ti:$LiNbO_3$ intersecting waveguides p72

Bogert, G.A. Ti:$LiNbO_3$ three-waveguide polarisation splitter p37

Bogert, G.A., and Veselka, J.J. see Veselka, J.J.

Boggis, J.M., Blank, L.C., Bryant, E.G., Lord, A., and Stallard, W.A. see Blank, L.C.

Bohlin, K.E., Tove, P.A., Magnusson, U., and Tiren, J. Complementary silicon MESFET technology p205

Bon, M., Mulawka, J., and Konczykowska, A. see Mulawka, J.

Boodaghians, S., Bowers, J.E., Chipaloski, A.C., and Carlin, J.W. see Bowers, J.E.

Boone, E., De Mey, G., and Rottiers, L. Temperature distribution on ceramic substrates p26

Boothroyd, C., Razeghi, M., Tardella, A., Davies, R.A., Long, A.P., Kelly, M.J., Britton, E., and Stobbs, W.M. see Razeghi, M.

Borissov, M., Spassov, L., Yosiffov, E., Balabanova, A., and Radeva, E. New cut of a quartz resonator with a linear temperature/frequency characteristic p169

Bornemann, J., Uher, J., and Arndt, F. see Uher, J.

Bornholdt, C., Döldissen, W., Fiedler, F., Kaiser, R., and Kowalsky, W. Waveguide-integrated PIN photodiode on InP p2

Bossis, Y., Simon, J.C., Landousies, B., Doussiere, P., Fernier, B., and Padioleau, D. see Simon, J.C.

Botez, D., Morrison, C.B., and Zinkiewicz, L.M. see Morrison, C.B.

Botez, D., Pham, T., and Tran, D. 0°-phase-shift, single-lobe operation from wide-waveguide interferometric (WWI) phase-locked arrays of InGaAsP/InP ($\lambda = 1{\cdot}3\ \mu$m) diode lasers p416

Bouadma, N., Grosmaire, S., and Brillouet, F. GaAs/AlGaAs ridge waveguide laser monolithically integrated with a photodetector using ion beam etching p855

Bouadma, N., Sansonetti, P., Ribot, H., Brandon, J., Menigaux, L., and Dugrand, L. see Sansonetti, P.

Boucouvalas, A.C., and Georgiou, G. Methods for fine-tuning the wavelength response of single-mode optical-fibre taper filters p410

Boucouvalas, A.C., and Robertson, S.C. Simple technique for measurement of equalisation wavelength in single-mode optical fibres p215

Boudou, A., Doyle, B.S., Bourcerie, M., Leclaire, P., and Dars, P. see Doyle, B.S.

Bourcerie, M., Doyle, B.S., Leclaire, P., Boudou, A., and Dars, P. see Doyle, B.S.

Bowers, J.E., Chipaloski, A.C., Boodaghians, S., and Carlin, J.W. Direct fibre-optic transmission of entire microwave satellite antenna signals p185

Bowers, J.E., Koren, U., Miller, B.I., Soccolich, C., and Jan, W.Y. High-speed, polyimide-based semi-insulating planar buried heterostructures p1263

Bowers, J.E., and Gnauck, A.H. see Gnauck, A.H.

Bowling, D.R., Dinger, R.J., and White, D.J. see Dinger, R.J.

Bowron, P., and Al-Kabbani, A.S.S. see Al-Kabbani, A.S.S.

Boyd, G.D., Koch, T.L., Koren, U., Corvini, P.J., and Duguay, M.A. see Koch, T.L.

Boyd, I.W. New interpretation of structure of thermally grown silicon dioxide p411

Boyd, I.W., and Micheli, F. Wavelength dependence of optical oxidation of silicon p298 e480

Bracewell, R.N. Alternative to split-radix Hartley transform p1148

Brackett, C.A., Kobrinski, H., Bulley, R.M., Goodman, M.S., Vecchi, M.P., Curtis, L., and Gimlett, J.L. see Kobrinski, H.

Bradley, P.J., Wheatley, P., Parry, G., Midwinter, J.E., Mistry, P., and Roberts, J.S. High-contrast optoelectronic logic device using a waveguide multiple-quantum-well optical modulator p213

Bradley, P.J., Wheatley, P., Whitehead, M., Parry, G., Midwinter, J.E., Mistry, P., Pate, M.A., and Roberts, J.S. see Wheatley, P.

Bradley, R.R., Hodson, P.D., Riffat, J.R., Joyce, T.B., and Wallis, R.H. see Hodson, P.D.

Bradley, R.R., Walker, R.G., and Shephard, H.E. see Walker, R.G.

Brandon, J., Sansonetti, P., Ribot, H., Menigaux, L., Dugrand, L., and Bouadma, N. see Sansonetti, P.

Bresse, J.F., Daoud-Ketata, K., Dubon-Chevallier, C., Besombes, C., and Henoc, P. see Daoud-Ketata, K.

Brierley, M.C., and France, P.W. Neodymium-doped fluoro-zirconate fibre laser p815

Brillouet, F., Bouadma, N., and Grosmaire, S. see Bouadma, N.

Brini, J., and Balestra, F. see Balestra, F.

Britton, E., Razeghi, M., Tardella, A., Davies, R.A., Long, A.P., Kelly, M.J., Boothroyd, C., and Stobbs, W.M. see Razeghi, M.

Broberg, B., Nilsson, S., and Tanbun-Ek, T. Very low-threshold 1·53 μm DFB lasers by VPE transport p624

Broennimann, J., and Künzi, K. see Künzi, K.

Broquetas, A., Rius, J.M., Ferrando, M., Jofre, L., de los Reyes, E., and Elias, A. see Rius, J.M.

Brosson, P., Benoit, J., Joullie, A., and Sermage, B. Analysis of threshold current density in 2·2 μm GaInAsSb/GaAlAsSb/GaSb DH lasers p417

Brosson, P., Fernier, B., Benoit, J., Simon, J.C., and Landousies, B. Design and realisation of high-gain 1·5 μm semiconductor TW optical amplifiers p254

Brown, A.S., Palmateer, L.F., Tasker, P.J., Itoh, T., Wicks, G.W., and Eastman, L.F. see Palmateer, L.F.

Brown, R.C. Interpretation of compact range measurements p263

Brown, R.C., Clarricoats, P.J.B., and Zhou, H. Polarisation discrimination in shaped beam applications p238

Brown, R.L., Cella, T., Dutta, N.K., and Piccirilli, A.B. see Cella, T.

Brunnschweiler, A., and Othman, M.B. see Othman, M.B.

Bryant, E.G., Blank, L.C., Lord, A., Boggis, J.M., and Stallard, W.A. see Blank, L.C.

Bubnov, M.M., Abramov, A.A., Bogatyrjov, V.A., and Dianov, E.M. see Abramov, A.A.

Bucciarelli, T., and Nardone, A. Robustness of a modified greatest-of CFAR detector p128

Bucholtz, F., Koo, K.P., and Dandridge, A. see Koo, K.P.
Bucholtz, F., Yurek, A.M., Koo, K.P., and Dandridge, A. Low-frequency, submicrogauss fibre-optic magnetometer p985
Budišin, S.Z. Supercomplementary sets of sequences p504
Budišin, S.Z., and Popović, B.M. see Popović, B.M.
Buhl, L.L., Cimini, L.J., and Stone, J. see Cimini, L.J.
Buhl, L.L., Eisenstein, G., Tucker, R.S., Korotky, S.K., Raybon, G., Veselka, J.J., Gnauck, A.H., Kasper, B.L., and Alferness, R.C. see Eisenstein, G.
Buhl, L.L., Heismann, F., and Alferness, R.C. see Heismann, F.
Buhl, L.L., Tucker, R.S., Eisenstein, G., Korotky, S.K., Koren, U., Raybon, G., Veselka, J.J., Kasper, B.L., and Alferness, R.C. see Tucker, R.S.
Buhl, L.L., Tucker, R.S., Eisenstein, G., Korotky, S.K., Veselka, J.J., Raybon, G., Kasper, B.L., and Alferness, R.C. see Tucker, R.S.
Buhl, L.L., and Olsson, N.A. see Olsson, N.A.
Buhrer, C.F., and Carlsen, W.J. see Carlsen, W.J.
Bull, D.R., and Horrocks, D.H. Reduced-complexity digital filtering structures using primitive operations p769
Bulley, R.M., Kobrinski, H., Goodman, M.S., Vecchi, M.P., Brackett, C.A., Curtis, L., and Gimlett, J.L. see Kobrinski, H.
Burbie, G., Pitt, C.W., and Wan, Tat see Pitt, C.W.
Burgener, M.L., and Lin, T.H. Fabrication of polysilicon gate FET in laser melted silicon on silicon dioxide on PLZT p353
Burpee, D.S., Young, W.C., Curtis, L., Cheung, N.K., and Wang, S.J. see Young, W.C.
Burrows, E.C., Ohtsu, M., Liou, K.-Y., Burrus, C.A., and Eisenstein, G. see Ohtsu, M.
Burrus, C.A., Darcie, T.E., Glance, B., Gayliard, K., Talman, J.R., and Kasper, B.L. see Darcie, T.E.
Burrus, C.A., Darcie, T.E., Gnauck, A.H., Kasper, B.L., and Talman, J.R. see Darcie, T.E.
Burrus, C.A., Glance, B., Fitzgerald, P.J., Pollack, K.J., Stone, J., Eisenstein, G., and Stulz, L.W. see Glance, B.
Burrus, C.A., Glance, B., Pollock, K., Kasper, B.L., Eisenstein, G., and Stulz, L.W. see Glance, B.
Burrus, C.A., Glance, B., Stone, J., Fitzgerald, P.J., Pollock, K.J., and Stulz, L.W. see Glance, B.
Burrus, C.A., Glance, B., and Stulz, L.W. see Glance, B.
Burrus, C.A., Ohtsu, M., Liou, K.-Y., Burrows, E.C., and Eisenstein, G. see Ohtsu, M.
Burrus, C.A., Tzeng, L.D., Emkey, W.L., and Jack, C.A. see Tzeng, L.D.
Burrus, C.A., Weiner, J.S., Gossard, A.C., English, J.H., Miller, D.A.B., and Chemla, D.S. see Weiner, J.S.
Burrus, C.A., Wood, T.H., Carr, E.C., Henry, J.E., Gossard, A.C., and English, J.H. see Wood, T.H.
Burrus, C.A., Wood, T.H., Carr, E.C., Tucker, R.S., Chiu, T.-H., and Tsang, W.-T. see Wood, T.H.
Burrus, C.A., Zah, C.E., Osinski, J.S., Menocal, S.G., Tabatabaie, N., Lee, T.P., and Dentai, A.G. see Zah, C.E.
Butler, B.R., Armistead, C.J., Clements, S.J., Collar, A.J., Moule, D.J., Wheeler, S.A., Fice, M.J., and Ahmed, H. see Armistead, C.J.
Butler, J.K., Carlson, N.W., and Masin, V.J. see Carlson, N.W.
Byron, K.C. Kerr modulation of signals at 1·3 and 1·5 μm in polarisation-maintaining fibres pumped at 1·06 μm p1324

C

Caglio, N., Constant, E., Chevallier, J., and Pesant, J.C. see Constant, E.
Calvez, L.C., and Vilbe, P. see Vilbe, P.
Calzada, A., Ruiz-Moreno, S., Junyent, G., and Usandizaga, J.R. see Ruiz-Moreno, S.
Camacho-Peñalosa, C. Numerical technique for determining steady-state response of nonlinear circuits to multitone input signals p828
Camacho-Peñalosa, C., Mariscal-Rico, L., and Alonso-Pardo, A. Efficient calculation of partial derivatives in nonlinear conductances driven by periodic input signals p565
Campbell, A.C., Kesan, V.P., Crook, G.E., Maziar, C.M., Neikirk, D.P., and Streetman, B.G. Impedance switching effects in GaAs/AlAs barrier structures p926
Campbell, J.C., Chandrasekhar, S., Dentai, A.G., and Qua, G.J. see Chandrasekhar, S.
Campbell, J.C., Dentai, A.G., Joyner, C.H., and Qua, G.J. see Dentai, A.G.
Canali, C., Chiussi, F., Fantini, F., Umena, L., and Vanzi, M. Electromigration effects in power MESFET rectifying and ohmic contacts p364
Canali, C., Donzelli, G., Fantini, F., Vanzi, M., and Paccagnella, A. Gold-based gate-sinking enhanced by inhomogeneities in power MESFETs p83
Caneau, C., Zah, C.E., Osinski, J.S., Menocal, S.G., Reith, L.A., Salzman, J., Shokoohi, F.K., and Lee, T.P. see Zah, C.E.
Capasso, F., Sen, S., Beltram, F., and Cho, A.Y. Resonant tunnelling gate field-effect transistor p225
Capasso, F., Sen, S., Cho, A.Y., and Hutchinson, A.L. Resonant tunnelling electron spectroscopy p28
Capasso, F., Sen, S., Hutchinson, A.L., and Cho, A.Y. see Sen, S.
Cardinal, M., Welch, D.F., DeVito, M., Abraham, M., Kung, H., Harnagel, G., Cross, P., Scifres, D., and Streifer, W. see Welch, D.F.
Cardinal, M., Welch, D.F., Streifer, W., Scifres, D.R., and Cross, P.S. see Welch, D.F.
Carle, P.L. New accurate and simple equivalent circuit for circular E-plane bends in rectangular waveguide p531
Carlin, J.W., Bowers, J.E., Chipaloski, A.C., and Boodaghians, S. see Bowers, J.E.
Carlsen, W.J., and Buhrer, C.F. Flat passband birefringent wavelength-division multiplexers p106
Carlson, N.W., Butler, J.K., and Masin, V.J. Coupled mode analysis of wavefront properties of phased array diode lasers e306
Carlson, N.W., Evans, G.A., Hammer, J.M., and Neil, C.C. Measurement of effective index and dispersion in an index-guided surface-emitting distributed Bragg reflector laser p355
Carlson, N.W., Goldstein, B., Evans, G.A., Dinkel, N.A., and Masin, V.J. see Goldstein, B.
Carr, E.C., Wood, T.H., Burrus, C.A., Henry, J.E., Gossard, A.C., and English, J.H. see Wood, T.H.
Carr, E.C., Wood, T.H., Burrus, C.A., Tucker, R.S., Chiu, T.-H., and Tsang, W.-T. see Wood, T.H.
Carre, M., Yi-Yan, A., Carru, H., Correc, P., Chandouineau, J.P., and Dugrand, L. see Yi-Yan, A.
Carru, H., Yi-Yan, A., Correc, P., Chandouineau, J.P., Dugrand, L., and Carre, M. see Yi-Yan, A.
Carruthers, C., and Mavor, J. Anomalous oscillation in depletion-mode MOSFETs at low temperature p178
Carruthers, C., and Mavor, J. Low-noise operation of buried channel MOS transistors p1173
Cassidy, S.A., and Yennadhiou, P. Wavelength dependence of a D-fibre optical switch p1385
Cella, T., Dutta, N.K., Piccirilli, A.B., and Brown, R.L. Monolithically integrated thermoelectrically tunable distributed Bragg reflector laser p1031
Cetin, A.E., and Ansari, R. Iterative procedure for designing two-dimensional FIR filters p131
Chaabi, A., Dieulesaint, E., Royer, D., and Formery, B. see Dieulesaint, E.
Chad, R.J., Kolinsky, P.V., Jones, R.J., Hall, S.R., Norman, P.A., Bloor, D., and Obhi, J.S. see Kolinsky, P.V.
Chae, Chang-Joon, and Kwon, Young-Se GaAs/AlGaAs rooftop reflector laser for optoelectronic integrated circuits p1118
Cham, W.K. DC coefficient restoration by cosine and sine transforms p349
Champlin, K.S., Hietala, V.M., and Kwon, Y.R. see Hietala, V.M.
Chan, W.K., Abeles, J.H., Kastalsky, A., Harbison, J.P., Florez, L.T., and Bhat, R. see Abeles, J.H.
Chan, W.K., Abeles, J.H., Shokoohi, F.K., Bhat, R., and Koza, M.A. see Abeles, J.H.
Chan, W.K., Cox, H.M., Abeles, J.H., and Kelty, S.P. Langmuir-Blodgett deposited cadmium gate inverted InP-GaInAs modulation-doped field-effect transistors p1346
Chandouineau, J.P., Yi-Yan, A., Carru, H., Correc, P., Dugrand, L., and Carre, M. see Yi-Yan, A.
Chandrasekhar, S., Campbell, J.C., Dentai, A.G., and Qua, G.J. Monolithic integrated waveguide photodetector p501
Chang, Byung-hwa, Kim, Seong-Dae, and Kim, Jae-kyoon Threshold selection algorithm for extracting a uniform colour region in an image p1362
Chang, C.T., Albares, D.J., Garcia, G.A., and Reedy, R.E. see Albares, D.J.
Chang, C.Y., Wang, Y.H., Yarn, K.F., and Jame, M.S. see Wang, Y.H.
Chang, G.-K., Leblanc, H.P., and Shumate, P.W. Novel high-speed LED transmitter for single-mode fibre and wideband loop transmission systems p1338
Chang, G.-K., Reith, L.A., Leblanc, H.P., and Chin, A.K. WDM experiment using 1300/1500 nm dual-wavelength LED for single-mode fibre transmission systems p1267
Chang, J., Harada, N., and Kashiwa, S. High-frequency acousto-optic deflector using ZnO thin films deposited on an amorphous substrate p1384
Chang, K., Tahim, R.S., and Hummer, K.A. see Tahim, R.S.
Chang, K., and Gao, X.Z. see Gao, X.Z.
Chang, K., and Klein, J. Dielectrically shielded microstrip (DSM) lines p535
Chang, T.N. Numerical convergence in calculating the propagation constants by the transverse modal analysis technique p40
Chang, T.Y., Taylor, G.W., Lebby, M.S., Gnall, R.N., Sauer, N., Tell, B., and Simmons, J.G. see Taylor, G.W.
Chang, W.S.C., Lin, S.C., Jing, X.L., Chin, M.K., Walpita, L.M., and Yu, P.K.L. see Lin, S.C.
Chao, J., and Tsujii, S. New configuration of echo canceller adaptable during double talk p1314
Chao, Q.P., and Tang, Z. Fast and dense low-power multiple-valued I^2L circuit p968
Chaplin, D., and Sage, I. see Sage, I.
Charlton, D.E., Blackman, M.V., Jenner, M.D., Purdy, D.R., Wotherspoon, J.T.M., Elliott, C.T., and White, A.M. see Blackman, M.V.
Chaudhry, G.M., and Bedi, J.S. Modular memory model using state-variable approach p617
Chaves, M.B.F., and Migliora, C.G. see Migliora, C.G.
Cheetham, B.M.G. Adaptive LSP filter p89
Cheetham, B.M.G., and Freij, G.J. see Freij, G.J.
Chemla, D.S., Koren, U., Miller, B.I., Tucker, R.S., Eisenstein, G., Bar-Joseph, I., and Miller, D.A.B. see Koren, U.
Chemla, D.S., Weiner, J.S., Gossard, A.C., English, J.H., Miller, D.A.B., and Burrus, C.A. see Weiner, J.S.
Chen, C.D., Chou, Y.C., Lee, C.T., and Chu, K.C. see Chou, Y.C.
Chen, C.L., Black, J.G., Mahoney, L.J., Doran, S.P., Courtney, W.E., Ehrlich, D.J., and Murphy, R.A. GaAs monolithic microwave integrated circuit trimming using laser-direct-written tungsten microstrip lines p402
Chen, H.Z., Ghaffari, A., Morkoç, H., and Yariv, A. Very low threshold current densities (under 100 A/cm^2) in AlGaAs/GaAs single-quantum-well GRINSCH lasers grown by molecular beam epitaxy p1334
Chen, He-Ming, and Freude, W. Tables of integrals: misprint in a convolution-type integral with Gauss-Laguerre functions p966 e1211
Chen, L., Yang, K.H., and Zhang, S.Y. see Yang, K.H.
Chen, M., Schaff, W.J., Tasker, P.J., and Eastman, L.F. Self-aligned GaAs gate heterojunction SISFET p105
Chen, M., Schaff, W.J., Tasker, P.J., and Eastman, L.F. Transconductance dependence on gate length for GaAs gate SISFETs p800
Chen, P.C., Fan, C., and Yu, P.K.L. see Fan, C.
Chen, T.R., Wang, H., Liu, Y.Y., Mittelstein, M., and Yariv, A. see Wang, H.
Chen, Y.K., Wojtczuk, S.J., Ballantyne, J.M., and Wanuga, S. see Wojtczuk, S.J.
Chen, Yuh-Long, and Wei, Che-Ho Convolutional coding for BPSK system with orthogonal sounding tone on fast Rayleigh fading channel e306
Cheng, C.L., Wang, K.-W., and Zima, S.M. see Wang, K.-W.
Cheng, S.S., and Kobrinski, H. see Kobrinski, H.
Cheng, Y.H., and Okoshi, T. see Okoshi, T.
Cheung, N.K., Choy, M.M., Gimlett, J.L., Welter, R., and Kazovsky, L.G. see Choy, M.M.
Cheung, N.K., Young, W.C., Curtis, L., Wang, S.J., and Burpee, D.S. see Young, W.C.
Cheung, R., Thoms, S., Beamont, S.P., Doughty, G., Law, V., and Wilkinson, C.D.W. Reactive ion etching of GaAs using a mixture of methane and hydrogen p857
Chevallier, J., Constant, E., Caglio, N., and Pesant, J.C. see Constant, E.
Chiang, K.S. Birefringent-fibre polarisation splitters p908
Chiang, K.S. Design criterion for low-loss optical coupler tapers p112
Chiang, K.S. Mode dispersion for optical fibres of arbitrary cross-section p160
Chiang, K.S. Perturbation analysis of fused tapered single-mode fibre couplers p717
Chiang, K.S. Single-polarisation single-mode guidance in stress-induced birefringence fibres with lossy stress-applying sections p506
Chiba, K., Nojima, T., and Nishiki, S. see Nojima, T.
Chicharo, J.F., and Ng, T.S. Cramer-Rao lower bound for cascaded adaptive notch filtering p707
Chidgey, P.J., and Smith, D.W. Sampled optical time-division multiplexing of asynchronous data p1228
Chin, A.K., Chang, G.-K., Reith, L.A., and Leblanc, H.P. see Chang, G.-K.
Chin, B.H., Koszi, L.A., Temkin, H., Napholtz, S.G., and Segner, B.P. see Koszi, L.A.
Chin, M.K., Lin, S.C., Jing, X.L., Walpita, L.M., Yu, P.K.L., and Chang, W.S.C. see Lin, S.C.
Chipaloski, A.C., Bowers, J.E., Boodaghians, S., and Carlin, J.W. see Bowers, J.E.
Chiu, T.-H., Wood, T.H., Carr, E.C., Burrus, C.A., Tucker, R.S., and Tsang, W.-T. see Wood, T.H.
Chiu, T.H., Tsang, W.T., and Levi, A.F.J. Electron transport of (Al, Ga)Sb/InAs heterojunctions prepared by molecular beam epitaxy p917
Chiussi, F., Canali, C., Fantini, F., Umena, L., and Vanzi, M. see Canali, C.
Chive, M., Ledee, R., Pribetich, P., and Kennis, P. see Ledee, R.
Cho, A.Y., Capasso, F., Sen, S., and Beltram, F. see Capasso, F.
Cho, A.Y., Capasso, F., Sen, S., and Hutchinson, A.L. see Capasso, F.
Cho, A.Y., Sen, S., Capasso, F., and Hutchinson, A.L. see Sen, S.
Cho, G.-H., Shin, D.-H., and Park, S.-B. see Shin, D.-H.
Choi, W.K., Owen, A.E., Delima, J.J., and Gage, S.M. Model for the switching voltage of MISS devices based on an analogy with the thyristor p1
Choi, Y.-H., and Ra, J.-W. Simple adaptive algorithm for rejection of interference p1038
Chou, Y.C., Lee, C.T., Chen, C.D., and Chu, K.C. Growth temperature dependence of low-noise MESFET in molecular-beam epitaxy p7
Chouan, Y., Loisel, B., Pedrono, N., and Joubert, P.

see Loisel, B.
Choy, M.M., Gimlett, J.L., Welter, R., Kazovsky, L.G., and Cheung, N.K. Interferometric conversion of laser phase noise to intensity noise by single-mode fibre-optic components p1151
Christodoulides, D.N., Reith, L.A., and Saifi, M.A. Coupling efficiency and sensitivity of an LED to a single-mode fibre e251
Christodoulides, D.N., and Saifi, M.A. LED pulse distortion in single-mode fibres near the wavelength of zero dispersion e251
Christou, A., Morgan, D.V., Thomas, H., Anderson, W.T., Thompson, P., and Diskett, D.J. see Morgan, D.V.
Christou, A., and Anand, Y. see Anand, Y.
Chu, K.C., Chou, Y.C., Lee, C.T., and Chen, C.D. see Chou, Y.C.
Chu, P.L., and Desem, C. see Desem, C.
Chu, P.L., and Snyder, A.W. Theory of twin-core optical fibre frequency shifter p1101
Chu, W.K., Humphreys, T.P., Das, K., Bedair, S.M., Wortman, J.J., Parikh, N., El-Masry, N., and Tarn, J.C.L. see Humphreys, T.P.
Chua, S.J., Kooi, P.S., and Leong, M.S. Performance of a GaAlAs laser diode used for multichannel video transmission employing multiplexed UHF subcarriers p366
Chubachi, N., and Kushibiki, J. see Kushibiki, J.
Chun, Young-Yun, Park, Moon-Soo, and Hwang, Jun-Am see Park, Moon-Soo
Chung, H.K., Baier, S.M., Lee, G.Y., Fure, B.J., and Cirillo, N.C. see Baier, S.M.
Chung, Hung-Yuan, and Sun, York-Yih Analysis of singular systems using Taylor series approach e306
Chung, Hung-yuan, and Sun, York-yih Taylor series approach to functional approximation for inversion of Laplace transforms p480 e306
Chung, K.S. Zero-crossing estimation in signal generation of narrowband digita' angle-modulated signals p697
Chung, Y.C., and Shay, T.M. 450 Hz relative frequency stability in an AlGaAs diode laser p1044
Cimini, L.J., Habbab, I.M.I., John, R.K., and Saleh, A.A.M. Preservation of polarisation orthogonality through a linear optical system p1365
Cimini, L.J., Stone, J., and Buhl, L.L. Optical-fibre Fabry–Perot frequency discriminator for communications applications p463
Cinguino, P., Genova, F., Morasca, S., Rigo, C., and Stano, A. Low-loss ridge optical waveguides in quaternary InGaAlAs/InP grown by MBE p235
Cirillo, N.C., Arch, D.K., Abrokwah, J.K., Vold, P.J., Fraasch, A.M., and Grung, B.L. see Arch, D.K.
Cirillo, N.C., Baier, S.M., Lee, G.Y., Chung, H.K., and Fure, B.J. see Baier, S.M.
Citerne, J., Lepeltier, P., and Floc'h, J.M. see Lepeltier, P.
Clapeau, M., Blondy, J.M., Blanc, A.M., and Facq, P. see Blondy, J.M.
Clarricoats, P.J.B., Brown, R.C., and Zhou, H. see Brown, R.C.
Clauberg, R., Blacha, A., Seitz, H.K., and Beha, H. see Blacha, A.
Cleaver, J.R.A., Kirk, E.C.G., and Ahmed, H. see Kirk, E.C.G.
Clemans, J.E., Reynolds, C.L., and Gibson, W.C. see Reynolds, C.L.
Clements, S., Fice, M.J., and Ahmed, H. see Fice, M.J.
Clements, S.J., Armistead, C.J., Butler, B.R., Collar, A.J., Moule, D.J., Wheeler, S.A., Fice, M.J., and Ahmed, H. see Armistead, C.J.
Cline, T.W., Park, Y.K., Granlund, S.W., Kuo, C.Y., Dixon, M., Smith, R.W., Dutta, N.K., and Vannucci, G. see Park, Y.K.
Cochran, S.R. Microwave amplifier based RF optical receivers p1283
Cochrane, P., Hunwicks, A.R., and Rosher, P.A. Novel fibre break locator for optical duplex transmission systems p440
Cochrane, P., and Gangopadhyay, R. see Gangopadhyay, R.
Cohen, S.S., and Gildenblat, G.S. see Gildenblat, G.S.
Coldren, L.A., Alping, A., and Wu, X.S. see Alping, A.
Colinge, J.P. Voltage-controlled bipolar-MOS (VCBM) ring oscillator p1023
Colinge, J.P., and Kamins, T.I. CMOS circuits made in thin SIMOX films p1162 e1397
Collar, A.J., Armistead, C.J., Butler, B.R., Clements, S.J., Moule, D.J., Wheeler, S.A., Fice, M.J., and Ahmed, H. see Armistead, C.J.
Collar, A.J., Murison, R.F., Houghton, A.J.N., Goodwin, A.R., and Davies, I.G.A. see Murison, R.F.
Colleran, W.T., and Abidi, A.A. Wideband monolithic GaAs amplifier using cascodes p951
Collins, D., Hinchliffe, S., and Hobson, L. Optimised class-E amplifier with load variation p973
Constant, E., Caglio, N., Chevallier, J., and Pesant, J.C. Fabrication of a new type of field-effect transistor using neutralisation of shallow donors by atomic hydrogen in *n*-GaAs (Si) p841
Contolini, R.J., Osinski, J.S., Zah, C.E., Bhat, R., Beebe, E.D., Lee, T.P., Cummings, K.D., and Harriott, L.R. see Osinski, J.S.
Cornbleet, S. Aspheric double mirror systems p199
Correc, P., Yi-Yan, A., Carru, H., Chandouineau, J.P., Dugrand, L., and Carre, M. see Yi-Yan, A.
Corvini, P.J., Koch, T.L., Koren, U., Boyd, G.D., and Duguay, M.A. see Koch, T.L.
Costa, R.A., Herman, J.R., Duggan, C.C., Thompson, W.I., and DeLuca, D.M. see Herman, J.R.
Cotter, D., Ainslie, B.J., and Girdlestone, H.P. see Ainslie, B.J.
Courtney, W.E., Chen, C.L., Black, J.G., Mahoney, L.J., Doran, S.P., Ehrlich, D.J., and Murphy, R.A. see Chen, C.L.
Courville, C., Black, A., Schultheis, G., and Heinrich, H. see Black, A.
Cox, H.M., Chan, W.K., Abeles, J.H., and Kelty, S.P. see Chan, W.K.
Craig, K.H., and Kennedy, G.R. Case study of line-of-sight microwave multipath propagation p483
Craig, S.P., Gouveia-Neto, A.S., Gomes, A.S.L., Taylor, J.R., and Ainslie, B.J. see Gouveia-Neto, A.S.
Craig, S.P., Liu, K., Digonnet, M., Shaw, H.J., and Ainslie, B.J. see Liu, K.
Craig, S.P., Millar, C.A., Miller, I.D., Ainslie, B.J., and Armitage, J.R. see Millar, C.A.
Cremer, C., Heise, G., März, R., Riechert, H., and Schienle, M. InGaAsP Y-branch grating demultiplexer p321
Crespo, P., Kazovsky, L.G., Elrefaie, A.F., Meissner, P., Welter, R., Gimlett, J., and Smith, R.W. see Kazovsky, L.G.
Crimes, G.J., Ashley, T., Elliott, C.T., White, A.M., and Harker, A.T. see Ashley, T.
Crisman, E.E., Lee, J.I., Stiles, P.J., and Gregory, O.J. Characterisation of *N*-channel germanium MOSFET with gate insulator formed by high-pressure thermal oxidation p8
Crook, G.E., Campbell, A.C., Kesan, V.P., Maziar, C.M., Neikirk, D.P., and Streetman, B.G. see Campbell, A.C.
Cross, P., Welch, D.F., DeVito, M., Cardinal, M., Abraham, M., Kung, H., Harnagel, G., Scifres, D., and Streifer, W. see Welch, D.F.
Cross, P.S., Berger, J., Welch, D.F., Scifres, D.R., and Streifer, W. see Berger, J.
Cross, P.S., Harnagel, G.L., Lennon, C.R., DeVito, M., and Scifres, D.R. see Harnagel, G.L.
Cross, P.S., Welch, D.F., Cardinal, M., Streifer, W., and Scifres, D.R. see Welch, D.F.
Cross, P.S., Welch, D.F., Scifres, D.R., and Streifer, W. see Welch, D.F.
Crowe, A., and Jack, M.A. Globally optimising formant tracker using generalised centroids p1019
Cucchi, S., Glavina, R., and Sicuranza, G.L. see Glavina, R.
Cullen, T.J., Assanto, G., Gabel, A., Seaton, C.T., Stegeman, G.I., and Ironside, C.N. see Assanto, G.
Culshaw, B., Shabeer, M., and Andonovic, I. see Shabeer, M.
Culshaw, B., Uttamchandani, D., Thornton, K.E.B., and Nixon, J. see Uttamchandani, D.
Culshaw, B., Uttamchandani, D., and Thornton, K.E.B. see Uttamchandani, D.
Cummings, K.D., Osinski, J.S., Zah, C.E., Bhat, R., Contolini, R.J., Beebe, E.D., Lee, T.P., and Harriott, L.R. see Osinski, J.S.
Cunningham, C.T., Davies, S.R., and Little, L.T. see Davies, S.R.
Cunningham, D.G., Garnham, R.A., and Stallard, W.A. see Garnham, R.A.
Curtins, H., Wyrsch, N., and Shah, A.V. High-rate deposition of amorphous hydrogenated silicon: effect of plasma excitation frequency p228
Curtis, L., Kobrinski, H., Bulley, R.M., Goodman, M.S., Vecchi, M.P., Brackett, C.A., and Gimlett, J.L. see Kobrinski, H.
Curtis, L., Young, W.C., Cheung, N.K., Wang, S.J., and Burpee, D.S. see Young, W.C.
Cush, R. Optimum control beam angle for a biased optical bistable device p619
Cush, R., Trundle, C., Kirkby, C.J.G., and Bennion, I. Bistable optical switching and logic elements in photochromic fulgides with single-wavelength illumination p419
Cuthbert, L.G., and Sharestani, E. see Sharestani, E.
Cyr, N., Villeneuve, B., and Tetu, M. see Villeneuve, B.
Czarnul, Z., and Tsividis, Y. Independent tuning of quality factor and unity-gain frequency in a transconductance-capacitance integrator d913

D

Dahele, J.S., Mitchell, R.J., Luk, K.M., and Lee, K.F. Effect of curvature on characteristics of rectangular patch antenna p748
Dandridge, A., Bucholtz, F., Yurek, A.M., and Koo, K.P. see Bucholtz, F.
Dandridge, A., Kersey, A.D., Yurek, A.M., and Weller, J.F. see Kersey, A.D.
Dandridge, A., Koo, K.P., and Bucholtz, F. see Koo, K.P.
Dandridge, A., Mermelstein, M.D., and Askins, C. see Mermelstein, M.D.
Dandridge, A., Tveten, A.B., Kersey, A.D., and Yurek, A.M. Multiplexing of interferometric sensors using phase-generated carrier techniques p665 e867
Dandridge, A., and Kersey, A.D. see Kersey, A.D.
Dangla, J., Palmier, J.F., Sibille, A., and Harmand, J.C. see Palmier, J.F.
Daniel, H., Leaver, K.D., and Green, M. see Leaver, K.D.
Daniel, J.P. Directivity of linear microstrip arrays p897
Daniel, J.P., Mahdjoubi, K., Penard, E., and Terret, C. see Mahdjoubi, K.
Daoud-Ketata, K., Dubon-Chevallier, C., Besombes, C., Bresse, J.F., and Henoc, P. Molybdenum germanide ohmic contact to *n*-GaAs p17
Darcie, T.E., Burrus, C.A., Gnauck, A.H., Kasper, B.L., and Talman, J.R. Two-channel system demonstration of differential frequency-deviation multiplexing p1278
Darcie, T.E., Glance, B., Gayliard, K., Talman, J.R., Kasper, B.L., and Burrus, C.A. Polarisation-diversity receiver for coherent FSK communications p1369
Darcie, T.E., Jopson, R.M., Gayliard, K.T., Ku, R.T., Tench, R.E., Rice, T.C., and Olsson, N.A. see Jopson, R.M.
Darcie, T.E., Jopson, R.M., and Tkach, R.W. Intermodulation distortion in optical amplifiers from carrier-density modulation p1392
Darcie, T.E., and Iannone, P. see Iannone, P.
Darnell, M., and Jowett, A.P. see Jowett, A.P.
Dars, P., Doyle, B.S., Bourcerie, M., Leclaire, P., and Boudou, A. see Doyle, B.S.
Darwazeh, I., and Wilson, B. see Wilson, B.
Das, K. Increased carrier lifetimes in epitaxial silicon layers on buried silicon nitride produced by ion implantation d579
Das, K., Humphreys, T.P., Bedair, S.M., Wortman, J.J., Parikh, N., Chu, W.K., El-Masry, N., and Tarn, J.C.L. see Humphreys, T.P.
Daut, D.G., Elrefaie, A.F., Wagner, R.E., and Atlas, D.A. see Elrefaie, A.F.
Davey, S.T., Scott, E.G., and Davies, G.J. see Scott, E.G.
David, J.P.R., Whitehead, M., Parry, G., Roberts, J.S., Mistry, P., and Li Kam Wa, P. see Whitehead, M.
Davies, G.J., Hill, J.R., Dunn, P.L., Oliver, S.N., Pantelis, P., and Rush, J.D. see Hill, J.R.
Davies, G.J., Scott, E.G., and Davey, S.T. see Scott, E.G.
Davies, I.G.A., Murison, R.F., Houghton, A.J.N., Goodwin, A.R., and Collar, A.J. see Murison, R.F.
Davies, J.I., Hodson, P.D., and Wallis, R.H. see Hodson, P.D.
Davies, J.I., Moseley, A.J., Scott, M.D., Williams, P.J., Wallis, R.H., and Riffat, J.R. see Moseley, A.J.
Davies, J.I., Moseley, A.J., Urquhart, J., Hodson, P.D., and Riffat, J.R. see Moseley, A.J.
Davies, R.A., Kelly, M.J., and Kerr, T.M. Tailoring the *I/V* characteristics of a superlattice tunnel diode p90
Davies, R.A., Razeghi, M., Tardella, A., Long, A.P., Kelly, M.J., Britton, E., Boothroyd, C., and Stobbs, W.M. see Razeghi, M.
Davies, S.R., Little, L.T., and Cunningham, C.T. Low-noise SIS heterodyne receiver at 230 GHz p946
Davis, A.W., Pettitt, M.J., Remedios, D., Hadjifotiou, A., and Wright, S. see Pettitt, M.J.
Davis, R.J., Tihanyi, P., Wagner, D.K., Vollmer, H.J., Roza, A.J., Harding, C.M., and Wolf, E.D. see Tihanyi, P.
Davison, A.S., and White, I.H. Highly efficient linearly polarised Raman generation in a germania-core optical fibre p1343
Day, D.J., Houston, P.A., Blaauw, C., Margittai, A., Svilans, M.N., Puetz, N., Shepherd, F.R., and Springthorpe, A.J. see Houston, P.A.
de Cogan, D., and Henini, M. Nonlinear thermal effects in thin-film conductors on insulating substrates p552
de Heij, W.J.A., and Seevinck, E. Independent tuning of quality factor and unity-gain frequency in a transconductance-capacitance integrator d913
de Jong, G.G., and Abu-Zeid, M.M. see Abu-Zeid, M.M.
de los Reyes, E., Rius, J.M., Ferrando, M., Jofre, L., Elias, A., and Broquetas, A. see Rius, J.M.
di Forte-Poisson, M.A., Delacourt, D., Papuchon, M., and Razeghi, M. see Delacourt, D.
De La Rue, R.M., Duffy, J.F., and Al-Shukri, S.M. see Duffy, J.F.
De Marchis, G., Betti, S., Iannone, E., and Martellucci, A. see Betti, S.
De Mey, G., Boone, E., and Rottiers, L. see Boone, E.
DeFreez, R.K., Elliott, R.A., Hartnett, K., and Welch, D.F. Quasi-instantaneous (< 20 ps) phase locking in single-lobe Y-coupled laser diode arrays p589
DeFreez, R.K., Puretz, J., Elliott, R.A., Orloff, J., and Paoli, T.L. see Puretz, J.
DeLuca, D.M., Herman, J.R., Duggan, C.C., Thompson, W.I., and Costa, R.A. see Herman, J.R.
DeVito, M., Harnagel, G.L., Cross, P.S., Lennon, C.R., and Scifres, D.R. see Harnagel, G.L.
DeVito, M., Welch, D.F., Cardinal, M., Abraham, M., Kung, H., Harnagel, G., Cross, P., Scifres, D., and Streifer, W. see Welch, D.F.
Dean, D.J. Temperature distribution on ceramic substrates p26
Dean, D.J. Thermal model of laser diode arrays p457

Debarge, G., and Gallion, P. see Gallion, P.
Deconinck, P., Wolny, M., Aguila, T., Moroni, D., and Andre, J.P. see Wolny, M.
Deichmann, P., and Rønn, L. see Rønn, L.
Delacourt, D., Papuchon, M., di Forte-Poisson, M.A., and Razeghi, M. Very low-loss GaInAs/InP optical waveguides for the 10·6 μm wavelength p451
Delima, J.J., Choi, W.K., Owen, A.E., and Gage, S.M. see Choi, W.K.
Den Dulk, R.C., and Haartsen, J.C. see Haartsen, J.C.
Dentai, A.G., Campbell, J.C., Joyner, C.H., and Qua, G.J. InGaAs PIN photodiodes grown on GaAs substrates by metal organic vapour phase epitaxy p38
Dentai, A.G., Chandrasekhar, S., Campbell, J.C., and Qua, G.J. see Chandrasekhar, S.
Dentai, A.G., Zah, C.E., Osinski, J.S., Menocal, S.G., Tabatabaie, N., Lee, T.P., and Burrus, C.A. see Zah, C.E.
Denyer, P.B., McGregor, M.S., Smith, S.G., and Murray, A.F. see McGregor, M.S.
Denyer, P.B., Nagara, S., Smith, S.G., and Keightley, M. see Nagara, S.
Deri, R.J., Kapon, E., and Schiavone, L.M. Bend losses in GaAs/AlGaAs optical waveguides p845
Deschacht, D., Auvergne, D., and Robert, M. see Auvergne, D.
Desem, C., and Chu, P.L. Soliton propagation in the presence of source chirping and mutual interaction in single-mode optical fibres p260
Deshpande, M.D., and Reddy, C.J. see Reddy, C.J.
Deval, P., Valencic, V., and Krummenacher, F. see Valencic, V.
Di Bello, C. Quasisinusoidal oscillators with cubic-type nonlinearity p20
Dianov, E.M., Abramov, A.A., Bogatyrjov, V.A., and Bubnov, M.M. see Abramov, A.A.
Dianov, E.M., Vasiljev, A.V., Dmitruk, L.N., and Plotnichenko, V.G. see Vasiljev, A.V.
Dietrich, E., Enning, B., Gross, R., and Knupke, H. Heterodyne transmission of a 560 Mbit/s optical signal by means of polarisation shift keying p421
Dietrich, H., Thompson, P., Anand, Y., Higgins, V., and Hillson, J. see Thompson, P.
Dieulesaint, E., Mazerolle, D., and Royer, D. YAG resonator p581
Dieulesaint, E., Royer, D., Chaabi, A., and Formery, B. Lamb wave graphic tablet p982
Dieumegard, D., Regolini, J.L., Dutartre, D., Bensahel, D., Karapiperis, L., and Garry, G. see Regolini, J.L.
Digonnet, M., Liu, K., Shaw, H.J., Ainslie, B.J., and Craig, S.P. see Liu, K.
Dimitrijev, S., Župac, D., and Stojadinović, N. New analytical expression for the drain current of short-channel MOS transistors in the triode region p862
Dinger, R.J., White, D.J., and Bowling, D.R. 10 GHz space power combiner with parasitic injection locking p397
Dinkel, N.A., Goldstein, B., Carlson, N.W., Evans, G.A., and Masin, V.J. see Goldstein, B.
Diskett, D.J., Morgan, D.V., Thomas, H., Anderson, W.T., Thompson, P., and Christou, A. see Morgan, D.V.
Dixon, M., Park, Y.K., Granlund, S.W., Kuo, C.Y., Cline, T.W., Smith, R.W., Dutta, N.K., and Vannucci, G. see Park, Y.K.
Dmitruk, L.N., Vasiljev, A.V., Dianov, E.M., and Plotnichenko, V.G. see Vasiljev, A.V.
Döldissen, W., Bornholdt, C., Fiedler, F., Kaiser, R., and Kowalsky, W. see Bornholdt, C.
Dolfi, D.W., Jungerman, R.L., Johnsen, C.A., and Nazarathy, M. see Jungerman, R.L.
Donaldson, A., and Wong, K.K. Phase-matched mode convertor in $LiNbO_3$ using near-Z-axis propagation p1378
Dong, Tian-Lin New approach to analysing conductor-dielectric periodic structures p1231
Donzelli, G., Canali, C., Fantini, F., Vanzi, M., and Paccagnella, A. see Canali, C.
Doran, S.P., Chen, C.L., Black, J.G., Mahoney, L.J., Courtney, W.E., Ehrlich, D.J., and Murphy, R.A. see Chen, C.L.
Dorey, M., Glavas, E., Townsend, P.D., Droungas, G., Wong, K.K., and Allen, L. see Glavas, E.
Dougherty, W., and Thaniyavarn, S. see Thaniyavarn, S.
Doughty, G., Cheung, R., Thoms, S., Beamont, S.P., Law, V., and Wilkinson, C.D.W. see Cheung, R.
Doussiere, P., Simon, J.C., Landousies, B., Bossis, Y., Fernier, B., and Padioleau, D. see Simon, J.C.
Doyle, B.S., Bourcerie, M., Leclaire, P., Boudou, A., and Dars, P. Hot electron degradation in the source of asymmetrical LDD structures p1356
Doyle, O. Measuring modulus and phase of chirp/modulated power ratio p133
Drexhage, M.G., Quimby, R.S., and Suscavage, M.J. see Quimby, R.S.
Drexhage, M.G., Schroeder, J., Hwa, L.G., Shyong, M.C., Floudas, G.A., and Thompson, D.A. see Schroeder, J.
Driessen, P.F. Binary frame synchronisation sequences for packet radio p1190
Driver, R., Percival, T.M.P., and Thorn, J.S. see Percival, T.M.P.
Droungas, G., Glavas, E., Townsend, P.D., Dorey, M., Wong, K.K., and Allen, L. see Glavas, E.
Drummond, E.I. Resistance of Ti : $LiNbO_3$ devices to ionising radiation p1214 e1397
Dubon-Chevallier, C., Daoud-Ketata, K., Besombes, C., Bresse, J.F., and Henoc, P. see Daoud-Ketata, K.
Dubost, G. Theoretical radiation resistance of an isolated slot ring resonator p928
Duffy, J.F., Al-Shukri, S.M., and De La Rue, R.M. Guided-wave acousto-optic interaction on proton-exchanged lithium tantalate p849
Duggan, C.C., Herman, J.R., Thompson, W.I., Costa, R.A., and DeLuca, D.M. see Herman, J.R.
Dugrand, L., Sansonetti, P., Ribot, H., Brandon, J., Menigaux, L., and Bouadma, N. see Sansonetti, P.
Dugrand, L., Yi-Yan, A., Carru, H., Correc, P., Chandouineau, J.P., and Carre, M. see Yi-Yan, A.
Duguay, M.A., Koch, T.L., Koren, U., Boyd, G.D., and Corvini, P.J. see Koch, T.L.
Dumas, J.-M., Garat, F., and Lecrosnier, D. Development of gate-lag effect on GaAs power MESFETs during aging p139
Duncan, G., Huang, X.D., and Jack, M.A. see Huang, X.D.
Dunn, P.L., Hill, J.R., Davies, G.J., Oliver, S.N., Pantelis, P., and Rush, J.D. see Hill, J.R.
Dunstan, D.J., Greene, P.D., Prins, A.D., and Adams, A.R. see Greene, P.D.
Durteste, Y., and Monerie, M. see Monerie, M.
Dutartre, D., Regolini, J.L., Bensahel, D., Karapiperis, L., Garry, G., and Dieumegard, D. see Regolini, J.L.
Dutta Roy, S.C., and Rajagopal, L.R. see Rajagopal, L.R.
Dutta, N.K., Cella, T., Piccirilli, A.B., and Brown, R.L. see Cella, T.
Dutta, N.K., Park, Y.K., Granlund, S.W., Kuo, C.Y., Dixon, M., Cline, T.W., Smith, R.W., and Vannucci, G. see Park, Y.K.
Dutta, N.K., and Olsson, N.A. Electroabsorption in GaAs quantum-well waveguides p853

E

Eames, R., and Evans, R.A. see Evans, R.A.
Eastman, L.F., Chen, M., Schaff, W.J., and Tasker, P.J. see Chen, M.
Eastman, L.F., Palmateer, L.F., Tasker, P.J., Itoh, T., Brown, A.S., and Wicks, G.W. see Palmateer, L.F.
Eccleston, W., Taylor, S., Barlow, K.J., and Kiermasz, A. see Taylor, S.
Eccleston, W., Taylor, S., and Watkinson, P. see Taylor, S.
Edagawa, N., Mochizuki, K., and Iwamoto, Y. Simulataneous amplification of wavelength-division-multiplexed signals by a highly efficient fibre Raman amplifier pumped by high-power semiconductor lasers p196
Eguchi, M., Hayata, K., Koshiba, M., and Suzuki, M. see Hayata, K.
Ehrlich, D.J., Chen, C.L., Black, J.G., Mahoney, L.J., Doran, S.P., Courtney, W.E., and Murphy, R.A. see Chen, C.L.
Eisenhauer, W., and Richter, H. Light coupling from a semiconductor laser into a polarisation-maintaining single-mode fibre p201
Eisenstein, G., Glance, B., Fitzgerald, P.J., Pollack, K.J., Stone, J., Burrus, C.A., and Stulz, L.W. see Glance, B.
Eisenstein, G., Glance, B., Pollock, K., Burrus, C.A., Kasper, B.L., and Stulz, L.W. see Glance, B.
Eisenstein, G., Johnson, B.C., and Raybon, G. Travelling-wave optical amplifier at 1·3 μm p1020
Eisenstein, G., Jopson, R.M., Hall, K.L., Raybon, G., and Whalen, M.S. see Jopson, R.M.
Eisenstein, G., Koren, U., Miller, B.I., Tucker, R.S., Bar-Joseph, I., Miller, D.A.B., and Chemla, D.S. see Koren, U.
Eisenstein, G., Ohtsu, M., Liou, K.-Y., Burrows, E.C., and Burrus, C.A. see Ohtsu, M.
Eisenstein, G., Tucker, R.S., Korotky, S.K., Buhl, L.L., Veselka, J.J., Raybon, G., Kasper, B.L., and Alferness, R.C. see Tucker, R.S.
Eisenstein, G., Tucker, R.S., Korotky, S.K., Koren, U., Raybon, G., Veselka, J.J., Buhl, L.L., Kasper, B.L., and Alferness, R.C. see Tucker, R.S.
Eisenstein, G., Tucker, R.S., Korotky, S.K., Raybon, G., Veselka, J.J., Buhl, L.L., Gnauck, A.H., Kasper, B.L., and Alferness, R.C. Optical time-division multiplexed transmission system experiment at 8 Gbit/s p1115
El Fatatry, A., and Shipley, S.P. see Shipley, S.P.
El Mashade, M.B., and Arnaud, J. Accuracy of Fabry–Perot method of semiconductor laser gain measurement p568
El-Amawy, A. Improving the performance of non-planar systolic architectures through increased fan-out p765
El-Masry, N., Humphreys, T.P., Das, K., Bedair, S.M., Wortman, J.J., Parikh, N., Chu, W.K., and Tarn, J.C.L. see Humphreys, T.P.
Elias, A., Rius, J.M., Ferrando, M., Jofre, L., de los Reyes, E., and Broquetas, A. see Rius, J.M.
Elliott, C.T., Ashley, T., White, A.M., Crimes, G.J., and Harker, A.T. see Ashley, T.
Elliott, C.T., Blackman, M.V., Charlton, D.E., Jenner, M.D., Purdy, D.R., Wotherspoon, J.T.M., and White, A.M. see Blackman, M.V.
Elliott, R.A., DeFreez, R.K., Hartnett, K., and Welch, D.F. see DeFreez, R.K.
Elliott, R.A., Puretz, J., DeFreez, R.K., Orloff, J., and Paoli, T.L. see Puretz, J.
Elrefaie, A.E., Stern, M., Millicker, D.J., and Runge, K. see Stern, M.
Elrefaie, A.F., Kazovsky, L.G., Meissner, P., Welter, R., Crespo, P., Gimlett, J., and Smith, R.W. see Kazovsky, L.G.
Elrefaie, A.F., Wagner, R.E., Atlas, D.A., and Daut, D.G. Chromatic dispersion limitations in coherent optical fibre transmission systems p756
Emeis, N., and Beneking, H. InP/GaInAs heterojunction bipolar transistors with improved electrical characteristics grown on strained buffer layers p295
Emkey, W.L., Tzeng, L.D., Jack, C.A., and Burrus, C.A. see Tzeng, L.D.
Emura, K., Yamaguchi, M., Kitamura, M., Mito, I., and Kobayashi, K. see Yamaguchi, M.
Emura, K., Yamazaki, S., Murata, S., Komatsu, K., Koizumi, Y., and Fujita, S. see Yamazaki, S.
English, J.H., Weiner, J.S., Gossard, A.C., Miller, D.A.B., Chemla, D.S., and Burrus, C.A. see Weiner, J.S.
English, J.H., Wood, T.H., Carr, E.C., Burrus, C.A., Henry, J.E., and Gossard, A.C. see Wood, T.H.
Enjeti, P., and Lindsay, J.F. Solving nonlinear equations of harmonic elimination PWM in power control p656
Enning, B., Dietrich, E., Gross, R., and Knupke, H. see Dietrich, E.
Enoki, T., Osafune, K., Muraguchi, M., and Ohwada, K. see Osafune, K.
Epler, J.E., Thornton, R.L., and Paoli, T.L. Dependence of central-lobe output power on fill factor of an in-phase laser array p754
Essebar, A., and Saquet, P. see Saquet, P.
Esterowitz, L., Kintz, G.J., and Allen, R. see Kintz, G.J.
Eswaran, C., and Prasad, K.S. see Prasad, K.S.
Evans, B.G., and Kondoz, A. see Kondoz, A.
Evans, B.G., and Zarkadis, D.J. see Zarkadis, D.J.
Evans, D.H., and Bates, R.N. Novel 93 GHz injection-locked impatt oscillator p771
Evans, G.A., Carlson, N.W., Hammer, J.M., and Neil, C.C. see Carlson, N.W.
Evans, G.A., Goldstein, B., Carlson, N.W., Dinkel, N.A., and Masin, V.J. see Goldstein, B.
Evans, R.A., and Eames, R. Modified bit-level systolic inner product/convolver architecture with increased throughput p460
Excell, P.S., and Sid Ahmed, S.A.I. see Sid Ahmed, S.A.I.
Eydgahi, A.M., and Singh, H. Family of reduced-order models for linear multivariable systems p1178
Ezis, A., Rai, A.K., and Langer, D.W. Lateral protrusions of ohmic contacts to AlGaAs/GaAs MODFET material p113

F

Facq, P., Blondy, J.M., Blanc, A.M., and Clapeau, M. see Blondy, J.M.
Fairhurst, M.C., and Abdel Wahab, H.M.S. Approach to performance optimisation in frequency-weighted memory network pattern classifiers p1116
Faist, J., Reinhart, F.K., and Martin, D. Comparison of phase modulation of GaAs/AlGaAs double heterostructures p1391
Falco, L., and Berthou, H. see Berthou, H.
Fan, C., Yu, P.K.L., and Chen, P.C. High-speed, self-passivated InGaAs PIN photodiode for microwave fibre links p571
Fan, C., and Yu, P.K.L. Self-aligned diffusion technique for n-InP JFETs p981
Fang, J., Zhang, X., and Mei, K.K. Dispersion characteristics of microstrip lines in the vicinity of a coplanar ground p1142
Fantini, F., Canali, C., Chiussi, F., Umena, L., and Vanzi, M. see Canali, C.
Fantini, F., Canali, C., Donzelli, G., Vanzi, M., and Paccagnella, A. see Canali, C.
Farahi, F., Gerges, A.S., Newson, T.P., Jones, J.D.C., and Jackson, D.A. see Gerges, A.S.
Farhat, K.S. Technique for fast and accurate prediction of antenna far-field patterns p609
Farnell, G.W., Safaai-Jazi, A., and Jen, C.K. see Safaai-Jazi, A.
Farries, M.C., Russell, P.St.J., Fermann, M.E., and Payne, D.N. Second-harmonic generation in an optical fibre by self-written $\chi^{(2)}$ grating p322
Faucher, S., Hill, K.O., Johnson, D.C., and Bilodeau, F. see Hill, K.O.
Faucher, S., Johnson, D.C., Hill, K.O., and Bilodeau, F. see Johnson, D.C.
Faulkner, D.W., Stern, J.R., Ballance, J.W., Hornung, S., Payne, D.B., and Oakley, K. see Stern, J.R.
Favennec, P.N., L'Haridon, H., Le Corre, A., Salvi, M., and Gauneau, M. Nondiffusion and 1·54 μm luminescence of erbium implanted in InP p684
Feeney, S., and Bates, R.N. see Bates, R.N.
Feng, I.J., Riaziat, M., Majidi-Ahy, R., and Auld, B.A. see Riaziat, M.
Feng, Tian, Yizun, Wu, Kejian, Guan, and Tong, Yu see Yizun, Wu
Feng, Tian, Yizun, Wu, Xinwei, Yang, and Tong, Yu see Yizun, Wu

Fermann, M.E., Farries, M.C., Russell, P.St.J., and Payne, D.N. see Farries, M.C.
Fernholz, G., Westphalen, R., Lange, W., and Beneking, H. Enhanced Schottky barrier heights on *n*-type $Ga_{0.47}In_{0.53}As$ by Be implantation p722
Fernier, B., Brosson, P., Benoit, J., Simon, J.C., and Landousies, B. see Brosson, P.
Fernier, B., Simon, J.C., Landousies, B., Bossis, Y., Doussiere, P., and Padioleau, D. see Simon, J.C.
Ferrando, M., Rius, J.M., Jofre, L., de los Reyes, E., Elias, A., and Broquetas, A. see Rius, J.M.
Ferreira, H.C., Hope, J.F., and Nel, A.L. see Hope, J.F.
Ferreira, H.C., Stegmann, W. de V., and Wyman, C.R. Comparison between the Jacoby–Kost and Horiguchi–Morita binary two-thirds rate modulation codes p837
Fice, M.J., Ahmed, H., and Clements, S. Fabrication of first-order gratings for 1·5 μm DFB lasers by high-voltage electron-beam lithography p590
Fice, M.J., Armistead, C.J., Butler, B.R., Clements, S.J., Collar, A.J., Moule, D.J., Wheeler, S.A., and Ahmed, H. see Armistead, C.J.
Fiedler, F., Bornholdt, C., Döldissen, W., Kaiser, R., and Kowalsky, W. see Bornholdt, C.
Findakly, T.K., Suchoski, P.G., and Leonberger, F.J. see Suchoski, P.G.
Fischer, G. Simple and effective frequency stabilisation for HeNe lasers at 1·52 μm p206
Fitzgerald, P.J., Glance, B., Pollack, K.J., Stone, J., Burrus, C.A., Eisenstein, G., and Stulz, L.W. see Glance, B.
Fitzgerald, P.J., Glance, B., Stone, J., Pollock, K.J., Burrus, C.A., and Stulz, L.W. see Glance, B.
Fleming, D.A., MacChesney, J.B., Johnson, D.W., and Walz, F.W. see MacChesney, J.B.
Fleming, S.C. Preferred approaches to the determination of optical fibre mode field diameter p338
Fletcher, I. Comparison of regenerator tolerance to sinusoidal and Gaussian alignment jitter p67
Floc'h, J.M., Lepeltier, P., and Citerne, J. see Lepeltier, P.
Florez, L.T., Abeles, J.H., Chan, W.K., Kastalsky, A., Harbison, J.P., and Bhat, R. see Abeles, J.H.
Floru, F., Silard, A., Ştefan, C., and Nani, G. see Silard, A.
Floudas, G.A., Schroeder, J., Hwa, L.G., Shyong, M.C., Thompson, D.A., and Drexhage, M.G. see Schroeder, J.
Formery, B., Dieulesaint, E., Royer, D., and Chaabi, A. see Dieulesaint, E.
Forsberg, G.S. Optical receiver with optical feedback p478 e663
Forsmann, F., Jäger, D., and Zhai, H.-C. see Jäger, D.
Foulds, K.W.H., Andres, M.V., and Tudor, M.J. see Andres, M.V.
Fourie, A.P.C., and Austin, B.A. Improved HF broadband wire antenna p276
Fraasch, A.M., Arch, D.K., Abrokwah, J.K., Vold, P.J., Grung, B.L., and Cirillo, N.C. see Arch, D.K.
France, P.W., and Brierley, M.C. see Brierley, M.C.
Francois, P.L., Alard, F., and Monerie, M. Chromatic dispersion measurement from Fourier transform of white-light interference patterns p357
Franzen, D.L., Yamabayashi, Y., and Kanada, T. Optical sampling with gain-switched, pulse-compressed, distributed feedback laser diodes p289
Freij, G.J., and Cheetham, B.M.G. Performance of LMS algorithm as a function of input signal pole loci p474
Freude, W., and Chen, He-Ming see Chen, He-Ming
Friesem, A.A., Yaffe, H.H., Waarts, R.G., and Lichtman, E. see Yaffe, H.H.
Frost, J., Lee, K.Y., Al-Mudares, M., Beaumont, S.P., Wilkinson, C.D.W., and Stanley, C.R. see Lee, K.Y.
Fujii, H., Kawata, S., Kobayashi, K., Gomyo, A., Hino, I., and Suzuki, T. see Kawata, S.
Fujii, H., Kobayashi, K., Kawata, S., Gomyo, A., Hino, I., Hotta, H., and Suzuki, T. High-power operation of a transverse-mode stabilised AlGaInP visible light ($\lambda_L = 683$ nm) semiconductor laser p938
Fujii, T., Imamura, K., Muto, S., Ohnishi, H., and Yokoyama, N. see Imamura, K.
Fujii, T., Nobuhara, H., and Wada, O. see Nobuhara, H.
Fujioka, A., Tsujii, S., Itoh, T., Kurosawa, K., and Matsumoto, T. see Tsujii, S.
Fujise, M., Shimizu, K., and Nunokawa, M. see Shimizu, K.
Fujita, S., Hayashi, J., Isoda, Y., Uji, T., and Shikada, M. 2 Gbit/s and 600 Mbit/s single-mode fibre transmission experiments using a high-speed Zn-doped 1·3 μm edge-emitting LED p636
Fujita, S., Suzuki, A., Itoh, T., Terakado, T., Kasahara, K., Asano, K., Inomoto, Y., Ishihara, H., and Torikai, T. see Suzuki, A.
Fujita, S., Yamazaki, S., Murata, S., Komatsu, K., Koizumi, Y., and Emura, K. see Yamazaki, S.
Fujita, T., Schremer, A., and Tang, C.L. Polarisation switching in a single-frequency external-cavity semiconductor laser p803
Fujiwara, M., Ajisawa, A., Shimizu, J., Sugimoto, M., Uchida, M., and Ohta, Y. see Ajisawa, A.
Fujiwara, M., Takemoto, A., Sakakibara, Y., Nakajima, Y., Kakimoto, S., Namizaki, H., and Susaki, W. see Takemoto, A.
Fukuda, M., Kawaguchi, H., Oe, K., Yasaka, H., Magari, K., and Itaya, Y. see Kawaguchi, H.
Fukuda, M., Nakano, Y., Itaya, Y., Noguchi, Y., Yasaka, H., and Oe, K. see Nakano, Y.
Fukui, Y., and Higashimura, M. see Higashimura, M.
Fukumitsu, O., Yokota, M., and Kudou, T. see Yokota, M.
Funamizu, M., Nishibe, T., Okuda, H., Furuyama, H., Hirayama, Y., Nakamura, M., and Iwamoto, M. see Nishibe, T.
Fure, R.J., Baier, S.M., Lee, G.Y., Chung, H.K., and Cirillo, N.C. see Baier, S.M.
Furusawa, K., Namihira, Y., Ryu, S., Mochizuki, K., and Iwamoto, Y. see Namihira, Y.
Furutsu, M., Soda, H., Kihara, K., Matsuda, M., Seki, H., Ogita, S., Ishikawa, H., and Imai, H. see Soda, H.
Furuyama, H., Hirayama, Y., Okuda, H., Kinoshita, J., and Nakamura, M. see Hirayama, Y.
Furuyama, H., Nakamura, M., and Kurobe, A. see Nakamura, M.
Furuyama, H., Nishibe, T., Funamizu, M., Okuda, H., Hirayama, Y., Nakamura, M., and Iwamoto, M. see Nishibe, T.

G

Gabel, A., Assanto, G., Seaton, C.T., Stegeman, G.I., Ironside, C.N., and Cullen, T.J. see Assanto, G.
Gage, S.M., Choi, W.K., Owen, A.E., and Delima, J.J. see Choi, W.K.
Gallagher, D.F.G., Garrett, B., and White, I.H. see Garrett, B.
Gallion, P., and Debarge, G. Relationship between linewidth and chirp reductions in gain-detuned composite-cavity semiconductor lasers p1375
Gallois, A.P., and Böck, A.M. Variable-data-rate systems applicable to fading satellite channels p766
Gambling, W.A., Morishita, K., and Yataki, M.S. see Morishita, K.
Gangopadhyay, R., and Cochrane, P. Data clock jitter in supersampling multiplex transmission p1203
Gans, M.J., Trambarulo, R., and Schneider, M.V. see Trambarulo, R.
Gao, X.Z., and Chang, K. Analysis of microstripline coupled to microstrip antenna p694
Garat, F., Dumas, J.-M., and Lecrosnier, D. see Dumas, J.-M.
Garcia, G.A., Albares, D.J., Chang, C.T., and Reedy, R.E. see Albares, D.J.
Garg, R., and Long, S.A. Resonant frequency of electrically thick rectangular microstrip antennas p1149
Garnham, R.A., Cunningham, D.G., and Stallard, W.A. 34 Mbit/s optical fibre transmission system experiment at a wavelength of 2·4 μm p1063
Garrett, B., White, I.H., and Gallagher, D.F.G. Self longitudinal-mode stabilisation in GaAs/(AlGa)As quantum-well lasers p1193
Garrett, B., and Glew, R.W. Low-threshold, high-power zero-order lateral-mode DQW-SCH metal-clad ridge waveguide (AlGa)As/GaAs lasers p371
Garrett, I., Jacobsen, G., and Kan, J.X. see Jacobsen, G.
Garrett, I., Kan, J.X., and Jacobsen, G. see Kan, J.X.
Garry, G., Regolini, J.L., Dutartre, D., Bensahel, D., Karapiperis, L., and Dieumegard, D. see Regolini, J.L.
Garth, S.J. Fields in a bent single-mode fibre p373
Gatenby, P.V., Switzer, D.L., and Green, N. Broadband correlators employing fibre-optic recirculating delay lines p1246
Gaukel, G., and Wittmann, J. see Wittmann, J.
Gauneau, M., Favennec, P.N., L'Haridon, H., Le Corre, A., and Salvi, M. see Favennec, P.N.
Gayliard, K., Darcie, T.E., Glance, B., Talman, J.R., Kasper, B.L., and Burrus, C.A. see Darcie, T.E.
Gayliard, K.T., Jopson, R.M., Darcie, T.E., Ku, R.T., Tench, R.E., Rice, T.C., and Olsson, N.A. see Jopson, R.M.
Geerts, M.J., van Oort, R.C., van den Heuvel, J.C., and Metselaar, J.W. see van Oort, R.C.
Geissberger, A.E., Sadler, R.A., Griffin, E.L., Bahl, I.J., and Balzan, M.L. Refractory self-aligned gate technology for GaAs microwave FETs and MMICs p1073
Genova, F., Cinguino, P., Morasca, S., Rigo, C., and Stano, A. see Cinguino, P.
Georgiou, G., and Boucouvalas, A.C. see Boucouvalas, A.C.
Gerges, A.S., Farahi, F., Newson, T.P., Jones, J.D.C., and Jackson, D.A. Interferometric fibre-optic sensor using a short-coherence-length source p1110
Gersho, A., and Zeger, K.A. see Zeger, K.A.
Ghaffari, A., Chen, H.Z., Morkoç, H., and Yariv, A. see Chen, H.Z.
Ghassemlooy, Z., and Wilson, B. see Wilson, B.
Ghobrial, S.I., Hemeidi, M.A., and Tawfig, M.E. Observations on 2 and 7·5 GHz microwave links during dust storms p44
Gibbs, M.R.J., and Squire, P.T. see Squire, P.T.
Gibson, W.C., Reynolds, C.L., and Clemans, J.E. see Reynolds, C.L.
Gilbert, M.J., Allan, D.A., and O'Sullivan, P.J. see Allan, D.A.
Gildenblat, G.S., and Cohen, S.S. New analytical solution for a current/voltage characteristic of space-charge-limited currents with a nonlinear velocity-field relationship e251
Giles, R.C., and Reichmann, K.C. Optical self-homodyne DPSK transmission at 1 and 2 Gbit/s over 86 km of fibre p1180
Gilliland, J.W., and Powers, D.R. Nitrogen-related absorption bands in optical fibres p144
Gillner, L., Nilsson, O., and Goobar, E. see Nilsson, O.
Gimlett, J., Kazovsky, L.G., Elrefaie, A.F., Meissner, P., Welter, R., Crespo, P., and Smith, R.W. see Kazovsky, L.G.
Gimlett, J.L. Low-noise 8 GHz PIN/FET optical receiver p281
Gimlett, J.L., Choy, M.M., Welter, R., Kazovsky, L.G., and Cheung, N.K. see Choy, M.M.
Gimlett, J.L., Kobrinski, H., Bulley, R.M., Goodman, M.S., Vecchi, M.P., Brackett, C.A., and Curtis, L. see Kobrinski, H.
Girdlestone, H.P., Ainslie, B.J., and Cotter, D. see Ainslie, B.J.
Glance, B., Burrus, C.A., and Stulz, L.W. Fast frequency tunable external-cavity laser p98
Glance, B., Darcie, T.E., Gayliard, K., Talman, J.R., Kasper, B.L., and Burrus, C.A. see Darcie, T.E.
Glance, B., Fitzgerald, P.J., Pollack, K.J., Stone, J., Burrus, C.A., Eisenstein, G., and Stulz, L.W. Frequency stabilisation of FDM optical signals p750
Glance, B., Pollock, K., Burrus, C.A., Kasper, B.L., Eisenstein, G., and Stulz, L.W. Densely spaced WDM coherent optical star network p875
Glance, B., Stone, J., Fitzgerald, P.J., Pollock, K.J., Burrus, C.A., and Stulz, L.W. Frequency stabilisation of FDM optical signals originating from different locations p1243
Glavas, E., Townsend, P.D., Droungas, G., Dorey, M., Wong, K.K., and Allen, L. Optical damage resistance of ion-implanted $LiNbO_3$ waveguides p73
Glavina, R., Cucchi, S., and Sicuranza, G.L. Nonlinear interpolation of TV image sequences p778
Gleason, K.R., Seo, K.S., and Bhattacharya, P.K. see Seo, K.S.
Glew, R.W., and Garrett, B. see Garrett, B.
Glick, M., Pavuna, D., and Reinhart, F.K. Electro-optic effects and electroabsorption in a GaAs/AlGaAs multiquantum-well heterostructure near the bandgap p1235
Glisic, S.G. Efficiency of block error-correcting codes p557
Gnall, R.N., Taylor, G.W., Lebby, M.S., Chang, T.Y., Sauer, N., Tell, B., and Simmons, J.G. see Taylor, G.W.
Gnauck, A.H., Darcie, T.E., Burrus, C.A., Kasper, B.L., and Talman, J.R. see Darcie, T.E.
Gnauck, A.H., Eisenstein, G., Tucker, R.S., Korotky, S.K., Raybon, G., Veselka, J.J., Buhl, L.L., Kasper, B.L., and Alferness, R.C. see Eisenstein, G.
Gnauck, A.H., Linke, R.A., Kasper, B.L., Pollock, K.J., Reichmann, K.C., Valenzuela, R., and Alferness, R.C. Coherent lightwave transmission at 2 Gbit/s over 170 km of optical fibre using phase modulation p286
Gnauck, A.H., and Bowers, J.E. 16 Gbit/s direct modulation of an InGaAsP laser p801
Goel, A.K. Dependence of interconnection delays on driving mechanism for GaAs-based VLSI p1066
Goldberg, L., Tamburrini, M., Parent, M., and Stillwell, D. see Tamburrini, M.
Goldberg, L., Tamburrini, M., and Weller, J.F. see Tamburrini, M.
Goldstein, B., Carlson, N.W., Evans, G.A., Dinkel, N.A., and Masin, V.J. Performance of a channelled-substrate-planar high-power phase-locked array operating in the diffraction limit p1136
Gomes, A.S.L., Gouveia-Neto, A.S., Taylor, J.R., Ainslie, B.J., and Craig, S.P. see Gouveia-Neto, A.S.
Gomes, A.S.L., Gouveia-Neto, A.S., and Taylor, J.R. see Gouveia-Neto, A.S.
Gomes, N.J., and Seeds, A.J. Novel optically pumped electronic mixer using a Mott diode structure p1084
Gomyo, A., Fujii, H., Kobayashi, K., Kawata, S., Hino, I., Hotta, H., and Suzuki, T. see Fujii, H.
Gomyo, A., Kawata, S., Fujii, H., Kobayashi, K., Hino, I., and Suzuki, T. see Kawata, S.
Gomyo, A., Kobayashi, K., Kawata, S., Hino, I., and Suzuki, T. Aging characteristics of AlGaInP/GaInP visible-light lasers ($\lambda_L = 678$ nm) p85
Gonzalez, G., and Avanic, B. Design of crystal oscillators with fundamental frequencies in the UHF and microwave regions p1379
Goobar, E., Nilsson, O., and Gillner, L. see Nilsson, O.
Goodman, M.S., Kobrinski, H., Bulley, R.M., Vecchi, M.P., Brackett, C.A., Curtis, L., and Gimlett, J.L. see Kobrinski, H.
Goodwin, A.R., Murison, R.F., Houghton, A.J.N., Collar, A.J., and Davies, I.G.A. see Murison, R.F.
Gossard, A.C., Weiner, J.S., English, J.H., Miller, D.A.B., Chemla, D.S., and Burrus, C.A. see Weiner, J.S.
Gossard, A.C., Wood, T.H., Carr, E.C., Burrus,

C.A., Henry, J.E., and English, J.H. see Wood, T.H.
Gouveia-Neto, A.S., Gomes, A.S.L., Taylor, J.R., Ainslie, B.J., and Craig, S.P. Femtosecond single-pass cascade Raman soliton generation at 1·5 μm p1034
Gouveia-Neto, A.S., Gomes, A.S.L., and Taylor, J.R. Femtosecond soliton Raman ring laser p537
Granestrand, P., Blumenthal, D.J., Prucnal, P.R., and Thylen, L. see Blumenthal, D.J.
Granjoux, P., Henry, L., and Vaudry, C. see Henry, L.
Granlund, S.W., Park, Y.K., Kuo, C.Y., Dixon, M., Cline, T.W., Smith, R.W., Dutta, N.K., and Vannucci, G. see Park, Y.K.
Gransden, D.W., and O'Sullivan, M.S. see O'Sullivan, M.S.
Green, M., Leaver, K.D., and Daniel, H. see Leaver, K.D.
Green, M., and Tate, T.J. Fabrication of twin-rectangular-cored fibre couplers p593 e867
Green, N., Gatenby, P.V., and Switzer, D.L. see Gatenby, P.V.
Greene, P.D., Heasman, K.C., Adams, A.R., and Henshall, G.D. see Heasman, K.C.
Greene, P.D., Prins, A.D., Dunstan, D.J., and Adams, A.R. Indium phosphide and quaternary doping superlattices grown by liquid-phase epitaxy p324
Gregory, O.J., Crisman, E.E., Lee, J.I., and Stiles, P.J. see Crisman, E.E.
Griffin, E.L., Geissberger, A.E., Sadler, R.A., Bahl, I.J., and Balzan, M.L. see Geissberger, A.E.
Griffiths, J.W.R., and Lee, B.S. see Lee, B.S.
Großkopf, G., Ludwig, R., Waarts, R.G., and Weber, H.G. Optical amplifier configurations with low polarisation sensitivity p1387
Groh, W., Meier, J., Lieber, W., Heinlein, W., Herbrechtsmeier, P., and Theis, J. see Meier, J.
Grosmaire, S., Bouadma, N., and Brillouet, F. see Bouadma, N.
Gross, R. Optimal local oscillator power in PSK homodyne systems p124
Gross, R., Dietrich, E., Enning, B., and Knupke, H. see Dietrich, E.
Grover, W.D., Moore, T.E., and McEachern, J.E. Measured pulse-stuffing jitter in asynchronous DS-1/SONET multiplexing with and without stuff-threshold modulation circuit p959
Gruhle, A., Vescan, L., and Beneking, H. Dual-gate silicon permeable-base transistors built on LPVPE-grown material p447
Grung, B.L., Arch, D.K., Abrokwah, J.K., Vold, P.J., Fraasch, A.M., and Cirillo, N.C. see Arch, D.K.
Guerin, R., Guivarc'h, A., and Secoue, M. see Guivarc'h, A.
Guibert, M., Ronarch, D., and Pophillat, L. see Ronarch, D.
Guivarc'h, A., Guerin, R., and Secoue, M. Epitaxial, thermodynamically stabilised metal/III-V compound semiconductor interface: NiGa on GaAs (001) p1004
Gupta, K.C., and Benalla, A. see Benalla, A.

H

Hławiczka, A. BIST structure using multi-input shift register with initial value p476
Haartsen, J.C., and Den Dulk, R.C. Novel circuit design and implementation of adaptive phase comparators p551
Habara, K. $LiNbO_3$ directional-coupler polarisation splitter p614
Habara, K., and Kikuchi, K. Geometrical design considerations for a tree-structured optical switch matrix p376
Habbab, I.M.I., Cimini, L.J., John, R.K., and Saleh, A.A.M. see Cimini, L.J.
Hadjifotiou, A., Pettitt, M.J., Remedios, D., Davis, A.W., and Wright, S. see Pettitt, M.J.
Haigh, D.G., Betts, A.K., and Taylor, J.T. see Betts, A.K.
Haigh, D.G., and Ryan, P.J. see Ryan, P.J.
Haigh, D.G., and Taylor, J.T. see Taylor, J.T.
Haigh, D.G., and Taylor, J.T. State-space description and realisation of elliptic lowpass *LCR* ladder filters p1032
Haigh, D.G., and Toumazou, C. see Toumazou, C.
Hall, K.L., Jopson, R.M., Eisenstein, G., Raybon, G., and Whalen, M.S. see Jopson, R.M.
Hall, K.L., Whalen, M.S., Tennant, D.M., Koren, U., and Raybon, G. see Whalen, M.S.
Hall, P.S. Feed radiation effects in sequentially rotated microstrip patch arrays p877
Hall, P.S. Probe compensation in thick microstrip patches p606
Hall, P.S., and Sparrow, A. Microstrip log-periodic antenna array with endfire beam p912
Hall, S.R., Kolinsky, P.V., Chad, R.J., Jones, R.J., Norman, P.A., Bloor, D., and Obhi, J.S. see Kolinsky, P.V.
Hamanaka, K., Kameya, M., Tai, S., Kojima, K., Kyuma, K., and Nakayama, T. see Kameya, M.
Hamanaka, K., Ohta, J., Kuroda, K., Mitsunaga, K., Kyuma, K., and Nakayama, T. see Ohta, J.
Hamer, G., Kazeminejad, S., and Howson, D.P. see Kazeminejad, S.
Hammer, J.M., Carlson, N.W., Evans, G.A., and Neil, C.C. see Carlson, N.W.
Hammett, P.G. Complexity reduction in fully vector quantised stochastic coders p253
Hanada, Y., Seki, M., Sugawara, R., Okuda, E., Wada, H., and Yamasaki, T. see Seki, M.
Hanafusa, H., Hibino, Y., Itoh, H., and Yamamoto, F. Influence of impurities on loss increase in optical fibre p10
Hansom, A.M., Parker, D.G., Say, P.G., and Sibbett, W. see Parker, D.G.
Hanyi, Zhang, Bingkun, Zhou, Yuanxiang, Wu, Jianying, Zhou, Jian, Li, and Zhenwu, Pan see Bingkun, Zhou
Harada, I., and Adachi, T. New clustering approach to chip floorplan using functional data p900
Harada, N., Chang, J., and Kashiwa, S. see Chang, J.
Harbison, J.P., Abeles, J.H., Chan, W.K., Kastalsky, A., Florez, L.T., and Bhat, R. see Abeles, J.H.
Harding, C.M., Tihanyi, P., Wagner, D.K., Vollmer, H.J., Roza, A.J., Davis, R.J., and Wolf, E.D. see Tihanyi, P.
Hardy, W.N., and Hürlimann, M.D. see Hürlimann, M.D.
Harker, A.T., Ashley, T., Elliott, C.T., White, A.M., and Crimes, G.J. see Ashley, T.
Harmand, J.C., Palmier, J.F., Sibille, A., and Dangla, J. see Palmier, J.F.
Harmon, R.A., Hodgkinson, T.G., and Smith, D.W. see Hodgkinson, T.G.
Harnagel, G., Welch, D.F., DeVito, M., Cardinal, M., Abraham, M., Kung, H., Cross, P., Scifres, D., and Streifer, W. see Welch, D.F.
Harnagel, G.L., Cross, P.S., Lennon, C.R., DeVito, M., and Scifres, D.R. Ultra-high-power quasi-CW monolithic laser diode arrays with high power conversion efficiency p743
Harriott, L.R., Osinski, J.S., Zah, C.E., Bhat, R., Contolini, R.J., Beebe, E.D., Lee, T.P., and Cummings, K.D. see Osinski, J.S.
Hartnett, K., DeFreez, R.K., Elliott, R.A., and Welch, D.F. see DeFreez, R.K.
Hasegawa, M., Tomaru, S., Kubodera, K., Zembutsu, S., and Takeda, K. see Tomaru, S.
Hashimoto, Y., Liu, H.-F., and Kamiya, T. see Liu, H.-F.
Hassan, M.H., and Siy, P. Polygonal approximation for image segmentation p1001
Hassan, M.H., and Siy, P. Real-time thresholding technique p339
Hatano, S., Katsuyama, Y., Hogari, K., and Kokubun, T. see Katsuyama, Y.
Hauden, D., Bigler, E., and Theobald, G. see Bigler, E.
Hay, S.G. Offset dual-reflector multiple-beam antennas using circularly symmetric main reflectors p888
Hay, S.G. Subreflector shaping to improve multiple-beam performance of a Cassegrain antenna p789
Hayama, N., Tanaka, S., Madihian, M., Toyoshima, H., and Honjo, K. see Tanaka, S.
Hayashi, J., Fujita, S., Isoda, Y., Uji, T., and Shikada, M. see Fujita, S.
Hayata, K., Koshiba, M., Eguchi, M., and Suzuki, M. Novel finite-element formulation without any spurious solutions for dielectric waveguides e251
Hayata, K., Koshiba, M., and Suzuki, M. Finite-element solution of arbitrarily nonlinear, graded-index slab waveguides p429 e1397
Hayata, K., Koshiba, M., and Suzuki, M. Novel trial field of single-mode graded-index fibres usable for non-Gaussian field distributions e251
Hayata, K., Nagai, M., and Koshiba, M. Finite-element theory of nonlinear TM-polarised guided waves p1305
Hayata, K., and Koshiba, M. Direct supermode analysis of phase-locked diode laser arrays p935
Hayes, J.R., Bhat, R., Schumacher, H., and Koza, M. OMCVD-grown InP/GaInAs heterojunction bipolar transistors p1298
Hazra, S.N., and Reddy, M.S. see Reddy, M.S.
Heasman, K.C., Adams, A.R., Greene, P.D., and Henshall, G.D. Pressure dependence of threshold current and carrier lifetime in 1·55 μm GaInAsP lasers p492
Heasman, K.C., Adams, A.R., and Plumb, R.G. Scanning the laser gain spectrum using distributed feedback and hydrostatic pressure p555
Heidemann, R., Scholz, U., and Wedding, B. 5 Gbit/s transmission system experiment over 111 km of optical fibre p1030
Heidrich, H., von Helmolt, C.H., Hoffmann, D., Hensel, H.-J., and Kleinwächter, A. Polarisation transformer on Ti : $LiNbO_3$ with reset-free optical operation for heterodyne/homodyne receivers p335
Heinlein, W., Meier, J., Lieber, W., Groh, W., Herbrechtsmeier, P., and Theis, J. see Meier, J.
Heinrich, H., Black, A., Courville, C., and Schultheis, G. see Black, A.
Heise, G., Cremer, C., März, R., Riechert, H., and Schienle, M. see Cremer, C.
Heismann, F., Buhl, L.L., and Alferness, R.C. Electro-optically tunable, narrowband Ti : $LiNbO_3$ wavelength filter p572
Heliot, F., Renaud, J.C., N'Guyen, L., Allovon, M., Lugiez, F., and Scavennec, A. see Renaud, J.C.
Helszajn, J., Nisbet, W.T., and Sharp, J. Mode charts of gyromagnetic planar ring resonators p1290
Hemeidi, M.A., Ghobrial, S.I., and Tawfig, M.E. see Ghobrial, S.I.
Henini, M., and de Cogan, D. see de Cogan, D.
Henning, I.D., McIlroy, P.W.A., Rodgers, P.M., Singh, J.S., and Spurdens, P.C. see McIlroy, P.W.A.
Henning, I.D., Wake, D., Walling, R.H., and Sargood, S.K. see Wake, D.
Henning, I.D., and Rodgers, P.M. Improved method of measuring loss and phase shifts in waveguide devices p1245
Henoc, P., Daoud-Ketata, K., Dubon-Chevallier, C., Besombes, C., and Bresse, J.F. see Daoud-Ketata, K.
Henry, C.H., Olsson, N.A., Johnson, B.H., Lee, H.J., Kazarinov, R.F., Ackerman, D.A., and Anthony, P.J. see Olsson, N.A.
Henry, J.E., Wood, T.H., Carr, E.C., Burrus, C.A., Gossard, A.C., and English, J.H. see Wood, T.H.
Henry, L., Lecrosnier, D., Le Corre, A., and Vaudry, C. see Lecrosnier, D.
Henry, L., Vaudry, C., and Granjoux, P. Novel process for integration of optoelectronic devices using reactive ion etching without chlorinated gas p1253
Hensel, E., Skorupa, W., Kreissig, U., and Bartsch, H. see Skorupa, W.
Hensel, H.-J., Heidrich, H., von Helmolt, C.H., Hoffmann, D., and Kleinwächter, A. see Heidrich, H.
Henshall, G.D., Heasman, K.C., Adams, A.R., and Greene, P.D. see Heasman, K.C.
Herbrechtsmeier, P., Meier, J., Lieber, W., Heinlein, W., Groh, W., and Theis, J. see Meier, J.
Herman, J.R., Duggan, C.C., Thompson, W.I., Costa, R.A., and DeLuca, D.M. Narrowband digital voice communications over a meteor burst channel p59 e480
Hibino, Y., Hanafusa, H., Itoh, H., and Yamamoto, F. see Hanafusa, H.
Hietala, V.M., Kwon, Y.R., and Champlin, K.S. Broadband continuously variable microwave phase shifter employing a distributed Schottky contact on silicon p675
Higashimura, M., and Fukui, Y. New lossless tunable floating FDNR simulation using two current conveyors and an INIC p529
Higashimura, M., and Fukui, Y. Novel method for realising lossless floating immittance using current conveyors p498
Higgins, V., Thompson, P., Dietrich, H., Anand, Y., and Hillson, J. see Thompson, P.
Hill, G., Wheatley, P., Parry, G., Midwinter, J.E., Mistry, P., Pate, M.A., and Roberts, J.S. see Wheatley, P.
Hill, J.R., Dunn, P.L., Davies, G.J., Oliver, S.N., Pantelis, P., and Rush, J.D. Efficiency frequency-doubling in a poled PVDF copolymer guest/host composite p700
Hill, K.O., Johnson, D.C., Bilodeau, F., and Faucher, S. see Johnson, D.C.
Hill, K.O., Johnson, D.C., Bilodeau, F., and Faucher, S. Narrow-bandwidth optical waveguide transmission filters p465
Hill, P., Olshansky, R., Powazinik, W., Lanzisera, V., and Lauer, R.B. see Olshansky, R.
Hillerich, B. New analysis of LED to single-mode fibre coupling e1397 e306
Hillson, J., Thompson, P., Dietrich, H., Anand, Y., and Higgins, V. see Thompson, P.
Himeno, A., Kobayashi, M., Yamada, M., Yamada, Y., and Terui, H. see Kobayashi, M.
Himeno, A., Yamada, M., Terui, H., Yamada, Y., and Kobayashi, M. see Yamada, M.
Himeno, A., and Kobayashi, M. Single-mode guided-wave optical gate matrix switch using Mach–Zehnder interferometer gates p887
Hinata, S., Aoyagi, T., Shigihara, K., Seiwa, Y., Ikeda, K., and Susaki, W. see Aoyagi, T.
Hinchliffe, S., Collins, D., and Hobson, L. see Collins, D.
Hinchliffe, S., Thomas, K., and Hobson, L. see Thomas, K.
Hinchliffe, S., and Hobson, L. Voltage-fed transistorised induction heating power supply p549
Hino, I., Fujii, H., Kobayashi, K., Kawata, S., Gomyo, A., Hotta, H., and Suzuki, T. see Fujii, H.
Hino, I., Gomyo, A., Kobayashi, K., Kawata, S., and Suzuki, T. see Gomyo, A.
Hino, I., Kawata, S., Fujii, H., Kobayashi, K., Gomyo, A., and Suzuki, T. see Kawata, S.
Hirano, M., Ogita, S., Soda, H., Yano, M., Ishikawa, H., and Imai, H. see Ogita, S.
Hirao, M., Okai, M., Tsuji, S., and Matsumura, H. see Okai, M.
Hirata, S., Tamamura, K., and Kojima, C. λ/4-shifted AlGaAs/GaAs DFB lasers with double window structures p627
Hirayama, M., Yamane, Y., Takahashi, Y., and Ishii, H. see Yamane, Y.
Hirayama, Y., Nishibe, T., Funamizu, M., Okuda, H., Furuyama, H., Nakamura, M., and Iwamoto, M. see Nishibe, T.
Hirayama, Y., Okuda, H., Furuyama, H., Kinoshita, J., and Nakamura, M. Determination of coupling coefficient of DFB lasers by a newly proposed method p101
Hobson, L., Collins, D., and Hinchliffe, S. see Collins, D.
Hobson, L., Thomas, K., and Hinchliffe, S. see Thomas, K.
Hobson, L., and Hinchliffe, S. see Hinchliffe, S.
Hobson, L., and Tebb, D.W. see Tebb, D.W.

Hodgkinson, T.G., Harmon, R.A., and Smith, D.W. Polarisation-insensitive heterodyne detection using polarisation scrambling p513
Hodson, C.M.T., and Wood, J. Effect of process parameters on plasma-enhanced chemical vapour deposition of tungsten p733
Hodson, P.D., Bradley, R.R., Riffat, J.R., Joyce, T.B., and Wallis, R.H. GaInAs PIN photodiodes grown on silicon substrates for 1·55 μm detection p1094
Hodson, P.D., Moseley, A.J., Urquhart, J., Riffat, J.R., and Davies, J.I. see Moseley, A.J.
Hodson, P.D., Wallis, R.H., and Davies, J.I. Low-leakage InGaAs photodiodes grown on GaAs substrates using a graded strained-layer superlattice p273
Hoekstra, J. Simple JCCD logic at 20 MHz p246
Hoffmann, D., Heidrich, H., von Helmolt, C.H., Hensel, H.-J., and Kleinwächter, A. see Heidrich, H.
Hogari, K., Katsuyama, Y., Hatano, S., and Kokubun, T. see Katsuyama, Y.
Hohkawa, K., Aihara, K., and Miyahara, K. see Aihara, K.
Holcroft, B., Roberts, G.G., Barraud, A., and Richard, J. Surface-acoustic-wave device incorporating conducting Langmuir–Blodgett films p446
Holt, A.R., Antar, Y.M.M., and Allan, L.E. see Antar, Y.M.M.
Hong, J.S., and Shi, J.M. Modelling microstrip step discontinuities by the transmission matrix p678
Hong-xun, Liu, Xiao-song, Jiang, Li-sheng, Yu, and Shu-min, Wang see Xiao-song, Jiang
Honjo, K., Tanaka, S., Madihian, M., Toyoshima, H., and Hayama, N. see Tanaka, S.
Hope, J.F., Ferreira, H.C., and Nel, A.L. Capacities of sequences of currently used ternary line codes p681
Horiguchi, M., Kitagawa, T., and Shibata, S. see Kitagawa, T.
Horiguchi, M., Shimizu, M., and Suda, H. see Shimizu, M.
Horiuchi, Y., Namihira, Y., Kuwazuru, M., Nunokawa, M., and Iwamoto, Y. see Namihira, Y.
Horiuchi, Y., Namihira, Y., Wakabayashi, H., Oshimi, T., Kitagawa, K., and Ooka, T. see Namihira, Y.
Horiuchi, Y., Namihira, Y., and Wakabayashi, H. see Namihira, Y.
Hornung, S., Stern, J.R., Ballance, J.W., Faulkner, D.W., Payne, D.B., and Oakley, K. see Stern, J.R.
Horrocks, D.H., and Bull, D.R. see Bull, D.R.
Hosaka, T., Sudo, S., and Okamoto, K. Dispersion of pure GeO_2 glass core and F-doped GeO_2 glass cladding single-mode optical fibre p24
Hossain, S.Q.A.M.A., and Lowry, A. see Lowry, A.
Hotta, H., Fujii, H., Kobayashi, K., Kawata, S., Gomyo, A., Hino, I., and Suzuki, T. see Fujii, H.
Houghton, A.J.N., Murison, R.F., Goodwin, A.R., Collar, A.J., and Davies, I.G.A. see Murison, R.F.
Houston, P.A., Blaauw, C., Margittai, A., Svilans, M.N., Puetz, N., Day, D.J., Shepherd, F.R., and Springthorpe, A.J. Double-heterojunction bipolar transistors in InP/GaInAs grown by metal organic chemical vapour deposition p931
Howson, D.P., Kazeminejad, S., and Hamer, G. see Kazeminejad, S.
Hsu, Chau-Yun, and Wu, Ja-Ling Block-diagonal structure of Walsh–Hadamard/discrete cosine transform p1123 e1397
Hsu, Chau-Yun, and Wu, Ja-Ling Fast computation of discrete Hartley transform via Walsh–Hadamard transform p466
Hürlimann, M.D., and Hardy, W.N. Measurement of flicker phase noise of 1·4 GHz MESFET amplifier at temperatures between 300 K and 1·26 K p283
Hua, Y.L., Petty, M.C., Roberts, G.G., Ahmad, M.M., Yates, H.M., Maung, N.J., and Williams, J.O. Blue electroluminescence from ZnSe/Langmuir-Blodgett film MIS diodes p231
Huang, X.D., Duncan, G., and Jack, M.A. Automatic formant estimation algorithm based on pointwise analysis p807
Huang, X.D., Jack, M.A., and Duncan, G. Formant labelling using pole-focused spectra p1047
Huber, S., and Wenger, J. see Wenger, J.
Huertas, J.L., Barriga, A., and Sánchez-Gómez, G. Multivalued dynamic circuits p502
Huertas, J.L., Rodriguez-Vazquez, A., Rueda, A., and Perez-Verdu, B. see Rodriguez-Vazquez, A.
Huihai, Yao, and Zhihao, Chen see Zhihao, Chen
Hummer, K.A., Tahim, R.S., and Chang, K. see Tahim, R.S.
Humphreys, T.P., Das, K., Bedair, S.M., Wortman, J.J., Parikh, N., Chu, W.K., El-Masry, N., and Tarn, J.C.L. Molecular-beam-epitaxial growth of GaAs on high-temperature hydrogen-annealed (100) silicon p1079
Hung-chia, Huang, and Yijiang, Chen see Yijiang, Chen
Hunwicks, A.R., Cochrane, P., and Rosher, P.A. see Cochrane, P.
Hunwicks, A.R., and Rosher, P.A. Duplex–diplex optical transmission in the 1300 nm and 1500 nm fibre windows: an installed system p542
Hussey, C.D., and Minelly, J.D. see Minelly, J.D.
Hutchinson, A.L., Capasso, F., Sen, S., and Cho, A.Y. see Capasso, F.
Hutchinson, A.L., Sen, S., Capasso, F., and Cho, A.Y. see Sen, S.
Hwa, L.G., Schroeder, J., Shyong, M.C., Floudas, G.A., Thompson, D.A., and Drexhage, M.G. see Schroeder, J.
Hwang, Jun-Am, Park, Moon-Soo, and Chun, Young-Yun see Park, Moon-Soo

I

Iannone, E., Betti, S., De Marchis, G., and Martellucci, A. see Betti, S.
Iannone, P., and Darcie, T.E. Multichannel intermodulation distortion in high-speed GaInAsP lasers p1361
Iannone, P.P., Kaminow, I.P., Stone, J., and Stulz, L.W. see Kaminow, I.P.
İdemen, M., and Serbest, A.H. Boundary conditions of the electromagnetic field p704
Iga, K., Kinoshita, S., and Koyama, F. Microcavity GaAlAs/GaAs surface-emitting laser with I_{th} = 6 mA p134
Iga, K., Kokubun, Y., Baba, T., and Sakaki, T. see Kokubun, Y.
Iga, K., and Zhu, X. see Zhu, X.
Ikeda, K., Aoyagi, T., Hinata, S., Shigihara, K., Seiwa, Y., and Susaki, W. see Aoyagi, T.
Ikeda, M., Nakano, K., Toda, A., and Kojima, C. see Nakano, K.
Ilyas, M. General probability density function of packet service times for computer networks p31
Imada, G., Yamauchi, J., and Nakano, H. see Yamauchi, J.
Imai, H., Kihara, K., Kamite, K., Sudo, H., Tanahashi, T., Kusunoki, T., Isozumi, S., and Ishikawa, H. see Kihara, K.
Imai, H., Kotaki, Y., Matsuda, M., Yano, M., and Ishikawa, H. see Kotaki, Y.
Imai, H., Ogita, S., Hirano, M., Soda, H., Yano, M., and Ishikawa, H. see Ogita, S.
Imai, H., Ogita, S., Yano, M., and Ishikawa, H. see Ogita, S.
Imai, H., Soda, H., Kihara, K., Furutsu, M., Matsuda, M., Seki, H., Ogita, S., and Ishikawa, H. see Soda, H.
Imai, H., Soda, H., Nakai, K., and Ishikawa, H. see Soda, H.
Imai, H., Soda, H., and Ishikawa, H. see Soda, H.
Imai, H., and Yamaguchi, K. see Yamaguchi, K.
Imamoto, H., Imanaka, K., Sato, F., Asai, M., and Shimura, M. see Imanaka, K.
Imamura, K., Muto, S., Ohnishi, H., Fujii, T., and Yokoyama, N. Resonant-tunnelling hot-electron transistor (RHET) using a GaInAs/(AlGa)InAs heterostructure p870
Imamura, Y., Itaya, Y., Oishi, M., Nakao, M., Sato, K., and Kondo, Y. see Itaya, Y.
Imanaka, K., Imamoto, H., Sato, F., Asai, M., and Shimura, M. Inner-stripe AlGaAs/GaAs laser diode by single-step molecular beam epitaxy p209
Imoto, K., Sano, H., Miyazaki, M., and Takasaki, Y. Guided-wave multi/demultiplexers with high stopband rejection p472
Imoto, K., Sano, H., and Miyazaki, M. Guided-wave multi/demultiplexers with compensation for centre wavelength shift by fabrication process fluctuations p735
Inomoto, Y., Suzuki, A., Itoh, T., Terakado, T., Kasahara, K., Asano, K., Ishihara, H., Torikai, T., and Fujita, S. see Suzuki, A.
Inoue, K. High-speed all-optical gate switching experiment in a Fabry–Perot semiconductor laser amplifier p921
Inoue, K. Observation of crosstalk due to four-wave mixing in a laser amplifier for FDM transmission p1293
Inoue, K., Mukai, T., and Saitoh, T. see Mukai, T.
Inoue, K., Mukai, T., and Saitoh, T. Gain saturation dependence on signal wavelength in a travelling-wave semiconductor laser amplifier p328
Inoue, K., Utsumi, K., Tezuka, A., Nishii, K., Bando, K., and Onuma, T. see Utsumi, K.
Inoue, N., and Okugawa, S. see Okugawa, S.
Ironside, C.N., Assanto, G., Gabel, A., Seaton, C.T., Stegeman, G.I., and Cullen, T.J. see Assanto, G.
Ishibashi, T., Nagata, K., Nakajima, O., Nittono, T., and Ito, H. see Nagata, K.
Ishibashi, T., Yamauchi, Y., Nagata, K., Nakajima, O., Ito, H., and Nittono, T. see Yamauchi, Y.
Ishibashi, T., and Ito, H. see Ito, H.
Ishibashi, T., and Yamauchi, Y. see Yamauchi, Y.
Ishida, M., Maenaka, K., Ohgusu, T., and Nakamura, T. see Maenaka, K.
Ishida, T., Okayama, H., Matoba, A., and Shibuya, R. see Okayama, H.
Ishihara, H., Suzuki, A., Itoh, T., Terakado, T., Kasahara, K., Asano, K., Inomoto, Y., Torikai, T., and Fujita, S. see Suzuki, A.
Ishii, H., Yamane, Y., Takahashi, Y., and Hirayama, M. see Yamane, Y.
Ishii, M., Kamon, K., Shimazu, M., Mihara, M., Kumabe, H., and Isshiki, K. Planar TJS lasers fabricated in semi-insulating GaAs substrates for optoelectronic integrated circuits p179
Ishikawa, H., Kamada, M., Kobayashi, T., Mori, Y., Kaneko, K., and Kojima, C. see Kamada, M.
Ishikawa, H., Kihara, K., Kamite, K., Sudo, H., Tanahashi, T., Kusunoki, T., Isozumi, S., and Imai, H. see Kihara, K.
Ishikawa, H., Kotaki, Y., Matsuda, M., Yano, M., and Imai, H. see Kotaki, Y.
Ishikawa, H., Ogita, S., Hirano, M., Soda, H., Yano, M., and Imai, H. see Ogita, S.
Ishikawa, H., Ogita, S., Yano, M., and Imai, H. see Ogita, S.
Ishikawa, H., Soda, H., Kihara, K., Furutsu, M., Matsuda, M., Seki, H., Ogita, S., and Imai, H. see Soda, H.
Ishikawa, H., Soda, H., Nakai, K., and Imai, H. see Soda, H.
Ishikawa, H., Soda, H., and Imai, H. see Soda, H.
Ishikawa, R., Kondo, M., Ohta, Y., Tanisawa, Y., and Aoyama, T. see Kondo, M.
Ishino, F., Suzuki, S., Yabusaki, M., and Arita, T. see Suzuki, S.
Ishizuka, S., Matsuda, K., Minemoto, H., Toda, K., and Kamada, O. see Matsuda, K.
Ismail, M. Four-transistor continuous-time MOS transconductor p1099
Isoda, Y., Fujita, S., Hayashi, J., Uji, T., and Shikada, M. see Fujita, S.
Isozumi, S., Kihara, K., Kamite, K., Sudo, H., Tanahashi, T., Kusunoki, T., Ishikawa, H., and Imai, H. see Kihara, K.
Isshiki, K., Ishii, M., Kamon, K., Shimazu, M., Mihara, M., and Kumabe, H. see Ishii, M.
Itaya, Y., Kawaguchi, H., Oe, K., Yasaka, H., Magari, K., and Fukuda, M. see Kawaguchi, H.
Itaya, Y., Nakano, Y., Fukuda, M., Noguchi, Y., Yasaka, H., and Oe, K. see Nakano, Y.
Itaya, Y., Oishi, M., Nakao, M., Sato, K., Kondo, Y., and Imamura, Y. Low-threshold operation of 1·5 μm buried-heterostructure DFB lasers grown entirely by low-pressure MOVPE p193
Ito, H., Nagata, K., Nakajima, O., Nittono, T., and Ishibashi, T. see Nagata, K.
Ito, H., Yamauchi, Y., Nagata, K., Nakajima, O., Nittono, T., and Ishibashi, T. see Yamauchi, Y.
Ito, H., and Ishibashi, T. MBE-grown AlGaAs/GaAs HBTs on InP substrate p394
Ito, T., Kurosawa, K., and Takeuchi, M. see Kurosawa, K.
Itoh, H., Hanafusa, H., Hibino, Y., and Yamamoto, F. see Hanafusa, H.
Itoh, H., Mukai, S., Itoh, M., Watanabe, M., and Yajima, H. see Mukai, S.
Itoh, H., Mukai, S., Watanabe, M., and Yajima, H. see Mukai, S.
Itoh, M., Mukai, S., Watanabe, M., Itoh, H., and Yajima, H. see Mukai, S.
Itoh, T. Efficient probabilistic algorithm for solving quadratic equations over finite fields p869
Itoh, T., Palmateer, L.F., Tasker, P.J., Brown, A.S., Wicks, G.W., and Eastman, L.F. see Palmateer, L.F.
Itoh, T., Suzuki, A., Terakado, T., Kasahara, K., Asano, K., Inomoto, Y., Ishihara, H., Torikai, T., and Fujita, S. see Suzuki, A.
Itoh, T., Tsujii, S., Fujioka, A., Kurosawa, K., and Matsumoto, T. see Tsujii, S.
Itoh, T., Tsujii, S., and Kurosawa, K. see Tsujii, S.
Ivanov, K.P., and Miteva, V.I. see Miteva, V.I.
Iwamoto, M., Nishibe, T., Funamizu, M., Okuda, H., Furuyama, H., Hirayama, Y., and Nakamura, M. see Nishibe, T.
Iwamoto, Y., Edagawa, N., and Mochizuki, K. see Edagawa, N.
Iwamoto, Y., Namihira, Y., Horiuchi, Y., Kuwazuru, M., and Nunokawa, M. see Namihira, Y.
Iwamoto, Y., Namihira, Y., Ryu, S., Kuwazuru, M., and Mochizuki, K. see Namihira, Y.
Iwamoto, Y., Namihira, Y., Ryu, S., Mochizuki, K., and Furusawa, K. see Namihira, Y.
Iwashita, K., Takachio, N., Nakano, Y., and Tsuzuki, N. Optical CPFSK 2 Gbit/s 202 km transmission experiment using a narrow-linewidth multielectrode DFB LD p1022
Iwashita, K., and Takachio, N. 2 Gbit/s optical CPFSK heterodyne transmission through 200 km single-mode fibre p341
Izumi, K., Matsumoto, S., and Ohno, T. see Matsumoto, S.
Izumi, K., Ohno, T., Shimaya, M., and Shiono, N. see Ohno, T.

J

Jäger, D., Forsmann, F., and Zhai, H.-C. Hybrid optical bistability based on increasing absorption in depletion layer of an Si Schottky SEED device p490
Jäger, D., Paulus, P., and Langenhorst, R. see Paulus, P.
Jack, C.A., Tzeng, L.D., Emkey, W.L., and Burrus, C.A. see Tzeng, L.D.
Jack, M.A., Huang, X.D., and Duncan, G. see Huang, X.D.
Jack, M.A., and Crowe, A. see Crowe, A.
Jack, M.A., and McInnes, F.R. see McInnes, F.R.
Jackson, D.A., Gerges, A.S., Farahi, F., Newson, T.P., and Jones, J.D.C. see Gerges, A.S.
Jackson, D.A., Pannell, C.N., Tatam, R.P., and Jones, J.D.C. see Pannell, C.N.
Jackson, T., Nees, J., Vallee, R., and Mourou, G. Novel method for ultrahigh-frequency electro-optic time-domain reflectometry p1130
Jacobsen, G., Kan, J.X., and Bødtker, E. see Kan, J.X.
Jacobsen, G., Kan, J.X., and Garrett, I. see Kan, J.X.
Jacobsen, G., Kan, J.X., and Garrett, I. Improved design of tuned optical receivers p787

Jaggard, D.L., and Schultz, K.I. see Schultz, K.I.
Jajszczyk, A., and Kabaciński, W. Methods for the connection of signalling units to switching networks p443
Jajszczyk, A., and Tyszer, J. Tester architecture for a time-division switch p1064
Jame, M.S., Wang, Y.H., Yarn, K.F., and Chang, C.Y. see Wang, Y.H.
Jan, W.Y., Bowers, J.E., Koren, U., Miller, B.I., and Soccolich, C. see Bowers, J.E.
Janković, N.D. Role of source N^+N^- structure in parasitic bipolar action of lightly doped short-channel MOSFETs p461
Jansen, M., Wilcox, J.Z., and Yang, J.J. see Wilcox, J.Z.
Jansen, R.H., and Wiemer, L. see Wiemer, L.
Jaskorzynska, B., and Schadt, D. see Schadt, D.
Jauhari, G., and Malaviya, N. see Malaviya, N.
Jauncey, I.M., Mears, R.J., Reekie, L., and Payne, D.N. see Mears, R.J.
Jauncey, I.M., Reekie, L., Poole, S.B., and Payne, D.N. see Reekie, L.
Jayasumana, A.P., Rajsuman, R., and Malaiya, Y.K. see Rajsuman, R.
Jen, C.K., Safaai-Jazi, A., and Farnell, G.W. see Safaai-Jazi, A.
Jenner, M.D., Blackman, M.V., Charlton, D.E., Purdy, D.R., Wotherspoon, J.T.M., Elliott, C.T., and White, A.M. see Blackman, M.V.
Jerman, J.H., and Mallinson, S.R. see Mallinson, S.R.
Jha, R.M., Sudhakar, V., and Balakrishnan, N. Ray analysis of mutual coupling between antennas on a general paraboloid of revolution (GPOR) p583
Jia, B., and Mirshekar-Syahkal, D. see Mirshekar-Syahkal, D.
Jian, Li, Bingkun, Zhou, Hanyi, Zhang, Yuanxiang, Wu, Jianying, Zhou, and Zhenwu, Pan see Bingkun, Zhou
Jianying, Zhou, Bingkun, Zhou, Hanyi, Zhang, Yuanxiang, Wu, Jian, Li, and Zhenwu, Pan see Bingkun, Zhou
Jin-guang, Chen, and Wen-hong, Shi see Wen-hong, Shi
Jing, X.L., Lin, S.C., Chin, M.K., Walpita, L.M., Yu, P.K.L., and Chang, W.S.C. see Lin, S.C.
Jofre, L., Rius, J.M., Ferrando, M., de los Reyes, E., Elias, A., and Broquetas, A. see Rius, J.M.
John, R.K., Cimini, L.J., Habbab, I.M.I., and Saleh, A.A.M. see Cimini, L.J.
Johnsen, C.A., Jungerman, R.L., Dolfi, D.W., and Nazarathy, M. see Jungerman, R.L.
Johnson, B.C., Eisenstein, G., and Raybon, G. see Eisenstein, G.
Johnson, B.H., Olsson, N.A., Lee, H.J., Henry, C.H., Kazarinov, R.F., Ackerman, D.A., and Anthony, P.J. see Olsson, N.A.
Johnson, D.C., Hill, K.O., Bilodeau, F., and Faucher, S. see Hill, K.O.
Johnson, D.C., Hill, K.O., Bilodeau, F., and Faucher, S. New design concept for a narrow-band wavelength-selective optical tap and combiner p668
Johnson, D.W., MacChesney, J.B., Fleming, D.A., and Walz, F.W. see MacChesney, J.B.
Johnston, R.L., Watts, R.K., and Manchanda, L. see Watts, R.K.
Jones, E.V., and Zhu, S. Data sequence coding for low jitter timing recovery p337
Jones, G., and Luk, W. see Luk, W.
Jones, J.D.C., Gerges, A.S., Farahi, F., Newson, T.P., and Jackson, D.A. see Gerges, A.S.
Jones, J.D.C., Pannell, C.N., Tatam, R.P., and Jackson, D.A. see Pannell, C.N.
Jones, R.J., Kolinsky, P.V., Chad, R.J., Hall, S.R., Norman, P.A., Bloor, D., and Obhi, J.S. see Kolinsky, P.V.
Jones, S.K., and Blair, D.G. High-quality factors for a sapphire-loaded superconducting cavity resonator p817
Jones, W.L., Ageno, S.K., and Sato, T.Y. Very low-noise HEMTs using a 0·2 μm T-gate p844
Jopson, R.M., Darcie, T.E., Gayliard, K.T., Ku, R.T., Tench, R.E., Rice, T.C., and Olsson, N.A. Measurement of carrier-density mediated intermodulation distortion in an optical amplifier p1394
Jopson, R.M., Darcie, T.E., and Tkach, R.W. see Darcie, T.E.
Jopson, R.M., Hall, K.L., Eisenstein, G., Raybon, G., and Whalen, M.S. Observation of two-colour gain saturation in an optical amplifier p510
Jose, K.A., Aanandan, C.K., and Nair, K.G. Low backscattered TM-polarised strip gratings p905
Jose, K.A., and Nair, K.G. Reflector-backed perfectly blazed strip gratings simulate corrugated reflector effects p86
Joubert, P., Loisel, B., Chouan, Y., and Pedrono, N. see Loisel, B.
Joullie, A., Brosson, P., Benoit, J., and Sermage, B. see Brosson, P.
Jovičić, S.T., and Randjelović, P.Ž. Crosscorrelation pitch extraction method p1317
Jowett, A.P., and Darnell, M. Automatic channel selection using template correlation p1209
Joyce, T.B., Hodson, P.D., Bradley, R.R., Riffat, J.R., and Wallis, R.H. see Hodson, P.D.
Joyner, C.H., Dentai, A.G., Campbell, J.C., and Qua, G.J. see Dentai, A.G.
Judah, S.K., and Wright, A.S. see Wright, A.S.
Jullien, G.A., Taheri, M., and Miller, W.C. see Taheri, M.
Jung, H., and Marschall, P. Out-diffusion and reactivation of Zn in InP substrates p1010
Jung, S.H., and Kim, N.C. see Kim, N.C.
Jungerman, R.L., Johnsen, C.A., Dolfi, D.W., and Nazarathy, M. Coded phase-reversal $LiNbO_3$ modulator with bandwidth greater than 20 GHz at 1·3 μm wavelength p172
Junyent, G., Ruiz-Moreno, S., Usandizaga, J.R., and Calzada, A. see Ruiz-Moreno, S.

K

Kabaciński, W., and Jajszczyk, A. see Jajszczyk, A.
Kaddour, M., Baudrand, H., and Ahmadpanah, M. see Baudrand, H.
Kahlert, J., Mulombe, N., Piscalar, W., and Seehausen, G. see Mulombe, N.
Kaino, T., Kubodera, K.-I., Tomaru, S., Kurihara, T., Saito, S., Tsutsui, T., and Tokito, S. Optical third-harmonic generation from poly(*p*-phenylenevinylene) thin films p1095
Kaiser, R., Bornholdt, C., Döldissen, W., Fiedler, F., and Kowalsky, W. see Bornholdt, C.
Kajfez, D., and Lebaric, J. Field patterns of TM_0 modes in a shielded dielectric resonator p944
Kajiwara, T., Sasai, Y., Ohya, J., and Ogura, M. see Sasai, Y.
Kak, S.C. Aryabhata algorithm for polynomials p838
Kak, S.C. Generating *d*-sequences p202
Kak, S.C. New result on *d*-sequences p617
Kakimoto, S., Takemoto, A., Sakakibara, Y., Nakajima, Y., Fujiwara, M., Namizaki, H., and Susaki, W. see Takemoto, A.
Kamada, M., Kobayashi, T., Ishikawa, H., Mori, Y., Kaneko, K., and Kojima, C. High-transconductance AlInAs/GaInAs HIFETs grown by MOCVD p297
Kamada, O., Matsuda, K., Minemoto, H., Toda, K., and Ishizuka, S. see Matsuda, K.
Kameya, M., Tai, S., Kojima, K., Kyuma, K., Hamanaka, K., and Nakayama, T. Stabilisation of oscillation frequency of an AlGaAs/GaAs ridge waveguide distributed feedback laser p245
Kaminow, I.P., Iannone, P.P., Stone, J., and Stulz, L.W. FDM-FSK star network with a tunable optical filter demultiplexer p1102
Kamins, T.I. Gate-oxide integrity of silicon-on-insulator transistors p175
Kamins, T.I., and Colinge, J.P. see Colinge, J.P.
Kamite, K., Kihara, K., Sudo, H., Tanahashi, T., Kusunoki, T., Isozumi, S., Ishikawa, H., and Imai, H. see Kihara, K.
Kamiya, T., Liu, H.-F., and Hashimoto, Y. see Liu, H.-F.
Kamon, K., Ishii, M., Shimazu, M., Mihara, M., Kumabe, H., and Isshiki, K. see Ishii, M.
Kan, J.X., Garrett, I., and Jacobsen, G. Transformer-tuned front-ends for heterodyne optical receivers p785
Kan, J.X., Jacobsen, G., and Bødtker, E. Noise performance of Gbit/s tuned optical receivers p434
Kan, J.X., Jacobsen, G., and Garrett, I. see Jacobsen, G.
Kanada, T., Franzen, D.L., and Yamabayashi, Y. see Franzen, D.L.
Kandiyoor, S., and Limb, J.O. see Limb, J.O.
Kaneko, K., Kamada, M., Kobayashi, T., Ishikawa, H., Mori, Y., and Kojima, C. see Kamada, M.
Kaneko, K., Taira, K., and Kawai, H. see Taira, K.
Kano, G., Ueda, D., Takagi, H., and Teramoto, I. see Ueda, D.
Kaouri, H.A., McCanny, J.V., and Millar, W. Fast search techniques for use in vector quantisation and related pattern matching applications p311
Kaouri, H.A., and McCanny, J.V. Improved postfiltering technique for block quantisation of speech p1288
Kapon, E. Nonuniform phased arrays of diode lasers for fundamental supermode operation p879
Kapon, E., Deri, R.J., and Schiavone, L.M. see Deri, R.J.
Karapiperis, L., Regolini, J.L., Dutartre, D., Bensahel, D., Garry, G., and Dieumegard, D. see Regolini, J.L.
Kasahara, K., Suzuki, A., Itoh, T., Terakado, T., Asano, K., Inomoto, Y., Ishihara, H., Torikai, T., and Fujita, S. see Suzuki, A.
Kashiwa, S., Chang, J., and Harada, N. see Chang, J.
Kasper, B.L., Darcie, T.E., Burrus, C.A., Gnauck, A.H., and Talman, J.R. see Darcie, T.E.
Kasper, B.L., Darcie, T.E., Glance, B., Gayliard, K., Talman, J.R., and Burrus, C.A. see Darcie, T.E.
Kasper, B.L., Eisenstein, G., Tucker, R.S., Korotky, S.K., Raybon, G., Veselka, J.J., Buhl, L.L., Gnauck, A.H., and Alferness, R.C. see Eisenstein, G.
Kasper, B.L., Glance, B., Pollock, K., Burrus, C.A., Eisenstein, G., and Stulz, L.W. see Glance, B.
Kasper, B.L., Gnauck, A.H., Linke, R.A., Pollock, K.J., Reichmann, K.C., Valenzuela, R., and Alferness, R.C. see Gnauck, A.H.
Kasper, B.L., Tucker, R.S., Eisenstein, G., Korotky, S.K., Buhl, L.L., Veselka, J.J., Raybon, G., and Alferness, R.C. see Tucker, R.S.
Kasper, B.L., Tucker, R.S., Eisenstein, G., Korotky, S.K., Koren, U., Raybon, G., Veselka, J.J., Buhl, L.L., and Alferness, R.C. see Tucker, R.S.
Kasper, E., Luy, J.-F., and Baur, G. see Luy, J.-F.
Kastalsky, A., Abeles, J.H., Chan, W.K., Harbison, J.P., Florez, L.T., and Bhat, R. see Abeles, J.H.
Katsuyama, Y., Hatano, S., Hogari, K., and Kokubun, T. Higher-density single-mode optical fibre cables than 1 fibre/mm^2, containing hundreds of fibres p481
Kaufman, B., and Pozar, D.M. see Pozar, D.M.
Kawaguchi, H., Oe, K., Yasaka, H., Magari, K., Fukuda, M., and Itaya, Y. Tunable optical-wavelength conversion using a multielectrode distributed-feedback laser diode with a saturable absorber p1088
Kawaguchi, H., and Kawamura, Y. Room-temperature 1·55 μm optical bistability in a GaInAs/AlInAs multiple-quantum-well etalon p1013
Kawaguchi, Y., Wakita, K., Nojima, S., and Nakashima, K. see Wakita, K.
Kawai, H., Taira, K., and Kaneko, K. see Taira, K.
Kawai, Y., and Oshiba, S. see Oshiba, S.
Kawamura, Y., Tanaka, H., and Asahi, H. see Tanaka, H.
Kawamura, Y., Wakita, K., Asahi, H., and Oe, K. Optically bistable operation in InGaAs/InAlAs MQW laser diodes using resonant tunnelling effect p719
Kawamura, Y., Wakita, K., and Yoshikuni, Y. see Wakita, K.
Kawamura, Y., and Kawaguchi, H. see Kawaguchi, H.
Kawasaki, T., Yamada, A., and Kawashima, M. see Yamada, A.
Kawashima, M., Yamada, A., and Kawasaki, T. see Yamada, A.
Kawata, S., Fujii, H., Kobayashi, K., Gomyo, A., Hino, I., Hotta, H., and Suzuki, T. see Fujii, H.
Kawata, S., Fujii, H., Kobayashi, K., Gomyo, A., Hino, I., and Suzuki, T. Room-temperature continuous-wave operation of a 640 nm AlGaInP visible-light semiconductor laser p1327
Kawata, S., Gomyo, A., Kobayashi, K., Hino, I., and Suzuki, T. see Gomyo, A.
Kawata, T., Miyajima, Y., and Negishi, Y. see Miyajima, Y.
Kazarinov, R.F., Olsson, N.A., Johnson, B.H., Lee, H.J., Henry, C.H., Ackerman, D.A., and Anthony, P.J. see Olsson, N.A.
Kazeminejad, S., Howson, D.P., and Hamer, G. Base station multicoupler design for UK cellular radio systems p812
Kazovsky, L.G., Choy, M.M., Gimlett, J.L., Welter, R., and Cheung, N.K. see Choy, M.M.
Kazovsky, L.G., Elrefaie, A.F., Meissner, P., Welter, R., Crespo, P., Gimlett, J., and Smith, R.W. Impact of laser intensity noise on ASK two-port optical homodyne receivers p871
Kean, P.N., Smith, K., Sinclair, B.D., Sibbett, W., Rowe, C.J., and Reid, D.C.J. Characterisation of a fibre Raman oscillator using fibre grating reflectors p1241
Keightley, M., Nagara, S., Smith, S.G., and Denyer, P.B. see Nagara, S.
Keightley, M., and Smith, S.G. see Smith, S.G.
Kejian, Guan, Yizun, Wu, Tong, Yu, and Feng, Tian see Yizun, Wu
Kelly, M.J., Davies, R.A., and Kerr, T.M. see Davies, R.A.
Kelly, M.J., Razeghi, M., Tardella, A., Davies, R.A., Long, A.P., Britton, E., Boothroyd, C., and Stobbs, W.M. see Razeghi, M.
Kelty, S.P., Chan, W.K., Cox, H.M., and Abeles, J.H. see Chan, W.K.
Kendall, P.C., Stern, M.S., and Robson, P.N. Huygens-type formula for curvature loss from dielectric waveguides in optoelectronics p850
Kennedy, G.R., and Craig, K.H. see Craig, K.H.
Kennis, P., Ledee, R., Pribetich, P., and Chive, M. see Ledee, R.
Kerbyson, P., Anderson, A.P., and Bennett, J.C. Effect of support strut diffraction on reflector surface profile assessment p146
Kerr, T.M., Davies, R.A., and Kelly, M.J. see Davies, R.A.
Kersey, A.D., Dandridge, A., Tveten, A.B., and Yurek, A.M. see Dandridge, A.
Kersey, A.D., Yurek, A.M., Dandridge, A., and Weller, J.F. New polarisation-insensitive detection technique for coherent optical fibre heterodyne communications p924
Kersey, A.D., and Dandridge, A. Monomode fibre polarisation scrambler p634
Kesan, V.P., Campbell, A.C., Crook, G.E., Maziar, C.M., Neikirk, D.P., and Streetman, B.G. see Campbell, A.C.
Kheirallah, H.N., Rashwan, H.M., and Aboul-Saoud, A.K. see Rashwan, H.M.
Kheirallah, H.N., Rashwan, H.M., and Aboul-Saoud, A.K. M-profile ray tracing technique for multipath propagation p82
Khoe, G.D., and Mahon, C.J. see Mahon, C.J.
Ki Cho, Young Analysis of a narrow slit in a parallel-plate transmission line: *E*-polarisation case p1105 e1397
Ki, W.H., and Temes, G.C. see Temes, G.C.
Kiermasz, A., Taylor, S., Barlow, K.J., and Eccleston, W. see Taylor, S.
Kihara, K., Kamite, K., Sudo, H., Tanahashi, T., Kusunoki, T., Isozumi, S., Ishikawa, H., and Imai, H. High-power, wide-bandwidth, 1·55 μm-wavelength GaInAsP/InP distributed feedback laser p941

Kihara, K., Soda, H., Furutsu, M., Matsuda, M., Seki, H., Ogita, S., Ishikawa, H., and Imai, H. see Soda, H.
Kikuchi, K. Impact of 1/f-type FM noise on coherent optical communications p885
Kikuchi, K., and Habara, K. see Habara, K.
Kikuchi, K., and Yamaguchi, M. see Yamaguchi, M.
Kikuchi, K., and Zah, C.E. Spectral, phase noise and phase modulation characteristics of AM sideband injection-locked semiconductor lasers p437
Kim, B., Shih, H.D., and Wurtele, M. see Shih, H.D.
Kim, B., Wurtele, M., Shih, H.D., and Tserng, H.Q. High-performance GaAs power MESFET with AlGaAs buffer layer p1008
Kim, C.W., and Park, S.B. New four-quadrant CMOS analogue multiplier p1268
Kim, H.D., and Un, C.K. Embedded ADPCM with noise spectral shaping for packet voice transmission p239
Kim, J.-K., and Koh, J.-S. see Koh, J.-S.
Kim, Jae-kyoon, Chang, Byung-hwa, and Kim, Seong-Dae see Chang, Byung-hwa
Kim, N.C., and Jung, S.H. Adaptive image restoration using local statistics and directional gradient information p610
Kim, Se-Yun, and Ra, Jung-Woong Diffraction by a dielectric wedge with the Neumann expansion of correction currents on interfaces p630
Kim, Seong-Dae, Chang, Byung-hwa, and Kim, Jae-kyoon see Chang, Byung-hwa
Kim, Y.G., and Park, S.B. New dynamic focusing scheme for ultrasound scanners p181
Kimberley, M. Comparison of two statistical tests for keystream sequences p365
Kimura, T., and Sugimura, A. Linewidth reduction by coupled phase-shift distributed-feedback lasers p1014
Kinoshita, J. Validity of κL evaluation by stopband method for $\lambda/4$ DFB lasers with low reflecting facets p499
Kinoshita, J., Hirayama, Y., Okuda, H., Furuyama, H., and Nakamura, M. see Hirayama, Y.
Kinoshita, S., Iga, K., and Koyama, F. see Iga, K.
Kinoshita, T., Yamashita, K., Maeda, M., and Sekine, Y. Wideband variable peaking AGC amplifier for high-speed lightwave digital transmission p23
Kintz, G.J., Esterowitz, L., and Allen, R. CW diode-pumped Tm^{3+}, Ho^{3+}:YAG 2·1 μm room-temperature laser p616
Kipnis, I. 20 GHz frequency-divider silicon bipolar MMIC p1085
Kirk, E.C.G., Cleaver, J.R.A., and Ahmed, H. Observation of voltage contrast in scanning ion microscopy of integrated circuits p585
Kirkby, C.J.G. Implementation of multistage space-switch interconnections via the perfect shuffle p971
Kirkby, C.J.G., Cush, R., Trundle, C., and Bennion, I. see Cush, R.
Kishimoto, T., Sasaki, S., and Matsui, N. see Sasaki, S.
Kishimoto, T., and Sasaki, S. Cooling characteristics of diamond-shaped interrupted cooling fin for high-power LSI devices p456
Kishk, A.A., Auda, H.A., and Ahn, B.C. Accurate prediction of radiation patterns of dielectric resonator antennas p1374
Kitagawa, K., Namihira, Y., Horiuchi, Y., Wakabayashi, H., Oshimi, T., and Ooka, T. see Namihira, Y.
Kitagawa, T., Shibata, S., and Horiguchi, M. Wholly synthesised fluorine-doped silica optical fibres by sol-gel method p1295
Kitamura, M., Yamaguchi, M., Emura, K., Mito, I., and Kobayashi, K. see Yamaguchi, M.
Kitchener, D., Raghavan, K., and Parini, C.G. Mutual coupling in a finite planar array of rectangular apertures p1169
Klein, J., and Chang, K. see Chang, K.
Kleine, U. Novel sorter architecture for image processing rank order filters p45
Kleinwächter, A., Heidrich, H., von Helmolt, C.H., Hoffmann, D., and Hensel, H.-J. see Heidrich, H.
Knop, C.M. Front-to-back ratio of a smooth metallic-wall conical horn p388 e710
Knupke, H., Dietrich, E., Enning, B., and Gross, R. see Dietrich, E.
Kobayashi, K., Fujii, H., Kawata, S., Gomyo, A., Hino, I., Hotta, H., and Suzuki, T. see Fujii, H.
Kobayashi, K., Gomyo, A., Kawata, S., Hino, I., and Suzuki, T. see Gomyo, A.
Kobayashi, K., Kawata, S., Fujii, H., Gomyo, A., Hino, I., and Suzuki, T. see Kawata, S.
Kobayashi, K., Murata, S., and Mito, I. see Murata, S.
Kobayashi, K., Yamaguchi, M., Emura, K., Kitamura, M., and Mito, I. see Yamaguchi, M.
Kobayashi, M., Yamada, M., Terui, H., Yamada, Y., and Himeno, A. see Yamada, M.
Kobayashi, M., Yamada, M., Yamada, Y., Himeno, A., and Terui, H. Guided-wave optical chip-to-chip interconnections p143
Kobayashi, M., and Himeno, A. see Himeno, A.
Kobayashi, T., Kamada, M., Ishikawa, H., Mori, Y., Kaneko, K., and Kojima, C. see Kamada, M.
Kobrinski, H. Crossconnection of wavelength-division-multiplexed high-speed channels p974
Kobrinski, H., Bulley, R.M., Goodman, M.S., Vecchi, M.P., Brackett, C.A., Curtis, L., and Gimlett, J.L. Demonstration of high capacity in the LAMBDANET architecture: a multiwavelength optical network p824
Kobrinski, H., and Cheng, S.S. Laser power sharing in the subscriber loop p943
Koch, T.L., Koren, U., Boyd, G.D., Corvini, P.J., and Duguay, M.A. Antiresonant reflecting optical waveguides for III-V integrated optics p244
Koh, J.-S., and Kim, J.-K. Simple block-effect reduction method for image coding with vector quantisation p713
Koike, H., Shimba, M., Sato, T., and Sato, K. see Shimba, M.
Koizumi, Y., Yamazaki, S., Murata, S., Komatsu, K., Fujita, S., and Emura, K. see Yamazaki, S.
Kojima, C., Hirata, S., and Tamamura, K. see Hirata, S.
Kojima, C., Kamada, M., Kobayashi, T., Ishikawa, H., Mori, Y., and Kaneko, K. see Kamada, M.
Kojima, C., Nakano, K., Ikeda, M., and Toda, A. see Nakano, K.
Kojima, K., Kameya, M., Tai, S., Kyuma, K., Hamanaka, K., and Nakayama, T. see Kameya, M.
Kokkinakis, G., and Lymberopoulos, D. see Lymberopoulos, D.
Kokubun, T., Katsuyama, Y., Hatano, S., and Hogari, K. see Katsuyama, Y.
Kokubun, Y., Baba, T., Sakaki, T., and Iga, K. Low-loss antiresonant reflecting optical waveguide on Si substrate in visible-wavelength region e251
Kolinsky, P.V., Chad, R.J., Jones, R.J., Hall, S.R., Norman, P.A., Bloor, D., and Obhi, J.S. Second-harmonic generation in single crystals of 2-(N,N-dimethylamino)-5-nitroacetanilide (DAN) at 1·3 μm p791
Komatsu, K., Yamazaki, S., Murata, S., Koizumi, Y., Fujita, S., and Emura, K. see Yamazaki, S.
Konczykowska, A., Mulawka, J., and Bon, M. see Mulawka, J.
Kondo, M., Ohta, Y., Tanisawa, Y., Aoyama, T., and Ishikawa, R. Low-drive-voltage and low-loss polarisation-independent $LiNbO_3$ optical waveguide switches p1167
Kondo, Y., Itaya, Y., Oishi, M., Nakao, M., Sato, K., and Imamura, Y. see Itaya, Y.
Kondoz, A., and Evans, B.G. Vector-quantised transform coder for speech coding at 9·6 kbit/s and below p1286
Koo, K.P., Bucholtz, F., Yurek, A.M., and Dandridge, A. see Bucholtz, F.
Koo, K.P., Bucholtz, F., and Dandridge, A. Sideband noise of a large phase carrier in interferometric sensors p1062
Kooi, P.S., Chua, S.J., and Leong, M.S. see Chua, S.J.
Koren, U., Bowers, J.E., Miller, B.I., Soccolich, C., and Jan, W.Y. see Bowers, J.E.
Koren, U., Koch, T.L., Boyd, G.D., Corvini, P.J., and Duguay, M.A. see Koch, T.L.
Koren, U., Miller, B.I., Tucker, R.S., Eisenstein, G., Bar-Joseph, I., Miller, D.A.B., and Chemla, D.S. High-frequency InGaAs/InP multiple-quantum-well buried-mesa electroabsorption optical modulator p621
Koren, U., Tucker, R.S., Eisenstein, G., Korotky, S.K., Raybon, G., Veselka, J.J., Buhl, L.L., Kasper, B.L., and Alferness, R.C. see Tucker, R.S.
Koren, U., Whalen, M.S., Hall, K.L., Tennant, D.M., and Raybon, G. see Whalen, M.S.
Korotky, S.K., Eisenstein, G., Tucker, R.S., Raybon, G., Veselka, J.J., Buhl, L.L., Gnauck, A.H., Kasper, B.L., and Alferness, R.C. see Eisenstein, G.
Korotky, S.K., Tucker, R.S., Eisenstein, G., Buhl, L.L., Veselka, J.J., Raybon, G., Kasper, B.L., and Alferness, R.C. see Tucker, R.S.
Korotky, S.K., Tucker, R.S., Eisenstein, G., Koren, U., Raybon, G., Veselka, J.J., Buhl, L.L., Kasper, B.L., and Alferness, R.C. see Tucker, R.S.
Koshiba, M., Hayata, K., Eguchi, M., and Suzuki, M. see Hayata, K.
Koshiba, M., Hayata, K., and Nagai, M. see Hayata, K.
Koshiba, M., Hayata, K., and Suzuki, M. see Hayata, K.
Koshiba, M., and Hayata, K. see Hayata, K.
Koszi, L.A., Temkin, H., Chin, B.H., Napholtz, S.G., and Segner, B.P. Fabrication and performance of an InP/InGaAsP monolithic 12 × 12-element matrixed LED array p284
Kotaki, Y., Matsuda, M., Yano, M., Ishikawa, H., and Imai, H. 1·55 μm wavelength tunable FBH-DBR laser p325
Kouyoumjian, R.G., Manara, G., Tiberio, R., Pelosi, G., and Pathak, P.H. see Manara, G.
Kowalsky, W., Bornholdt, C., Döldissen, W., Fiedler, F., and Kaiser, R. see Bornholdt, C.
Koyama, F., Iga, K., and Kinoshita, S. see Iga, K.
Koyama, K. Identity-based conference key distribution system p495
Koyama, K., and Ohta, K. Identity-based conference key distribution systems in broadcast networks p647
Koza, M., Hayes, J.R., Bhat, R., and Schumacher, H. see Hayes, J.R.
Koza, M.A., Abeles, J.H., Chan, W.K., Shokoohi, F.K., and Bhat, R. see Abeles, J.H.
Krain, M., Way, W.I., and Wolff, R.S. see Way, W.I.
Kreissig, U., Skorupa, W., Hensel, E., and Bartsch, H. see Skorupa, W.
Kreit, D., and Youngquist, R.C. Polarisation-insensitive optical heterodyne receiver for coherent FSK communications p168
Krishnamurthy, V., and Sastry, G.V.K.R. see Sastry, G.V.K.R.
Krummenacher, F., Valencic, V., and Deval, P. see Valencic, V.
Ku, R.T., Jopson, R.M., Darcie, T.E., Gayliard, K.T., Tench, R.E., Rice, T.C., and Olsson, N.A. see Jopson, R.M.
Künzi, K., and Broennimann, J. Novel contacting method for millimetre-wave mixers p107
Kubodera, K., Tomaru, S., Zembutsu, S., Takeda, K., and Hasegawa, M. see Tomaru, S.
Kubodera, K.-I., Kaino, T., Tomaru, S., Kurihara, T., Saito, S., Tsutsui, T., and Tokito, S. see Kaino, T.
Kudou, T., Yokota, M., and Fukumitsu, O. see Yokota, M.
Kumabe, H., Ishii, M., Kamon, K., Shimazu, M., Mihara, M., and Isshiki, K. see Ishii, M.
Kumabe, H., Shima, A., Yamawaki, T., Saito, H., Matsubara, H., Murakami, T., Ohtaki, K., and Susaki, W. see Shima, A.
Kumar, A. Acetylene black: a single-layer microwave absorber p184
Kumar, A., and Sodha, M.S. General formalism for the study of nonlinear pulse propagation in optical fibres p275
Kumazawa, H., and Ohtomo, I. see Ohtomo, I.
Kung, H., Welch, D.F., DeVito, M., Cardinal, M., Abraham, M., Harnagel, G., Cross, P., Scifres, D., and Streifer, W. see Welch, D.F.
Kuo, C.Y., Park, Y.K., Granlund, S.W., Dixon, M., Cline, T.W., Smith, R.W., Dutta, N.K., and Vannucci, G. see Park, Y.K.
Kurihara, T., Kaino, T., Kubodera, K.-I., Tomaru, S., Saito, S., Tsutsui, T., and Tokito, S. see Kaino, T.
Kurobe, A., Nakamura, M., and Furuyama, H. see Nakamura, M.
Kurobe, A., and Newson, D.J. see Newson, D.J.
Kuroda, K., Nakano, J., Yuda, M., and Ueki, M. 3·0 ps switching operation in all-Nb Josephson logic gates p163
Kuroda, K., Ohta, J., Mitsunaga, K., Kyuma, K., Hamanaka, K., and Nakayama, T. see Ohta, J.
Kurosawa, K. kth least significant bit of a plaintext in reciprocal number cryptosystem p810
Kurosawa, K., Ito, T., and Takeuchi, M. Public key cryptosystem using a reciprocal number with same intractability as factoring a large number p809
Kurosawa, K., Tsujii, S., Itoh, T., Fujioka, A., and Matsumoto, T. see Tsujii, S.
Kurosawa, K., Tsujii, S., and Itoh, T. see Tsujii, S.
Kushibiki, J., and Chubachi, N. Application of LFB acoustic microscope to film thickness measurements p652
Kusunoki, T., Kihara, K., Kamite, K., Sudo, H., Tanahashi, T., Isozumi, S., Ishikawa, H., and Imai, H. see Kihara, K.
Kuwazuru, M., Namihira, Y., Horiuchi, Y., Nunokawa, M., and Iwamoto, Y. see Namihira, Y.
Kuwazuru, M., Namihira, Y., Ryu, S., Mochizuki, K., and Iwamoto, Y. see Namihira, Y.
Kwan, H.K. New systolic array for realising second-order recursive digital filters p442
Kwon, Y.R., Hietala, V.M., and Champlin, K.S. see Hietala, V.M.
Kwon, Young-Se, and Chae, Chang-Joon see Chae, Chang-Joon
Kyuma, K., Kameya, M., Tai, S., Kojima, K., Hamanaka, K., and Nakayama, T. see Kameya, M.
Kyuma, K., Ohta, J., Kuroda, K., Mitsunaga, K., Hamanaka, K., and Nakayama, T. see Ohta, J.

L

L'Haridon, H., Favennec, P.N., Le Corre, A., Salvi, M., and Gauneau, M. see Favennec, P.N.
Ladbrooke, P.H., Barton, T.M., Snowden, C.M., and Richardson, J.R. see Barton, T.M.
Lam, W.H., and Steele, R. Combined space and adaptive correlation diversity in the CD900 system p496
Land, D.V. Improved method for resonant-frequency perturbation measurements p1166
Landousies, B., Brosson, P., Fernier, B., Benoit, J., and Simon, J.C. see Brosson, P.
Landousies, B., Simon, J.C., Bossis, Y., Doussiere, P., Fernier, B., and Padioleau, D. see Simon, J.C.
Lange, W., Fernholz, G., Westphalen, R., and Beneking, H. see Fernholz, G.
Langenhorst, R., Paulus, P., and Jäger, D. see Paulus, P.
Langer, D.W., Ezis, A., and Rai, A.K. see Ezis, A.
Langmann, U., and Wang, Z. see Wang, Z.
Lanzisera, V., Olshansky, R., Powazinik, W., Hill, P., and Lauer, R.B. see Olshansky, R.
Lanzisera, V.A., and Olshansky, R. see Olshansky, R.
Lapierre, L., Larroque, J., Sombrin, J., and Sautereau, J.F. see Larroque, J.
Larroque, J., Sombrin, J., Lapierre, L., and Sautereau, J.F. High carrier rejection for a 3·7 to 4·2 GHz BPSK modulator p305
Lau, C.-L., and Ansari, R. see Ansari, R.
Lau, C.H. Self: A self-timed systems design technique p269

Lau, W.H., Austin, J., and Vilar, E. Improved Prony algorithm to identify multipath components p1059
Lauer, P., Leroy, Y., Van de Velde, J.C., and Mamouni, A. Thermometry of impedances by correlation radiometry p1348
Lauer, R.B., Olshansky, R., Powazinik, W., Hill, P., and Lanzisera, V. see Olshansky, R.
Law, V., Cheung, R., Thoms, S., Beamont, S.P., Doughty, G., and Wilkinson, C.D.W. see Cheung, R.
Le Corre, A., Favennec, P.N., L'Haridon, H., Salvi, M., and Gauneau, M. see Favennec, P.N.
Le Corre, A., Lecrosnier, D., Henry, L., and Vaudry, C. see Lecrosnier, D.
Leaver, K.D., Green, M., and Daniel, H. Behaviour of a novel cylindrical glass fibre optical coupler buried in KDP p820
Lebaric, J., and Kajfez, D. see Kajfez, D.
Lebby, M.S., Taylor, G.W., Chang, T.Y., Gnall, R.N., Sauer, N., Tell, B., and Simmons, J.G. see Taylor, G.W.
Leblanc, H.P., Chang, G.-K., Reith, L.A., and Chin, A.K. see Chang, G.-K.
Leblanc, H.P., Chang, G.-K., and Shumate, P.W. see Chang, G.-K.
Leclaire, P., Doyle, B.S., Bourcerie, M., Boudou, A., and Dars, P. see Doyle, B.S.
Lecrosnier, D., Dumas, J.-M., and Garat, F. see Dumas, J.-M.
Lecrosnier, D., Henry, L., Le Corre, A., and Vaudry, C. GaInAs junction FET fully dry etched by metal organic reactive ion etching technique p1254
Ledee, R., Pribetich, P., Kennis, P., and Chive, M. Approach to modelling of microstrip-microslot applicator p829
Lee, B.S., and Griffiths, J.W.R. Application of the simplex technique in motion estimation p903
Lee, C.-E., Atkins, R.A., and Taylor, H.F. Reflectively tapped optical fibre transversal filters p596
Lee, C.Q., and Batarseh, I. Performance characteristics of parallel resonant convertor p1273
Lee, C.T., Chou, Y.C., Chen, C.D., and Chu, K.C. see Chou, Y.C.
Lee, G.Y., Baier, S.M., Chung, H.K., Fure, B.J., and Cirillo, N.C. see Baier, S.M.
Lee, H.J., Olsson, N.A., Johnson, B.H., Henry, C.H., Kazarinov, R.F., Ackerman, D.A., and Anthony, P.J. see Olsson, N.A.
Lee, J.I., Crisman, E.E., Stiles, P.J., and Gregory, O.J. see Crisman, E.E.
Lee, K.F., Dahele, J.S., Mitchell, R.J., and Luk, K.M. see Dahele, J.S.
Lee, K.F., Lee, R.Q., and Acosta, R. see Lee, R.Q.
Lee, K.F., Lee, R.Q., and Bobinchak, J. see Lee, R.Q.
Lee, K.Y., Al-Mudares, M., Beaumont, S.P., Wilkinson, C.D.W., Frost, J., and Stanley, C.R. Very high-transconductance short-channel GaAs MESFETs with $Ga_{0.3}Al_{0.7}As$ buffer layer p11
Lee, Kwang-Won, and Park, Song-Bai Novel current control method for PWM inverters p1125
Lee, M., Shin, D., and Park, M. see Shin, D.
Lee, R.Q., Acosta, R., and Lee, K.F. Radiation characteristics of microstrip arrays with parasitic elements p835
Lee, R.Q., Lee, K.F., and Bobinchak, J. Characteristics of a two-layer electromagnetically coupled rectangular patch antenna p1070
Lee, R.Q.H., Oberhart, M.L., and Lo, Y.T. see Oberhart, M.L.
Lee, T.P., Menocal, S.G., Sakano, S., Valster, A., and Tsuji, S. Linewidth and FM characteristics of a distributed feedback laser monolithically integrated with a tunable external cavity p153
Lee, T.P., Osinski, J.S., Zah, C.E., Bhat, R., Contolini, R.J., Beebe, E.D., Cummings, K.D., and Harriott, L.R. see Osinski, J.S.
Lee, T.P., Zah, C.E., Osinski, J.S., Caneau, C., Menocal, S.G., Reith, L.A., Salzman, J., and Shokoohi, F.K. see Zah, C.E.
Lee, T.P., Zah, C.E., Osinski, J.S., Menocal, S.G., Tabatabaie, N., Dentai, A.G., and Burrus, C.A. see Zah, C.E.
Lee, W.S. Sensitivity of GaAs analogue integrated circuit building blocks to the effect of back-gating p587
Lee, W.S., and Mun, J. Improved negative feedback technique to reduce drain conductance of GaAs MESFETs for precision analogue ICs p705
Leminger, O., and Zengerle, R. Bandwidth of directional-coupler wavelength filters made of dissimilar optical fibres p241
Lennon, C.R., Harnagel, G.L., Cross, P.S., DeVito, M., and Scifres, D.R. see Harnagel, G.L.
Leonberger, F.J., Suchoski, P.G., and Findakly, T.K. see Suchoski, P.G.
Leong, M.S., Chua, S.J., and Kooi, P.S. see Chua, S.J.
Lepeltier, P., Floc'h, J.M., and Citerne, J. Complete and rigorous analysis of electromagnetically coupled transverse microstrip dipole p822
Leroy, M., and Monavon, M. see Monavon, M.
Leroy, Y., Lauer, P., Van de Velde, J.C., and Mamouni, A. see Lauer, P.
Levi, A.F.J., Chiu, T.H., and Tsang, W.T. see Chiu, T.H.
Li Kam Wa, P., Whitehead, M., Parry, G., Roberts, J.S., Mistry, P., and David, J.P.R. see Whitehead, M.
Li-sheng, Yu, Xiao-song, Jiang, Shu-min, Wang, and Hong-xun, Liu see Xiao-song, Jiang
Lichtman, E., Yaffe, H.H., Waarts, R.G., and Friesem, A.A. see Yaffe, H.H.
Lieber, W., Meier, J., Heinlein, W., Groh, W., Herbrechtsmeier, P., and Theis, J. see Meier, J.
Limb, J.O., and Kandiyoor, S. Improved scheduling of traffic for a high-speed slotted ring p806
Lin, S.C., Jing, X.L., Chin, M.K., Walpita, L.M., Yu, P.K.L., and Chang, W.S.C. GaInAsP buried channel EA modulator for 1·3 μm fibre links p1257
Lin, T.H., and Burgener, M.L. see Burgener, M.L.
Lindsay, J.F., and Enjeti, P. see Enjeti, P.
Linke, R.A., Gnauck, A.H., Kasper, B.L., Pollock, K.J., Reichmann, K.C., Valenzuela, R., and Alferness, R.C. see Gnauck, A.H.
Liou, K.-Y., Ohtsu, M., Burrows, E.C., Burrus, C.A., and Eisenstein, G. see Ohtsu, M.
Little, L.T., Davies, S.R., and Cunningham, C.T. see Davies, S.R.
Liu, G.S. Parallel merger p1069
Liu, H.-F., Hashimoto, Y., and Kamiya, T. Proposal of an optical triggering scheme for bistable semiconductor lasers: combination with photoconductors p532
Liu, K., Digonnet, M., Shaw, H.J., Ainslie, B.J., and Craig, S.P. 10 mW superfluorescent single-mode fibre source at 1060 nm p1320
Liu, Y.Y., Wang, H., Mittelstein, M., Chen, T.R., and Yariv, A. see Wang, H.
Livesey, M.J., and Owczarczyk, J. Fault-tolerant schemes for parallel architectures p1206
Lo, K.W., and Vu, T.B. Minimisation of mutual coupling effect on null steering by using guard elements p854
Lo, K.W., and Vu, T.B. Minimisation of mutual coupling effect on DOA estimation by using guard elements p611
Lo, Y.T., Oberhart, M.L., and Lee, R.Q.H. see Oberhart, M.L.
Lockhart, G.B., Bayes, T., Mehdi, A.A.A., and Al-Jalili, Y.O. Embedding data in DSB-AM using zero-synchronous modulation p745
Loisel, B., Chouan, Y., Pedrono, N., and Joubert, P. Low-temperature process for high-mobility polysilicon TFTs p288
Long, A.P., Razeghi, M., Tardella, A., Davies, R.A., Kelly, M.J., Britton, E., Boothroyd, C., and Stobbs, W.M. see Razeghi, M.
Long, S.A., and Garg, R. see Garg, R.
Lord, A., Blank, L.C., Bryant, E.G., Boggis, J.M., and Stallard, W.A. see Blank, L.C.
Loualiche, S., and Pauty, E. High-sensitivity sampling technique for luminescence time constant measurement p1017
Love, A.W. Equivalent circuit for aperture antennas p708
Love, J.D. Spot size, adiabaticity and diffraction in tapered fibres p993
Love, J.D., and Snyder, A.W. Radiation from single-mode helical fibres p1109
Love, J.D., and Stevenson, A.J. see Stevenson, A.J.
Lowe, K.S. High-speed GaAs 4 × 4-bit parallel multiplier using super capacitor FET logic p425
Lowry, A., and Hossain, S.Q.A.M.A. Vector quantisation for minimum residual energy in pitch prediction of speech p999
Lu, C.Y., Riffe, P.C., Tsai, N.S., Ahrens, R.E., and Banak, M.A. Using oxide sidewall taper to improve breakdown voltage in planar junction of DMOS devices by a simple process p407
Lucas, T.N. Taylor series approach to functional approximation for inversion of Laplace transforms p230
Ludwig, R., Großkopf, G., Waarts, R.G., and Weber, H.G. see Großkopf, G.
Luettgen, M., and Malvar, H.S. see Malvar, H.S.
Lugiez, F., Renaud, J.C., N'Guyen, L., Allovon, M., Heliot, F., and Scavennec, A. see Renaud, J.C.
Luk, K.M., Dahele, J.S., Mitchell, R.J., and Lee, K.F. see Dahele, J.S.
Luk, W., and Jones, G. Systolic arrays for recursive digital filtering p1174
Lundstrom, M.S., and Maziar, C.M. see Maziar, C.M.
Luo, Y., Nakano, Y., and Tada, K. see Nakano, Y.
Luy, J.-F., Baur, G., and Kasper, E. Space-charge-influenced avalanche-breakdown characteristics: an improved approximation p638
Lymberopoulos, D., and Kokkinakis, G. Method for analytic subscriber traffic data acquisition in telephone networks p1057

M

März, R., Cremer, C., Heise, G., Riechert, H., and Schienle, M. see Cremer, C.
Maamari, F., and Rajski, J. Reconvergent fanout analysis and fault simulation complexity of combinational circuits p1131
MacChesney, J.B., Johnson, D.W., Fleming, D.A., and Walz, F.W. Hybridised sol-gel process for optical fibres p1005
Madihian, M., Tanaka, S., Toyoshima, H., Hayama, N., and Honjo, K. see Tanaka, S.
Maeda, M., Kinoshita, T., Yamashita, K., and Sekine, Y. see Kinoshita, T.
Maenaka, K., Ohgusu, T., Ishida, M., and Nakamura, T. Novel vertical Hall cells in standard bipolar technology p1104
Magari, K., Kawaguchi, H., Oe, K., Yasaka, H., Fukuda, M., and Itaya, Y. see Kawaguchi, H.
Magnusson, U., Bohlin, K.E., Tove, P.A., and Tiren, J. see Bohlin, K.E.
Mahdjoubi, K., Penard, E., Daniel, J.P., and Terret, C. Mutual coupling between circular disc microstrip antennas p27
Mahon, C.J., and Khoe, G.D. Endless polarisation state matching control experiment using two controllers of finite control range p1234
Mahoney, L.J., Chen, C.L., Black, J.G., Doran, S.P., Courtney, W.E., Ehrlich, D.J., and Murphy, R.A. see Chen, C.L.
Majidi-Ahy, R., Omori, M., and Stoneham, E. Monolithic 2–6 GHz limiting amplifier p910
Majidi-Ahy, R., Riaziat, M., Feng, I.J., and Auld, B.A. see Riaziat, M.
Majidi-Ahy, R., Weingarten, K.J., Riaziat, M., Auld, B.A., and Bloom, D.M. Electro-optic sampling measurement of coplanar waveguide (coupled slot line) modes p1262
Malaiya, Y.K., Rajsuman, R., and Jayasumana, A.P. see Rajsuman, R.
Malaviya, N., and Jauhari, G. Power spectral density of CMI-coded TV signal transmitted through fibre-optic heterodyne system p1072
Malherbe, J.A.G., and Olivier, J.C. Resonant coupled stub in nonradiative dielectric waveguide p749
Malherbe, J.A.G., and Pistorius, C.W.I. Prediction of error due to distance in measurement or calculation of electromagnetic backscatter from a cylindrical body p1310
Malherbe, J.A.G., and Wijnbeek, M.C. Gunn diode oscillator constructed in nonradiative dielectric waveguide p1368
Mallinson, S.R., and Jerman, J.H. Miniature micromachined Fabry–Perot interferometers in silicon p1041
Malvar, H.S., and Luettgen, M. Temperature compensation of OTA-based filters and amplifiers p890
Mamouni, A., Lauer, P., Leroy, Y., and Van de Velde, J.C. see Lauer, P.
Manara, G., Tiberio, R., Pelosi, G., Pathak, P.H., and Kouyoumjian, R.G. Double diffraction by wedges in nonperfectly conducting surfaces p671
Manchanda, L., Watts, R.K., and Johnston, R.L. see Watts, R.K.
Mann, J.W., and Reith, L.A. see Reith, L.A.
Margittai, A., Houston, P.A., Blaauw, C., Svilans, M.N., Puetz, N., Day, D.J., Shepherd, F.R., and Springthorpe, A.J. see Houston, P.A.
Mariscal-Rico, L., Camacho-Peñalosa, C., and Alonso-Pardo, A. see Camacho-Peñalosa, C.
Marschall, P., and Jung, H. see Jung, H.
Marshall, I.W., Spirit, D.M., and O'Mahony, M.J. Picosecond pulse response of a travelling-wave semiconductor laser amplifier p818
Marshall, I.W., and O'Mahony, M.J. 10 GHz optical receiver using a travelling-wave semiconductor laser preamplifier p1052
Marshall, I.W., and Steele, R.C. see Steele, R.C.
Martellucci, A., Betti, S., De Marchis, G., and Iannone, E. see Betti, S.
Martin, D., Faist, J., and Reinhart, F.K. see Faist, J.
Martin, K.W. Gain enhancement technique for differential pairs p154
Maseng, T. Opening the knapsack by DFTs p95
Masin, V.J., Carlson, N.W., and Butler, J.K. see Carlson, N.W.
Masin, V.J., Goldstein, B., Carlson, N.W., Evans, G.A., and Dinkel, N.A. see Goldstein, B.
Mathew, A.V., and Unnikrishnan, R. see Unnikrishnan, R.
Matoba, A., Okayama, H., Shibuya, R., and Ishida, T. see Okayama, H.
Matsubara, H., Shima, A., Yamawaki, T., Saito, H., Murakami, T., Ohtaki, K., Kumabe, H., and Susaki, W. see Shima, A.
Matsuda, K., Minemoto, H., Toda, K., Kamada, O., and Ishizuka, S. Low-noise LD module with an optical isolator using a highly Bi-substituted garnet film p203
Matsuda, M., Kotaki, Y., Yano, M., Ishikawa, H., and Imai, H. see Kotaki, Y.
Matsuda, M., Soda, H., Kihara, K., Furutsu, M., Seki, H., Ogita, S., Ishikawa, H., and Imai, H. see Soda, H.
Matsui, N., Sasaki, S., and Kishimoto, T. see Sasaki, S.
Matsui, T., Sugimoto, H., Abe, Y., and Ogata, H. see Sugimoto, H.
Matsumoto, H., and Watanabe, K. Spike-free switched-capacitor circuits p428
Matsumoto, S., Ohno, T., and Izumi, K. CMOS on local SOI using SIMOX technology p576
Matsumoto, T., Tsujii, S., Itoh, T., Fujioka, A., and Kurosawa, K. see Tsujii, S.
Matsumura, H., Okai, M., Tsuji, S., and Hirao, M. see Okai, M.
Matsushima, Y., Akiba, S., Usami, M., and Utaka, K. see Akiba, S.
Matsushima, Y., Utaka, K., Sakai, K., and Takeuchi, O. Room-temperature CW operation of MBE-grown GaInAs/AlInAs MQW lasers in 1·5 μm range p1271
Maung, N.J., Hua, Y.L., Petty, M.C., Roberts, G.G.,

Ahmad, M.M., Yates, H.M., and Williams, J.O. see Hua, Y.L.
Mavor, J., and Carruthers, C. see Carruthers, C.
Mazerolle, D., Dieulesaint, E., and Royer, D. see Dieulesaint, E.
Maziar, C.M., Campbell, A.C., Kesan, V.P., Crook, G.E., Neikirk, D.P., and Streetman, B.G. see Campbell, A.C.
Maziar, C.M., and Lundstrom, M.S. Monte Carlo simulation of GaAs Schottky barrier behaviour p61
McCanny, J.V., Kaouri, H.A., and Millar, W. see Kaouri, H.A.
McCanny, J.V., and Kaouri, H.A. see Kaouri, H.A.
McConaghy, C. Optically strobed sample-and-hold circuit p234
McEachern, J.E., Grover, W.D., and Moore, T.E. see Grover, W.D.
McGillem, C.D., and Rappaport, T.S. see Rappaport, T.S.
McGregor, M.S., Smith, S.G., Denyer, P.B., and Murray, A.F. Serial-data computation on twin pipelines p292
McIlroy, P.W.A., Rodgers, P.M., Singh, J.S., Spurdens, P.C., and Henning, I.D. Low-loss single-mode InP/InGaAsP waveguides grown by MOVPE p701
McInnes, F.R., and Jack, M.A. Reference template adaptation in speaker-independent isolated word speech recognition p1304
McNamara, D.A. Excitations providing maximum directivity for difference arrays of discrete elements p780
McNamara, D.A. Maximisation of normalised boresight slope of a difference array of discrete elements p1158
McNamara, D.A. Quadratic forms for performance indices of symmetrical and antisymmetrical linear arrays p148
Mears, R.J., Reekie, L., Jauncey, I.M., and Payne, D.N. Low-noise erbium-doped fibre amplifier operating at 1·54 μm p1026
Mecozzi, A., Piazzolla, S., Sapia, A., and Spano, P. Statistics of phase noise in single-mode semiconductor lasers: free-running, weak external feedback and injection-locking configurations p1183
Mehdi, A.A.A., Lockhart, G.B., Bayes, T., and Al-Jalili, Y.O. see Lockhart, G.B.
Mei, K.K., Fang, J., and Zhang, X. see Fang, J.
Meißner, J. Calculation of the radiation losses of groove-guide *E*-plane bends p65
Meier, J., Lieber, W., Heinlein, W., Groh, W., Herbrechtsmeier, P., and Theis, J. Time-domain bandwidth measurements of step-index plastic optical fibres p1208
Meissner, E. Novel type of fibre-optic ring resonator p683
Meissner, P., Kazovsky, L.G., Elrefaie, A.F., Welter, R., Crespo, P., Gimlett, J., and Smith, R.W. see Kazovsky, L.G.
Menigaux, L., Sansonetti, P., Ribot, H., Brandon, J., Dugrand, L., and Bouadma, N. see Sansonetti, P.
Menocal, S.G., Lee, T.P., Sakano, S., Valster, A., and Tsuji, S. see Lee, T.P.
Menocal, S.G., Zah, C.E., Osinski, J.S., Caneau, C., Reith, L.A., Salzman, J., Shokoohi, F.K., and Lee, T.P. see Zah, C.E.
Menocal, S.G., Zah, C.E., Osinski, J.S., Tabatabaie, N., Lee, T.P., Dentai, A.G., and Burrus, C.A. see Zah, C.E.
Mermelstein, M.D., Askins, C., and Dandridge, A. Stress-relieved magnetoelastic amorphous metal DC magnetometer p280
Metselaar, J.W., van Oort, R.C., Geerts, M.J., and van den Heuvel, J.C. see van Oort, R.C.
Michalski, K.A. Missing boundary conditions of electromagnetics p480
Micheli, F., and Boyd, I.W. see Boyd, I.W.
Mickle, M.H., Tan, F., and Vogt, W.G. see Tan, F.
Midwinter, J.E., Bradley, P.J., Wheatley, P., Parry, G., Mistry, P., and Roberts, J.S. see Bradley, P.J.
Midwinter, J.E., Wheatley, P., Bradley, P.J., Whitehead, M., Parry, G., Mistry, P., Pate, M.A., and Roberts, J.S. see Wheatley, P.
Midwinter, J.E., Wheatley, P., Parry, G., Hill, G., Mistry, P., Pate, M.A., and Roberts, J.S. see Wheatley, P.
Migliora, C.G., and Chaves, M.B.F. Electromagnetic scattering by inhomogeneous dielectric cylinders p795
Mihara, M., Ishii, M., Kamon, K., Shimazu, M., Kumabe, H., and Isshiki, K. see Ishii, M.
Miler, M., and Skok, P. see Skok, P.
Millar, C.A., Miller, I.D., Ainslie, B.J., Craig, S.P., and Armitage, J.R. Low-threshold CW operation of an erbium-doped fibre laser pumped at 807 nm wavelength p865
Millar, W., Kaouri, H.A., and McCanny, J.V. see Kaouri, H.A.
Miller, B.I., Bowers, J.E., Koren, U., Soccolich, C., and Jan, W.Y. see Bowers, J.E.
Miller, B.I., Koren, U., Tucker, R.S., Eisenstein, G., Bar-Joseph, I., Miller, D.A.B., and Chemla, D.S. see Koren, U.
Miller, D.A.B., Koren, U., Miller, B.I., Tucker, R.S., Eisenstein, G., Bar-Joseph, I., and Chemla, D.S. see Koren, U.
Miller, D.A.B., Weiner, J.S., Gossard, A.C., English, J.H., Chemla, D.S., and Burrus, C.A. see Weiner, J.S.
Miller, I.D., Millar, C.A., Ainslie, B.J., Craig, S.P., and Armitage, J.R. see Millar, C.A.
Miller, W.C., Taheri, M., and Jullien, G.A. see Taheri, M.
Millicker, D.J., Stern, M., Elrefaie, A.E., and Runge, K. see Stern, M.
Millicker, D.J., and Standley, R.D. 2 Gbit/s timing recovery circuit using dielectric resonator filter p738
Min, Qian, and Wu, P.H. see Wu, P.H.
Minelly, J.D., and Hussey, C.D. Single-mode fibre Y-junction beam-splitter p1087
Minemoto, H., Matsuda, K., Toda, K., Kamada, O., and Ishizuka, S. see Matsuda, K.
Mirshekar-Syahkal, D., and Jia, B. Analysis of bilateral finline couplers p577
Mirshekar-Syahkal, D., and Mohammad Taheri, M. Unified approach to determination of modes in cylindrical cavities axisymmetrically loaded with dielectrics p1177
Mistry, P., Bradley, P.J., Wheatley, P., Parry, G., Midwinter, J.E., and Roberts, J.S. see Bradley, P.J.
Mistry, P., Powell, A.L., Roberts, J.S., and Rockett, P.I. see Powell, A.L.
Mistry, P., Roberts, J.S., Woodhead, J., Singh, K.C., and Sotomayor-Torres, C.M. see Roberts, J.S.
Mistry, P., Wheatley, P., Bradley, P.J., Whitehead, M., Parry, G., Midwinter, J.E., Pate, M.A., and Roberts, J.S. see Wheatley, P.
Mistry, P., Wheatley, P., Parry, G., Midwinter, J.E., Hill, G., Pate, M.A., and Roberts, J.S. see Wheatley, P.
Mistry, P., Whitehead, M., Parry, G., Roberts, J.S., Li Kam Wa, P., and David, J.P.R. see Whitehead, M.
Mitchell, C., and Wild, P. Switch reduction for bidirectional telephone systems p346
Mitchell, R.J., Dahele, J.S., Luk, K.M., and Lee, K.F. see Dahele, J.S.
Miteva, V.I., and Ivanov, K.P. Nonreciprocal effects in an azimuthally magnetised millimetre-wave solid-plasma circular guide p118
Mito, I., Murata, S., and Kobayashi, K. see Murata, S.
Mito, I., Ono, Y., Takano, S., and Nishida, N. see Ono, Y.
Mito, I., Yamaguchi, M., Emura, K., Kitamura, M., and Kobayashi, K. see Yamaguchi, M.
Mitsuhashi, Y., and Tsuchida, H. see Tsuchida, H.
Mitsunaga, K., Ohta, J., Kuroda, K., Kyuma, K., Hamanaka, K., and Nakayama, T. see Ohta, J.
Mittelstein, M., Wang, H., Liu, Y.Y., Chen, T.R., and Yariv, A. see Wang, H.
Miyahara, K., Aihara, K., and Hohkawa, K. see Aihara, K.
Miyajima, Y., Kawata, T., and Negishi, Y. Considerations on group delay fitting equations for dispersion-shifted fibres p1381
Miyashita, H., Onozawa, A., and Ueda, K. see Onozawa, A.
Miyazaki, M., Imoto, K., Sano, H., and Takasaki, Y. see Imoto, K.
Miyazaki, M., Imoto, K., and Sano, H. see Imoto, K.
Miyoshi, S., Aoki, A., and Shirafuji, J. see Aoki, A.
Mochizuki, K., Edagawa, N., and Iwamoto, Y. see Edagawa, N.
Mochizuki, K., Namihira, Y., Ryu, S., Furusawa, K., and Iwamoto, Y. see Namihira, Y.
Mochizuki, K., Namihira, Y., Ryu, S., Kuwazuru, M., and Iwamoto, Y. see Namihira, Y.
Mochizuki, K., Ryu, S., and Yamamoto, S. see Ryu, S.
Mohammad Taheri, M., and Mirshekar-Syahkal, D. see Mirshekar-Syahkal, D.
Mohanty, B.P., and Todd, T.D. Connection-based media access for multichannel local and metropolitan area networks p1237
Molesini, G., and Righini, G.C. see Righini, G.C.
Monavon, M., and Leroy, M. Numerical simulation of cruiser or aircraft lightning p640
Monerie, M., Francois, P.L., and Alard, F. see Francois, P.L.
Monerie, M., and Alard, F. Birefringence and polarisation dispersion measurements in high-birefringence single-mode fibres p198
Monerie, M., and Durteste, Y. Direct interferometric measurement of nonlinear refractive index of optical fibres by crossphase modulation p961
Moore, T.E., Grover, W.D., and McEachern, J.E. see Grover, W.D.
Morasca, S., Cinguino, P., Genova, F., Rigo, C., and Stano, A. see Cinguino, P.
Morgan, D.V., Thomas, H., Anderson, W.T., Thompson, P., Christou, A., and Diskett, D.J. High-temperature metallisation systems for transient annealing of GaAs p1154
Mori, Y., Kamada, M., Kobayashi, T., Ishikawa, H., Kaneko, K., and Kojima, C. see Kamada, M.
Morioka, T., Saruwatari, M., and Takada, A. Ultrafast optical multi/demultiplexer utilising optical Kerr effect in polarisation-maintaining single-mode fibres p453
Morioka, T., and Saruwatari, M. Determination of nondiagonal component n_{2BL} of nonlinear refractive index in polarisation-maintaining fibres utilising optical Kerr modulation scheme p1330
Morishita, K., Yataki, M.S., and Gambling, W.A. In-line optical fibre filters using dispersive materials p319
Morkoç, H., Chen, H.Z., Ghaffari, A., and Yariv, A. see Chen, H.Z.
Moroni, D., Wolny, M., Aguila, T., Deconinck, P., and Andre, J.P. see Wolny, M.
Morrison, C.B., Botez, D., and Zinkiewicz, L.M. 150 mW quasi-CW fundamental-mode operation from modified twin-channel laser p1025
Moseley, A.J., Scott, M.D., Williams, P.J., Wallis, R.H., Davies, J.I., and Riffat, J.R. Exciton electroabsorption at room temperature in InGaAs/InP multiquantum-well structures grown by p516
Moseley, A.J., Urquhart, J., Hodson, P.D., Riffat, J.R., and Davies, J.I. InGaAs/InP SAGM avalanche photodiodes incorporating a pseudoquaternary superlattice graded heterojunction grown by atmospheric-pressure MOCVD p914
Motosugi, G., Yasaka, H., Yoshikuni, Y., and Oe, K. see Yasaka, H.
Moule, D.J., Armistead, C.J., Butler, B.R., Clements, S.J., Collar, A.J., Wheeler, S.A., Fice, M.J., and Ahmed, H. see Armistead, C.J.
Mourou, G., Jackson, T., Nees, J., and Vallee, R. see Jackson, T.
Mukai, S., Itoh, M., Watanabe, M., Itoh, H., and Yajima, H. Buried-heterostructure diode lasers with *in-situ*-grown self-aligned GaAs mask for Zn diffusion p755
Mukai, S., Suzuki, Y., Yajima, H., and Sato, T. see Suzuki, Y.
Mukai, S., Watanabe, M., Itoh, H., and Yajima, H. Local beam deflector integrated in a diode laser cavity p361
Mukai, S., and Ogura, M. see Ogura, M.
Mukai, T., Inoue, K., and Saitoh, T. see Inoue, K.
Mukai, T., Inoue, K., and Saitoh, T. Signal gain saturation in two-channel common amplification using a 1·5 μm InGaAsP travelling-wave laser amplifier p396
Mukai, T., and Saitoh, T. see Saitoh, T.
Mukai, T., and Saitoh, T. 5·2 dB noise figure in a 1·5 μm InGaAsP travelling-wave laser amplifier p216
Mulawka, J., Konczykowska, A., and Bon, M. Switched-capacitor biquad with low influence of finite gains p1198
Mulombe, N., Kahlert, J., Piscalar, W., and Seehausen, G. 8·8 Gbit/s travelling-pulse word generator p703
Mun, J., and Lee, W.S. see Lee, W.S.
Muraguchi, M., Osafune, K., Enoki, T., and Ohwada, K. see Osafune, K.
Murakami, T., Shima, A., Yamawaki, T., Saito, H., Matsubara, H., Ohtaki, K., Kumabe, H., and Susaki, W. see Shima, A.
Murata, S., Mito, I., and Kobayashi, K. Frequency modulation and spectral characteristics for a 1·5 μm phase-tunable DFB laser p12
Murata, S., Mito, I., and Kobayashi, K. Over 720 GHz (5·8 nm) frequency tuning by a 1·5 μm DBR laser with phase and Bragg wavelength control regions p403
Murata, S., Yamazaki, S., Komatsu, K., Koizumi, Y., Fujita, S., and Emura, K. see Yamazaki, S.
Murch, A.R., and Bates, R.H.T. see Bates, R.H.T.
Murison, R.F., Houghton, A.J.N., Goodwin, A.R., Collar, A.J., and Davies, I.G.A. CW performance and life of 1·3 μm InGaAsP/InP lasers emitting at high facet power densities p601
Murphy, R.A., Chen, C.L., Black, J.G., Mahoney, L.J., Doran, S.P., Courtney, W.E., and Ehrlich, D.J. see Chen, C.L.
Murray, A.F., McGregor, M.S., Smith, S.G., and Denyer, P.B. see McGregor, M.S.
Murray, A.F., and Smith, A.V.W. Asynchronous arithmetic for VLSI neural systems p642
Muto, S., Imamura, K., Ohnishi, H., Fujii, T., and Yokoyama, N. see Imamura, K.

N

N'Guyen, L., Renaud, J.C., Allovon, M., Heliot, F., Lugiez, F., and Scavennec, A. see Renaud, J.C.
Nagai, M., Hayata, K., and Koshiba, M. see Hayata, K.
Nagara, S., Smith, S.G., Denyer, P.B., and Keightley, M. New channel routing algorithm for bit-slice applications p1389
Nagase, R., Shintaku, T., and Sugita, E. Effect of axial compressive force for connection stability in PC optic fibre connectors p103
Nagata, K., Nakajima, O., Nittono, T., Ito, H., and Ishibashi, T. Improved AlGaAs/GaAs HBT performance by InGaAs emitter cap layer p566
Nagata, K., Nakajima, O., Nittono, T., Ito, H., and Ishibashi, T. Self-aligned AlGaAs/GaAs HBT with InGaAs emitter cap layer p64
Nagata, K., Yamauchi, Y., Nakajima, O., Ito, H., Nittono, T., and Ishibashi, T. see Yamauchi, Y.
Nair, K.G., Jose, K.A., and Aanandan, C.K. see Jose, K.A.
Nair, K.G., and Aanandan, C.K. see Aanandan, C.K.
Nair, K.G., and Jose, K.A. see Jose, K.A.
Nakai, K., Soda, H., Ishikawa, H., and Imai, H. see Soda, H.
Nakajima, O., Nagata, K., Nittono, T., Ito, H., and Ishibashi, T. see Nagata, K.
Nakajima, O., Yamauchi, Y., Nagata, K., Ito, H., Nittono, T., and Ishibashi, T. see Yamauchi, Y.
Nakajima, Y., Takemoto, A., Sakakibara, Y., Fujiwara, M., Kakimoto, S., Namizaki, H., and Susaki, W. see Takemoto, A.
Nakamura, K., and Shimizu, H. Bulk-acoustic-wave

transducer consisting of intergidital electrodes on a grooved surface of $LiNbO_3$ p74
Nakamura, M., Furuyama, H., and Kurobe, A. 1 Gbit/s automatic-power-control-free zero-bias modulation of very-low threshold MQW laser diodes p1352
Nakamura, M., Hirayama, Y., Okuda, H., Furuyama, H., and Kinoshita, J. see Hirayama, Y.
Nakamura, M., Nishibe, T., Funamizu, M., Okuda, H., Furuyama, H., Hirayama, Y., and Iwamoto, M. see Nishibe, T.
Nakamura, T., Maenaka, K., Ohgusu, T., and Ishida, M. see Maenaka, K.
Nakano, H., Sato, M., and Yamauchi, J. Generation of a wide circularly polarised wave from a conical-helix antenna p387
Nakano, H., Yamauchi, J., and Imada, G. see Yamauchi, J.
Nakano, J., Kuroda, K., Yuda, M., and Ueki, M. see Kuroda, K.
Nakano, K., Ikeda, M., Toda, A., and Kojima, C. Very low threshold current density of a GaInP/AlGaInP double-heterostructure laser grown by MOCVD p894
Nakano, Y., Itaya, Y., Fukuda, M., Noguchi, Y., Yasaka, H., and Oe, K. 1·55 μm narrow-linewidth multielectrode DFB laser for coherent FSK transmission p826
Nakano, Y., Iwashita, K., Takachio, N., and Tsuzuki, N. see Iwashita, K.
Nakano, Y., Luo, Y., and Tada, K. AlGaAs/GaAs visible distributed feedback laser operating at 770 nm p1342
Nakano, Y., Yasaka, H., Yoshikuni, Y., and Oe, K. see Yasaka, H.
Nakao, M., Itaya, Y., Oishi, M., Sato, K., Kondo, Y., and Imamura, Y. see Itaya, Y.
Nakashima, K., Wakita, K., Nojima, S., and Kawaguchi, Y. see Wakita, K.
Nakayama, T., Kameya, M., Tai, S., Kojima, K., Kyuma, K., and Hamanaka, K. see Kameya, M.
Nakayama, T., Ohta, J., Kuroda, K., Mitsunaga, K., Kyuma, K., and Hamanaka, K. see Ohta, J.
Nakwaski, W. Thermal model of laser diode arrays p458
Namihira, Y., Horiuchi, Y., Kuwazuru, M., Nunokawa, M., and Iwamoto, Y. Optimum fibre parameters of low-loss single-mode optical fibres for use in 1·55 μm-wavelength region p963
Namihira, Y., Horiuchi, Y., Wakabayashi, H., Oshimi, T., Kitagawa, K., and Ooka, T. OTDR in a 147 km single-mode fibre in 1·55 μm wavelength region using an LD and GaInAs/InP APD at room temperature p1219
Namihira, Y., Horiuchi, Y., and Wakabayashi, H. Dynamic polarisation fluctuation characteristics of optical fibre submarine cable coupling under periodic variable tension p1201
Namihira, Y., Horiuchi, Y., and Wakabayashi, H. Spectral response measurements on polarisation splitting ratio of fused-taper single-mode fibre couplers p1204
Namihira, Y., Ryu, S., Kuwazuru, M., Mochizuki, K., and Iwamoto, Y. Polarisation fluctuation of submarine-cabled single-mode optical fibres in ocean installation p343
Namihira, Y., Ryu, S., Mochizuki, K., Furusawa, K., and Iwamoto, Y. Polarisation fluctuation in optical-fibre submarine cable under 8000 m deep sea environmental conditions p100 e306
Namizaki, H., Takemoto, A., Sakakibara, Y., Nakajima, Y., Fujiwara, M., Kakimoto, S., and Susaki, W. see Takemoto, A.
Nandi, R. Precise realisation of an insensitive floating negative admittance convertor p775
Nani, G., Silard, A., Floru, F., and Ştefan, C. see Silard, A.
Napholtz, S.G., Koszi, L.A., Temkin, H., Chin, B.H., and Segner, B.P. see Koszi, L.A.
Nardone, A., and Bucciarelli, T. see Bucciarelli, T.
Nathu, V.P., Poole, C.D., Bergano, N.S., Schulte, H.J., Wagner, R.E., Amon, J.M., and Rosenberg, R.L. see Poole, C.D.
Nauwelaers, B., and Van De Capelle, A. Characteristic impedance of stripline p930
Nazarathy, M., Jungerman, R.L., Johnsen, C.A., and Dolfi, D.W. see Jungerman, R.L.
Nees, J., Jackson, T., Vallee, R., and Mourou, G. see Jackson, T.
Negishi, Y., Miyajima, Y., and Kawata, T. see Miyajima, Y.
Neikirk, D.P., Campbell, A.C., Kesan, V.P., Crook, G.E., Maziar, C.M., and Streetman, B.G. see Campbell, A.C.
Neil, C.C., Carlson, N.W., Evans, G.A., and Hammer, J.M. see Carlson, N.W.
Nel, A.L., Hope, J.F., and Ferreira, H.C. see Hope, J.F.
Neumann, E.-G., and Schwierz, H. see Schwierz, H.
Newson, D.J., and Kurobe, A. Effect of residual doping on optimum structure of multiquantum-well optical modulators p439
Newson, T.P., Gerges, A.S., Farahi, F., Jones, J.D.C., and Jackson, D.A. see Gerges, A.S.
Newton, S.A., and Sorin, W.V. see Sorin, W.V.
Neyer, A., and Pohlmann, T. Fabrication of low-loss titanium-diffused $LiNbO_3$ waveguides using a closed platinum crucible p1187
Ng, T.S., and Chicharo, J.F. see Chicharo, J.F.
Nguyen, D.T., and Xu, D.-Y. Efficient technique for scale-space imaging of planar objects p1326
Nichols, T.B., and Wyndham, B.A. see Wyndham, B.A.
Nicholson, G., and Stephens, T.D. see Stephens, T.D.
Niiro, Y., and Sakaguchi, H. see Sakaguchi, H.
Nikoonahad, M. Differential phase contrast acoustic microscopy using tilted transducers p489
Nilsson, O., Gillner, L., and Goobar, E. Formulas for direct frequency modulation response of two-electrode diode lasers: proposals for improvement p1371
Nilsson, S., Broberg, B., and Tanbun-Ek, T. see Broberg, B.
Nisbet, W.T., Helszajn, J., and Sharp, J. see Helszajn, J.
Nishibe, T., Funamizu, M., Okuda, H., Furuyama, H., Hirayama, Y., Nakamura, M., and Iwamoto, M. Entirely VPE-grown 1·5 μm DFB lasers with low threshold currents p34
Nishida, N., Ono, Y., Takano, S., and Mito, I. see Ono, Y.
Nishii, K., Utsumi, K., Tezuka, A., Bando, K., Inoue, K., and Onuma, T. see Utsumi, K.
Nishiki, S., Nojima, T., and Chiba, K. see Nojima, T.
Nittono, T., Nagata, K., Nakajima, O., Ito, H., and Ishibashi, T. see Nagata, K.
Nittono, T., Yamauchi, Y., Nagata, K., Nakajima, O., Ito, H., and Ishibashi, T. see Yamauchi, Y.
Nixon, J., Uttamchandani, D., Thornton, K.E.B., and Culshaw, B. see Uttamchandani, D.
Nobuhara, H., Fujii, T., and Wada, O. Low-drive-current, high-efficiency AlGaAs/GaAs SQW laser p645
Nobuhara, H., Wada, O., and Fujii, T. Slope angle influence on silicon doping in AlGaAs/GaAs MBE-grown on stepped surface of (100) GaAs substrate p35
Noerpel, A.R., and Ranade, A. see Ranade, A.
Noguchi, Y., Nakano, Y., Itaya, Y., Fukuda, M., Yasaka, H., and Oe, K. see Nakano, Y.
Nojima, S., Wakita, K., Nakashima, K., and Kawaguchi, Y. see Wakita, K.
Nojima, T., Nishiki, S., and Chiba, K. High-efficiency quasimicrowave GaAs FET power amplifier p512
Norman, P.A., Kolinsky, P.V., Chad, R.J., Jones, R.J., Hall, S.R., Bloor, D., and Obhi, J.S. see Kolinsky, P.V.
Nose, T., and Sato, S. Linearising method for nonlinear properties in a liquid-crystal lens p878
Nosu, K., Toba, H., Oda, K., and Takato, N. see Toba, H.
Nosu, K., and Toba, H. see Toba, H.
Nozawa, T. Growth and properties of an $LiNbO_3$ film on sapphire with an $LiNbO_3$ buffer layer p1321
Nudd, G.R., and Vaudin, G.J. see Vaudin, G.J.
Nunokawa, M., Namihira, Y., Horiuchi, Y., Kuwazuru, M., and Iwamoto, Y. see Namihira, Y.
Nunokawa, M., Shimizu, K., and Fujise, M. see Shinizu, K.

O

O'Byrne, V., and O'Reilly, J.J. Nonlinear distortion produced by an injection-locked laser p955
O'Mahony, M.J., Marshall, I.W., and Spirit, D.M. see Marshall, I.W.
O'Mahony, M.J., and Marshall, I.W. see Marshall, I.W.
O'Mahony, M.J., and Westlake, H.J. see Westlake, H.J.
O'Reilly, J.J., and O'Byrne, V. see O'Byrne, V.
O'Reilly, J.J., and Schumacher, K. see Schumacher, K.
O'Reilly, J.J., and Silva, H.J.A. Chirp-induced penalty in optical fibre systems p992
O'Sullivan, M.S., and Gransden, D.W. Fizeau fringe interferometer for fibre outside diameter measurements p666
O'Sullivan, P.J., Allan, D.A., and Gilbert, M.J. see Allan, D.A.
Oakley, K., Stern, J.R., Ballance, J.W., Faulkner, D.W., Hornung, S., and Payne, D.B. see Stern, J.R.
Oberhart, M.L., Lo, Y.T., and Lee, R.Q.H. New simple feed network for an array module of four microstrip elements p436
Obhi, J.S., Kolinsky, P.V., Chad, R.J., Jones, R.J., Hall, S.R., Norman, P.A., and Bloor, D. see Kolinsky, P.V.
Oda, K., Toba, H., Takato, N., and Nosu, K. see Toba, H.
Odasso, M., and Scapino, F. Graphical technique for crosstalk timing analysis p864
Oe, K., Kawaguchi, H., Yasaka, H., Magari, K., Fukuda, M., and Itaya, Y. see Kawaguchi, H.
Oe, K., Kawamura, Y., Wakita, K., and Asahi, H. see Kawamura, Y.
Oe, K., Nakano, Y., Itaya, Y., Fukuda, M., Noguchi, Y., and Yasaka, H. see Nakano, Y.
Oe, K., Yasaka, H., Yoshikuni, Y., and Motosugi, G. see Yasaka, H.
Oe, K., Yasaka, H., Yoshikuni, Y., and Nakano, Y. see Yasaka, H.
Ogata, H., Sugimoto, H., Abe, Y., and Matsui, T. see Sugimoto, H.
Ogita, S., Hirano, M., Soda, H., Yano, M., Ishikawa, H., and Imai, H. Dependence of spectral linewidth of DFB lasers on facet reflectivity p347
Ogita, S., Soda, H., Kihara, K., Furutsu, M., Matsuda, M., Seki, H., Ishikawa, H., and Imai, H. see Soda, H.
Ogita, S., Yano, M., Ishikawa, H., and Imai, H. Linewidth reduction in DFB laser by detuning effect p393
Ogura, M., Sasai, Y., Ohya, J., and Kajiwara, T. see Sasai, Y.
Ogura, M., Wu, Y.-H., Werner, M., and Wang, S. see Wu, Y.-H.
Ogura, M., and Mukai, S. Distributed-feedback, surface-emitting laser diode with lateral double heterostructure p758
Oh, K.H., Ong, C.K., and Tan, B.T.G. Elimination of ambiguity in measurement of permittivity with short-circuited waveguide p1181
Ohgusu, T., Maenaka, K., Ishida, M., and Nakamura, T. see Maenaka, K.
Ohishi, Y., and Sakaguchi, S. Spectral attenuation measurement for fluoride glass single-mode fibres by Fourier transform techniques p272
Ohnishi, H., Imamura, K., Muto, S., Fujii, T., and Yokoyama, N. see Imamura, K.
Ohno, K., and Adachi, F. GMSK frequency detection using decision feedback equalisation p1350
Ohno, K., and Adachi, F. Half-bit offset decision frequency detection of differentially encoded GMSK signals p1311
Ohno, T., Izumi, K., Shimaya, M., and Shiono, N. CMOS/SIMOX devices having a radiation hardness of 2 Mrad(Si) p141
Ohno, T., Matsumoto, S., and Izumi, K. see Matsumoto, S.
Ohta, J., Kuroda, K., Mitsunaga, K., Kyuma, K., Hamanaka, K., and Nakayama, T. Monolithic integration of a transverse-junction stripe laser and metal-semiconductor field-effect transistors on a semi-insulating GaAs substrate p509
Ohta, K., and Koyama, K. see Koyama, K.
Ohta, Y., Ajisawa, A., Fujiwara, M., Shimizu, J., Sugimoto, M., and Uchida, M. see Ajisawa, A.
Ohta, Y., Kondo, M., Tanisawa, Y., Aoyama, T., and Ishikawa, R. see Kondo, M.
Ohtaki, K., Shima, A., Yamawaki, T., Saito, H., Matsubara, H., Murakami, T., Kumabe, H., and Susaki, W. see Shima, A.
Ohtomo, I., and Kumazawa, H. Low-loss and lightweight on-board 20 GHz-band pill-box-type directional filter p582
Ohtoshi, T. Effect of facet coatings on far fields of semiconductor lasers p570
Ohtsu, M., Liou, K.-Y., Burrows, E.C., Burrus, C.A., and Eisenstein, G. Interferometric method for preventing mode-hopping in tunable external-cavity semiconductor lasers p1111
Ohwada, K., Osafune, K., Enoki, T., and Muraguchi, M. see Osafune, K.
Ohya, J., Sasai, Y., Ogura, M., and Kajiwara, T. see Sasai, Y.
Oishi, M., Itaya, Y., Nakao, M., Sato, K., Kondo, Y., and Imamura, Y. see Itaya, Y.
Okai, M., Tsuji, S., Hirao, M., and Matsumura, H. New high-resolution positive and negative photoresist method for $\lambda/4$-shifted DFB lasers p370
Okamoto, K., Hosaka, T., and Sudo, S. see Hosaka, T.
Okamoto, T. Modification of a public-key cryptosystem p814
Okamura, H. Fibre-optic magnetic sensor utilising metal-coated fibre p834
Okayama, H., Matoba, A., Shibuya, R., and Ishida, T. Optically biased $LiNbO_3$ $\Delta\beta$ reversal directional coupler switch p1145
Okoshi, T., and Cheng, Y.H. Four-port homodyne receiver for optical fibre communications comprising phase and polarisation diversities p377
Okuda, E., Seki, M., Sugawara, R., Hanada, Y., Wada, H., and Yamasaki, T. see Seki, M.
Okuda, H., Hirayama, Y., Furuyama, H., Kinoshita, J., and Nakamura, M. see Hirayama, Y.
Okuda, H., Nishibe, T., Funamizu, M., Furuyama, H., Hirayama, Y., Nakamura, M., and Iwamoto, M. see Nishibe, T.
Okugawa, S., and Inoue, N. Systematic design of D flip-flops using two state variables p909
Oldfield, J.V., Williams, R.D., and Wiseman, N.E. Content-addressable memories for storing and processing recursively subdivided images and trees p262
Oliver, S.N., Hill, J.R., Dunn, P.L., Davies, G.J., Pantelis, P., and Rush, J.D. see Hill, J.R.
Olivier, J.C., and Malherbe, J.A.G. see Malherbe, J.A.G.
Olivier, P.D. Reduced-order models using optimal Laguerre approximations p257
Olshansky, R., Powazinik, W., Hill, P., Lanzisera, V., and Lauer, R.B. InGaAsP buried heterostructure laser with 22 GHz bandwidth and high modulation efficiency p839
Olshansky, R., and Lanzisera, V.A. 60-channel FM video subcarrier multiplexed optical communication system p1196
Olsson, H.K. Novel microstrip transformer for superconducting microelectronics p1152
Olsson, N.A. 15 000 km fibre-optic transmission using a linear repeater p659
Olsson, N.A., Johnson, B.H., Lee, H.J., Henry, C.H., Kazarinov, R.F., Ackerman, D.A., and Anthony, P.J. Coherent transmission using an external waveguide Bragg reflector laser with direct frequency modulation p687
Olsson, N.A., Jopson, R.M., Darcie, T.E., Gayliard,

K.T., Ku, R.T., Tench, R.E., and Rice, T.C. see Jopson, R.M.
Olsson, N.A., and Buhl, L.L. Single-laser high-selectivity bidirectional transmission system for local-area-network applications p62
Olsson, N.A., and Dutta, N.K. see Dutta, N.K.
Omori, M., Majidi-Ahy, R., and Stoneham, E. see Majidi-Ahy, R.
Ong, C.K., Oh, K.H., and Tan, B.T.G. see Oh, K.H.
Ono, Y., Takano, S., Mito, I., and Nishida, N. Phase-shifted diffraction-grating fabrication using holographic wavefront reconstruction p57
Onozawa, A., Miyashita, H., and Ueda, K. Probabilistic compaction algorithm for LSI cell layout design p408
Onuma, T., Utsumi, K., Tezuka, A., Nishii, K., Bando, K., and Inoue, K. see Utsumi, K.
Ooka, T., Namihira, Y., Horiuchi, Y., Wakabayashi, H., Oshimi, T., and Kitagawa, K. see Namihira, Y.
Orloff, J., Puretz, J., DeFreez, R.K., Elliott, R.A., and Paoli, T.L. see Puretz, J.
Orta, R., Tascone, R., and Zich, R. Efficient choice of basis functions in moment method analysis of frequency-selective surfaces p586
Orton, D.W.R. Novel CMOS latch with clock hysteresis p1221
Osafune, K., Enoki, T., Muraguchi, M., and Ohwada, K. 20 GHz dynamic frequency divider with GaAs advanced SAINT and air-bridge technology p300
Oshiba, S., and Kawai, Y. High-power aging tests of 1·3 and 1·5 μm VIPS lasers p843
Oshimi, T., Namihira, Y., Horiuchi, Y., Wakabayashi, H., Kitagawa, K., and Ooka, T. see Namihira, Y.
Osinski, J.S., Zah, C.E., Bhat, R., Contolini, R.J., Beebe, E.D., Lee, T.P., Cummings, K.D., and Harriott, L.R. Miniature integrated optical beam-splitter in AlGaAs/GaAs ridge waveguides p1156
Osinski, J.S., Zah, C.E., Caneau, C., Menocal, S.G., Reith, L.A., Salzman, J., Shokoohi, F.K., and Lee, T.P. see Zah, C.E.
Osinski, J.S., Zah, C.E., Menocal, S.G., Tabatabaie, N., Lee, T.P., Dentai, A.G., and Burrus, C.A. see Zah, C.E.
Osowski, S. Computer simulation of SC circuits using NAP p547 e763
Othman, M.B., and Brunnschweiler, A. Electrothermally excited silicon beam mechanical resonators p728
Owczarczyk, J. Design of PE structure of a parallel image processor p121
Owczarczyk, J., and Livesey, M.J. see Livesey, M.J.
Owen, A.E., Choi, W.K., Delima, J.J., and Gage, S.M. see Choi, W.K.

P

Paccagnella, A., Canali, C., Donzelli, G., Fantini, F., and Vanzi, M. see Canali, C.
Pacifici, G., and Pattavina, A. see Pattavina, A.
Padioleau, D., Simon, J.C., Landousies, B., Bossis, Y., Doussiere, P., and Fernier, B. see Simon, J.C.
Palmateer, L.F., Tasker, P.J., Itoh, T., Brown, A.S., Wicks, G.W., and Eastman, L.F. Microwave characterisation of 1 μm-gate $Al_{0.48}In_{0.52}As/Ga_{0.47}In_{0.53}As/InP$ MODFETs p53
Palmier, J.F., Sibille, A., Harmand, J.C., and Dangla, J. AlGaAs/GaAs bipolar transistors with a modulation-doped superlattice emitter p936
Pannell, C.N., Tatam, R.P., Jones, J.D.C., and Jackson, D.A. Optical frequency shifter using linearly birefringent monomode fibre p847
Pantchev, B.G. One-step field-assisted ion exchange for fabrication of buried multimode optical strip waveguides p1188
Pantelis, P., Hill, J.R., Dunn, P.L., Davies, G.J., Oliver, S.N., and Rush, J.D. see Hill, J.R.
Paoli, T., Welch, D.F., Thornton, R.L., and Streifer, W. see Welch, D.F.
Paoli, T.L., Epler, J.E., and Thornton, R.L. see Epler, J.E.
Paoli, T.L., Puretz, J., DeFreez, R.K., Elliott, R.A., and Orloff, J. see Puretz, J.
Papuchon, M., Delacourt, D., di Forte-Poisson, M.A., and Razeghi, M. see Delacourt, D.
Parent, M., Tamburrini, M., Goldberg, L., and Stillwell, D. see Tamburrini, M.
Parikh, N., Humphreys, T.P., Das, K., Bedair, S.M., Wortman, J.J., Chu, W.K., El-Masry, N., and Tarn, J.C.L. see Humphreys, T.P.
Parini, C.G., Kitchener, D., and Raghavan, K. see Kitchener, D.
Park, M., Shin, D., and Lee, M. see Shin, D.
Park, Moon-Soo, Hwang, Jun-Am, and Chun, Young-Yun Flicker noise effect on sensitivity of PIN-(GaAs)FET fibre-optic receiver p631
Park, S.-B., Shin, D.-H., and Cho, G.-H. see Shin, D.-H.
Park, S.B., and Kim, C.W. see Kim, C.W.
Park, S.B., and Kim, Y.G. see Kim, Y.G.
Park, Song-Bai, and Lee, Kwang-Won see Lee, Kwang-Won
Park, Y.K., Granlund, S.W., Kuo, C.Y., Dixon, M., Cline, T.W., Smith, R.W., Dutta, N.K., and Vannucci, G. Crosstalk penalty in a two-channel ASK heterodyne detection system with non-negligible laser linewidth p1291
Parker, D.G., Say, P.G., Hansom, A.M., and Sibbett, W. 110 GHz high-efficiency photodiodes fabricated from indium tin oxide/GaAs p527
Parry, G., Bradley, P.J., Wheatley, P., Midwinter, J.E., Mistry, P., and Roberts, J.S. see Bradley, P.J.
Parry, G., Wheatley, P., Bradley, P.J., Whitehead, M., Midwinter, J.E., Mistry, P., Pate, M.A., and Roberts, J.S. see Wheatley, P.
Parry, G., Wheatley, P., Midwinter, J.E., Hill, G., Mistry, P., Pate, M.A., and Roberts, J.S. see Wheatley, P.
Parry, G., Whitehead, M., Roberts, J.S., Mistry, P., Li Kam Wa, P., and David, J.P.R. see Whitehead, M.
Pate, M.A., Wheatley, P., Bradley, P.J., Whitehead, M., Parry, G., Midwinter, J.E., Mistry, P., and Roberts, J.S. see Wheatley, P.
Pate, M.A., Wheatley, P., Parry, G., Midwinter, J.E., Hill, G., Mistry, P., and Roberts, J.S. see Wheatley, P.
Pathak, P.H., Manara, G., Tiberio, R., Pelosi, G., and Kouyoumjian, R.G. see Manara, G.
Pattavina, A., and Pacifici, G. Bandwidth allocation in buffer insertion rings p220
Paulus, P., Langenhorst, R., and Jäger, D. Stable pulsations of semiconductor lasers by optoelectronic feedback with avalanche photodiodes p471
Pauty, E., and Loualiche, S. see Loualiche, S.
Pavuna, D., Glick, M., and Reinhart, F.K. see Glick, M.
Payne, D.B., Stern, J.R., Ballance, J.W., Faulkner, D.W., Hornung, S., and Oakley, K. see Stern, J.R.
Payne, D.N., Farries, M.C., Russell, P.St.J., and Fermann, M.E. see Farries, M.C.
Payne, D.N., Mears, R.J., Reekie, L., and Jauncey, I.M. see Mears, R.J.
Payne, D.N., Reekie, L., Jauncey, I.M., and Poole, S.B. see Reekie, L.
Payne, D.N., Townsend, J.E., and Poole, S.B. see Townsend, J.E.
Payne, F.P. Second-harmonic generation in single-mode optical fibres p1215
Pedrono, N., Loisel, B., Chouan, Y., and Joubert, P. see Loisel, B.
Pellaux, J.-P., and Thevenaz, L. see Thevenaz, L.
Pellaux, J.-P., von der Weid, J.-P., and Thevenaz, L. see von der Weid, J.-P.
Pelosi, G., Manara, G., Tiberio, R., Pathak, P.H., and Kouyoumjian, R.G. see Manara, G.
Penard, E., Mahdjoubi, K., Daniel, J.P., and Terret, C. see Mahdjoubi, K.
Peransin, J.M., Rigaud, D., and Alabedra, R. Avalanche noise associated with gate current of Si JFET p970
Percival, T.M.P., Thorn, J.S., and Driver, R. Measurements of high-T_c superconductivity in a microwave cavity p1225
Perez-Rodriquez, R., and Ungvichian, V. see Ungvichian, V.
Perez-Verdu, B., Rodriguez-Vazquez, A., Rueda, A., and Huertas, J.L. see Rodriguez-Vazquez, A.
Pesant, J.C., Constant, E., Caglio, N., and Chevallier, J. see Constant, E.
Petermann, K., Wang, J., and Schunk, N. see Wang, J.
Petkov, N. Systolic array for all-nearest-neighbours problem p1259
Petriu, E.M. New pseudorandom encoding technique for shaft encoders with any desired resolution p507
Pettitt, M.J., Remedios, D., Davis, A.W., Hadjifotiou, A., and Wright, S. Optical FSK transmission system using a phase-diversity receiver p1075
Petty, M.C., Hua, Y.L., Roberts, G.G., Ahmad, M.M., Yates, H.M., Maung, N.J., and Williams, J.O. see Hua, Y.L.
Pham, T., Botez, D., and Tran, D. see Botez, D.
Piazzolla, S., Mecozzi, A., Sapia, A., and Spano, P. see Mecozzi, A.
Piccirilli, A.B., Cella, T., Dutta, N.K., and Brown, R.L. see Cella, T.
Pirri, F., and Bigalli, O. Interpolator engine for graphic applications p331
Piscalar, W., Mulombe, N., Kahlert, J., and Seehausen, G. see Mulombe, N.
Pistorius, C.W.I., and Malherbe, J.A.G. see Malherbe, J.A.G.
Pitt, C.W., Burbie, G., and Wan, Tat Electric-field-assisted proton-exchanged optical waveguides in lithium niobate p987
Planat, M., and Zhang, Y.W. see Zhang, Y.W.
Plotnichenko, V.G., Vasiljev, A.V., Dianov, E.M., and Dmitruk, L.N. see Vasiljev, A.V.
Plumb, R.G., Heasman, K.C., and Adams, A.R. see Heasman, K.C.
Pohlmann, T., and Neyer, A. see Neyer, A.
Pollack, K.J., Glance, B., Fitzgerald, P.J., Stone, J., Burrus, C.A., Eisenstein, G., and Stulz, L.W. see Glance, B.
Pollock, K., Glance, B., Burrus, C.A., Kasper, B.L., Eisenstein, G., and Stulz, L.W. see Glance, B.
Pollock, K.J., Glance, B., Stone, J., Fitzgerald, P.J., Burrus, C.A., and Stulz, L.W. see Glance, B.
Pollock, K.J., Gnauck, A.H., Linke, R.A., Kasper, B.L., Reichmann, K.C., Valenzuela, R., and Alferness, R.C. see Gnauck, A.H.
Pookaiyaudom, S., and Samootrut, K. Current-mirror phase-shifter oscillator p21
Poole, C.D., Bergano, N.S., Schulte, H.J., Wagner, R.E., Nathu, V.P., Amon, J.M., and Rosenberg, R.L. Polarisation fluctuations in a 147 km undersea lightwave cable during installation p1113
Poole, S.B., Reekie, L., Jauncey, I.M., and Payne, D.N. see Reekie, L.
Poole, S.B., Townsend, J.E., and Payne, D.N. see Townsend, J.E.
Pophillat, L., Ronarch, D., and Guibert, M. see Ronarch, D.
Popović, B.M., and Budišin, S.Z. Generalised sub-complementary sets of sequences p422
Popović, N. Novel feedline for linearly tapered slot-line antenna (LTSA) p1285
Powazinik, W., Olshansky, R., Hill, P., Lanzisera, V., and Lauer, R.B. see Olshansky, R.
Powell, A.L., Mistry, P., Roberts, J.S., and Rockett, P.I. $Al_{0.45}Ga_{0.55}As/GaAs$ HEMTs grown by MOVPE exhibiting high transconductance p528
Powers, D.R., and Gilliland, J.W. see Gilliland, J.W.
Pozar, D.M., and Kaufman, B. Increasing the bandwidth of a microstrip antenna by proximity coupling p368
Prasad, K.S., and Eswaran, C. Sensitivity of driving-point function based wave digital filters p46
Pribetich, P., Ledee, R., Kennis, P., and Chive, M. see Ledee, R.
Prieto, A., Rodriguez, J., and Solano, M.A. Y-junctions in dielectric waveguides using very wide aperture angles p137
Prins, A.D., Greene, P.D., Dunstan, D.J., and Adams, A.R. see Greene, P.D.
Prucnal, P.R., Blumenthal, D.J., Thylen, L., and Granestrand, P. see Blumenthal, D.J.
Prucnal, P.R., Blumenthal, D.J., and Santoro, M.A. 12·5 Gbit/s fibre-optic network using all-optical processing p629
Puerta, A., and Sanz, M. see Sanz, M.
Puetz, N., Houston, P.A., Blaauw, C., Margittai, A., Svilans, M.N., Day, D.J., Shepherd, F.R., and Springthorpe, A.J. see Houston, P.A.
Purdy, D.R., Blackman, M.V., Charlton, D.E., Jenner, M.D., Wotherspoon, J.T.M., Elliott, C.T., and White, A.M. see Blackman, M.V.
Puretz, J., DeFreez, R.K., Elliott, R.A., Orloff, J., and Paoli, T.L. 300 mW operation of a surface-emitting phase-locked array of diode lasers p130
Puthenpura, S., and Sinha, N.K. Extended power method and stability of linear discrete-time systems p4
Puthenpura, S., and Sinha, N.K. Iterative method for obtaining the argument of the dominant complex pole-pair p674
Putrino, M., Vassiliadis, S., and Schwarz, E. see Vassiliadis, S.
Putrino, M., Vassiliadis, S., and Schwarz, E. Array two's-complement multiplier and square function p1185

Q

Qua, G.J., Chandrasekhar, S., Campbell, J.C., and Dentai, A.G. see Chandrasekhar, S.
Qua, G.J., Dentai, A.G., Campbell, J.C., and Joyner, C.H. see Dentai, A.G.
Quimby, R.S., Drexhage, M.G., and Suscavage, M.J. Efficient frequency up-conversion via energy transfer in fluoride glasses p32

R

Rønn, L., and Deichmann, P. 16 × 8 space switch for 2·24 Gbit/s transmission p236
Ra, J.-W., and Choi, Y.-H. see Choi, Y.-H.
Ra, Jung-Woong, and Kim, Se-Yun see Kim, Se-Yun
Radeva, E., Borissov, M., Spassov, L., Yosiffov, E., and Balabanova, A. see Borissov, M.
Raghavan, K., Kitchener, D., and Parini, C.G. see Kitchener, D.
Rai, A.K., Ezis, A., and Langer, D.W. see Ezis, A.
Rajagopal, L.R., and Dutta Roy, S.C. Matrix approach for the coefficients of maximally flat FIR filter transfer functions expressed in powers of cos w p391
Rajski, J., and Maamari, F. see Maamari, F.
Rajsuman, R., Jayasumana, A.P., and Malaiya, Y.K. Testing of complex gates p813
Ramponi, G., and Sicuranza, G.L. Decision-directed nonlinear filter for image processing p1218
Ranade, A., and Noerpel, A.R. Microwave energy scattered off building surfaces shows strong dependence on orientation of city blocks p922
Randjelović, P.Ž., and Jovičić, S.T. see Jovičić, S.T.
Rappaport, T.S., and McGillem, C.D. Characterising the UHF factory radio channel p1015
Rashwan, H.M., Aboul-Saoud, A.K., and Kheirallah, H.N. Analytical investigation of LOS multipath propagation p746
Rashwan, H.M., Kheirallah, H.N., and Aboul-Saoud, A.K. see Kheirallah, H.N.
Ratnam, P. Selectively implanted buried oxide (SIBO) process for VLSI applications p1316
Raybon, G., Eisenstein, G., Tucker, R.S., Korotky, S.K., Veselka, J.J., Buhl, L.L., Gnauck, A.H., Kasper, B.L., and Alferness, R.C. see Eisenstein, G.

Raybon, G., Eisenstein, G., and Johnson, B.C. see Eisenstein, G.
Raybon, G., Jopson, R.M., Hall, K.L., Eisenstein, G., and Whalen, M.S. see Jopson, R.M.
Raybon, G., Tucker, R.S., Eisenstein, G., Korotky, S.K., Buhl, L.L., Veselka, J.J., Kasper, B.L., and Alferness, R.C. see Tucker, R.S.
Raybon, G., Tucker, R.S., Eisenstein, G., Korotky, S.K., Koren, U., Veselka, J.J., Buhl, L.L., Kasper, B.L., and Alferness, R.C. see Tucker, R.S.
Raybon, G., Whalen, M.S., Hall, K.L., Tennant, D.M., and Koren, U. see Whalen, M.S.
Razeghi, M., Delacourt, D., Papuchon, M., and di Forte-Poisson, M.A. see Delacourt, D.
Razeghi, M., Tardella, A., Davies, R.A., Long, A.P., Kelly, M.J., Britton, E., Boothroyd, C., and Stobbs, W.M. Negative differential resistance at room temperature from resonant tunnelling in GaInAs/InP double-barrier heterostructures p116
Reddy, C.J., and Deshpande, M.D. Characteristics of inhomogeneous coupled cylindrical striplines p821
Reddy, M.S., and Hazra, S.N. Design of elliptically symmetric two-dimensional FIR filters with arbitrary orientation p964
Reed, G.T., and Weiss, B.L. Electro-optic effect in He^+-implanted optical waveguides in $LiNbO_3$ p424
Reed, G.T., and Weiss, B.L. Low-loss optical stripe waveguides in $LiNbO_3$ formed by He^+ implantation p792
Reedy, R.E., Albares, D.J., Garcia, G.A., and Chang, C.T. see Albares, D.J.
Reekie, L., Jauncey, I.M., Poole, S.B., and Payne, D.N. Diode-laser-pumped Nd^{3+}-doped fibre laser operating at 938 nm p884
Reekie, L., Jauncey, I.M., Poole, S.B., and Payne, D.N. Diode-laser-pumped operation of an Er^{3+}-doped single-mode fibre laser p1076
Reekie, L., Mears, R.J., Jauncey, I.M., and Payne, D.N. see Mears, R.J.
Regolini, J.L., Dutartre, D., Bensahel, D., Karapiperis, L., Garry, G., and Dieumegard, D. Laser recrystallised SOI with periodical seeding filled by selective epitaxial growth p493
Reichmann, K.C., Gnauck, A.H., Linke, R.A., Kasper, B.L., Pollock, K.J., Valenzuela, R., and Alferness, R.C. see Gnauck, A.H.
Reichmann, K.C., and Giles, R.C. see Giles, R.C.
Reid, D.C.J., Kean, P.N., Smith, K., Sinclair, B.D., Sibbett, W., and Rowe, C.J. see Kean, P.N.
Reimann, R., Weger, P., Treitinger, L., and Rein, H.-M. see Weger, P.
Rein, H.-M., Weger, P., Treitinger, L., and Reimann, R. see Weger, P.
Reinhart, F.K., Faist, J., and Martin, D. see Faist, J.
Reinhart, F.K., Glick, M., and Pavuna, D. see Glick, M.
Reith, L.A., Chang, G.-K., Leblanc, H.P., and Chin, A.K. see Chang, G.-K.
Reith, L.A., Christodoulides, D.N., and Saifi, M.A. see Christodoulides, D.N.
Reith, L.A., Zah, C.E., Osinski, J.S., Caneau, C., Menocal, S.G., Salzman, J., Shokoohi, F.K., and Lee, T.P. see Zah, C.E.
Reith, L.A., and Mann, J.W. Design parameters for a 1·3 μm connectorised low-cost laser package for subscriber loop using graded-index lenses p520
Remedios, D., Pettitt, M.J., Davis, A.W., Hadjifotiou, A., and Wright, S. see Pettitt, M.J.
Renaud, J.C., N'Guyen, L., Allovon, M., Heliot, F., Lugiez, F., and Scavennec, A. Monolithic photoreceiver integrating GaInAs PIN/JFET with diffused junctions p1055
Reynolds, C.L., Gibson, W.C., and Clemans, J.E. Uniformity of threshold voltage for MESFETs fabricated on VGF GaAs substrates p1222
Riaziat, M., Feng, I.J., Majidi-Ahy, R., and Auld, B.A. Single-mode operation of coplanar waveguides p1281
Riaziat, M., Majidi-Ahy, R., Weingarten, K.J., Auld, B.A., and Bloom, D.M. see Majidi-Ahy, R.
Ribot, H., Sansonetti, P., Brandon, J., Menigaux, L., Dugrand, L., and Bouadma, N. see Sansonetti, P.
Rice, T.C., Jopson, R.M., Darcie, T.E., Gayliard, K.T., Ku, R.T., Tench, R.E., and Olsson, N.A. see Jopson, R.M.
Richard, J., Holcroft, B., Roberts, G.G., and Barraud, A. see Holcroft, B.
Richardson, J.R., Barton, T.M., Snowden, C.M., and Ladbrooke, P.H. see Barton, T.M.
Richter, H., and Eisenhauer, W. see Eisenhauer, W.
Riechert, H., Cremer, C., Heise, G., März, R., and Schienle, M. see Cremer, C.
Ries, R. Signal transmission with optical carriers in multimode range of single-mode fibres p71
Riffat, J.R., Hodson, P.D., Bradley, R.R., Joyce, T.B., and Wallis, R.H. see Hodson, P.D.
Riffat, J.R., Moseley, A.J., Scott, M.D., Williams, P.J., Wallis, R.H., and Davies, J.I. see Moseley, A.J.
Riffat, J.R., Moseley, A.J., Urquhart, J., Hodson, P.D., and Davies, J.I. see Moseley, A.J.
Riffe, P.C., Lu, C.Y., Tsai, N.S., Ahrens, R.E., and Banak, M.A. see Lu, C.Y.
Rigaud, D., Peransin, J.M., and Alabedra, R. see Peransin, J.M.
Righini, G.C., and Molesini, G. Refractive waveguide lenses: a new design p302
Rigo, C., Cinguino, P., Genova, F., Morasca, S., and Stano, A. see Cinguino, P.
Rius, J.M., Ferrando, M., Jofre, L., de los Reyes, E., Elias, A., and Broquetas, A. Microwave tomography: an algorithm for cylindrical geometries p564
Robert, M., Auvergne, D., and Deschacht, D. see Auvergne, D.
Roberts, D.A., and Stern, M.S. Accuracy of method of moments and weighted index method p784
Roberts, G.G., Holcroft, B., Barraud, A., and Richard, J. see Holcroft, B.
Roberts, G.G., Hua, Y.L., Petty, M.C., Ahmad, M.M., Yates, H.M., Maung, N.J., and Williams, J.O. see Hua, Y.L.
Roberts, J.S., Bradley, P.J., Wheatley, P., Parry, G., Midwinter, J.E., and Mistry, P. see Bradley, P.J.
Roberts, J.S., Powell, A.L., Mistry, P., and Rockett, P.I. see Powell, A.L.
Roberts, J.S., Wheatley, P., Bradley, P.J., Whitehead, M., Parry, G., Midwinter, J.E., Mistry, P., and Pate, M.A. see Wheatley, P.
Roberts, J.S., Wheatley, P., Parry, G., Midwinter, J.E., Hill, G., Mistry, P., and Pate, M.A. see Wheatley, P.
Roberts, J.S., Whitehead, M., Parry, G., Mistry, P., Li Kam Wa, P., and David, J.P.R. see Whitehead, M.
Roberts, J.S., Woodhead, J., Mistry, P., Singh, K.C., and Sotomayor-Torres, C.M. p-type modulation-doped AlGaAs/GaAs heterostructures grown by atmospheric-pressure metal organic vapour phase epitaxy (MOVPE) p605
Robertson, S.C., and Boucouvalas, A.C. see Boucouvalas, A.C.
Robson, P.N., Kendall, P.C., and Stern, M.S. see Kendall, P.C.
Rockett, P.I., Powell, A.L., Mistry, P., and Roberts, J.S. see Powell, A.L.
Rodgers, P.M., McIlroy, P.W.A., Singh, J.S., Spurdens, P.C., and Henning, I.D. see McIlroy, P.W.A.
Rodgers, P.M., and Henning, I.D. see Henning, I.D.
Rodriguez, J., Prieto, A., and Solano, M.A. see Prieto, A.
Rodriguez-Vazquez, A., Rueda, A., Perez-Verdu, B., and Huertas, J.L. Chaos via a piecewise-linear switched-capacitor circuit p662
Rodwell, M.J.W., Bloom, D.M., and Auld, B.A. Nonlinear transmission line for picosecond pulse compression and broadband phase modulation p109
Ronarch, D., Guibert, M., and Pophillat, L. Sensitivity improvement in low-temperature operation of a baseband photoreceiver containing a TEGFET p222
Rosenberg, R.L., Poole, C.D., Bergano, N.S., Schulte, H.J., Wagner, R.E., Nathu, V.P., and Amon, J.M. see Poole, C.D.
Rosher, P.A., Cochrane, P., and Hunwicks, A.R. see Cochrane, P.
Rosher, P.A., and Hunwicks, A.R. see Hunwicks, A.R.
Rottiers, L., Boone, E., and De Mey, G. see Boone, E.
Rottmann, F., and Voges, E. Low-insertion-loss, tunable wavelength multiplexer on lithium niobate p1007
Rowe, C.J., Kean, P.N., Smith, K., Sinclair, B.D., Sibbett, W., and Reid, D.C.J. see Kean, P.N.
Royer, D., Dieulesaint, E., Chaabi, A., and Formery, B. see Dieulesaint, E.
Royer, D., Dieulesaint, E., and Mazerolle, D. see Dieulesaint, E.
Roza, A.J., Tihanyi, P., Wagner, D.K., Vollmer, H.J., Harding, C.M., Davis, R.J., and Wolf, E.D. see Tihanyi, P.
Rueda, A., Rodriguez-Vazquez, A., Perez-Verdu, B., and Huertas, J.L. see Rodriguez-Vazquez, A.
Ruiz-Moreno, S., Junyent, G., Usandizaga, J.R., and Calzada, A. Resolution of moment equations in a nonlinear optical amplifier p15
Runge, K., Stern, M., Millicker, D.J., and Elrefaie, A.E. see Stern, M.
Rush, J.D., Hill, J.R., Dunn, P.L., Davies, G.J., Oliver, S.N., and Pantelis, P. see Hill, J.R.
Russell, P.St.J., Farries, M.C., Fermann, M.E., and Payne, D.N. see Farries, M.C.
Ryan, P.J., and Haigh, D.G. Novel fully differential MOS transconductor for integrated continuous-time filters p742
Ryu, S., Namihira, Y., Kuwazuru, M., Mochizuki, K., and Iwamoto, Y. see Namihira, Y.
Ryu, S., Namihira, Y., Mochizuki, K., Furusawa, K., and Iwamoto, Y. see Namihira, Y.
Ryu, S., Yamamoto, S., and Mochizuki, K. Polarisation-insensitive operation of coherent FSK transmission system using polarisation diversity p1382

S

Ştefan, C., Silard, A., Floru, F., and Nani, G. see Silard, A.
Sánchez-Gómez, G., Huertas, J.L., and Barriga, A. see Huertas, J.L.
Sadler, R.A., Geissberger, A.E., Griffin, E.L., Bahl, I.J., and Balzan, M.L. see Geissberger, A.E.
Safaai-Jazi, A., Jen, C.K., and Farnell, G.W. Perturbation analysis of fibre acoustic modes p350
Sage, I., and Chaplin, D. Low RI liquid crystals for integrated optics p1192
Saguet, P., and Wu, K. see Wu, K.
Saifi, M.A., Christodoulides, D.N., and Reith, L.A. see Christodoulides, D.N.
Saifi, M.A., and Christodoulides, D.N. see Christodoulides, D.N.
Saito, H., Shima, A., Yamawaki, T., Matsubara, H., Murakami, T., Ohtaki, K., Kumabe, H., and Susaki, W. see Shima, A.
Saito, S., Kaino, T., Kubodera, K.-I., Tomaru, S., Kurihara, T., Tsutsui, T., and Tokito, S. see Kaino, T.
Saitoh, T., Inoue, K., and Mukai, T. see Inoue, K.
Saitoh, T., Mukai, T., and Inoue, K. see Mukai, T.
Saitoh, T., and Mukai, T. see Mukai, T.
Saitoh, T., and Mukai, T. Broadband 1·5 μm GaInAsP travelling-wave laser amplifier with high-saturation output power p218
Sakaguchi, H., and Niiro, Y. Reduction of high surge voltage on coiled optical fibre submarine cable p1124
Sakaguchi, S., and Ohishi, Y. see Ohishi, Y.
Sakai, K., Matsushima, Y., Utaka, K., and Takeuchi, O. see Matsushima, Y.
Sakaki, T., Kokubun, Y., Baba, T., and Iga, K. see Kokubun, Y.
Sakakibara, Y., Takemoto, A., Nakajima, Y., Fujiwara, M., Kakimoto, S., Namizaki, H., and Susaki, W. see Takemoto, A.
Sakano, S., Lee, T.P., Menocal, S.G., Valster, A., and Tsuji, S. see Lee, T.P.
Saleh, A.A.M., Cimini, L.J., Habbab, I.M.I., and John, R.K. see Cimini, L.J.
Sali, S., and Anderson, A.P. Uncertainty in deriving phase information from far-field modulus only p426
Salvi, M., Favennec, P.N., L'Haridon, H., Le Corre, A., and Gauneau, M. see Favennec, P.N.
Salzman, J., Zah, C.E., Osinski, J.S., Caneau, C., Menocal, S.G., Reith, L.A., Shokoohi, F.K., and Lee, T.P. see Zah, C.E.
Samootrut, K., and Pookaiyaudom, S. see Pookaiyaudom, S.
Sano, H., Imoto, K., Miyazaki, M., and Takasaki, Y. see Imoto, K.
Sano, H., Imoto, K., and Miyazaki, M. see Imoto, K.
Sansonetti, P., Ribot, H., Brandon, J., Menigaux, L., Dugrand, L., and Bouadma, N. Low-threshold GaAs/GaAlAs buried heterostructure laser with an ion-beam-etched quarter ring cavity p485
Santoro, M.A., Prucnal, P.R., and Blumenthal, D.J. see Prucnal, P.R.
Sanz, M., and Puerta, A. Compact formulation for exact analysis of nonideal SC circuits p554
Sapia, A., Mecozzi, A., Piazzolla, S., and Spano, P. see Mecozzi, A.
Saquet, P., and Essebar, A. Experimental determination of finline post discontinuity parameters: application to stopband and lowpass filters p691
Sargood, S.K., Wake, D., Walling, R.H., and Henning, I.D. see Wake, D.
Saruwatari, M., Morioka, T., and Takada, A. see Morioka, T.
Saruwatari, M., and Morioka, T. see Morioka, T.
Sasai, Y., Ohya, J., Ogura, M., and Kajiwara, T. Dynamic spectral linewidth in InGaAsP multiquantum-well lasers grown by liquid-phase epitaxy p232
Sasaki, S., Kishimoto, T., and Matsui, N. Connection of VLSI chips to printed circuit board using stacked solder bumps p1238
Sasaki, S., and Kishimoto, T. see Kishimoto, T.
Sasaki, Y., Tajima, K., and Seikai, S. 26 km-long polarisation-maintaining optical fibre p127
Sasaki, Y., Tajima, K., and Seikai, S. Low-loss dispersion-shifted polarisation-maintaining fibres p279
Sasaki, Y., Tajima, K., and Yokohama, I. Bidirectional optical transmission using polarised light waves p692
Sastry, G.V.K.R., and Krishnamurthy, V. Biased model reduction by simplified Routh approximation method p1045
Sastry, G.V.K.R., and Krishnamurthy, V. State-space models using simplified Routh approximation method p1300
Sato, F., Imanaka, K., Imamoto, H., Asai, M., and Shimura, M. see Imanaka, K.
Sato, K., Itaya, Y., Oishi, M., Nakao, M., Kondo, Y., and Imamura, Y. see Itaya, Y.
Sato, K., Shimba, M., Sato, T., and Koike, H. see Shimba, M.
Sato, M., Nakano, H., and Yamauchi, J. see Nakano, H.
Sato, S., and Nose, T. see Nose, T.
Sato, T., Shimba, M., Koike, H., and Sato, K. see Shimba, M.
Sato, T., Suzuki, Y., Mukai, S., and Yajima, H. see Suzuki, Y.
Sato, T.Y., Jones, W.L., and Ageno, S.K. see Jones, W.L.
Satyanarayana, S., and Tsividis, Y. see Tsividis, Y.
Sauer, N., Taylor, G.W., Lebby, M.S., Chang, T.Y., Gnall, R.N., Tell, B., and Simmons, J.G. see Taylor, G.W.
Sautereau, J.F., Larroque, J., Sombrin, J., and Lapierre, L. see Larroque, J.
Say, P.G., Parker, D.G., Hansom, A.M., and Sibbett, W. see Parker, D.G.
Scapino, F., and Odasso, M. see Odasso, M.
Scavennec, A., Renaud, J.C., N'Guyen, L., Allovon,

M., Heliot, F., and Lugiez, F. see Renaud, J.C.
Schadt, D., and Jaskorzynska, B. Generation of short pulses from CW light by influence of cross-phase modulation (CPM) in optical fibres p1090 e1211
Schaff, W.J., Chen, M., Tasker, P.J., and Eastman, L.F. see Chen, M.
Schaubert, D.H., and Adrian, A. see Adrian, A.
Schaumann, R., and Tan, M.A. see Tan, M.A.
Schiavone, L.M., Deri, R.J., and Kapon, E. see Deri, R.J.
Schienle, M., Cremer, C., Heise, G., März, R., and Riechert, H. see Cremer, C.
Schneider, M.V., Trambarulo, R., and Gans, M.J. see Trambarulo, R.
Scholz, U., Heidemann, R., and Wedding, B. see Heidemann, R.
Schröder, J.E. Dual sinusoidal modulation scheme for directional laser Doppler velocimeter p114
Schremer, A., Fujita, T., and Tang, C.L. see Fujita, T.
Schroeder, J., Hwa, L.G., Shyong, M.C., Floudas, G.A., Thompson, D.A., and Drexhage, M.G. Brillouin scattering and phonon attenuation in halide glasses: stimulated Brillouin emission p1128
Schüppert, B. Reduction of bend losses in Ti : $LiNbO_3$ waveguides through MgO double diffusion p797
Schulte, H.J., Poole, C.D., Bergano, N.S., Wagner, R.E., Nathu, V.P., Amon, J.M., and Rosenberg, R.L. see Poole, C.D.
Schultheis, G., Black, A., Courville, C., and Heinrich, H. see Black, A.
Schultz, K.I., and Jaggard, D.L. Novel microwave projection imaging for determination of internal structure p267
Schumacher, H., Hayes, J.R., Bhat, R., and Koza, M. see Hayes, J.R.
Schumacher, K., and O'Reilly, J.J. Power penalty due to jitter on optical communication systems p718
Schunk, N., Wang, J., and Petermann, K. see Wang, J.
Schwarz, E., Putrino, M., and Vassiliadis, S. see Putrino, M.
Schwarz, E., Vassiliadis, S., and Putrino, M. see Vassiliadis, S.
Schwierz, H., and Neumann, E.-G. Bend losses of higher-order modes in dispersion-flattened multiple-clad optical fibres p1296
Scifres, D., Welch, D.F., DeVito, M., Cardinal, M., Abraham, M., Kung, H., Harnagel, G., Cross, P., and Streifer, W. see Welch, D.F.
Scifres, D.R., Berger, J., Welch, D.F., Streifer, W., and Cross, P.S. see Berger, J.
Scifres, D.R., Harnagel, G.L., Cross, P.S., Lennon, C.R., and DeVito, M. see Harnagel, G.L.
Scifres, D.R., Welch, D.F., Cardinal, M., Streifer, W., and Cross, P.S. see Welch, D.F.
Scifres, D.R., Welch, D.F., Cross, P.S., and Streifer, W. see Welch, D.F.
Scott, E.G., Davey, S.T., and Davies, G.J. Extremely high-quality GaInAs/AlInAs single quantum wells grown by molecular beam epitaxy p761
Scott, M.D., Moseley, A.J., Williams, P.J., Wallis, R.H., Davies, J.I., and Riffat, J.R. see Moseley, A.J.
Seaton, C.T., Assanto, G., Gabel, A., Stegeman, G.I., Ironside, C.N., and Cullen, T.J. see Assanto, G.
Secoue, M., Guivarc'h, A., and Guerin, R. see Guivarc'h, A.
Seeds, A.J., and Gomes, N.J. see Gomes, N.J.
Seehausen, G., Mulombe, N., Kahlert, J., and Piscalar, W. see Mulombe, N.
Seevinck, E., and de Heij, W.J.A. see de Heij, W.J.A.
Segner, B.P., Koszi, L.A., Temkin, H., Chin, B.H., and Napholtz, S.G. see Koszi, L.A.
Seikai, S., Sasaki, Y., and Tajima, K. see Sasaki, Y.
Seitz, H.K., Blacha, A., Clauberg, R., and Beha, H. see Blacha, A.
Seiwa, Y., Aoyagi, T., Hinata, S., Shigihara, K., Ikeda, K., and Susaki, W. see Aoyagi, T.
Seki, H., Soda, H., Kihara, K., Furutsu, M., Matsuda, M., Ogita, S., Ishikawa, H., and Imai, H. see Soda, H.
Seki, M., Sugawara, R., Hanada, Y., Okuda, E., Wada, H., and Yamasaki, T. High-performance guided-wave multi/demultiplexer based on novel design using embedded gradient-index waveguides in glass p948
Sekine, Y., Kinoshita, T., Yamashita, K., and Maeda, M. see Kinoshita, T.
Sen, S., Capasso, F., Beltram, F., and Cho, A.Y. see Capasso, F.
Sen, S., Capasso, F., Cho, A.Y., and Hutchinson, A.L. see Capasso, F.
Sen, S., Capasso, F., Hutchinson, A.L., and Cho, A.Y. Room-temperature operation of $Ga_{0.47}In_{0.53}As/Al_{0.48}In_{0.52}As$ resonant tunnelling diodes p1229
Senani, R. Generation of new two-amplifier synthetic floating inductors p1202
Sengupta, D.L., and Willis, T.M. see Willis, T.M.
Seo, K.S., Bhattacharya, P.K., and Gleason, K.R. DC and microwave characteristics of an $In_{0.53}Ga_{0.47}As/In_{0.52}Al_{0.48}As$ modulation-doped quasi-MISFET p259
Seraji, H. Transfer function matrix p256
Serbest, A.H., and İdemen, M. see İdemen, M.
Serizawa, Y., and Takeshita, S. Influence of raypath parameters on digital radio outage p1353
Sermage, B., Brosson, P., Benoit, J., and Joullie, A. see Brosson, P.
Severin, P.J. Self-routing fibre-optic networks and switches using multitailed receiver/transmitter units p651
Severin, P.J. Single-mode-fibre passive components made in the fused-head-end technique p449
Shabeer, M., Andonovic, I., and Culshaw, B. Fibre-optic multichannel correlation/convolution p310
Shafai, L., and Aboelsaad, M. see Aboelsaad, M.
Shah, A.V., Curtins, H., and Wyrsch, N. see Curtins, H.
Shanjia, Xu Simple method for analysing finlines with extremely narrow slotwidth and thick fins p677
Sharestani, E., and Cuthbert, L.G. Two-dimensional FIR digital filters designed to arbitrary group-delay specifications p603
Shark, L.-K., Simpson, R.J., and Terrell, T.J. New postdetection processing technique for frame synchronisers p1337
Sharp, J., Helszajn, J., and Nisbet, W.T. see Helszajn, J.
Shaw, H.J., Liu, K., Digonnet, M., Ainslie, B.J., and Craig, S.P. see Liu, K.
Shay, T.M., and Chung, Y.C. see Chung, Y.C.
Sheard, S.J., Appel, R.K., and Somekh, M.G. Photothermal radiometric imaging of semiconductors p227
Sheard, S.J., and Somekh, M.G. New mechanism for subsurface imaging in silicon p1134
Shen, T.M. Power penalty in bit error rate due to limited transmission bandwidth p927
Shephard, H.E., Walker, R.G., and Bradley, R.R. see Walker, R.G.
Shepherd, F.R., Houston, P.A., Blaauw, C., Margittai, A., Svilans, M.N., Puetz, N., Day, D.J., and Springthorpe, A.J. see Houston, P.A.
Shi, J.M., and Hong, J.S. see Hong, J.S.
Shi-wei, Gao, and Zheng, Bao Data-based matrix decomposition technique for high-resolution array processing of coherent signals p643
Shibata, S., Kitagawa, T., and Horiguchi, M. see Kitagawa, T.
Shibuya, R., Okayama, H., Matoba, A., and Ishida, T. see Okayama, H.
Shigihara, K., Aoyagi, T., Hinata, S., Seiwa, Y., Ikeda, K., and Susaki, W. see Aoyagi, T.
Shih, H.D., Kim, B., Wurtele, M., and Tserng, H.Q. see Kim, B.
Shih, H.D., Kim, B., and Wurtele, M. High-performance millimetre-wave GaAs power MESFET prepared by gas source molecular beam epitaxy p1141
Shijun, Jiang Simple explicit formula for calculating the $LP_{1,1}$ mode cutoff frequency p534
Shikada, M., Fujita, S., Hayashi, J., Isoda, Y., and Uji, T. see Fujita, S.
Shima, A., Yamawaki, T., Saito, H., Matsubara, H., Murakami, T., Ohtaki, K., Kumabe, H., and Susaki, W. High-power CW operation of 780 nm T^3 laser diodes p672
Shimaya, M., Ohno, T., Izumi, K., and Shiono, N. see Ohno, T.
Shimazu, M., Ishii, M., Kamon, K., Mihara, M., Kumabe, H., and Isshiki, K. see Ishii, M.
Shimba, M., Sato, T., Koike, H., and Sato, K. Signal level degradation due to snow accretion on a radome p739
Shimizu, H., and Nakamura, K. see Nakamura, K.
Shimizu, J., Ajisawa, A., Fujiwara, M., Sugimoto, M., Uchida, M., and Ohta, Y. see Ajisawa, A.
Shimizu, K., Fujise, M., and Nunokawa, M. Synchronous single-photon counting using an Si avalanche photodiode at room temperature p1307
Shimizu, M., Suda, H., and Horiguchi, M. High-efficiency Nd-doped fibre lasers using direct-coated dielectric mirrors p768
Shimura, M., Imanaka, K., Imamoto, H., Sato, F., and Asai, M. see Imanaka, K.
Shin, D., Park, M., and Lee, M. Self-correcting clock recovery circuit with improved jitter performance p110
Shin, D.-H., Cho, G.-H., and Park, S.-B. Optimised pulse-width modulation method of forced commutated cycloconvertor p760
Shintaku, T., Nagase, R., and Sugita, E. see Nagase, R.
Shiono, N., Ohno, T., Izumi, K., and Shimaya, M. see Ohno, T.
Shipley, S.P., and El Fatatry, A. All single-mode optical fibre wavelength-tunable WDM with very narrow pass/stopband separations p523
Shirafuji, J., Aoki, A., and Miyoshi, S. see Aoki, A.
Shokoohi, F.K., Abeles, J.H., Chan, W.K., Bhat, R., and Koza, M.A. see Abeles, J.H.
Shokoohi, F.K., Zah, C.E., Osinski, J.S., Caneau, C., Menocal, S.G., Reith, L.A., Salzman, J., and Lee, T.P. see Zah, C.E.
Shoucair, F.S. CMOS logic cell switching speed thermal characterisation p458
Shu-min, Wang, Xiao-song, Jiang, Li-sheng, Yu, and Hong-xun, Liu see Xiao-song, Jiang
Shumate, P.W., Chang, G.-K., and Leblanc, H.P. see Chang, G.-K.
Shyong, M.C., Schroeder, J., Hwa, L.G., Floudas, G.A., Thompson, D.A., and Drexhage, M.G. see Schroeder, J.
Sibbett, W., Kean, P.N., Smith, K., Sinclair, B.D., Rowe, C.J., and Reid, D.C.J. see Kean, P.N.
Sibbett, W., Parker, D.G., Say, P.G., and Hansom, A.M. see Parker, D.G.
Sibille, A., Palmier, J.F., Harmand, J.C., and Dangla, J. see Palmier, J.F.
Sicuranza, G.L., Glavina, R., and Cucchi, S. see Glavina, R.
Sicuranza, G.L., and Ramponi, G. see Ramponi, G.
Sid Ahmed, S.A.I., and Excell, P.S. Low-loss three-phase frequency conversion using a TDM-PWM technique p126
Silard, A., Floru, F., Ştefan, C., and Nani, G. Simple method for increasing current gain and voltage ratings of power transistors p1213
Silva, H.J.A., and O'Reilly, J.J. see O'Reilly, J.J.
Simmons, J.F.L., and Stewart, B.G. see Stewart, B.G.
Simmons, J.G., Taylor, G.W., Lebby, M.S., Chang, T.Y., Gnall, R.N., Sauer, N., and Tell, B. see Taylor, G.W.
Simmons, J.G., and Taylor, G.W. Heterostructure complementary technology p380
Simon, J.C., Brosson, P., Fernier, B., Benoit, J., and Landousies, B. see Brosson, P.
Simon, J.C., Landousies, B., Bossis, Y., Doussiere, P., Fernier, B., and Padioleau, D. Gain, polarisation sensitivity and saturation power of 1·5 μm near-travelling-wave semiconductor laser amplifier p332
Simpson, R.J., Shark, L.-K., and Terrell, T.J. see Shark, L.-K.
Sinclair, B.D., Kean, P.N., Smith, K., Sibbett, W., Rowe, C.J., and Reid, D.C.J. see Kean, P.N.
Singh, H., and Eydgahi, A.M. see Eydgahi, A.M.
Singh, J.S., McIlroy, P.W.A., Rodgers, P.M., Spurdens, P.C., and Henning, I.D. see McIlroy, P.W.A.
Singh, K.C., Roberts, J.S., Woodhead, J., Mistry, P., and Sotomayor-Torres, C.M. see Roberts, J.S.
Sinha, N.K., and Puthenpura, S. see Puthenpura, S.
Siy, P., and Hassan, M.H. see Hassan, M.H.
Skok, P., and Miler, M. Spatial filtering method of oblique slit for measurement of refractive-index profile of optical-fibre preforms p859
Skorupa, W., Kreissig, U., Hensel, E., and Bartsch, H. Increased carrier lifetimes in epitaxial silicon layers on buried silicon nitride produced by ion implantation d579
Smith, A.V.W., and Murray, A.F. see Murray, A.F.
Smith, C.B., and Yethiraj, A. see Yethiraj, A.
Smith, D.W., Hodgkinson, T.G., and Harmon, R.A. see Hodgkinson, T.G.
Smith, D.W., and Chidgey, P.J. see Chidgey, P.J.
Smith, K., Kean, P.N., Sinclair, B.D., Sibbett, W., Rowe, C.J., and Reid, D.C.J. see Kean, P.N.
Smith, K.C., Song, W., and Snelgrove, W.M. see Song, W.
Smith, R.W., Kazovsky, L.G., Elrefaie, A.F., Meissner, P., Welter, R., Crespo, P., and Gimlett, J. see Kazovsky, L.G.
Smith, R.W., Park, Y.K., Granlund, S.W., Kuo, C.Y., Dixon, M., Cline, T.W., Dutta, N.K., and Vannucci, G. see Park, Y.K.
Smith, S.G. Serial/parallel automultiplier p413
Smith, S.G., McGregor, M.S., Denyer, P.B., and Murray, A.F. see McGregor, M.S.
Smith, S.G., Nagara, S., Denyer, P.B., and Keightley, M. see Nagara, S.
Smith, S.G., and Keightley, M. Method for synthesis of MOSFET logic networks p902
Snelgrove, W.M., Song, W., and Smith, K.C. see Song, W.
Snowden, C.M., Barton, T.M., Richardson, J.R., and Ladbrooke, P.H. see Barton, T.M.
Snyder, A.W., Ankiewicz, A., and Altintas, A. Fundamental error of recent coupled mode formulations p1097
Snyder, A.W., and Ankiewicz, A. Fibre couplers composed of unequal cores e251
Snyder, A.W., and Chu, P.L. see Chu, P.L.
Snyder, A.W., and Love, J.D. see Love, J.D.
Snyder, A.W., and Zheng, X.H. see Zheng, X.H.
Soccolich, C., Bowers, J.E., Koren, U., Miller, B.I., and Jan, W.Y. see Bowers, J.E.
Soda, H., Ishikawa, H., and Imai, H. Design for single-mode asymmetric quarter-wavelength-shifted DFB laser with high differential efficiency p598
Soda, H., Kihara, K., Furutsu, M., Matsuda, M., Seki, H., Ogita, S., Ishikawa, H., and Imai, H. Wide temperature range of stable single-mode operation in weakly coupled asymmetric mirror reflectivity DFB lasers p724
Soda, H., Nakai, K., Ishikawa, H., and Imai, H. High-speed GaInAsP/InP buried-heterostructure optical intensity modulator with semi-insulating InP burying layers p1232
Soda, H., Ogita, S., Hirano, M., Yano, M., Ishikawa, H., and Imai, H. see Ogita, S.
Sodha, M.S., and Kumar, A. see Kumar, A.
Solano, M.A., Prieto, A., and Rodriguez, J. see Prieto, A.
Sombrin, J., Larroque, J., Lapierre, L., and Sautereau, J.F. see Larroque, J.
Somekh, M.G., Sheard, S.J., and Appel, R.K. see Sheard, S.J.
Somekh, M.G., and Sheard, S.J. see Sheard, S.J.
Song, W., Smith, K.C., and Snelgrove, W.M. Partitioning for pseudo-exhaustive testing is *NP*-complete p1060
Sono, A., and Vu, D.P. see Vu, D.P.
Sorin, W.V., and Newton, S.A. Tunable single-mode output of a multimode laser in a tunable fibre grating external cavity p390
Sotomayor-Torres, C.M., Roberts, J.S., Woodhead, J., Mistry, P., and Singh, K.C. see Roberts, J.S.

Souza, J.R. Conformal mapping analysis of shielded striplines p637
Sowerby, K.W., and Williamson, A.G. Outage probability calculations for a mobile radio system having multiple Rayleigh interferers p600
Sowerby, K.W., and Williamson, A.G. Outage probability calculations for a mobile radio system having two log-normal interferers p1345
Spano, P., Mecozzi, A., Piazzolla, S., and Sapia, A. see Mecozzi, A.
Sparrow, A., and Hall, P.S. see Hall, P.S.
Spassov, L., Borissov, M., Yosiffov, E., Balabanova, A., and Radeva, E. see Borissov, M.
Speier, P., Wünstel, K., and Tegude, F.J. MOVPE studies for the development of GaInAsP/InP lasers with semi-insulating InP blocking layers p1363
Spirit, D.M., Marshall, I.W., and O'Mahony, M.J. see Marshall, I.W.
Springthorpe, A.J., Houston, P.A., Blaauw, C., Margittai, A., Svilans, M.N., Puetz, N., Day, D.J., and Shepherd, F.R. see Houston, P.A.
Spurdens, P.C., McIlroy, P.W.A., Rodgers, P.M., Singh, J.S., and Henning, I.D. see McIlroy, P.W.A.
Squire, P.T., and Gibbs, M.R.J. Shear-wave magnetometry using metallic glass ribbon p147
Srinivas, S., and Biswas, N.N. see Biswas, N.N.
Stallard, W.A., Blank, L.C., Bryant, E.G., Lord, A., and Boggis, J.M. see Blank, L.C.
Stallard, W.A., Garnham, R.A., and Cunningham, D.G. see Garnham, R.A.
Standley, R.D., and Millicker, D.J. see Millicker, D.J.
Stanley, C.R., Lee, K.Y., Al-Mudares, M., Beaumont, S.P., Wilkinson, C.D.W., and Frost, J. see Lee, K.Y.
Stano, A., Cinguino, P., Genova, F., Morasca, S., and Rigo, C. see Cinguino, P.
Steele, R., and Lam, W.H. see Lam, W.H.
Steele, R.C., and Marshall, I.W. 100 Mbit/s PSK heterodyne experiment using a travelling-wave laser amplifier p296
Steer, M.B., and Trew, R.J. see Trew, R.J.
Stegeman, G.I., Assanto, G., Gabel, A., Seaton, C.T., Ironside, C.N., and Cullen, T.J. see Assanto, G.
Stegmann, W. de V., Ferreira, H.C., and Wyman, C.R. see Ferreira, H.C.
Stephan, K.D., Young, S.L., and Wong, S.C. Open-cavity resonator as high-Q microstrip circuit element p1028 e1397
Stephens, T.D., and Nicholson, G. Optical homodyne receiver with a six-port fibre coupler p1106
Stern, J.R., Ballance, J.W., Faulkner, D.W., Hornung, S., Payne, D.B., and Oakley, K. Passive optical local networks for telephony applications and beyond p1255
Stern, M., Millicker, D.J., Elrefaie, A.E., and Runge, K. Transmission at 1 Gbit/s over 7·4 km of single-mode fibre using an edge-emitting LED and PINFET receiver p386
Stern, M.S., Kendall, P.C., and Robson, P.N. see Kendall, P.C.
Stern, M.S., and Roberts, D.A. see Roberts, D.A.
Stevenson, A.J., and Love, J.D. Vector modes of six-port couplers p1011
Stewart, B.G., and Simmons, J.F.L. Rician envelope estimation and confidence intervals in low signal/noise levels p832
Stiles, P.J., Crisman, E.E., Lee, J.I., and Gregory, O.J. see Crisman, E.E.
Stillwell, D., Tamburrini, M., Parent, M., and Goldberg, L. see Tamburrini, M.
Stobbs, W.M., Razeghi, M., Tardella, A., Davies, R.A., Long, A.P., Kelly, M.J., Britton, E., and Boothroyd, C. see Razeghi, M.
Stock, G. Realisation of integrated-optical absorbers for Ti : $LiNbO_3$ p831
Stojadinović, N., Dimitrijev, S., and Župac, D. see Dimitrijev, S.
Stone, J., Cimini, L.J., and Buhl, L.L. see Cimini, L.J.
Stone, J., Glance, B., Fitzgerald, P.J., Pollack, K.J., Burrus, C.A., Eisenstein, G., and Stulz, L.W. see Glance, B.
Stone, J., Glance, B., Fitzgerald, P.J., Pollock, K.J., Burrus, C.A., and Stulz, L.W. see Glance, B.
Stone, J., Kaminow, I.P., Iannone, P.P., and Stulz, L.W. see Kaminow, I.P.
Stone, J., and Stulz, L.W. Pigtailed high-finesse tunable fibre Fabry–Perot interferometers with large, medium and small free spectral ranges p781
Stoneham, E., Majidi-Ahy, R., and Omori, M. see Majidi-Ahy, R.
Streetman, B.G., Campbell, A.C., Kesan, V.P., Crook, G.E., Maziar, C.M., and Neikirk, D.P. see Campbell, A.C.
Streifer, W. Coupled mode theory p315
Streifer, W., Berger, J., Welch, D.F., Scifres, D.R., and Cross, P.S. see Berger, J.
Streifer, W., Welch, D.F., Cardinal, M., Scifres, D.R., and Cross, P.S. see Welch, D.F.
Streifer, W., Welch, D.F., Cross, P.S., and Scifres, D.R. see Welch, D.F.
Streifer, W., Welch, D.F., DeVito, M., Cardinal, M., Abraham, M., Kung, H., Harnagel, G., Cross, P., and Scifres, D. see Welch, D.F.
Streifer, W., Welch, D.F., Thornton, R.L., and Paoli, T. see Welch, D.F.
Stulz, L.W., Glance, B., Fitzgerald, P.J., Pollack, K.J., Stone, J., Burrus, C.A., and Eisenstein, G. see Glance, B.
Stulz, L.W., Glance, B., Pollock, K., Burrus, C.A., Kasper, B.L., and Eisenstein, G. see Glance, B.
Stulz, L.W., Glance, B., Stone, J., Fitzgerald, P.J., Pollock, K.J., and Burrus, C.A. see Glance, B.
Stulz, L.W., Glance, B., and Burrus, C.A. see Glance, B.
Stulz, L.W., Kaminow, I.P., Iannone, P.P., and Stone, J. see Kaminow, I.P.
Stulz, L.W., and Stone, J. see Stone, J.
Suchoski, P.G., Findakly, T.K., and Leonberger, F.J. Depolarisation in Ti : $LiNbO_3$ waveguides and its effect on circuit design p1357
Suda, H., Shimizu, M., and Horiguchi, M. see Shimizu, M.
Sudhakar, V., Jha, R.M., and Balakrishnan, N. see Jha, R.M.
Sudo, H., Kihara, K., Kamite, K., Tanahashi, T., Kusunoki, T., Isozumi, S., Ishikawa, H., and Imai, H. see Kihara, K.
Sudo, S., Hosaka, T., and Okamoto, K. see Hosaka, T.
Sugawara, R., Seki, M., Hanada, Y., Okuda, E., Wada, H., and Yamasaki, T. see Seki, M.
Sugimoto, H., Abe, Y., Matsui, T., and Ogata, H. Novel fabrication method of quarter-wave-shifted gratings using ECR-CVD SiN_x films p1260
Sugimoto, M., Ajisawa, A., Fujiwara, M., Shimizu, J., Uchida, M., and Ohta, Y. see Ajisawa, A.
Sugimura, A., and Kimura, T. see Kimura, T.
Sugita, E., Nagase, R., and Shintaku, T. see Nagase, R.
Sun, York-Yih, and Chung, Hung-Yuan see Chung, Hung-Yuan
Sun, York-yih, and Chung, Hung-yuan see Chung, Hung-yuan
Susaki, W., Aoyagi, T., Hinata, S., Shigihara, K., Seiwa, Y., and Ikeda, K. see Aoyagi, T.
Susaki, W., Shima, A., Yamawaki, T., Saito, H., Matsubara, H., Murakami, T., Ohtaki, K., and Kumabe, H. see Shima, A.
Susaki, W., Takemoto, A., Sakakibara, Y., Nakajima, Y., Fujiwara, M., Kakimoto, S., and Namizaki, H. see Takemoto, A.
Suscavage, M.J., Quimby, R.S., and Drexhage, M.G. see Quimby, R.S.
Suzuki, A., Itoh, T., Terakado, T., Kasahara, K., Asano, K., Inomoto, Y., Ishihara, H., Torikai, T., and Fujita, S. Long-wavelength PINFET receiver OEIC on a GaAs-on-InP heterostructure p954
Suzuki, M., Hayata, K., Koshiba, M., and Eguchi, M. see Hayata, K.
Suzuki, M., Hayata, K., and Koshiba, M. see Hayata, K.
Suzuki, S., Yabusaki, M., Arita, T., and Ishino, F. Channel reallocatable onboard baseband switch p487
Suzuki, T., Fujii, H., Kobayashi, K., Kawata, S., Gomyo, A., Hino, I., and Hotta, H. see Fujii, H.
Suzuki, T., Gomyo, A., Kobayashi, K., Kawata, S., and Hino, I. see Gomyo, A.
Suzuki, T., Kawata, S., Fujii, H., Kobayashi, K., Gomyo, A., and Hino, I. see Kawata, S.
Suzuki, Y., Mukai, S., Yajima, H., and Sato, T. Transverse junction buried heterostructure (TJ-BH) AlGaAs diode laser p384
Svilans, M.N., Houston, P.A., Blaauw, C., Margittai, A., Puetz, N., Day, D.J., Shepherd, F.R., and Springthorpe, A.J. see Houston, P.A.
Switzer, D.L., Gatenby, P.V., and Green, N. see Gatenby, P.V.

T

Tabatabaie, N., Zah, C.E., Osinski, J.S., Menocal, S.G., Lee, T.P., Dentai, A.G., and Burrus, C.A. see Zah, C.E.
Tada, K., Nakano, Y., and Luo, Y. see Nakano, Y.
Taheri, M., Jullien, G.A., and Miller, W.C. Fault detection in RNS systolic arrays p165
Tahim, R.S., Chang, K., and Hummer, K.A. Wide-band microstrip balanced mixer p767
Tai, S., Kameya, M., Kojima, K., Kyuma, K., Hamanaka, K., and Nakayama, T. see Kameya, M.
Taira, K., Kawai, H., and Kaneko, K. MOCVD-grown AlGaAs/GaAs HBTs with epitaxially embedded p^+ layers in extrinsic base p989
Tajima, K., Sasaki, Y., and Seikai, S. see Sasaki, Y.
Tajima, K., Sasaki, Y., and Yokohama, I. see Sasaki, Y.
Takachio, N., Iwashita, K., Nakano, Y., and Tsuzuki, N. see Iwashita, K.
Takachio, N., and Iwashita, K. see Iwashita, K.
Takada, A., Morioka, T., and Saruwatari, M. see Morioka, T.
Takagi, H., Ueda, D., Kano, G., and Teramoto, I. see Ueda, D.
Takahashi, Y., Yamane, Y., Ishii, H., and Hirayama, M. see Yamane, Y.
Takano, S., Ono, Y., Mito, I., and Nishida, N. see Ono, Y.
Takasaki, Y., Imoto, K., Sano, H., and Miyazaki, M. see Imoto, K.
Takato, N., Toba, H., Oda, K., and Nosu, K. see Toba, H.
Takeda, K., Tomaru, S., Kubodera, K., Zembutsu, S., and Hasegawa, M. see Tomaru, S.
Takemoto, A., Sakakibara, Y., Nakajima, Y., Fujiwara, M., Kakimoto, S., Namizaki, H., and Susaki, W. 1·3 μm InGaAsP/InP distributed-feedback p-substrate partially inverted buried-heterostructure laser diode p546
Takeshita, S., and Serizawa, Y. see Serizawa, Y.
Takeuchi, M., Kurosawa, K., and Ito, T. see Kurosawa, K.
Takeuchi, O., Matsushima, Y., Utaka, K., and Sakai, K. see Matsushima, Y.
Talman, J.R., Darcie, T.E., Burrus, C.A., Gnauck, A.H., and Kasper, B.L. see Darcie, T.E.
Talman, J.R., Darcie, T.E., Glance, B., Gayliard, K., Kasper, B.L., and Burrus, C.A. see Darcie, T.E.
Tamamura, K., Hirata, S., and Kojima, C. see Hirata, S.
Tamburrini, M., Goldberg, L., and Weller, J.F. Optically induced modulation in FM sideband injection-locked laser diodes p1120
Tamburrini, M., Parent, M., Goldberg, L., and Stillwell, D. Optical feed for a phased array microwave antenna p680
Tan, B.T.G., Oh, K.H., and Ong, C.K. see Oh, K.H.
Tan, F., Vogt, W.G., and Mickle, M.H. Relaxing the detectability condition for the algebraic Riccati equation p1139
Tan, M.A., and Schaumann, R. Generation of transconductance-grounded-capacitor filters by signal-flow-graph methods for VLSI implementation p1093
Tanahashi, T., Kihara, K., Kamite, K., Sudo, H., Kusunoki, T., Isozumi, S., Ishikawa, H., and Imai, H. see Kihara, K.
Tanaka, H., Kawamura, Y., and Asahi, H. Observations of room-temperature excitons in InGaP/InGaAlP MQW structures p166
Tanaka, S., Madihian, M., Toyoshima, H., Hayama, N., and Honjo, K. Novel process for emitter-base-collector self-aligned heterojunction bipolar transistor using a pattern-inversion method p562
Tanbun-Ek, T., Broberg, B., and Nilsson, S. see Broberg, B.
Tang, C.L., Fujita, T., and Schremer, A. see Fujita, T.
Tang, Z., and Chao, Q.P. see Chao, Q.P.
Tanisawa, Y., Kondo, M., Ohta, Y., Aoyama, T., and Ishikawa, R. see Kondo, M.
Tardella, A., Razeghi, M., Davies, R.A., Long, A.P., Kelly, M.J., Britton, E., Boothroyd, C., and Stobbs, W.M. see Razeghi, M.
Tarn, J.C.L., Humphreys, T.P., Das, K., Bedair, S.M., Wortman, J.J., Parikh, N., Chu, W.K., and El-Masry, N. see Humphreys, T.P.
Tascone, R., Orta, R., and Zich, R. see Orta, R.
Tasker, P.J., Chen, M., Schaff, W.J., and Eastman, L.F. see Chen, M.
Tasker, P.J., Palmateer, L.F., Itoh, T., Brown, A.S., Wicks, G.W., and Eastman, L.F. see Palmateer, L.F.
Tatam, R.P., Pannell, C.N., Jones, J.D.C., and Jackson, D.A. see Pannell, C.N.
Tate, T.J., and Green, M. see Green, M.
Tawfig, M.E., Ghobrial, S.I., and Hemeidi, M.A. see Ghobrial, S.I.
Taylor, G.W., Lebby, M.S., Chang, T.Y., Gnall, R.N., Sauer, N., Tell, B., and Simmons, J.G. Very high-transconductance heterojunction field-effect transistor (HFET) p77
Taylor, G.W., and Simmons, J.G. see Simmons, J.G.
Taylor, H.F., Lee, C.-E., and Atkins, R.A. see Lee, C.-E.
Taylor, J.R., Gouveia-Neto, A.S., Gomes, A.S.L., Ainslie, B.J., and Craig, S.P. see Gouveia-Neto, A.S.
Taylor, J.R., Gouveia-Neto, A.S., and Gomes, A.S.L. see Gouveia-Neto, A.S.
Taylor, J.T., Betts, A.K., and Haigh, D.G. see Betts, A.K.
Taylor, J.T., and Haigh, D.G. see Haigh, D.G.
Taylor, J.T., and Haigh, D.G. Stray-free first-order circuit for correction of sample-and-hold amplitude distortion in switched-capacitor filters p177
Taylor, S., Barlow, K.J., Eccleston, W., and Kiermasz, A. Comparison of RF and microwave oxidation systems for the growth of thin oxides at low temperatures p309
Taylor, S., Eccleston, W., and Watkinson, P. Advances in electrical properties of plasma-grown oxides of silicon p732
Tebb, D.W., and Hobson, L. Computer simulation of an induction heating power supply using power MOSFETs p293
Tegude, F.J., Speier, P., and Wünstel, K. see Speier, P.
Tell, B., Taylor, G.W., Lebby, M.S., Chang, T.Y., Gnall, R.N., Sauer, N., and Simmons, J.G. see Taylor, G.W.
Temes, G.C., and Ki, W.H. Fast CMOS current amplifier and buffer stage p696
Temkin, H., Koszi, L.A., Chin, B.H., Napholtz, S.G., and Segner, B.P. see Koszi, L.A.
Tench, R.E., Jopson, R.M., Darcie, T.E., Gayliard, K.T., Ku, R.T., Rice, T.C., and Olsson, N.A. see Jopson, R.M.
Tennant, D.M., Whalen, M.S., Hall, K.L., Koren, U., and Raybon, G. see Whalen, M.S.
Terakado, T., Suzuki, A., Itoh, T., Kasahara, K., Asano, K., Inomoto, Y., Ishihara, H., Torikai, T., and Fujita, S. see Suzuki, A.
Teramoto, I., Ueda, D., Takagi, H., and Kano, G. see Ueda, D.
Terrell, T.J., Shark, L.-K., and Simpson, R.J. see

Shark, L.-K.
Terret, C., Mahdjoubi, K., Penard, E., and Daniel, J.P. see Mahdjoubi, K.
Terui, H., Kobayashi, M., Yamada, M., Yamada, Y., and Himeno, A. see Kobayashi, M.
Terui, H., Yamada, M., Yamada, Y., Himeno, A., and Kobayashi, M. see Yamada, M.
Tetu, M., Villeneuve, B., and Cyr, N. see Villeneuve, B.
Tezuka, A., Utsumi, K., Nishii, K., Bando, K., Inoue, K., and Onuma, T. see Utsumi, K.
Thaniyavarn, S., and Dougherty, W. Generation of a single-lobe radiation pattern from a phased-array laser using a near-contact variable phase-shift zone plate p5
Theis, J., Meier, J., Lieber, W., Heinlein, W., Groh, W., and Herbrechtsmeier, P. see Meier, J.
Theobald, G., Bigler, E., and Hauden, D. see Bigler, E.
Thevenaz, L., and Pellaux, J.-P. Modulation frequency-shift technique for dispersion measurements in optical fibres using LEDs p1078
Thevenaz, L., von der Weid, J.-P., and Pellaux, J.-P. see von der Weid, J.-P.
Thomas, H., Morgan, D.V., Anderson, W.T., Thompson, P., Christou, A., and Diskett, D.J. see Morgan, D.V.
Thomas, K., Hinchliffe, S., and Hobson, L. Class E switching-mode power amplifier for high-frequency electric process heating applications p80
Thompson, D.A., Schroeder, J., Hwa, L.G., Shyong, M.C., Floudas, G.A., and Drexhage, M.G. see Schroeder, J.
Thompson, G.H.B., and Whiteaway, J.E.A. Analysis of the stability of the highest-order supermode in semiconductor laser arrays p444
Thompson, P., Dietrich, H., Anand, Y., Higgins, V., and Hillson, J. Fully implanted GaAs millimetre-wave mixer diode using high energy implantation p725
Thompson, P., Morgan, D.V., Thomas, H., Anderson, W.T., Christou, A., and Diskett, D.J. see Morgan, D.V.
Thompson, W.I., Herman, J.R., Duggan, C.C., Costa, R.A., and DeLuca, D.M. see Herman, J.R.
Thoms, S., Cheung, R., Beamont, S.P., Doughty, G., Law, V., and Wilkinson, C.D.W. see Cheung, R.
Thorn, J.S., Percival, T.M.P., and Driver, R. see Percival, T.M.P.
Thornton, K.E.B., Uttamchandani, D., Nixon, J., and Culshaw, B. see Uttamchandani, D.
Thornton, K.E.B., Uttamchandani, D., and Culshaw, B. see Uttamchandani, D.
Thornton, R.L., Epler, J.E., and Paoli, T.L. see Epler, J.E.
Thornton, R.L., Welch, D.F., Streifer, W., and Paoli, T. see Welch, D.F.
Thylen, L., Blumenthal, D.J., Prucnal, P.R., and Granestrand, P. see Blumenthal, D.J.
Tiberio, R., Manara, G., Pelosi, G., Pathak, P.H., and Kouyoumjian, R.G. see Manara, G.
Tihanyi, P., Wagner, D.K., Vollmer, H.J., Roza, A.J., Harding, C.M., Davis, R.J., and Wolf, E.D. High-power etched-facet lasers p772
Tiren, J., Bohlin, K.E., Tove, P.A., and Magnusson, U. see Bohlin, K.E.
Tkach, R.W., Darcie, T.E., and Jopson, R.M. see Darcie, T.E.
Toba, H., Oda, K., Takato, N., and Nosu, K. 5 GHz-spaced, eight-channel, guided-wave tunable multi/demultiplexer for optical FDM transmission systems p788
Toba, H., and Nosu, K. High-speed modulation characteristics of a GaSb/AlGaAb multiquantum-well laser diode p188
Toda, A., Nakano, K., Ikeda, M., and Kojima, C. see Nakano, K.
Toda, K., Matsuda, K., Minemoto, H., Kamada, O., and Ishizuka, S. see Matsuda, K.
Todd, T.D., and Mohanty, B.P. see Mohanty, B.P.
Tokito, S., Kaino, T., Kubodera, K.-I., Tomaru, S., Kurihara, T., Saito, S., and Tsutsui, T. see Kaino, T.
Tomaru, S., Kaino, T., Kubodera, K.-I., Kurihara, T., Saito, S., Tsutsui, T., and Tokito, S. see Kaino, T.
Tomaru, S., Kubodera, K., Zembutsu, S., Takeda, K., and Hasegawa, M. Optical third-harmonic generation from polydiacetylene thin films deposited by vacuum evaporation p595
Tomlinson, G.H. Absolute-type shaft encoder using shift register sequences p398
Tomlinson, G.H., and Ball, E. Elimination of errors in absolute position encoders using *m*-sequences p1372
Tong, Yu, Yizun, Wu, Feng, Tian, and Xinwei, Yang see Yizun, Wu
Tong, Yu, Yizun, Wu, Kejian, Guan, and Feng, Tian see Yizun, Wu
Torikai, T., Suzuki, A., Itoh, T., Terakado, T., Kasahara, K., Asano, K., Inomoto, Y., Ishihara, H., and Fujita, S. see Suzuki, A.
Toumazou, C., and Haigh, D.G. Design of a high-gain, single-stage operational amplifier for GaAs switched-capacitor filters p752
Toumazou, C., and Haigh, D.G. Level-shifting differential to single-ended convertor circuits for GaAs MESFET implementation p1053
Tove, P.A., Bohlin, K.E., Magnusson, U., and Tiren, J. see Bohlin, K.E.
Townsend, J.E., Poole, S.B., and Payne, D.N. Solution-doping technique for fabrication of rare-earth-doped optical fibres p329
Townsend, P.D., Glavas, E., Droungas, G., Dorey, M., Wong, K.K., and Allen, L. see Glavas, E.
Toyoshima, H., Tanaka, S., Madihian, M., Hayama, N., and Honjo, K. see Tanaka, S.
Trambarulo, R., Schneider, M.V., and Gans, M.J. Gigabit QPSK modulator p998
Tran, D., Botez, D., and Pham, T. see Botez, D.
Treitinger, L., Weger, P., Reimann, R., and Rein, H.-M. see Weger, P.
Trew, R.J., and Steer, M.B. Millimetre-wave performance of state-of-the-art MESFET, MODFET and PBT transistors p149
Trommer, G. Tolerance requirements for the drawing ratio of single-mode fibres with arbitrary refractive-index profile p79
Trundle, C., Cush, R., Kirkby, C.J.G., and Bennion, I. see Cush, R.
Tsai, N.S., Lu, C.Y., Riffe, P.C., Ahrens, R.E., and Banak, M.A. see Lu, C.Y.
Tsang, W.-T., Wood, T.H., Carr, E.C., Burrus, C.A., Tucker, R.S., and Chiu, T.-H. see Wood, T.H.
Tsang, W.T., Chiu, T.H., and Levi, A.F.J. see Chiu, T.H.
Tserng, H.Q., Kim, B., Wurtele, M., and Shih, H.D. see Kim, B.
Tsividis, Y., and Czarnul, Z. see Czarnul, Z.
Tsividis, Y., and Satyanarayana, S. Analogue circuits for variable-synapse electronic neural networks p1313
Tsividis, Y.P. Minimal transistor-only micropower integrated VHF active filter p777
Tsividis, Y.P., and Anastassiou, D. Switched-capacitor neutral networks p958
Tsuchida, H., and Mitsuhashi, Y. Frequency stabilisation of a modulated semiconductor laser p1147
Tsuji, S., Lee, T.P., Menocal, S.G., Sakano, S., and Valster, A. see Lee, T.P.
Tsuji, S., Okai, M., Hirao, M., and Matsumura, H. see Okai, M.
Tsujii, S., Itoh, T., Fujioka, A., Kurosawa, K., and Matsumoto, T. Public-key cryptosystem based on the difficulty of solving a system of nonlinear equations p558
Tsujii, S., Itoh, T., and Kurosawa, K. ID-based cryptosystem using discrete logarithm problem p1318
Tsujii, S., and Chao, J. see Chao, J.
Tsutsui, T., Kaino, T., Kubodera, K.-I., Tomaru, S., Kurihara, T., Saito, S., and Tokito, S. see Kaino, T.
Tsuzuki, N., Iwashita, K., Takachio, N., and Nakano, Y. see Iwashita, K.
Tucker, R.S., Eisenstein, G., Korotky, S.K., Buhl, L.L., Veselka, J.J., Raybon, G., Kasper, B.L., and Alferness, R.C. 16 Gbit/s fibre transmission experiment using optical time-division multiplexing p1270
Tucker, R.S., Eisenstein, G., Korotky, S.K., Koren, U., Raybon, G., Veselka, J.J., Buhl, L.L., Kasper, B.L., and Alferness, R.C. Optical time-division multiplexing and demultiplexing in a multigigabit/second fibre transmission system p208
Tucker, R.S., Eisenstein, G., Korotky, S.K., Raybon, G., Veselka, J.J., Buhl, L.L., Gnauck, A.H., Kasper, B.L., and Alferness, R.C. see Eisenstein, G.
Tucker, R.S., Koren, U., Miller, B.I., Eisenstein, G., Bar-Joseph, I., Miller, D.A.B., and Chemla, D.S. see Koren, U.
Tucker, R.S., Wood, T.H., Carr, E.C., Burrus, C.A., Chiu, T.-H., and Tsang, W.-T. see Wood, T.H.
Tudor, M.J., Andres, M.V., and Foulds, K.W.H. see Andres, M.V.
Tveten, A.B., Dandridge, A., Kersey, A.D., and Yurek, A.M. see Dandridge, A.
Tyszer, J., and Jajszczyk, A. see Jajszczyk, A.
Tzeng, L.D., Emkey, W.L., Jack, C.A., and Burrus, C.A. Polarisation-insensitive coherent receiver using a double balanced optical hybrid system p1195

U

Uchida, M., Ajisawa, A., Fujiwara, M., Shimizu, J., Sugimoto, M., and Ohta, Y. see Ajisawa, A.
Ueda, D., Takagi, H., Kano, G., and Teramoto, I. GaAs lateral bipolar transistor with field-separated carriers p899
Ueda, K., Onozawa, A., and Miyashita, H. see Onozawa, A.
Ueki, M., Kuroda, K., Nakano, J., and Yuda, M. see Kuroda, K.
Uhde, K. Optoelectronic millimetre-wave switching using a finline-on-silicon substrate p1155
Uher, J., Arndt, F., and Bornemann, J. Dielectric slab matched ferrite gyrator p278
Uher, J., Bornemann, J., and Arndt, F. Ferrite tunable metal insert filter p804
Uji, T., Fujita, S., Hayashi, J., Isoda, Y., and Shikada, M. see Fujita, S.
Umena, L., Canali, C., Chiussi, F., Fantini, F., and Vanzi, M. see Canali, C.
Un, C.K., and Kim, H.D. see Kim, H.D.
Ungvichian, V., and Perez-Rodriquez, R. Prediction of electromagnetic radiation of a multilayer board p721
Unnikrishnan, R., and Mathew, A.V. Instabilities in numerical inversion of Laplace transforms using Taylor series approach p482
Urquhart, J., Moseley, A.J., Hodson, P.D., Riffat, J.R., and Davies, J.I. see Moseley, A.J.
Usami, M., Akiba, S., Matsushima, Y., and Utaka, K. see Akiba, S.
Usandizaga, J.R., Ruiz-Moreno, S., Junyent, G., and Calzada, A. see Ruiz-Moreno, S.
Utaka, K., Akiba, S., Matsushima, Y., and Usami, M. see Akiba, S.
Utaka, K., Matsushima, Y., Sakai, K., and Takeuchi, O. see Matsushima, Y.
Utsumi, K., Tezuka, A., Nishii, K., Bando, K., Inoue, K., and Onuma, T. Gigabit optical transmitter GaAs MESFET IC p374
Uttamchandani, D., Thornton, K.E.B., Nixon, J., and Culshaw, B. Optically excited resonant diaphragm pressure sensor p152
Uttamchandani, D., Thornton, K.E.B., and Culshaw, B. Optically excited resonant beam pressure sensor p1333

V

Vich, R. Homomorphic vector quantisation p561
Valdmanis, J.A. 1 THz-bandwidth prober for high-speed devices and integrated circuits p1308
Valencic, V., Deval, P., and Krummenacher, F. 8-bit micropower algorithmic A/D convertor p932
Valenzuela, R., Gnauck, A.H., Linke, R.A., Kasper, B.L., Pollock, K.J., Reichmann, K.C., and Alferness, R.C. see Gnauck, A.H.
Vallee, R., Jackson, T., Nees, J., and Mourou, G. see Jackson, T.
Valster, A., Lee, T.P., Menocal, S.G., Sakano, S., and Tsuji, S. see Lee, T.P.
Van De Capelle, A., and Nauwelaers, B. see Nauwelaers, B.
Van de Velde, J.C., Lauer, P., Leroy, Y., and Mamouni, A. see Lauer, P.
van Oort, R.C., Geerts, M.J., van den Heuvel, J.C., and Metselaar, J.W. Hydrogen plasma etching of amorphous and microcrystalline silicon p967
van den Heuvel, J.C., van Oort, R.C., Geerts, M.J., and Metselaar, J.W. see van Oort, R.C.
Vannucci, G., Park, Y.K., Granlund, S.W., Kuo, C.Y., Dixon, M., Cline, T.W., Smith, R.W., and Dutta, N.K. see Park, Y.K.
Vanzi, M., Canali, C., Chiussi, F., Fantini, F., and Umena, L. see Canali, C.
Vanzi, M., Canali, C., Donzelli, G., Fantini, F., and Paccagnella, A. see Canali, C.
Vasilescu, G.I. Computer-aided noise analysis of linear multiport networks p351
Vasiljev, A.V., Dianov, E.M., Dmitruk, L.N., and Plotnichenko, V.G. Single-crystal two-layer fibres for visible and infra-red transmission p117
Vassallo, C. Condensed formula for coupling coefficients between parallel dielectric waveguides p334
Vassiliadis, S., Putrino, M., and Schwarz, E. see Putrino, M.
Vassiliadis, S., Putrino, M., and Schwarz, E. Direct two's-complement algorithm for $XY \pm Z$ p538 e763
Vatarescu, A. Polarisation state stabilisation in optically nonlinear birefringent fibres p379
Vaudin, G.J., and Nudd, G.R. 3 μm VLSI processing element using the Cordic algorithm p1164
Vaudry, C., Henry, L., and Granjoux, P. see Henry, L.
Vaudry, C., Lecrosnier, D., Henry, L., and Le Corre, A. see Lecrosnier, D.
Vecchi, M.P., Kobrinski, H., Bulley, R.M., Goodman, M.S., Brackett, C.A., Curtis, L., and Gimlett, J.L. see Kobrinski, H.
Vescan, L., Gruhle, A., and Beneking, H. see Gruhle, A.
Vescan, L., Werres, C., and Beneking, H. see Werres, C.
Veselka, J.J., Eisenstein, G., Tucker, R.S., Korotky, S.K., Raybon, G., Buhl, L.L., Gnauck, A.H., Kasper, B.L., and Alferness, R.C. see Eisenstein, G.
Veselka, J.J., Tucker, R.S., Eisenstein, G., Korotky, S.K., Buhl, L.L., Raybon, G., Kasper, B.L., and Alferness, R.C. see Tucker, R.S.
Veselka, J.J., Tucker, R.S., Eisenstein, G., Korotky, S.K., Koren, U., Raybon, G., Buhl, L.L., Kasper, B.L., and Alferness, R.C. see Tucker, R.S.
Veselka, J.J., and Bogert, G.A. Low-insertion-loss channel waveguides in $LiNbO_3$ fabricated by proton exchange p265
Veselka, J.J., and Bogert, G.A. Low-loss TM-pass polariser fabricated by proton exchange for Z-cut Ti:$LiNbO_3$ waveguides p29
Vibet, C. Guide to choosing the sampling rate in computerised controllers p1002
Vilar, E., Lau, W.H., and Austin, J. see Lau, W.H.
Vilbe, P., and Calvez, L.C. Constrained l_2 sub-optimal model reduction p1340
Villeneuve, B., Cyr, N., and Tetu, M. Precise optical heterodyne beat frequency from laser diodes locked to atomic resonances p1082
Voges, E., and Rottmann, F. see Rottmann, F.
Vogt, W.G., Tan, F., and Mickle, M.H. see Tan, F.
Vold, P.J., Arch, D.K., Abrokwah, J.K., Fraasch, A.M., Grung, B.L., and Cirillo, N.C. see Arch, D.K.

Vollmer, H.J., Tihanyi, P., Wagner, D.K., Roza, A.J., Harding, C.M., Davis, R.J., and Wolf, E.D. see Tihanyi, P.
von Helmolt, C.H., Heidrich, H., Hoffmann, D., Hensel, H.-J., and Kleinwächter, A. see Heidrich, H.
von der Weid, J.-P., Thevenaz, L., and Pellaux, J.-P. Interferometric measurements of chromatic and polarisation mode dispersion in highly birefringent single-mode fibres p151
Vu, D.P., and Sono, A. Self-aligned Si MESFETs fabricated in thin silicon-on-insulator films p354
Vu, T.B., and Lo, K.W. see Lo, K.W.
Vu, T.B., and Lo, K.W. see Lo, K.W.

W

Waarts, R.G., Großkopf, G., Ludwig, R., and Weber, H.G. see Großkopf, G.
Waarts, R.G., Yaffe, H.H., Lichtman, E., and Friesem, A.A. see Yaffe, H.H.
Wada, H., Seki, M., Sugawara, R., Hanada, Y., Okuda, E., and Yamasaki, T. see Seki, M.
Wada, O., Nobuhara, H., and Fujii, T. see Nobuhara, H.
Wagner, D.K., Tihanyi, P., Vollmer, H.J., Roza, A.J., Harding, C.M., Davis, R.J., and Wolf, E.D. see Tihanyi, P.
Wagner, R.E., Elrefaie, A.F., Atlas, D.A., and Daut, D.G. see Elrefaie, A.F.
Wagner, R.E., Poole, C.D., Bergano, N.S., Schulte, H.J., Nathu, V.P., Amon, J.M., and Rosenberg, R.L. see Poole, C.D.
Wait, J.R. Physical model for the complex resistivity of the earth p979
Wakabayashi, H., Namihira, Y., Horiuchi, Y., Oshimi, T., Kitagawa, K., and Ooka, T. see Namihira, Y.
Wakabayashi, H., Namihira, Y., and Horiuchi, Y. see Namihira, Y.
Wake, D., Walling, R.H., Sargood, S.K., and Henning, I.D. $In_{0.53}Ga_{0.47}As$ PIN photodiode grown by MOVPE on a semi-insulating InP substrate for monolithic integration p415
Wakita, K., Kawamura, Y., Asahi, H., and Oe, K. see Kawamura, Y.
Wakita, K., Nojima, S., Nakashima, K., and Kawaguchi, Y. GaInAs/InP waveguide multiple-quantum-well optical modulator with 9 dB on/off ratio p1067
Wakita, K., Yoshikuni, Y., and Kawamura, Y. Highly efficient InGaAs/InAlAs MQW waveguide phase shifter p303
Walker, G.R., and Walker, N.G. see Walker, N.G.
Walker, G.R., and Walker, N.G. Alignment of polarisation-maintaining fibres by temperature modulation p689
Walker, N.G., and Walker, G.R. see Walker, G.R.
Walker, N.G., and Walker, G.R. Endless polarisation control using four fibre squeezers p290
Walker, R.G., Shephard, H.E., and Bradley, R.R. Narrow, high-NA GaAs/GaAlAs optical waveguides with losses below $0{\cdot}7 \pm 0{\cdot}1\,dB\,cm^{-1}$ p362
Walling, R.H., Wake, D., Sargood, S.K., and Henning, I.D. see Wake, D.
Wallis, R.H., Hodson, P.D., Bradley, R.R., Riffat, J.R., and Joyce, T.B. see Hodson, P.D.
Wallis, R.H., Hodson, P.D., and Davies, J.I. see Hodson, P.D.
Wallis, R.H., Moseley, A.J., Scott, M.D., Williams, P.J., Davies, J.I., and Riffat, J.R. see Moseley, A.J.
Walpita, L.M., Lin, S.C., Jing, X.L., Chin, M.K., Yu, P.K.L., and Chang, W.S.C. see Lin, S.C.
Walz, F.W., MacChesney, J.B., Johnson, D.W., and Fleming, D.A. see MacChesney, J.B.
Wan, Tat, Pitt, C.W., and Burbie, G. see Pitt, C.W.
Wang, H., Liu, Y.Y., Mittelstein, M., Chen, T.R., and Yariv, A. GaInAsP/InP unstable resonator lasers p949
Wang, J., Schunk, N., and Petermann, K. Linewidth enhancement for DFB lasers due to longitudinal field dependence in the laser cavity p715
Wang, K.-W., Cheng, C.L., and Zima, S.M. Fully ion-implanted abrupt *pn* junction on semi-insulating InP p1040
Wang, Q., and Bhargava, V.K. Error-correcting code for optical-fibre transmission systems d647
Wang, S., Wu, Y.-H., Ogura, M., and Werner, M. see Wu, Y.-H.
Wang, S.J., Young, W.C., Curtis, L., Cheung, N.K., and Burpee, D.S. see Young, W.C.
Wang, S.S., and Yeung, K.S. see Yeung, K.S.
Wang, Y., and Wang, Z. see Wang, Z.
Wang, Y.H., Yarn, K.F., Chang, C.Y., and Jame, M.S. New structure of three-terminal GaAs p^+-n^--$\delta(p^+)$-n^--n^+ switching device prepared by molecular beam epitaxy p873
Wang, Z., and Langmann, U. New proposal for a multigigabit/s clock recovery IC based on a standard silicon bipolar technology p454
Wang, Z., and Wang, Y. Comparative study of time efficiency of several algorithms for discrete W transform and discrete Hartley transform p219
Wanuga, S., Wojtczuk, S.J., Ballantyne, J.M., and Chen, Y.K. see Wojtczuk, S.J.
Watanabe, K., and Matsumoto, H. see Matsumoto, H.
Watanabe, M., Mukai, S., Itoh, H., and Yajima, H. see Mukai, S.
Watanabe, M., Mukai, S., Itoh, M., Itoh, H., and Yajima, H. see Mukai, S.
Watkinson, P., Taylor, S., and Eccleston, W. see Taylor, S.
Watts, R.K., Manchanda, L., and Johnston, R.L. Gate current in 0·75 μm *N*-channel MOSFETs with doubly diffused drain p468
Way, W.I., Krain, M., and Wolff, R.S. 1·3 μm 35 km fibre-optic microwave multicarrier transmission system for satellite earth stations p400
Weber, H.G., Großkopf, G., Ludwig, R., and Waarts, R.G. see Großkopf, G.
Wedding, B. SPICE simulation of laser diode modules p383
Wedding, B., Heidemann, R., and Scholz, U. see Heidemann, R.
Weger, P., Treitinger, L., Reimann, R., and Rein, H.-M. Static 7 GHz Frequency divider IC based on a 2 μm Si bipolar technology p192
Wei, Che-Ho, and Chen, Yuh-Long see Chen, Yuh-Long
Weiner, J.S., Gossard, A.C., English, J.H., Miller, D.A.B., Chemla, D.S., and Burrus, C.A. Low-voltage modulator and self-biased self-electro-optic-effect device p75
Weingarten, K.J., Majidi-Ahy, R., Riaziat, M., Auld, B.A., and Bloom, D.M. see Majidi-Ahy, R.
Weiss, B.L., and Reed, G.T. see Reed, G.T.
Welch, D.F., Berger, J., Scifres, D.R., Streifer, W., and Cross, P.S. see Berger, J.
Welch, D.F., Cardinal, M., Streifer, W., Scifres, D.R., and Cross, P.S. High-brightness, high-efficiency, single-quantum-well laser diode array p1240
Welch, D.F., Cross, P.S., Scifres, D.R., and Streifer, W. Single-lobe 'Y' coupled laser diode arrays p270
Welch, D.F., DeFreez, R.K., Elliott, R.A., and Hartnett, K. see DeFreez, R.K.
Welch, D.F., DeVito, M., Cardinal, M., Abraham, M., Kung, H., Harnagel, G., Cross, P., Scifres, D., and Streifer, W. Performance characteristics of high-brightness, CW, diode laser arrays p892
Welch, D.F., Thornton, R.L., Streifer, W., and Paoli, T. 2·4 W CW, 770 nm laser arrays with nonabsorbing mirrors p525
Weller, J.F., Kersey, A.D., Yurek, A.M., and Dandridge, A. see Kersey, A.D.
Weller, J.F., Tamburrini, M., and Goldberg, L. see Tamburrini, M.
Welter, R., Choy, M.M., Gimlett, J.L., Kazovsky, L.G., and Cheung, N.K. see Choy, M.M.
Welter, R., Kazovsky, L.G., Elrefaie, A.F., Meissner, P., Crespo, P., Gimlett, J., and Smith, R.W. see Kazovsky, L.G.
Wen-hong, Shi, and Jin-guang, Chen Improper decimation of *m*-sequences p210
Wen-hong, Shi, and Jin-guang, Chen Radiation pattern of a stripline excited rectangular aperture p187
Wenger, J., and Huber, S. Low-noise D-band impatt oscillators p475
Werner, M., Wu, Y.-H., Ogura, M., and Wang, S. see Wu, Y.-H.
Werres, C., Vescan, L., and Beneking, H. Noise in epitaxial silicon bulk unipolar diodes p613
Wesołowski, K. Efficient digital receiver structure for trellis-coded signals transmitted through channels with intersymbol interference p1265
Westbrook, L.D. Properties of quarter-wave-shifted DFB lasers in the presence of a taper p518
Westbrook, L.D., and Adams, M.J. Linewidth enhancement in quantum-well lasers p1223
Westlake, H.J., and O'Mahony, M.J. Bidirectional and two-channel transmission system measurements using a semiconductor-laser-amplifier repeater p649
Westphalen, R., Fernholz, G., Lange, W., and Beneking, H. see Fernholz, G.
Whalen, M.S., Hall, K.L., Tennant, D.M., Koren, U., and Raybon, G. Tunable fibre-extended-cavity laser p313
Whalen, M.S., Jopson, R.M., Hall, K.L., Eisenstein, G., and Raybon, G. see Jopson, R.M.
Wheatley, P., Bradley, P.J., Parry, G., Midwinter, J.E., Mistry, P., and Roberts, J.S. see Bradley, P.J.
Wheatley, P., Bradley, P.J., Whitehead, M., Parry, G., Midwinter, J.E., Mistry, P., Pate, M.A., and Roberts, J.S. Novel nonresonant optoelectronic logic device p92
Wheatley, P., Parry, G., Midwinter, J.E., Hill, G., Mistry, P., Pate, M.A., and Roberts, J.S. Dynamic response of an integrated optoelectronic logic device p1249
Wheeler, S.A., Armistead, C.J., Butler, B.R., Clements, S.J., Collar, A.J., Moule, D.J., Fice, M.J., and Ahmed, H. see Armistead, C.J.
White, A.M., Ashley, T., Elliott, C.T., Crimes, G.J., and Harker, A.T. see Ashley, T.
White, A.M., Blackman, M.V., Charlton, D.E., Jenner, M.D., Purdy, D.R., Wotherspoon, J.T.M., and Elliott, C.T. see Blackman, M.V.
White, D.J., Dinger, R.J., and Bowling, D.R. see Dinger, R.J.
White, I.H., Garrett, B., and Gallagher, D.F.G. see Garrett, B.
White, I.H., and Davison, A.S. see Davison, A.S.
Whiteaway, J.E.A., and Thompson, G.H.B. see Thompson, G.H.B.
Whitehead, M., Parry, G., Roberts, J.S., Mistry, P., Li Kam Wa, P., and David, J.P.R. Quantum confined Stark shifts in MOVPE-grown GaAs–AlGaAs multiple quantum wells p1048
Whitehead, M., Wheatley, P., Bradley, P.J., Parry, G., Midwinter, J.E., Mistry, P., Pate, M.A., and Roberts, J.S. see Wheatley, P.
Wicks, G.W., Palmateer, L.F., Tasker, P.J., Itoh, T., Brown, A.S., and Eastman, L.F. see Palmateer, L.F.
Wiemer, L., and Jansen, R.H. Determination of coupling capacitance of underpasses, air bridges and crossings in MICs and MMICs p344
Wijnbeek, M.C., and Malherbe, J.A.G. see Malherbe, J.A.G.
Wilcox, J.Z., Yang, J.J., and Jansen, M. Coupled-mode analysis of a periodic array of diode lasers p69
Wild, P., and Mitchell, C. see Mitchell, C.
Wilkinson, C.D.W., Cheung, R., Thoms, S., Beamont, S.P., Doughty, G., and Law, V. see Cheung, R.
Wilkinson, C.D.W., Lee, K.Y., Al-Mudares, M., Beaumont, S.P., Frost, J., and Stanley, C.R. see Lee, K.Y.
Williams, J.O., Hua, Y.L., Petty, M.C., Roberts, G.G., Ahmad, M.M., Yates, H.M., and Maung, N.J. see Hua, Y.L.
Williams, P.J., Moseley, A.J., Scott, M.D., Wallis, R.H., Davies, J.I., and Riffat, J.R. see Moseley, A.J.
Williams, R.D., Oldfield, J.V., and Wiseman, N.E. see Oldfield, J.V.
Williamson, A.G., and Barry, P.J. see Barry, P.J.
Williamson, A.G., and Sowerby, K.W. see Sowerby, K.W.
Willis, T.M., and Sengupta, D.L. Accuracy of standard patch antenna models p1376
Wilson, B., and Darwazeh, I. Transimpedance optical preamplifier with a very low input resistance p138
Wilson, B., and Ghassemlooy, Z. Differential phase error in pulse-width-modulated TV transmission systems p1133 e1397
Wiseman, N.E., Oldfield, J.V., and Williams, R.D. see Oldfield, J.V.
Wittmann, J., and Gaukel, G. Narrow-linewidth laser with a prism grating/GRIN rod lens combination serving as external cavity p524
Wojtczuk, S.J., Ballantyne, J.M., Chen, Y.K., and Wanuga, S. Monolithically integrated photoreceiver with large gain-bandwidth product p574
Wolf, E.D., Tihanyi, P., Wagner, D.K., Vollmer, H.J., Roza, A.J., Harding, C.M., and Davis, R.J. see Tihanyi, P.
Wolff, R.S., Way, W.I., and Krain, M. see Way, W.I.
Wolny, M., Aguila, T., Deconinck, P., Moroni, D., and Andre, J.P. High-performance WN-gate MISFETs fabricated from MOVPE wafers p1127
Wong, K.-F. Garbage collection coprocessor system p798
Wong, K.K., Glavas, E., Townsend, P.D., Droungas, G., Dorey, M., and Allen, L. see Glavas, E.
Wong, K.K., and Donaldson, A. see Donaldson, A.
Wong, S.C., Stephan, K.D., and Young, S.L. see Stephan, K.D.
Wood, J., and Hodson, C.M.T. see Hodson, C.M.T.
Wood, T.H., Carr, E.C., Burrus, C.A., Henry, J.E., Gossard, A.C., and English, J.H. High-speed 2 × 2 electrically driven spatial light modulator made with GaAs/AlGaAs multiple quantum wells (MQWs) p916
Wood, T.H., Carr, E.C., Burrus, C.A., Tucker, R.S., Chiu, T.-H., and Tsang, W.-T. High-speed waveguide optical modulator made from GaSb/AlGaSb multiple quantum wells (MQWs) p540
Woodhead, J., Roberts, J.S., Mistry, P., Singh, K.C., and Sotomayor-Torres, C.M. see Roberts, J.S.
Wortman, J.J., Humphreys, T.P., Das, K., Bedair, S.M., Parikh, N., Chu, W.K., El-Masry, N., and Tarn, J.C.L. see Humphreys, T.P.
Wotherspoon, J.T.M., Blackman, M.V., Charlton, D.E., Jenner, M.D., Purdy, D.R., Elliott, C.T., and White, A.M. see Blackman, M.V.
Wright, A.S., and Judah, S.K. Very broadband flat coupling hybrid ring p47
Wright, S., Pettitt, M.J., Remedios, D., Davis, A.W., and Hadjifotiou, A. see Pettitt, M.J.
Wu, Ja-Ling, and Hsu, Chau-Yun see Hsu, Chau-Yun
Wu, K., and Saguet, P. New technique for analysing planar waveguides with finite metallisation thickness e251
Wu, P.H., and Min, Qian Simple method to determine microwave phase p1050
Wu, X.S., Alping, A., and Coldren, L.A. see Alping, A.
Wu, Y.-H., Ogura, M., Werner, M., and Wang, S. New GaAlAs-GaAs surface-emitting laser diodes with lateral pumping structure p123
Wünstel, K., Speier, P., and Tegude, F.J. see Speier, P.
Wurtele, M., Kim, B., Shih, H.D., and Tserng, H.Q. see Kim, B.
Wurtele, M., Shih, H.D., and Kim, B. see Shih, H.D.
Wyman, C.R., Ferreira, H.C., and Stegmann, W. de V. see Ferreira, H.C.
Wyndham, B.A., and Nichols, T.B. Objective measurement of receiver sensitivity p1388
Wyrsch, N., Curtins, H., and Shah, A.V. see Curtins, H.

X

Xiao-song, Jiang, Li-sheng, Yu, Shu-min, Wang, and Hong-xun, Liu Simple method for measuring hot-electron temperature in GaAs p55
Xinwei, Yang, Yizun, Wu, Feng, Tian, and Tong, Yu see Yizun, Wu
Xu, D.-Y., and Nguyen, D.T. see Nguyen, D.T.
Xue-heng, Zheng Single-mode single-polarisation fibre using resonant absorbing effect p14

Y

Yabusaki, M., Suzuki, S., Arita, T., and Ishino, F. see Suzuki, S.
Yaffe, H.H., Waarts, R.G., Lichtman, E., and Friesem, A.A. Multiple-wave generation due to four-wave mixing in a single-mode fibre p42
Yajima, H., Mukai, S., Itoh, M., Watanabe, M., and Itoh, H. see Mukai, S.
Yajima, H., Mukai, S., Watanabe, M., and Itoh, H. see Mukai, S.
Yajima, H., Suzuki, Y., Mukai, S., and Sato, T. see Suzuki, Y.
Yamabayashi, Y., Franzen, D.L., and Kanada, T. see Franzen, D.L.
Yamada, A., Kawasaki, T., and Kawashima, M. Bonding silicon wafer to silicon nitride with spin-on glass as adhesive p314
Yamada, A., Kawasaki, T., and Kawashima, M. SOI by wafer bonding with spin-on glass as adhesive p39
Yamada, M., Kobayashi, M., Yamada, Y., Himeno, A., and Terui, H. see Kobayashi, M.
Yamada, M., Terui, H., Yamada, Y., Himeno, A., and Kobayashi, M. Efficient photodiode-waveguide coupling for hybrid integrated optical circuits p1056
Yamada, Y., Kobayashi, M., Yamada, M., Himeno, A., and Terui, H. see Kobayashi, M.
Yamada, Y., Yamada, M., Terui, H., Himeno, A., and Kobayashi, M. see Yamada, M.
Yamaguchi, K., and Imai, H. Highly reliable multilevel channel coding system using binary convolutional codes p939
Yamaguchi, M., Emura, K., Kitamura, M., Mito, I., and Kobayashi, K. InGaAsP carrier injection modulator integrated with DFB LD p190
Yamaguchi, M., and Kikuchi, K. Tuning characteristics and inverter/inverted-output flip-flop operation of tandem-electrode laser diode p120
Yamamoto, F., Hanafusa, H., Hibino, Y., and Itoh, H. see Hanafusa, H.
Yamamoto, H. Resonant tunnelling condition in a one-dimensional rectangular double-barrier structure p161
Yamamoto, S., Ryu, S., and Mochizuki, K. see Ryu, S.
Yamane, Y., Takahashi, Y., Ishii, H., and Hirayama, M. Selective formation of ohmic contacts to *n*-GaAs p382
Yamasaki, T., Seki, M., Sugawara, R., Hanada, Y., Okuda, E., and Wada, H. see Seki, M.
Yamashita, K., Kinoshita, T., Maeda, M., and Sekine, Y. see Kinoshita, T.
Yamauchi, J., Imada, G., and Nakano, H. Helicoidal director for circularly polarised waves p851
Yamauchi, J., Nakano, H., and Sato, M. see Nakano, H.
Yamauchi, Y., Nagata, K., Nakajima, O., Ito, H., Nittono, T., and Ishibashi, T. 22 GHz 1/4 frequency divider using AlGaAs/GaAs HBTs p881
Yamauchi, Y., and Ishibashi, T. Application of AlGaAs/GaAs HBTs for wideband direct-coupled amplifiers p156
Yamawaki, T., Shima, A., Saito, H., Matsubara, H., Murakami, T., Ohtaki, K., Kumabe, H., and Susaki, W. see Shima, A.
Yamazaki, S., Murata, S., Komatsu, K., Koizumi, Y., Fujita, S., and Emura, K. 1·2 Gbit/s optical DPSK heterodyne detection transmission system using monolithic external-cavity DFB LDs p860
Yang, J.J., Wilcox, J.Z., and Jansen, M. see Wilcox, J.Z.
Yang, K.H., Chen, L., and Zhang, S.Y. Laser interferometer using a dual interference method p699
Yano, M., Kotaki, Y., Matsuda, M., Ishikawa, H., and Imai, H. see Kotaki, Y.
Yano, M., Ogita, S., Hirano, M., Soda, H., Ishikawa, H., and Imai, H. see Ogita, S.
Yano, M., Ogita, S., Ishikawa, H., and Imai, H. see Ogita, S.
Yariv, A., Chen, H.Z., Ghaffari, A., and Morkoç, H. see Chen, H.Z.
Yariv, A., Wang, H., Liu, Y.Y., Mittelstein, M., and Chen, T.R. see Wang, H.
Yariv, A., and Agranat, A. see Agranat, A.
Yarn, K.F., Wang, Y.H., Chang, C.Y., and Jame, M.S. see Wang, Y.H.
Yasaka, H., Kawaguchi, H., Oe, K., Magari, K., Fukuda, M., and Itaya, Y. see Kawaguchi, H.
Yasaka, H., Nakano, Y., Itaya, Y., Fukuda, M., Noguchi, Y., and Oe, K. see Nakano, Y.
Yasaka, H., Yoshikuni, Y., Motosugi, G., and Oe, K. Optical frequency scanning of a stabilised and linewidth-reduced multielectrode DFB laser using current feedback p984
Yasaka, H., Yoshikuni, Y., Nakano, Y., and Oe, K. Optical frequency stabilisation and linewidth reduction of a multielectrode DFB laser with current feedback p1161
Yataki, M.S., Morishita, K., and Gambling, W.A. see Morishita, K.
Yates, H.M., Hua, Y.L., Petty, M.C., Roberts, G.G., Ahmad, M.M., Maung, N.J., and Williams, J.O. see Hua, Y.L.
Yeatman, E., and Ash, E.A. Surface plasmon microscopy p1091
Yennadhiou, P., and Cassidy, S.A. see Cassidy, S.A.
Yeo, S.P., and Ang, A.L. Six-port reflectometer p1160
Yethiraj, A., and Smith, C.B. Nonlinear feedback control of a class of nonlinear systems p18
Yeung, K.S., and Wang, S.S. Linear third-order discrete system stability under parameter variations p266
Yi Xian, Yang Correlation-immunity of Boolean functions p1335
Yi Xian, Yang Existence of one-dimensional perfect binary arrays p1277
Yi Xian, Yang Improved (conference) public-key distribution system based on matrices p934
Yi Xian, Yang New public-key distribution systems p560
Yi Xian, Yang Pieprzyk's public-key cryptosystem is insecure p1043
Yi-Yan, A., Carru, H., Correc, P., Chandouineau, J.P., Dugrand, L., and Carre, M. GaAs/GaAlAs rib waveguide grating filters for $\lambda = 1{\cdot}5\,\mu m$ p622
Yijiang, Chen, and Hung-chia, Huang Macrobends of bow-tie fibres with constant curvature p159
Yijiang, Chen, and Hung-chia, Huang Microbending losses of bow-tie and similar anisotropic fibres p157
Yip, G.L., and Albert, J. see Albert, J.
Yizun, Wu, Feng, Tian, Xinwei, Yang, and Tong, Yu Coherent optical fibre system with Zeeman lasers p49
Yizun, Wu, Kejian, Guan, Tong, Yu, and Feng, Tian Experiment on 1500 nm stabilised Zeeman laser p318
Yokohama, I., Sasaki, Y., and Tajima, K. see Sasaki, Y.
Yokota, M., Kudou, T., and Fukumitsu, O. High-frequency scattering of a Hermite-Gaussian beam mode by a perfectly conducting cylinder p174
Yokoyama, N., Imamura, K., Muto, S., Ohnishi, H., and Fujii, T. see Imamura, K.
Yoshikai, N. Error-correcting code for optical-fibre transmission systems p97 d647
Yoshikuni, Y., Wakita, K., and Kawamura, Y. see Wakita, K.
Yoshikuni, Y., Yasaka, H., Motosugi, G., and Oe, K. see Yasaka, H.
Yoshikuni, Y., Yasaka, H., Nakano, Y., and Oe, K. see Yasaka, H.
Yosiffov, E., Borissov, M., Spassov, L., Balabanova, A., and Radeva, E. see Borissov, M.
Young, S.L., Stephan, K.D., and Wong, S.C. see Stephan, K.D.
Young, W.C., Curtis, L., Cheung, N.K., Wang, S.J., and Burpee, D.S. Practical method of measuring reflection-induced power penalties in single-mode fibre transmission systems p56
Youngquist, R.C., and Kreit, D. see Kreit, D.
Yu, P.K.L., Fan, C., and Chen, P.C. see Fan, C.
Yu, P.K.L., Lin, S.C., Jing, X.L., Chin, M.K., Walpita, L.M., and Chang, W.S.C. see Lin, S.C.
Yu, P.K.L., and Fan, C. see Fan, C.
Yuanxiang, Wu, Bingkun, Zhou, Hanyi, Zhang, Jianying, Zhou, Jian, Li, and Zhenwu, Pan see Bingkun, Zhou
Yuda, M., Kuroda, K., Nakano, J., and Ueki, M. see Kuroda, K.
Yurek, A.M., Bucholtz, F., Koo, K.P., and Dandridge, A. see Bucholtz, F.
Yurek, A.M., Dandridge, A., Tveten, A.B., and Kersey, A.D. see Dandridge, A.
Yurek, A.M., Kersey, A.D., Dandridge, A., and Weller, J.F. see Kersey, A.D.

Z

Zah, C.E., Osinski, J.S., Bhat, R., Contolini, R.J., Beebe, E.D., Lee, T.P., Cummings, K.D., and Harriott, L.R. see Osinski, J.S.
Zah, C.E., Osinski, J.S., Caneau, C., Menocal, S.G., Reith, L.A., Salzman, J., Shokoohi, F.K., and Lee, T.P. Fabrication and performance of $1{\cdot}5\,\mu m$ GaInAsP travelling-wave laser amplifiers with angled facets p990
Zah, C.E., Osinski, J.S., Menocal, S.G., Tabatabaie, Wide-bandwidth and high-power $1{\cdot}3\,\mu m$ InGaAsP buried crescent lasers with semi-insulating Fe-doped InP current blocking layers p52
Zah, C.E., and Kikuchi, K. see Kikuchi, K.
Zarkadis, D.J., and Evans, B.G. 16 kbit/s adaptive predictive coding of speech with adaptive postfiltering p358
Zeger, K.A., and Gersho, A. Zero redundancy channel coding in vector quantisation p654
Zembutsu, S., Tomaru, S., Kubodera, K., Takeda, K., and Hasegawa, M. see Tomaru, S.
Zengerle, R., and Leminger, O. see Leminger, O.
Zhai, H.-C., Jäger, D., and Forsmann, F. see Jäger, D.
Zhang, S.Y., Yang, K.H., and Chen, L. see Yang, K.H.
Zhang, Wen-Xun, and Zhu, Lei New leaky-wave antenna for millimetre waves constructed from groove NRD waveguide p1191
Zhang, X., Fang, J., and Mei, K.K. see Fang, J.
Zhang, Y.W., and Planat, M. Bulk waves radiated from an interdigital metallic transducer deposited on an anisotropic substrate p68
Zheng, Bao, and Shi-wei, Gao see Shi-wei, Gao
Zheng, X.H., and Snyder, A.W. Fused couplers: condition for insensitivity to external refractive index p182
Zheng, X.H., and Snyder, A.W. Pattern of radiation from dielectric tapers p1184
Zhenwu, Pan, Bingkun, Zhou, Hanyi, Zhang, Yuanxiang, Wu, Jianying, Zhou, and Jian, Li see Bingkun, Zhou
Zhihao, Chen, and Huihai, Yao Birefringence in stress-applied polarisation-maintaining optical fibres p1081
Zhou, H., Brown, R.C., and Clarricoats, P.J.B. see Brown, R.C.
Zhu, Lei, and Zhang, Wen-Xun see Zhang, Wen-Xun
Zhu, S., and Jones, E.V. see Jones, E.V.
Zhu, X., and Iga, K. Index profiling of distributed-index lenses by a total reflection method p626
Zich, R., Orta, R., and Tascone, R. see Orta, R.
Zielonko, R., and Bartosiński, B. see Bartosiński, B.
Zima, S.M., Wang, K.-W., and Cheng, C.L. see Wang, K.-W.
Zinkiewicz, L.M., Morrison, C.B., and Botez, D. see Morrison, C.B.
Župac, D., Dimitrijev, S., and Stojadinović, N. see Dimitrijev, S.

Subject index

ACOUSTIC MICROSCOPY

Differential phase contrast acoustic microscopy using tilted transducers. M. Nikoonahad p489

ACOUSTIC WAVES

Lamb wave graphic tablet. E. Dieulesaint, D. Royer, A. Chaabi and B. Formery p982
Perturbation analysis of fibre acoustic modes. A. Safaai-Jazi, C.K. Jen and G.W. Farnell p350

ACOUSTICS

Perturbation analysis of fibre acoustic modes. A. Safaai-Jazi, C.K. Jen and G.W. Farnell p350

ACOUSTO-OPTICS

Bulk-acoustic-wave transducer consisting of intergidital electrodes on a grooved surface of $LiNbO_3$. K. Nakamura and H. Shimizu p74
Differential phase contrast acoustic microscopy using tilted transducers. M. Nikoonahad p489
Guided-wave acousto-optic interaction on proton-exchanged lithium tantalate. J.F. Duffy, S.M. Al-Shukri and R.M. De La Rue p849
High-frequency acousto-optic deflector using ZnO thin films deposited on an amorphous substrate. J. Chang, N. Harada and S. Kashiwa p1384

ACTIVE FILTERS

Independent tuning of quality factor and unity-gain frequency in a transconductance-capacitance integrator. Z. Czarnul and Y. Tsividis d913
Minimal transistor-only micropower integrated VHF active filter. Y.P. Tsividis p777

ACTIVE NETWORKS

Generation of new two-amplifier synthetic floating inductors. R. Senani p1202
New lossless tunable floating FDNR simulation using two current conveyors and an INIC. M. Higashimura and Y. Fukui p529
Novel method for realising lossless floating immittance using current conveyors. M. Higashimura and Y. Fukui p498

ADAPTIVE FILTERS

16 kbit/s adaptive predictive coding of speech with adaptive postfiltering. D.J. Zarkadis and B.G. Evans p358
Adaptive LSP filter. B.M.G. Cheetham p89
Cramer-Rao lower bound for cascaded adaptive notch filtering. J.F. Chicharo and T.S. Ng p707

ALGEBRA

Relaxing the detectability condition for the algebraic Riccati equation. F. Tan, W.G. Vogt and M.H. Mickle p1139

ALGORITHMS

3 μm VLSI processing element using the Cordic algorithm. G.J. Vaudin and G.R. Nudd p1164
Aryabhata algorithm for polynomials. S.C. Kak p838
Fast computation of $A * B$ modulo N. P.W. Baker p794
Performance of LMS algorithm as a function of input signal pole loci. G.J. Freij and B.M.G. Cheetham p474
Reduced-complexity digital filtering structures using primitive operations. D.R. Bull and D.H. Horrocks p769

AMORPHOUS SEMICONDUCTOR MATERIALS

High-rate deposition of amorphous hydrogenated silicon: effect of plasma excitation frequency. H. Curtins, N. Wyrsch and A.V. Shah p228
Hydrogen plasma etching of amorphous and microcrystalline silicon. R.C. van Oort, M.J. Geerts, J.C. van den Heuvel and J.W. Metselaar p967

AMPLIFIERS

Application of AlGaAs/GaAs HBTs for wideband direct-coupled amplifiers. Y. Yamauchi and T. Ishibashi p156
Design of a high-gain, single-stage operational amplifier for GaAs switched-capacitor filters. C. Toumazou and D.G. Haigh p752
Fast CMOS current amplifier and buffer stage. G.C. Temes and W.H. Ki p696
Gain enhancement technique for differential pairs. K.W. Martin p154
Level-shifting differential to single-ended convertor circuits for GaAs MESFET implementation. C. Toumazou and D.G. Haigh p1053
Optimised class-E amplifier with load variation. D. Collins, S. Hinchliffe and L. Hobson p973
Picosecond pulse response of a travelling-wave semiconductor laser amplifier. I.W. Marshall, D.M. Spirit and M.J. O'Mahony p818
Wideband monolithic GaAs amplifier using cascodes. W.T. Colleran and A.A. Abidi p951
Wideband variable peaking AGC amplifier for high-speed lightwave digital transmission. T. Kinoshita, K. Yamashita, M. Maeda and Y. Sekine p23

ANALOGUE/DIGITAL CONVERSION

8-bit micropower algorithmic A/D convertor. V. Valencic, P. Deval and F. Krummenacher p932

ANNEALING

High-temperature metallisation systems for transient annealing of GaAs. D.V. Morgan, H. Thomas, W.T. Anderson, P. Thompson, A. Christou and D.J. Diskett p1154

ANTENNA ARRAYS

Directivity of linear microstrip arrays. J.P. Daniel p897
Excitations providing maximum directivity for difference arrays of discrete elements. D.A. McNamara p780
Feed radiation effects in sequentially rotated microstrip patch arrays. P.S. Hall p877
Maximisation of normalised boresight slope of a difference array of discrete elements. D.A. McNamara p1158
Microstrip log-periodic antenna array with endfire beam. P.S. Hall and A. Sparrow p912
Minimisation of mutual coupling effect on null steering by using guard elements. K.W. Lo and T.B. Vu p854
Mutual coupling in a finite planar array of rectangular apertures. D. Kitchener, K. Raghavan and C.G. Parini p1169
Mutual coupling in finite coplanar rectangular waveguide arrays. T.S. Bird p1199
Quadratic forms for performance indices of symmetrical and antisymmetrical linear arrays. D.A. McNamara p148
Radiation characteristics of microstrip arrays with parasitic elements. R.Q. Lee, R. Acosta and K.F. Lee p835
Simple adaptive algorithm for rejection of interference. Y.-H. Choi and J.-W. Ra p1038

ANTENNA FEEDERS

Novel feedline for linearly tapered slotline antenna (LTSA). N. Popović p1285

ANTENNA PHASED ARRAYS

Minimisation of mutual coupling effect on DOA estimation by using guard elements. K.W. Lo and T.B. Vu p611

ANTENNA RADIATION PATTERNS

Accurate prediction of radiation patterns of dielectric resonator antennas. A.A. Kishk, H.A. Auda and B.C. Ahn p1374
Feed radiation effects in sequentially rotated microstrip patch arrays. P.S. Hall p877

ANTENNA THEORY

Accuracy of standard patch antenna models. T.M. Willis and D.L. Sengupta p1376

ANTENNAS

10 GHz space power combiner with parasitic injection locking. R.J. Dinger, D.J. White and D.R. Bowling p397
Accuracy of standard patch antenna models. T.M. Willis and D.L. Sengupta p1376
Accurate prediction of radiation patterns of dielectric resonator antennas. A.A. Kishk, H.A. Auda and B.C. Ahn p1374
Analysis of microstripline coupled to microstrip antenna. X.Z. Gao and K. Chang p694
Aspheric double mirror systems. S. Cornbleet p199
Characteristics of a two-layer electromagnetically coupled rectangular patch antenna. R.Q. Lee, K.F. Lee and J. Bobinchak p1070
Compact broadband microstrip antenna. C.K. Aanandan and K.G. Nair e306
Directivity of linear microstrip arrays. J.P. Daniel p897
Dual aperture-coupled microstrip antenna for dual or circular polarisation. A. Adrian and D.H. Schaubert p1226
Effect of curvature on characteristics of rectangular patch antenna. J.S. Dahele, R.J. Mitchell, K.M. Luk and K.F. Lee p748
Effect of support strut diffraction on reflector surface profile assessment. P. Kerbyson, A.P. Anderson and J.C. Bennett p146
Equivalent circuit for aperture antennas. A.W. Love p708
Excitations providing maximum directivity for difference arrays of discrete elements. D.A. McNamara p780
Feed radiation effects in sequentially rotated microstrip patch arrays. P.S. Hall p877
Front-to-back ratio of a smooth metallic-wall conical horn. C.M. Knop p388 e710
Generation of a wide circularly polarised wave from a conical-helix antenna. H. Nakano, M. Sato and J. Yamauchi p387
Helicoidal director for circularly polarised waves. J. Yamauchi, G. Imada and H. Nakano p851
Improved HF broadband wire antenna. A.P.C. Fourie and B.A. Austin p276
Increasing the bandwidth of a microstrip antenna by proximity coupling. D.M. Pozar and B. Kaufman p368
Influence of raypath parameters on digital radio outage. Y. Serizawa and S. Takeshita p1353
Interpretation of compact range measurements. R.C. Brown p263
Maximisation of normalised boresight slope of a difference array of discrete elements. D.A. McNamara p1158
Microstrip log-periodic antenna array with endfire beam. P.S. Hall and A. Sparrow p912
Minimisation of mutual coupling effect on DOA estimation by using guard elements. K.W. Lo and T.B. Vu p611
Minimisation of mutual coupling effect on null steering by using guard elements. K.W. Lo and T.B. Vu p854
Mutual coupling between circular disc microstrip antennas. K. Mahdjoubi, E. Penard, J.P. Daniel and C. Terret p27
Mutual coupling in a finite planar array of rectangular apertures. D. Kitchener, K. Raghavan and C.G. Parini p1169
Mutual coupling in finite coplanar rectangular waveguide arrays. T.S. Bird p1199
New approach to analysing conductor-dielectric periodic structures. Tian-Lin Dong p1231
New leaky-wave antenna for millimetre waves constructed from groove NRD waveguide. Wen-Xun Zhang and Lei Zhu p1191
New simple feed network for an array module of four microstrip elements. M.L. Oberhart, Y.T. Lo and R.Q.H. Lee p436
Novel feedline for linearly tapered slotline antenna (LTSA). N. Popović p1285
Offset dual-reflector multiple-beam antennas using circularly symmetric main reflectors. S.G. Hay p888
Optical feed for a phased array microwave antenna. M. Tamburrini, M. Parent, L. Goldberg and D. Stillwell p680
Polarisation discrimination in shaped beam applications. R.C. Brown, P.J.B. Clarricoats and H. Zhou p238
Probe compensation in thick microstrip patches. P.S. Hall p606
Radiation characteristics of microstrip arrays with parasitic elements. R.Q. Lee, R. Acosta and K.F. Lee p835
Radiation pattern of a stripline excited rectangular aperture. Shi Wen-hong and Chen Jin-guang p187
Ray analysis of mutual coupling between antennas on a general paraboloid of revolution (GPOR). R.M. Jha, V. Sudhakar and N. Balakrishnan p583

Resonant frequency of electrically thick rectangular microstrip antennas. R. Garg and S.A. Long p1149
Signal level degradation due to snow accretion on a radome. M. Shimba, T. Sato, H. Koike and K. Sato p739
Simple adaptive algorithm for rejection of interference. Y.-H. Choi and J.-W. Ra p1038
Subreflector shaping to improve multiple-beam performance of a Cassegrain antenna. S.G. Hay p789
Technique for fast and accurate prediction of antenna far-field patterns. K.S. Farhat p609
Uncertainty in deriving phase information from far-field modulus only. S. Sali and A.P. Anderson p426

ARTIFICIAL INTELLIGENCE

Garbage collection coprocessor system. K.-F. Wong p798
Switched-capacitor neutral networks. Y.P. Tsividis and D. Anastassiou p958

ATTENUATION

Signal level degradation due to snow accretion on a radome. M. Shimba, T. Sato, H. Koike and K. Sato p739
Spectral attenuation measurement for fluoride glass single-mode fibres by Fourier transform techniques. Y. Ohishi and S. Sakaguchi p272

AVALANCHE DIODES

InGaAs/InP SAGM avalanche photodiodes incorporating a pseudoquaternary superlattice graded heterojunction grown by atmospheric-pressure MOCVD. A.J. Moseley, J. Urquhart, P.D. Hodson, J.R. Riffat and J.I. Davies p914

BINARY SEQUENCES

Improper decimation of *m*-sequences. Shi Wen-hong and Chen Jin-guang p210

BIOMEDICAL ELECTRONICS

Approach to modelling of microstrip-microslot applicator. R. Ledee, P. Pribetich, P. Kennis and M. Chive p829
Asynchronous arithmetic for VLSI neural systems. A.F. Murray and A.V.W. Smith p642
Microwave tomography: an algorithm for cylindrical geometries. J.M. Rius, M. Ferrando, L. Jofre, E. de los Reyes, A. Elias and A. Broquetas p564
Semiparallel microelectronic implementation of neural network models using CCD technology. A. Agranat and A. Yariv p580

BIPOLAR DEVICES

20 GHz frequency-divider silicon bipolar MMIC. I. Kipnis p1085
AlGaAs/GaAs bipolar transistors with a modulation-doped superlattice emitter. J.F. Palmier, A. Sibille, J.C. Harmand and J. Dangla p936
Application of AlGaAs/GaAs HBTs for wideband direct-coupled amplifiers. Y. Yamauchi and T. Ishibashi p156
Double-heterojunction bipolar transistors in InP/GaInAs grown by metal organic chemical vapour deposition. P.A. Houston, C. Blaauw, A. Margittai, M.N. Svilans, N. Puetz, D.J. Day, F.R. Shepherd and A.J. Springthorpe p931
GaAs lateral bipolar transistor with field-separated carriers. D. Ueda, H. Takagi, G. Kano and I. Teramoto p899
Improved AlGaAs/GaAs HBT performance by InGaAs emitter cap layer. K. Nagata, O. Nakajima, T. Nittono, H. Ito and T. Ishibashi p566
InP/GaInAs heterojunction bipolar transistors with improved electrical characteristics grown on strained buffer layers. N. Emeis and H. Beneking p295
MBE-grown AlGaAs/GaAs HBTs on InP substrate. H. Ito and T. Ishibashi p394
MOCVD-grown AlGaAs/GaAs HBTs with epitaxially embedded p^+ layers in extrinsic base. K. Taira, H. Kawai and K. Kaneko p989
Novel process for emitter-base-collector self-aligned heterojunction bipolar transistor using a pattern-inversion method. S. Tanaka, M. Madihian, H. Toyoshima, N. Hayama and K. Honjo p562
OMCVD-grown InP/GaInAs heterojunction bipolar transistors. J.R. Hayes, R. Bhat, H. Schumacher and M. Koza p1298
Optical sampling of GHz charge density modulation in silicon bipolar junction transistors. A. Black, C. Courville, G. Schultheis and H. Heinrich p783
Self-aligned AlGaAs/GaAs HBT with InGaAs emitter cap layer. K. Nagata, O. Nakajima, T. Nittono, H. Ito and T. Ishibashi p64
Static 7 GHz Frequency divider IC based on a 2 μm Si bipolar technology. P. Weger, L. Treitinger, R. Reimann and H.-M. Rein p192

BIREFRINGENCE

Birefringence and polarisation dispersion measurements in high-birefringence single-mode fibres. M. Monerie and F. Alard p198
Birefringence in stress-applied polarisation-maintaining optical fibres. Chen Zhihao and Yao Huihai p1081
Macrobends of bow-tie fibres with constant curvature. Chen Yijiang and Huang Hung-chia p159
Microbending losses of bow-tie and similar anisotropic fibres. Chen Yijiang and Huang Hung-chia p157
Polarisation state stabilisation in optically nonlinear birefringent fibres. A. Vatarescu p379
Single-polarisation single-mode guidance in stress-induced birefringence fibres with lossy stress-applying sections. K.S. Chiang p506

BOOLEAN FUNCTIONS

Correlation-immunity of Boolean functions. Yang Yi Xian p1335

BROADCASTING

Embedding data in DSB-AM using zero-synchronous modulation. G.B. Lockhart, T. Bayes, A.A.A. Mehdi and Y.O. Al-Jalili p745

CABLES

Dynamic polarisation fluctuation characteristics of optical fibre submarine cable coupling under periodic variable tension. Y. Namihira, Y. Horiuchi and H. Wakabayashi p1201
Higher-density single-mode optical fibre cables than 1 fibre/mm^2, containing hundreds of fibres. Y. Katsuyama, S. Hatano, K. Hogari and T. Kokubun p481
Polarisation fluctuation in optical-fibre submarine cable under 8000 m deep sea environmental conditions. Y. Namihira, S. Ryu, K. Mochizuki, K. Furusawa and Y. Iwamoto p100 e306
Polarisation fluctuations in a 147 km undersea lightwave cable during installation. C.D. Poole, N.S. Bergano, H.J. Schulte, R.E. Wagner, V.P. Nathu, J.M. Amon and R.L. Rosenberg p1113
Reduction of high surge voltage on coiled optical fibre submarine cable. H. Sakaguchi and Y. Niiro p1124

CARRIER LIFETIME

Increased carrier lifetimes in epitaxial silicon layers on buried silicon nitride produced by ion implantation. W. Skorupa, U. Kreissig, E. Hensel and H. Bartsch d579

CELLULAR ARRAYS

Base station multicoupler design for UK cellular radio systems. S. Kazeminejad, D.P. Howson and G. Hamer p812

CERAMICS

Temperature distribution on ceramic substrates. E. Boone, G. De Mey and L. Rottiers p26

CHARGE-COUPLED DEVICES AND CIRCUITS

Semiparallel microelectronic implementation of neural network models using CCD technology. A. Agranat and A. Yariv p580
Simple JCCD logic at 20 MHz. J. Hoekstra p246

CIRCUIT RELIABILITY

Testing of complex gates. R. Rajsuman, A.P. Jayasumana and Y.K. Malaiya p813

CIRCUIT THEORY AND DESIGN

8-bit micropower algorithmic A/D convertor. V. Valencic, P. Deval and F. Krummenacher p932
Analogue circuits for variable-synapse electronic neural networks. Y. Tsividis and S. Satyanarayana p1313
Compact formulation for exact analysis of nonideal SC circuits. M. Sanz and A. Puerta p554
Computer simulation of SC circuits using NAP. S. Osowski p547 e763
Current-mirror phase-shifter oscillator. S. Pookaiyaudom and K. Samootrut p21
Design of a high-gain, single-stage operational amplifier for GaAs switched-capacitor filters. C. Toumazou and D.G. Haigh p752
Fast CMOS current amplifier and buffer stage. G.C. Temes and W.H. Ki p696
Four-transistor continuous-time MOS transconductor. M. Ismail p1099
Gain enhancement technique for differential pairs. K.W. Martin p154
Generation of new two-amplifier synthetic floating inductors. R. Senani p1202
Independent tuning of quality factor and unity-gain frequency in a transconductance-capacitance integrator. Z. Czarnul and Y. Tsividis d913
Level-shifting differential to single-ended convertor circuits for GaAs MESFET implementation. C. Toumazou and D.G. Haigh p1053
New classes of complementary signals. B. Bartosiński and R. Zielonko p433 e867
New four-quadrant CMOS analogue multiplier. C.W. Kim and S.B. Park p1268
New lossless tunable floating FDNR simulation using two current conveyors and an INIC. M. Higashimura and Y. Fukui p529
Novel circuit design and implementation of adaptive phase comparators. J.C. Haartsen and R.C. Den Dulk p551
Novel fully differential MOS transconductor for integrated continuous-time filters. P.J. Ryan and D.G. Haigh p742
Novel method for realising lossless floating immittance using current conveyors. M. Higashimura and Y. Fukui p498
Numerical technique for determining steady-state response of nonlinear circuits to multitone input signals. C. Camacho-Peñalosa p828
Optimised class-E amplifier with load variation. D. Collins, S. Hinchliffe and L. Hobson p973
Performance characteristics of parallel resonant convertor. C.Q. Lee and I. Batarseh p1273
Precise realisation of an insensitive floating negative admittance convertor. R. Nandi p775
Quasisinusoidal oscillators with cubic-type nonlinearity. C. Di Bello p20
Spike-free switched-capacitor circuits. H. Matsumoto and K. Watanabe p428

CODES AND CODING

Capacities of sequences of currently used ternary line codes. J.F. Hope, H.C. Ferreira and A.L. Nel p681
Comparison between the Jacoby–Kost and Horiguchi–Morita binary two-thirds rate modulation codes. H.C. Ferreira, W. de V. Stegmann and C.R. Wyman p837
Comparison of two statistical tests for keystream sequences. M. Kimberley p365
Convolutional coding for BPSK system with orthogonal sounding tone on fast Rayleigh fading channel. Yuh-Long Chen and Che-Ho Wei e306
Data sequence coding for low jitter timing recovery. E.V. Jones and S. Zhu p337
Efficiency of block error-correcting codes. S.G. Glisic p557
Efficient digital receiver structure for trellis-coded signals transmitted through channels with intersymbol interference. K. Wesołowski p1265
Error-correcting code for optical-fibre transmission systems. N. Yoshikai p97 d647
Generalised subcomplementary sets of sequences. B.M. Popović and S.Z. Budiš in p422
Generating *d*-sequences. S.C. Kak p202
Highly reliable multilevel channel coding system using binary convolutional codes. K. Yamaguchi and H. Imai p939
Identity-based conference key distribution system. K. Koyama p495
Improved postfiltering technique for block quantisation of speech. H.A. Kaouri and J.V. McCanny p1288
Modification of a public-key cryptosystem. T. Okamoto p814
New result on *d*-sequences. S.C. Kak p617
Public-key cryptosystem based on the difficulty of solving a system of nonlinear equations. S. Tsujii, T. Itoh, A. Fujioka, K. Kurosawa and T. Matsumoto p558
Supercomplementary sets of sequences. S.Z. Budišin p504

Vector-quantised transform coder for speech coding at 9·6 kbit/s and below. A. Kondoz and B.G. Evans p1286
Zero redundancy channel coding in vector quantisation. K.A. Zeger and A. Gersho p654

COMBINATORIAL CIRCUITS

Reconvergent fanout analysis and fault simulation complexity of combinational circuits. F. Maamari and J. Rajski p1131

COMMUNICATION NETWORKS

Bandwidth allocation in buffer insertion rings. A. Pattavina and G. Pacifici p220
Crossconnection of wavelength-division-multiplexed high-speed channels. H. Kobrinski p974
General probability density function of packet service times for computer networks. M. Ilyas p31
Improved scheduling of traffic for a high-speed slotted ring. J.O. Limb and S. Kandiyoor p806

COMPUTER GRAPHICS

Content-addressable memories for storing and processing recursively subdivided images and trees. J.V. Oldfield, R.D. Williams and N.E. Wiseman p262
Interpolator engine for graphic applications. F. Pirri and O. Bigalli p331
Lamb wave graphic tablet. E. Dieulesaint, D. Royer, A. Chaabi and B. Formery p982

COMPUTER-AIDED CIRCUIT ANALYSIS

Computer-aided noise analysis of linear multiport networks. G.I. Vasilescu p351

COMPUTERS

Array two's-complement multiplier and square function. M. Putrino, S. Vassiliadis and E. Schwarz p1185
Direct two's-complement algorithm for $XY \pm Z$. S. Vassiliadis, M. Putrino and E. Schwarz p538 e763
Fast computation of $A \bullet B$ modulo N. P.W. Baker p794
Fault-tolerant schemes for parallel architectures. M.J. Livesey and J. Owczarczyk p1206
Modular memory model using state-variable approach. G.M. Chaudhry and J.S. Bedi p617
New channel routing algorithm for bit-slice applications. S. Nagara, S.G. Smith, P.B. Denyer and M. Leightley p1389
Parallel merger. G.S. Liu p1069
Partitioning for pseudo-exhaustive testing is NP-complete. W. Song, K.C. Smith and W.M. Snelgrove p1060
Systolic array for all-nearest-neighbours problem. N. Petkov p1259

CONTROL THEORY

Analysis of singular systems using Taylor series approach. Hung-Yuan Chung and York-Yih Sun e306
Biased model reduction by simplified Routh approximation method. G.V.K.R. Sastry and V. Krishnamurthy p1045
Extended power method and stability of linear discrete-time systems. S. Puthenpura and N.K. Sinha p4
Family of reduced-order models for linear multivariable systems. A.M. Eydgahi and H. Singh p1178
Guide to choosing the sampling rate in computerised controllers. C. Vibet p1002
Instabilities in numerical inversion of Laplace transforms using Taylor series approach. R. Unnikrishnan and A.V. Mathew p482
Iterative method for obtaining the argument of the dominant complex pole-pair. S. Puthenpura and N.K. Sinha p674
Linear third-order discrete system stability under parameter variations. K.S. Yeung and S.S. Wang p266
Modular memory model using state-variable approach. G.M. Chaudhry and J.S. Bedi p617
Nonlinear feedback control of a class of nonlinear systems. A. Yethiraj and C.B. Smith p18
Novel current control method for PWM inverters. Kwang-Won Lee and Song-Bai Park p1125
Reduced-order models using optimal Laguerre approximations. P.D. Olivier p257
Relaxing the detectability condition for the algebraic Riccati equation. F. Tan, W.G. Vogt and M.H. Mickle p1139
State-space models using simplified Routh approximation method. G.V.K.R. Sastry and V. Krishnamurthy p1300
Taylor series approach to functional approximation for inversion of Laplace transforms. Hung-yuan Chung and York-yih Sun p480 e306
Transfer function matrix. H. Seraji p256

CONTROLLERS

Guide to choosing the sampling rate in computerised controllers. C. Vibet p1002

CONVERTORS

Class E switching-mode power amplifier for high-frequency electric process heating applications. K. Thomas, S. Hinchliffe and L. Hobson p80
Optimised pulse-width modulation method of forced commutated cycloconvertor. D.-H. Shin, G.-H. Cho and S.-B. Park p760
Performance characteristics of parallel resonant convertor. C.Q. Lee and I. Batarseh p1273

CONVOLUTION

Fibre-optic multichannel correlation/convolution. M. Shabeer, I. Andonovic and B. Culshaw p310
Modified bit-level systolic inner product/convolver architecture with increased throughput. R.A. Evans and R. Eames p460

CORRELATION AND CORRELATORS

Broadband correlators employing fibre-optic recirculating delay lines. P.V. Gatenby, D.L. Switzer and N. Green p1246
Combined space and adaptive correlation diversity in the CD900 system. W.H. Lam and R. Steele p496
Fibre-optic multichannel correlation/convolution. M. Shabeer, I. Andonovic and B. Culshaw p310

CROSSPOLARISATION

Polarisation discrimination in shaped beam applications. R.C. Brown, P.J.B. Clarricoats and H. Zhou p238

CROSSTALK

Amplifier-induced crosstalk in multichannel coherent lightwave systems. G.P. Agrawal p1175
Crosstalk penalty in a two-channel ASK heterodyne detection system with non-negligible laser linewidth. Y.K. Park, S.W. Granlund, C.Y. Kuo, M. Dixon, T.W. Cline, R.W. Smith, N.K. Dutta and G. Vannucci p1291
Evaluation of crosstalk penalty in multichannel ASK heterodyne optical communication systems. G.P. Agrawal p906
Observation of crosstalk due to four-wave mixing in a laser amplifier for FDM transmission. K. Inoue p1293

CRYSTALS

Second-harmonic generation in single crystals of 2-(N,N-dimethylamino)-5-nitroacetanilide (DAN) at 1·3 μm. P.V. Kolinsky, R.J. Chad, R.J. Jones, S.R. Hall, P.A. Norman, D. Bloor and J.S. Obhi p791

CURRENT CONVEYORS

New lossless tunable floating FDNR simulation using two current conveyors and an INIC. M. Higashimura and Y. Fukui p529
Novel method for realising lossless floating immittance using current conveyors. M. Higashimura and Y. Fukui p498
Precise realisation of an insensitive floating negative admittance convertor. R. Nandi p775

DATA COMPRESSION

Fast search techniques for use in vector quantisation and related pattern matching applications. H.A. Kaouri, J.V. McCanny and W. Millar p311

DATA PROCESSING

Serial-data computation on twin pipelines. M.S. McGregor, S.G. Smith, P.B. Denyer and A.F. Murray p292

DATA TRANSMISSION

Data clock jitter in supersampling multiplex transmission. R. Gangopadhyay and P. Cochrane p1203
Embedding data in DSB-AM using zero-synchronous modulation. G.B. Lockhart, T. Bayes, A.A.A. Mehdi and Y.O. Al-Jalili p745

DELAY LINES

Broadband correlators employing fibre-optic recirculating delay lines. P.V. Gatenby, D.L. Switzer and N. Green p1246

DETECTORS AND DETECTOR CIRCUITS

Robustness of a modified greatest-of CFAR detector. T. Bucciarelli and A. Nardone p128

DIELECTRIC LOSSES

Pattern of radiation from dielectric tapers. X.H. Zheng and A.W. Snyder p1184

DIELECTRIC WAVEGUIDES

Accuracy of method of moments and weighted index method. D.A. Roberts and M.S. Stern p784
Condensed formula for coupling coefficients between parallel dielectric waveguides. C. Vassallo p334
Finite-element theory of nonlinear TM-polarised guided waves. K. Hayata, M. Nagai and M. Koshiba p1305
Fundamental error of recent coupled mode formulations. A.W. Snyder, A. Ankiewicz and A. Altintas p1097
Huygens-type formula for curvature loss from dielectric waveguides in optoelectronics. P.C. Kendall, M.S. Stern and P.N. Robson p850
New leaky-wave antenna for millimetre waves constructed from groove NRD waveguide. Wen-Xun Zhang and Lei Zhu p1191
Resonant coupled stub in nonradiative dielectric waveguide. J.A.G. Malherbe and J.C. Olivier p749
Y-junctions in dielectric waveguides using very wide aperture angles. A. Prieto, J. Rodriguez and M.A. Solano p137

DIELECTRICS AND DIELECTRIC DEVICES

DC ionised field quantities as influenced by coronating conductor surface gradient. M. Aboelsaad and L. Shafai p162
Dielectric slab matched ferrite gyrator. J. Uher, F. Arndt and J. Bornemann p278
Dielectrically shielded microstrip (DSM) lines. K. Chang and J. Klein p535
Diffraction by a dielectric wedge with the Neumann expansion of correction currents on interfaces. Se-Yun Kim and Jung-Woong Ra p630
Electromagnetic scattering by inhomogeneous dielectric cylinders. C.G. Migliora and M.B.F. Chaves p795
Field patterns of TM_0 modes in a shielded dielectric resonator. D. Kajfez and J. Lebaric p944
New approach to analysing conductor-dielectric periodic structures. Tian-Lin Dong p1231
New leaky-wave antenna for millimetre waves constructed from groove NRD waveguide. Wen-Xun Zhang and Lei Zhu p1191
Physical model for the complex resistivity of the earth. J.R. Wait p979
Resonant coupled stub in nonradiative dielectric waveguide. J.A.G. Malherbe and J.C. Olivier p749
Theoretical radiation resistance of an isolated slot ring resonator. G. Dubost p928
Unified approach to determination of modes in cylindrical cavities axisymmetrically loaded with dielectrics. D. Mirshekar-Syahkal and M. Mohammad Taheri p1177

DIFFRACTION

Double diffraction by wedges in nonperfectly conducting surfaces. G. Manara, R. Tiberio, G. Pelosi, P.H. Pathak and R.G. Kouyoumjian p671

DIFFUSION

Fabrication of low-loss titanium-diffused $LiNbO_3$ waveguides using a closed platinum crucible. A. Neyer and T. Pohlmann p1187
Out-diffusion and reactivation of Zn in InP substrates. H. Jung and P. Marschall p1010
Reduction of bend losses in Ti : $LiNbO_3$ waveguides through MgO double diffusion. B. Schüppert p797
Self-aligned diffusion technique for *n*-InP JFETs. C. Fan and P.K.L. Yu p981

DIGITAL CIRCUITS

22 GHz 1/4 frequency divider using AlGaAs/GaAs HBTs. Y. Yamauchi, K. Nagata, O. Nakajima, H. Ito, T. Nittono and T. Ishibashi p881

DIGITAL COMMUNICATION SYSTEMS

Convolutional coding for BPSK system with orthogonal sounding tone on fast Rayleigh fading channel. Yuh-Long Chen and Che-Ho Wei e306
Improved Prony algorithm to identify multipath components. W.H. Lau, J. Austin and E. Vilar p1059

DIGITAL FILTERS

Cramer-Rao lower bound for cascaded adaptive notch filtering. J.F. Chicharo and T.S. Ng p707
Design of elliptically symmetric two-dimensional FIR filters with arbitrary orientation. M.S. Reddy and S.N. Hazra p964
Matrix approach for the coefficients of maximally flat FIR filter transfer functions expressed in powers of cos *w*. L.R. Rajagopal and S.C. Dutta Roy p391
New systolic array for realising second-order recursive digital filters. H.K. Kwan p442
Performance of LMS algorithm as a function of input signal pole loci. G.J. Freij and B.M.G. Cheetham p474
Reduced-complexity digital filtering structures using primitive operations. D.R. Bull and D.H. Horrocks p769
Sensitivity of driving-point function based wave digital filters. K.S. Prasad and C. Eswaran p46
Systolic arrays for recursive digital filtering. W. Luk and G. Jones p1174
Two-dimensional FIR digital filters designed to arbitrary group-delay specifications. E. Sharestani and L.G. Cuthbert p603

DIGITAL INTEGRATED CIRCUITS

Novel CMOS latch with clock hysteresis. D.W.R. Orton p1221

DIGITAL SYSTEMS

Extended power method and stability of linear discrete-time systems. S. Puthenpura and N.K. Sinha p4
Self: A self-timed systems design technique. C.H. Lau p269

DIGITAL TRANSMISSION

Comparison of regenerator tolerance to sinusoidal and Gaussian alignment jitter. I. Fletcher p67
GMSK frequency detection using decision feedback equalisation. K. Ohno and F. Adachi p1350
Narrowband digital voice communications over a meteor burst channel. J.R. Herman, C.C. Duggan, W.I. Thompson, R.A. Costa and D.M. DeLuca p59 e480
Self-correcting clock recovery circuit with improved jitter performance. D. Shin, M. Park and M. Lee p110
Wideband variable peaking AGC amplifier for high-speed lightwave digital transmission. T. Kinoshita, K. Yamashita, M. Maeda and Y. Sekine p23

DIODES

Room-temperature operation of $Ga_{0.47}In_{0.53}As/Al_{0.48}In_{0.52}As$ resonant tunnelling diodes. S. Sen, F. Capasso, A.L. Hutchinson and A.Y. Cho p1229

DIPOLE ANTENNAS

Complete and rigorous analysis of electromagnetically coupled transverse microstrip dipole. P. Lepeltier, J.M. Floc'h and J. Citerne p822

DIRECTIONAL COUPLERS

$LiNbO_3$ directional-coupler polarisation splitter. K. Habara p614
Six-port reflectometer. S.P. Yeo and A.L. Ang p1160

DISCRETE SYSTEMS

Linear third-order discrete system stability under parameter variations. K.S. Yeung and S.S. Wang p266

DISCRETE-TIME SYSTEMS

Iterative method for obtaining the argument of the dominant complex pole-pair. S. Puthenpura and N.K. Sinha p674

DISPERSION (WAVE)

Tolerance requirements for the drawing ratio of single-mode fibres with arbitrary refractive-index profile. G. Trommer p79

DISTORTION

2 Gbit/s optical CPFSK heterodyne transmission through 200 km single-mode fibre. K. Iwashita and N. Takachio p341
Nonlinear distortion produced by an injection-locked laser. V. O'Byrne and J.J. O'Reilly p955

DOPING

AlGaAs/GaAs bipolar transistors with a modulation-doped superlattice emitter. J.F. Palmier, A. Sibille, J.C. Harmand and J. Dangla p936
Effect of residual doping on optimum structure of multiquantum-well optical modulators. D.J. Newson and A. Kurobe p439
Neodymium-doped fluoro-zirconate fibre laser. M.C. Brierley and P.W. France p815
Wholly synthesised fluorine-doped silica optical fibres by sol-gel method. T. Kitagawa, S. Shibata and M. Horiguchi p1295

EIGEN VALUES

Extended power method and stability of linear discrete-time systems. S. Puthenpura and N.K. Sinha p4

ELECTRO-OPTICS

1 THz-bandwidth prober for high-speed devices and integrated circuits. J.A. Valdmanis p1308
Behaviour of a novel cylindrical glass fibre optical coupler buried in KDP. K.D. Leaver, M. Green and H. Daniel p820
Electro-optic effect in He^+-implanted optical waveguides in $LiNbO_3$. G.T. Reed and B.L. Weiss p424
Electro-optic effects and electroabsorption in a GaAs/AlGaAs multiquantum-well heterostructure near the bandgap. M. Glick, D. Pavuna and F.K. Reinhart p1235
Electro-optic sampling measurement of coplanar waveguide (coupled slot line) modes. R. Majidi-Ahy, K.J. Weingarten, M. Riaziat, B.A. Auld and D.M. Bloom p1262
GaInAsP buried channel EA modulator for 1·3 μm fibre links. S.C. Lin, X.L. Jing, M.K. Chin, L.M. Walpita, P.K.L. Yu and W.S.C. Chang p1257
Hybrid optical bistability based on increasing absorption in depletion layer of an Si Schottky SEED device. D. Jäger, F. Forsmann and H.-C. Zhai p490
Integration of GaAs MESFET drivers with GaAs directional-coupler electro-optic modulators. J.H. Abeles, W.K. Chan, F.K. Shokoohi, R. Bhat and M.A. Koza p1037
Narrow, high-NA GaAs/GaAlAs optical waveguides with losses below $0{\cdot}7 \pm 0{\cdot}1$ dB cm^{-1}. R.G. Walker, H.E. Shephard and R.R. Bradley p362
Optical sampling of GHz charge density modulation in silicon bipolar junction transistors. A. Black, C. Courville, G. Schultheis and H. Heinrich p783

ELECTROMAGNETIC FIELD THEORY

Boundary conditions of the electromagnetic field. M. İdemen and A.H. Serbest p704
Complete and rigorous analysis of electromagnetically coupled transverse microstrip dipole. P. Lepeltier, J.M. Floc'h and J. Citerne p822
DC ionised field quantities as influenced by coronating conductor surface gradient. M. Aboelsaad and L. Shafai p162
High-frequency scattering of a Hermite-Gaussian beam mode by a perfectly conducting cylinder. M. Yokota, T. Kudou and O. Fukumitsu p174
Missing boundary conditions of electromagnetics. K.A. Michalski p480
New approach to analysing conductor-dielectric periodic structures. Tian-Lin Dong p1231
Prediction of error due to distance in measurement or calculation of electromagnetic backscatter from a cylindrical body. J.A.G. Malherbe and C.W.I. Pistorius p1310

ELECTROMAGNETIC INTERFERENCE

Front-to-back ratio of a smooth metallic-wall conical horn. C.M. Knop p388 e710
Numerical simulation of cruiser or aircraft lightning. M. Monavon and M. Leroy p640
Prediction of electromagnetic radiation of a multilayer board. V. Ungvichian and R. Perez-Rodriquez p721

ELECTROMAGNETIC WAVES

Backscattering matrix of dielectric objects at 9·6 GHz. Y.M.M. Antar, L.E. Allan and A.R. Holt p996
Boundary conditions of the electromagnetic field. M. İdemen and A.H. Serbest p704
Double diffraction by wedges in nonperfectly conducting surfaces. G. Manara, R. Tiberio, G. Pelosi, P.H. Pathak and R.G. Kouyoumjian p671
Efficient choice of basis functions in moment method analysis of frequency-selective surfaces. R. Orta, R. Tascone and R. Zich p586
Electromagnetic scattering by inhomogeneous dielectric cylinders. C.G. Migliora and M.B.F. Chaves p795
Helicoidal director for circularly polarised waves. J. Yamauchi, G. Imada and H. Nakano p851
High-frequency scattering of a Hermite-Gaussian beam mode by a perfectly conducting cylinder. M. Yokota, T. Kudou and O. Fukumitsu p174
Low backscattered TM-polarised strip gratings. K.A. Jose, C.K. Aanandan and K.G. Nair p905
Missing boundary conditions of electromagnetics. K.A. Michalski p480
New approach to analysing conductor-dielectric periodic structures. Tian-Lin Dong p1231
Numerical simulation of cruiser or aircraft lightning. M. Monavon and M. Leroy p640
Prediction of electromagnetic radiation of a multilayer board. V. Ungvichian and R. Perez-Rodriquez p721
Reflector-backed perfectly blazed strip gratings simulate corrugated reflector effects. K.A. Jose and K.G. Nair p86
Scattering of arbitrarily polarised, arbitrarily directed incident plane waves by frequency-selective surfaces. M.J. Archer p660

ELECTRON DEVICES

Electron transport of (Al, Ga)Sb/InAs heterojunctions prepared by molecular beam epitaxy. T.H. Chiu, W.T. Tsang and A.F.J. Levi p917

EPITAXY AND EPITAXIAL GROWTH

Extremely high-quality GaInAs/AlInAs single quantum wells grown by molecular beam epitaxy. E.G. Scott, S.T. Davey and G.J. Davies p761
Growth and properties of an $LiNbO_3$ film on sapphire with an $LiNbO_3$ buffer layer. T. Nozawa p1321
MOVPE studies for the development of GaInAsP/InP lasers with semi-insulating InP blocking layers. P. Speier, K. Wünstel and F.J. Tegude p1363
Molecular-beam-epitaxial growth of GaAs on high-temperature hydrogen-annealed (100) silicon. T.P. Humphreys, K. Das, S.M. Bedair, J.J. Wortman, N. Parikh, W.K. Chu, N. El-Masry and J.C.L. Tarn p1079
Very low-threshold 1·53 μm DFB lasers by VPE transport. B. Broberg, S. Nilsson and T. Tanbun-Ek p624

EQUALISERS

Efficient digital receiver structure for trellis-coded signals transmitted through channels with intersymbol interference. K. Wesolowski p1265

EQUIVALENT CIRCUITS

Equivalent circuit for aperture antennas. A.W. Love p708
New accurate and simple equivalent circuit for circular *E*-plane bends in rectangular waveguide. P.L. Carle p531

ERROR-CORRECTION CODES

Efficiency of block error-correcting codes. S.G. Glisic p557

FERRITE DEVICES

Dielectric slab matched ferrite gyrator. J. Uher, F. Arndt and J. Bornemann p278
Ferrite tunable metal insert filter. J. Uher, J. Bornemann and F. Arndt p804

FIBRE OPTICS

Bandwidth of directional-coupler wavelength filters made of dissimilar optical fibres. O. Leminger and R. Zengerle p241
Fibre-optic multichannel correlation/convolution. M. Shabeer, I. Andonovic and B. Culshaw p310
Novel type of fibre-optic ring resonator. E. Meissner p683
Self-routing fibre-optic networks and switches using multitailed receiver/transmitter units. P.J. Severin p651
Single-mode-fibre passive components made in the fused-head-end technique. P.J. Severin p449
Tunable single-mode output of a multimode laser in a tunable fibre grating external cavity. W.V. Sorin and S.A. Newton p390

FIELD-EFFECT TRANSISTORS

8·8 Gbit/s travelling-pulse word generator. N. Mulombe, J. Kahlert, W. Piscalar and G. Seehausen p703
Anomalous oscillation in depletion-mode MOSFETs at low temperature. C. Carruthers and J. Mavor p178
Avalanche noise associated with gate current of Si JFET. J.M. Peransin, D. Rigaud and R. Alabedra p970
Characterisation of *N*-channel germanium MOSFET with gate insulator formed by high-pressure thermal oxidation. E.E. Crisman, J.I. Lee, P.J. Stiles and O.J. Gregory p8
Complementary silicon MESFET technology. K.E. Bohlin, P.A. Tove, U. Magnusson and J. Tiren p205
DC and microwave characteristics of an $In_{0.53}Ga_{0.47}As/In_{0.52}Al_{0.48}As$ modulation-doped quasi-MISFET. K.S. Seo, P.K. Bhattacharya and K.R. Gleason p259
Electromigration effects in power MESFET rectifying and ohmic contacts. C. Canali, F. Chiussi, F. Fantini, L. Umena and M. Vanzi p364
Fabrication of a new type of field-effect transistor using neutralisation of shallow donors by atomic hydrogen in *n*-GaAs (Si). E. Constant, N. Caglio, J. Chevallier and J.C. Pesant p841
Fabrication of polysilicon gate FET in laser melted silicon on silicon dioxide on PLZT. M.L. Burgener and T.H. Lin p353
GaInAs junction FET fully dry etched by metal organic reactive ion etching technique. D. Lecrosnier, L. Henry, A. Le Corre and C. Vaudry p1254
Gate current in 0·75 μm *N*-channel MOSFETs with doubly diffused drain. R.K. Watts, L. Manchanda and R.L. Johnston p468
Gold-based gate-sinking enhanced by inhomogeneities in power MESFETs. C. Canali, G. Donzelli, F. Fantini, M. Vanzi and A. Paccagnella p83
Growth temperature dependence of low-noise MESFET in molecular-beam epitaxy. Y.C. Chou, C.T. Lee, C.D. Chen and K.C. Chu p7
Heterostructure complementary technology. J.G. Simmons and G.W. Taylor p380
High-performance GaAs power MESFET with AlGaAs buffer layer. B. Kim, M. Wurtele, H.D. Shih and H.Q. Tserng p1008
High-performance WN-gate MISFETs fabricated from MOVPE wafers. M. Wolny, T. Aguila, P. Deconinck, D. Moroni and J.P. Andre p1127
High-transconductance AlInAs/GaInAs HIFETs grown by MOCVD. M. Kamada, T. Kobayashi, H. Ishikawa, Y. Mori, K. Kaneko and C. Kojima p297
Improved negative feedback technique to reduce drain conductance of GaAs MESFETs for precision analogue ICs. W.S. Lee and J. Mun p705
Ion-implanted *P*-channel GaAs MESFET using Schottky barrier height tailoring. S.M. Baier, G.Y. Lee, H.K. Chung, B.J. Fure and N.C. Cirillo p223
Langmuir-Blodgett deposited cadmium gate inverted InP-GaInAs modulation-doped field-effect transistors. W.K. Chan, H.M. Cox, J.H. Abeles and S.P. Kelty p1346
MOSFET model continuous from weak to strong inversion. M.M. Abu-Zeid and G.G. de Jong p1299
Microwave characterisation of 1 μm-gate $Al_{0.48}In_{0.52}As/Ga_{0.47}In_{0.53}As/InP$ MODFETs. L.F. Palmateer, P.J. Tasker, T. Itoh, A.S. Brown, G.W. Wicks and L.F. Eastman p53
Narrow pulse measurement of drain characteristics of GaAs MESFETs. T.M. Barton, C.M. Snowden, J.R. Richardson and P.H. Ladbrooke p686
Refractory self-aligned gate technology for GaAs microwave FETs and MMICs. A.E. Geissberger, R.A. Sadler, E.L. Griffin, I.J. Bahl and M.L. Balzan p1073
Resonant tunnelling gate field-effect transistor. F. Capasso, S. Sen, F. Beltram and A.Y. Cho p225
Role of source N^+N^- structure in parasitic bipolar action of lightly doped short-channel MOSFETs. N.D. Janković p461
SOI MOSFET in weak inversion and weak accumulation. F. Balestra and J. Brini p211
Self-aligned GaAs gate heterojunction SISFET. M. Chen, W.J. Schaff, P.J. Tasker and L.F. Eastman p105
Self-aligned Si MESFETs fabricated in thin silicon-on-insulator films. D.P. Vu and A. Sono p354
Self-aligned diffusion technique for *n*-InP JFETs. C. Fan and P.K.L. Yu p981
Static random-access memory based on self-aligned-gate (Al, Ga)As/n^+-GaAs superlattice modulation-doped FETs. D.K. Arch, J.K. Abrokwah, P.J. Vold, A.M. Fraasch, B.L. Grung and N.C. Cirillo p87
Transconductance dependence on gate length for GaAs gate SISFETs. M. Chen, W.J. Schaff, P.J. Tasker and L.F. Eastman p800
Uniformity of threshold voltage for MESFETs fabricated on VGF GaAs substrates. C.L. Reynolds, W.C. Gibson and J.E. Clemans p1222
Very high-transconductance heterojunction field-effect transistor (HFET). G.W. Taylor, M.S. Lebby, T.Y. Chang, R.N. Gnall, N. Sauer, B. Tell and J.G. Simmons p77
Very high-transconductance short-channel GaAs MESFETs with $Ga_{0.3}Al_{0.7}As$ buffer layer. K.Y. Lee, M. Al-Mudares, S.P. Beaumont, C.D.W. Wilkinson, J. Frost and C.R. Stanley p11

FILTERING AND PREDICTION THEORY

Adaptive image restoration using local statistics and directional gradient information. N.C. Kim and S.H. Jung p610

FILTERS

2 Gbit/s timing recovery circuit using dielectric resonator filter. D.J. Millicker and R.D. Standley p738
Adaptive LSP filter. B.M.G. Cheetham p89
Behaviour of actively compensated bandpass filters at higher signal levels. A.S.S. Al-Kabbani and P. Bowron p1108
Clocking schemes for switched-capacitor FIR decimators. A.K. Betts, J.T. Taylor and D.G. Haigh p1323
Cramer-Rao lower bound for cascaded adaptive notch filtering. J.F. Chicharo and T.S. Ng p707
Decision-directed nonlinear filter for image processing. G. Ramponi and G.L. Sicuranza p1218
Design of a high-gain, single-stage operational amplifier for GaAs switched-capacitor filters. C. Toumazou and D.G. Haigh p752
Design of elliptically symmetric two-dimensional FIR filters with arbitrary orientation. M.S. Reddy and S.N. Hazra p964
Efficient technique for scale-space imaging of planar objects. D.T. Nguyen and D.-Y. Xu p1326
Experimental determination of finline post discontinuity parameters: application to stopband and lowpass filters. P. Saquet and A. Essebar p691
Flat passband birefringent wavelength-division multiplexers. W.J. Carlsen and C.F. Buhrer p106
Generation of transconductance-grounded-capacitor filters by signal-flow-graph methods for VLSI implementation. M.A. Tan and R. Schaumann p1093
Iterative procedure for designing two-dimensional FIR filters. A.E. Cetin and R. Ansari p131
Matrix approach for the coefficients of maximally flat FIR filter transfer functions expressed in powers of cos *w*. L.R. Rajagopal and S.C. Dutta Roy p391
Minimal transistor-only micropower integrated VHF active filter. Y.P. Tsividis p777
Narrow-aperture SAW filter with both transducers finger-length-weighted. C.D. Blake p1248
New configuration of echo canceller adaptable during double talk. J. Chao and S. Tsujii p1314
New systolic array for realising second-order recursive digital filters. H.K. Kwan p442
Novel fully differential MOS transconductor for integrated continuous-time filters. P.J. Ryan and D.G. Haigh p742
Novel sorter architecture for image processing rank order filters. U. Kleine p45
Performance of LMS algorithm as a function of input signal pole loci. G.J. Freij and B.M.G. Cheetham p474
Reduced-complexity digital filtering structures using primitive operations. D.R. Bull and D.H. Horrocks p769
Sensitivity of driving-point function based wave digital filters. K.S. Prasad and C. Eswaran p46
State-space description and realisation of elliptic lowpass *LCR* ladder filters. D.G. Haigh and J.T. Taylor p1032
Stray-free first-order circuit for correction of sample-and-hold amplitude distortion in switched-capacitor filters. J.T. Taylor and D.G. Haigh p177
Switched-capacitor biquad with low influence of finite gains. J. Mulawka, A. Konczykowska and M. Bon p1198
Systolic arrays for recursive digital filtering. W. Luk and G. Jones p1174
Temperature compensation of OTA-based filters and amplifiers. H.S. Malvar and M. Luettgen p890
Two-dimensional FIR digital filters designed to arbitrary group-delay specifications. E. Sharestani and L.G. Cuthbert p603
Two-dimensional IIR filters for exact reconstruction in tree-structured sub-band decomposition. R. Ansari and C.-L. Lau p633

FOURIER TRANSFORMS

Opening the knapsack by DFTs. T. Maseng p95
Spectral attenuation measurement for fluoride glass single-mode fibres by Fourier transform techniques. Y. Ohishi and S. Sakaguchi p272

FREQUENCY CONVERTORS

Low-loss three-phase frequency conversion using a TDM-PWM technique. S.A.I. Sid Ahmed and P.S. Excell p126

FREQUENCY DIVIDERS

20 GHz dynamic frequency divider with GaAs advanced SAINT and air-bridge technology. K. Osafune, T. Enoki, M. Muraguchi and K. Ohwada p300
22 GHz 1/4 frequency divider using AlGaAs/GaAs HBTs. Y. Yamauchi, K. Nagata, O. Nakajima, H. Ito, T. Nittono and T. Ishibashi p881
Static 7 GHz Frequency divider IC based on a 2 μm Si bipolar technology. P. Weger, L. Treitinger, R. Reimann and H.-M. Rein p192

FREQUENCY MODULATION

Frequency modulation and spectral characteristics for a 1·5 μm phase-tunable DFB laser. S. Murata, I. Mito and K. Kobayashi p12

FREQUENCY SHIFT KEYING

Nonlinear distortion produced by an injection-locked laser. V. O'Byrne and J.J. O'Reilly p955
Polarisation-diversity receiver for coherent FSK communications. T.E. Darcie, B. Glance, K. Gayliard, J.R. Talman, B.L. Kasper and C.A. Burrus p1369
Polarisation-insensitive operation of coherent FSK transmission system using polarisation diversity. S. Ryu, S. Yamamoto and K. Mochizuki p1382

GALLIUM ARSENIDE

High-pressure thermal oxidation of gallium arsenide at 250°C. K.N. Bhat and N. Basu p1329
High-temperature metallisation systems for transient annealing of GaAs. D.V. Morgan, H. Thomas, W.T. Anderson, P. Thompson, A. Christou and D.J. Diskett p1154
Level-shifting differential to single-ended convertor circuits for GaAs MESFET implementation. C. Toumazou and D.G. Haigh p1053

Molecular-beam-epitaxial growth of GaAs on high-temperature hydrogen-annealed (100) silicon. T.P. Humphreys, K. Das, S.M. Bedair, J.J. Wortman, N. Parikh, W.K. Chu, N. El-Masry and J.C.L. Tarn p1079
New tungsten silicide thin-film resistor technology applied to GaAs integrated circuits. D.A. Allan, M.J. Gilbert and P.J. O'Sullivan p1216
Quantum confined Stark shifts in MOVPE-grown GaAs–AlGaAs multiple quantum wells. M. Whitehead, G. Parry, J.S. Roberts, P. Mistry, P. Li Kam Wa and J.P.R. David p1048
Reactive ion etching of GaAs using a mixture of methane and hydrogen. R. Cheung, S. Thoms, S.P. Beamont, G. Doughty, V. Law and C.D.W. Wilkinson p857
Selective formation of ohmic contacts to *n*-GaAs. Y. Yamane, Y. Takahashi, H. Ishii and M. Hirayama p382

GLASS

Efficient frequency up-conversion via energy transfer in fluoride glasses. R.S. Quimby, M.G. Drexhage and M.J. Suscavage p32

GUNN DEVICES AND EFFECTS

Gunn diode oscillator constructed in nonradiative dielectric waveguide. J.A.G. Malherbe and M.C. Wijnbeek p1368
Novel 93 GHz injection-locked impatt oscillator. D.H. Evans and R.N. Bates p771
Novel varactor-tuned millimetre-wave Gunn oscillator. R.N. Bates and S. Feeney p714

GYRATORS

Dielectric slab matched ferrite gyrator. J. Uher, F. Arndt and J. Bornemann p278

HARMONIC GENERATION

Optical third-harmonic generation from poly(*p*-phenylenevinylene) thin films. T. Kaino, K.-I. Kubodera, S. Tomaru, T. Kurihara, S. Saito, T. Tsutsui and S. Tokito p1095
Optical third-harmonic generation from polydiacetylene thin films deposited by vacuum evaporation. S. Tomaru, K. Kubodera, S. Zembutsu, K. Takeda and M. Hasegawa p595
Second-harmonic generation in an optical fibre by self-written $\chi^{(2)}$ grating. M.C. Farries, P.St.J. Russell, M.E. Fermann and D.N. Payne p322
Second-harmonic generation in single crystals of 2-(N,N-dimethylamino)-5-nitroacetanilide (DAN) at 1·3 μm. P.V. Kolinsky, R.J. Chad, R.J. Jones, S.R. Hall, P.A. Norman, D. Bloor and J.S. Obhi p791
Second-harmonic generation in single-mode optical fibres. F.P. Payne p1215

HOLOGRAPHY

Phase-shifted diffraction-grating fabrication using holographic wavefront reconstruction. Y. Ono, S. Takano, I. Mito and N. Nishida p57

IMAGE PROCESSING

3 μm VLSI processing element using the Cordic algorithm. G.J. Vaudin and G.R. Nudd p1164
Adaptive image restoration using local statistics and directional gradient information. N.C. Kim and S.H. Jung p610
Application of the simplex technique in motion estimation. B.S. Lee and J.W.R. Griffiths p903
Content-addressable memories for storing and processing recursively subdivided images and trees. J.V. Oldfield, R.D. Williams and N.E. Wiseman p262
DC coefficient restoration by cosine and sine transforms. W.K. Cham p349
Decision-directed nonlinear filter for image processing. G. Ramponi and G.L. Sicuranza p1218
Design of PE structure of a parallel image processor. J. Owczarczyk p121
Efficient technique for scale-space imaging of planar objects. D.T. Nguyen and D.-Y. Xu p1326
Nonlinear interpolation of TV image sequences. R. Glavina, S. Cucchi and G.L. Sicuranza p778
Novel sorter architecture for image processing rank order filters. U. Kleine p45
Polygonal approximation for image segmentation. M.H. Hassan and P. Siy p1001
Real-time thresholding technique. M.H. Hassan and P. Siy p339
Simple block-effect reduction method for image coding with vector quantisation. J.-S. Koh and J.-K. Kim p713
Threshold selection algorithm for extracting a uniform colour region in an image. Byung-hwa Chang, Seong-Dae Kim and Jae-kyoon Kim p1362

IMPATTS

Low-noise D-band impatt oscillators. J. Wenger and S. Huber p475
Novel 93 GHz injection-locked impatt oscillator. D.H. Evans and R.N. Bates p771

INDUCTANCE SIMULATION

Generation of new two-amplifier synthetic floating inductors. R. Senani p1202

INFORMATION THEORY

Aryabhata algorithm for polynomials. S.C. Kak p838
Capacities of sequences of currently used ternary line codes. J.F. Hope, H.C. Ferreira and A.L. Nel p681
Comparison between the Jacoby–Kost and Horiguchi–Morita binary two-thirds rate modulation codes. H.C. Ferreira, W. de V. Stegmann and C.R. Wyman p837
Correlation-immunity of Boolean functions. Yang Yi Xian p1335
Existence of one-dimensional perfect binary arrays. Yang Yi Xian p1277
ID-based cryptosystem using discrete logarithm problem. S. Tsujii, T. Itoh and K. Kurosawa p1318
Identity-based conference key distribution system. K. Koyama p495
Identity-based conference key distribution systems in broadcast networks. K. Koyama and K. Ohta p647
Improved (conference) public-key distribution system based on matrices. Yang Yi Xian p934
Modification of a public-key cryptosystem. T. Okamoto p814
New public-key distribution systems. Yang Yi Xian p560
Opening the knapsack by DFTs. T. Maseng p95
Perfect binary arrays with 36 elements. L. Bömer and M. Antweiler p730
Pieprzyk's public-key cryptosystem is insecure. Yang Yi Xian p1043
Public key cryptosystem using a reciprocal number with same intractability as factoring a large number. K. Kurosawa, T. Ito and M. Takeuchi p809
kth least significant bit of a plaintext in reciprocal number cryptosystem. K. Kurosawa p810

INTEGRATED CIRCUITS

1 THz-bandwidth prober for high-speed devices and integrated circuits. J.A. Valdmanis p1308
Connection of VLSI chips to printed circuit board using stacked solder bumps. S. Sasaki, T. Kishimoto and N. Matsui p1238
Dependence of interconnection delays on driving mechanism for GaAs-based VLSI. A.K. Goel p1066
Determination of coupling capacitance of underpasses, air bridges and crossings in MICs and MMICs. L. Wiemer and R.H. Jansen p344
GaAs monolithic microwave integrated circuit trimming using laser-direct-written tungsten microstrip lines. C.L. Chen, J.G. Black, L.J. Mahoney, S.P. Doran, W.E. Courtney, D.J. Ehrlich and R.A. Murphy p402
GaAs/AlGaAs rooftop reflector laser for optoelectronic integrated circuits. Chang-Joon Chae and Young-Se Kwon p1118
Graphical technique for crosstalk timing analysis. M. Odasso and F. Scapino p864
Improved negative feedback technique to reduce drain conductance of GaAs MESFETs for precision analogue ICs. W.S. Lee and J. Mun p705
New channel routing algorithm for bit-slice applications. S. Nagara, S.G. Smith, P.B. Denyer and M. Keightley p1389
New clustering approach to chip floorplan using functional data. I. Harada and T. Adachi p900
New proposal for a multigigabit/s clock recovery IC based on a standard silicon bipolar technology. Z. Wang and U. Langmann p454
New tungsten silicide thin-film resistor technology applied to GaAs integrated circuits. D.A. Allan, M.J. Gilbert and P.J. O'Sullivan p1216
Nonlinear transmission line for picosecond pulse compression and broadband phase modulation. M.J.W. Rodwell, D.M. Bloom and B.A. Auld p109
Novel CMOS latch with clock hysteresis. D.W.R. Orton p1221
Observation of voltage contrast in scanning ion microscopy of integrated circuits. E.C.G. Kirk, J.R.A. Cleaver and H. Ahmed p585
Optically strobed sample-and-hold circuit. C. McConaghy p234
Partitioning for pseudo-exhaustive testing is *NP*-complete. W. Song, K.C. Smith and W.M. Snelgrove p1060
Probabilistic compaction algorithm for LSI cell layout design. A. Onozawa, H. Miyashita and K. Ueda p408
SOI by wafer bonding with spin-on glass as adhesive. A. Yamada, T. Kawasaki and M. Kawashima p39
Sensitivity of GaAs analogue integrated circuit building blocks to the effect of back-gating. W.S. Lee p587
Temperature distribution on ceramic substrates. E. Boone, G. De Mey and L. Rottiers p26
Wideband variable peaking AGC amplifier for high-speed lightwave digital transmission. T. Kinoshita, K. Yamashita, M. Maeda and Y. Sekine p23

INTEGRATED OPTICS

Accuracy of method of moments and weighted index method. D.A. Roberts and M.S. Stern p784
All-optical switching in prism coupling to semiconductor-doped glass waveguides. G. Assanto, A. Gabel, C.T. Seaton, G.I. Stegeman, C.N. Ironside and T.J. Cullen p484
Analysis of a PIN photodiode with integrated waveguide. M.-C. Amann p895
Antiresonant reflecting optical waveguides for III-V integrated optics. T.L. Koch, U. Koren, G.D. Boyd, P.J. Corvini and M.A. Duguay p244
Bend losses in GaAs/AlGaAs optical waveguides. R.J. Deri, E. Kapon and L.M. Schiavone p845
Bistable optical switching and logic elements in photochromic fulgides with single-wavelength illumination. R. Cush, C. Trundle, C.J.G. Kirkby and I. Bennion p419
Characterisation of a fibre Raman oscillator using fibre grating reflectors. P.N. Kean, K. Smith, B.D. Sinclair, W. Sibbett, C.J. Rowe and D.C.J. Reid p1241
Coded phase-reversal $LiNbO_3$ modulator with bandwidth greater than 20 GHz at 1·3 μm wavelength. R.L. Jungerman, C.A. Johnsen, D.W. Dolfi and M. Nazarathy p172
Depolarisation in Ti : $LiNbO_3$ waveguides and its effect on circuit design. P.G. Suchoski, T.K. Findakly and F.J. Leonberger p1357
Dynamic response of an integrated optoelectronic logic device. P. Wheatley, G. Parry, J.E. Midwinter, G. Hill, P. Mistry, M.A. Pate and J.S. Roberts p1249
Efficient photodiode-waveguide coupling for hybrid integrated optical circuits. M. Yamada, H. Terui, Y. Yamada, A. Himeno and M. Kobayashi p1056
Electric-field-assisted proton-exchanged optical waveguides in lithium niobate. C.W. Pitt, G. Burbie and Tat Wan p987
Electro-optic effect in He^+-implanted optical waveguides in $LiNbO_3$. G.T. Reed and B.L. Weiss p424
Electro-optically tunable, narrowband Ti:$LiNbO_3$ wavelength filter. F. Heismann, L.L. Buhl and R.C. Alferness p572
Fabrication of low-loss titanium-diffused $LiNbO_3$ waveguides using a closed platinum crucible. A. Neyer and T. Pohlmann p1187
GaInAsP buried channel EA modulator for 1·3 μm fibre links. S.C. Lin, X.L. Jing, M.K. Chin, L.M. Walpita, P.K.L. Yu and W.S.C. Chang p1257
Geometrical design considerations for a tree-structured optical switch matrix. K. Habara and K. Kikuchi p376
Growth and properties of an $LiNbO_3$ film on sapphire with an $LiNbO_3$ buffer layer. T. Nozawa p1321
Guided-wave optical chip-to-chip interconnections. M. Kobayashi, M. Yamada, Y. Yamada, A. Himeno and H. Terui p143
Integration of GaAs MESFET drivers with GaAs directional-coupler electro-optic modulators. J.H. Abeles, W.K. Chan, F.K. Shokoohi, R. Bhat and M.A. Koza p1037
Laser power sharing in the subscriber loop. H. Kobrinski and S.S. Cheng p943
$LiNbO_3$ directional-coupler polarisation splitter. K. Habara p614
Low RI liquid crystals for integrated optics. I. Sage and D. Chaplin p1192
Low-drive-voltage and low-loss polarisation-independent $LiNbO_3$ optical waveguide switches. M. Kondo, Y. Ohta, Y. Tanisawa, T. Aoyama and R. Ishikawa p1167
Low-insertion-loss channel waveguides in $LiNbO_3$ fabricated by proton exchange. J.J. Veselka and G.A. Bogert p265
Low-insertion-loss, tunable wavelength multiplexer on lithium niobate. F. Rottmann and E. Voges p1007
Low-loss TM-pass polariser fabricated by proton exchange for *Z*-cut Ti:$LiNbO_3$ waveguides. J.J. Veselka and G.A. Bogert p29
Low-loss antiresonant reflecting optical waveguide on Si substrate in visible-wavelength region. Y. Kokubun, T. Baba, T. Sakaki and K. Iga e251

Low-loss optical stripe waveguides in $LiNbO_3$ formed by He^+ implantation. G.T. Reed and B.L. Weiss p792
Low-loss single-mode InP/InGaAsP waveguides grown by MOVPE. P.W.A. McIlroy, P.M. Rodgers, J.S. Singh, P.C. Spurdens and I.D. Henning p701
Low-voltage modulator and self-biased self-electro-optic-effect device. J.S. Weiner, A.C. Gossard, J.H. English, D.A.B. Miller, D.S. Chemla and C.A. Burrus p75
Miniature integrated optical beam-splitter in AlGaAs/GaAs ridge waveguides. J.S. Osinski, C.E. Zah, R. Bhat, R.J. Contolini, E.D. Beebe, T.P. Lee, K.D. Cummings and L.R. Harriott p1156
Monolithically integrated optical gate 2×2 matrix switch using GaAs/AlGaAs multiple quantum well structure. A. Ajisawa, M. Fujiwara, J. Shimizu, M. Sugimoto, M. Uchida and Y. Ohta p1121
Narrow, high-NA GaAs/GaAlAs optical waveguides with losses below $0{\cdot}7 \pm 0{\cdot}1\,dB\,cm^{-1}$. R.G. Walker, H.E. Shephard and R.R. Bradley p362
New analysis of LED to single-mode fibre coupling. B. Hillerich e1397 e306
Novel process for integration of optoelectronic devices using reactive ion etching without chlorinated gas. L. Henry, C. Vaudry and P. Granjoux p1253
One-step field-assisted ion exchange for fabrication of buried multimode optical strip waveguides. B.G. Pantchev p1188
Optical third-harmonic generation from poly(*p*-phenylenevinylene) thin films. T. Kaino, K.-I. Kubodera, S. Tomaru, T. Kurihara, S. Saito, T. Tsutsui and S. Tokito p1095
Optical third-harmonic generation from polydiacetylene thin films deposited by vacuum evaporation. S. Tomaru, K. Kubodera, S. Zembutsu, K. Takeda and M. Hasegawa p595
Optically biased $LiNbO_3$ $\Delta\beta$ reversal directional coupler switch. H. Okayama, A. Matoba, R. Shibuya and T. Ishida p1145
Performance of an 8×8 $LiNbO_3$ switch matrix as a gigahertz self-routing switching node. D.J. Blumenthal, P.R. Prucnal, L. Thylen and P. Granestrand p1359
Phase-matched mode convertor in $LiNbO_3$ using near-*Z*-axis propagation. A. Donaldson and K.K. Wong p1378
Planar TJS lasers fabricated in semi-insulating GaAs substrates for optoelectronic integrated circuits. M. Ishii, K. Kamon, M. Shimazu, M. Mihara, H. Kumabe and K. Isshiki p179
Polarisation transformer on Ti : $LiNbO_3$ with reset-free optical operation for heterodyne/homodyne receivers. H. Heidrich, C.H. von Helmolt, D. Hoffmann, H.-J. Hensel and A. Kleinwächter p335
Realisation of integrated-optical absorbers for Ti : $LiNbO_3$. G. Stock p831
Reduction of bend losses in Ti : $LiNbO_3$ waveguides through MgO double diffusion. B. Schüppert p797
Resistance of Ti : $LiNbO_3$ devices to ionising radiation. E.I. Drummond p1214 e1397
Stress-induced index change for K^+–Na^+ ion exchange in glass. J. Albert and G.L. Yip p737
Ti:$LiNbO_3$ intersecting waveguides. G.A. Bogert p72
Ti : $LiNbO_3$ three-waveguide polarisation splitter. G.A. Bogert p37
Very low-loss GaInAs/InP optical waveguides for the 10·6 μm wavelength. D. Delacourt, M. Papuchon, M.A. di Forte-Poisson and M. Razeghi p451

INTERFERENCE

Rician envelope estimation and confidence intervals in low signal/noise levels. B.G. Stewart and J.F.L. Simmons p832

INTERFEROMETERS

Fizeau fringe interferometer for fibre outside diameter measurements. M.S. O'Sullivan and D.W. Gransden p666
Laser interferometer using a dual interference method. K.H. Yang, L. Chen and S.Y. Zhang p699
Miniature micromachined Fabry–Perot interferometers in silicon. S.R. Mallinson and J.H. Jerman p1041
Multiplexing of interferometric sensors using phase-generated carrier techniques. A. Dandridge, A.B. Tveten, A.D. Kersey and A.M. Yurek p665 e867
Optical-fibre Fabry–Perot frequency discriminator for communications applications. L.J. Cimini, J. Stone and L.L. Buhl p463
Pigtailed high-finesse tunable fibre Fabry–Perot interferometers with large, medium and small free spectral ranges. J. Stone and L.W. Stulz p781
Sideband noise of a large phase carrier in interferometric sensors. K.P. Koo, F. Bucholtz and A. Dandridge p1062

INTERMODULATION

Crosstalk penalty in a two-channel ASK heterodyne detection system with non-negligible laser linewidth. Y.K. Park, S.W. Granlund, C.Y. Kuo, M. Dixon, T.W. Cline, R.W. Smith, N.K. Dutta and G. Vannucci p1291

INTERSYMBOL INTERFERENCE

Efficient digital receiver structure for trellis-coded signals transmitted through channels with intersymbol interference. K. Wesołowski p1265

INVERTERS

Explicit formulation of delays in CMOS VLSI. D. Auvergne, D. Deschacht and M. Robert p741

ION IMPLANTATION

Enhanced Schottky barrier heights on *n*-type $Ga_{0\cdot47}In_{0\cdot53}As$ by Be implantation. G. Fernholz, R. Westphalen, W. Lange and H. Beneking p722
Fully implanted GaAs millimetre-wave mixer diode using high energy implantation. P. Thompson, H. Dietrich, Y. Anand, V. Higgins and J. Hillson p725
Fully ion-implanted abrupt *pn* junction on semi-insulating InP. K.-W. Wang, C.L. Cheng and S.M. Zima p1040
Increased carrier lifetimes in epitaxial silicon layers on buried silicon nitride produced by ion implantation. W. Skorupa, U. Kreissig, E. Hensel and H. Bartsch d579
Low-loss optical stripe waveguides in $LiNbO_3$ formed by He^+ implantation. G.T. Reed and B.L. Weiss p792
Using oxide sidewall taper to improve breakdown voltage in planar junction of DMOS devices by a simple process. C.Y. Lu, P.C. Riffe, N.S. Tsai, R.E. Ahrens and M.A. Banak p407

ION MICROSCOPY

Observation of voltage contrast in scanning ion microscopy of integrated circuits. E.C.G. Kirk, J.R.A. Cleaver and H. Ahmed p585

IONISATION

DC ionised field quantities as influenced by coronating conductor surface gradient. M. Aboelsaad and L. Shafai p162

JITTER

Comparison of regenerator tolerance to sinusoidal and Gaussian alignment jitter. I. Fletcher p67
Data clock jitter in supersampling multiplex transmission. R. Gangopadhyay and P. Cochrane p1203
Data sequence coding for low jitter timing recovery. E.V. Jones and S. Zhu p337
Measured pulse-stuffing jitter in asynchronous DS-1/SONET multiplexing with and without stuff-threshold modulation circuit. W.D. Grover, T.E. Moore and J.E. McEachern p959
Power penalty due to jitter on optical communication systems. K. Schumacher and J.J. O'Reilly p718
Self-correcting clock recovery circuit with improved jitter performance. D. Shin, M. Park and M. Lee p110

JOSEPHSON JUNCTIONS

3·0 ps switching operation in all-Nb Josephson logic gates. K. Kuroda, J. Nakano, M. Yuda and M. Ueki p163
Novel microstrip transformer for superconducting microelectronics. H.K. Olsson p1152

JUNCTION STRUCTURES

Avalanche noise associated with gate current of Si JFET. J.M. Peransin, D. Rigaud and R. Alabedra p970
GaInAs junction FET fully dry etched by metal organic reactive ion etching technique. D. Lecrosnier, L. Henry, A. Le Corre and C. Vaudry p1254
Heterostructure complementary technology. J.G. Simmons and G.W. Taylor p380

LADDER NETWORKS

State-space description and realisation of elliptic lowpass *LCR* ladder filters. D.G. Haigh and J.T. Taylor p1032

LAPLACE TRANSFORMS

Instabilities in numerical inversion of Laplace transforms using Taylor series approach. R. Unnikrishnan and A.V. Mathew p482
Taylor series approach to functional approximation for inversion of Laplace transforms. Hung-yuan Chung and York-yih Sun p480 e306

LARGE-SCALE INTEGRATION

3 μm VLSI processing element using the Cordic algorithm. G.J. Vaudin and G.R. Nudd p1164
Connection of VLSI chips to printed circuit board using stacked solder bumps. S. Sasaki, T. Kishimoto and N. Matsui p1238
Cooling characteristics of diamond-shaped interrupted cooling fin for high-power LSI devices. T. Kishimoto and S. Sasaki p456
Dependence of interconnection delays on driving mechanism for GaAs-based VLSI. A.K. Goel p1066
Fast and dense low-power multiple-valued I^2L circuit. Q.P. Chao and Z. Tang p968
New channel routing algorithm for bit-slice applications. S. Nagara, S.G. Smith, P.B. Denyer and M. Keightley p1389
New clustering approach to chip floorplan using functional data. I. Harada and T. Adachi p900
Novel CMOS latch with clock hysteresis. D.W.R. Orton p1221
Partitioning for pseudo-exhaustive testing is *NP*-complete. W. Song, K.C. Smith and W.M. Snelgrove p1060
Probabilistic compaction algorithm for LSI cell layout design. A. Onozawa, H. Miyashita and K. Ueda p408

LASERS AND LASER APPLICATIONS

0°-phase-shift, single-lobe operation from wide-waveguide interferometric (WWI) phase-locked arrays of InGaAsP/InP ($\lambda = 1{\cdot}3\,\mu m$) diode lasers. D. Botez, T. Pham and D. Tran p416
150 mW quasi-CW fundamental-mode operation from modified twin-channel laser. C.B. Morrison, D. Botez and L.M. Zinkiewicz p1025
1·55 μm narrow-linewidth multielectrode DFB laser for coherent FSK transmission. Y. Nakano, Y. Itaya, M. Fukuda, Y. Noguchi, H. Yasaka and K. Oe p826
2·4 W CW, 770 nm laser arrays with nonabsorbing mirrors. D.F. Welch, R.L. Thornton, W. Streifer and T. Paoli p525
300 mW operation of a surface-emitting phase-locked array of diode lasers. J. Puretz, R.K. DeFreez, R.A. Elliott, J. Orloff and T.L. Paoli p130
450 Hz relative frequency stability in an AlGaAs diode laser. Y.C. Chung and T.M. Shay p1044
Buried-heterostructure diode lasers with *in-situ*-grown self-aligned GaAs mask for Zn diffusion. S. Mukai, M. Itoh, M. Watanabe, H. Itoh and H. Yajima p755
Coupled mode analysis of wavefront properties of phased array diode lasers. N.W. Carlson, J.K. Butler and V.J. Masin e306
Dependence of central-lobe output power on fill factor of an in-phase laser array. J.E. Epler, R.L. Thornton and T.L. Paoli p754
Dependence of spectral linewidth of DFB lasers on facet reflectivity. S. Ogita, M. Hirano, H. Soda, M. Yano, H. Ishikawa and H. Imai p347
Diode-laser-pumped operation of an Er^{3+}-doped single-mode fibre laser. L. Reekie, I.M. Jauncey, S.B. Poole and D.N. Payne p1076
Direct supermode analysis of phase-locked diode laser arrays. K. Hayata and M. Koshiba p935
Distributed-feedback, surface-emitting laser diode with lateral double heterostructure. M. Ogura and S. Mukai p758
Experiment on 1500 nm stabilised Zeeman laser. Wu Yizun, Guan Kejian, Yu Tong and Tian Feng p318
Femtosecond soliton Raman ring laser. A.S. Couveia-Neto, A.S.L. Gomes and J.R. Taylor p537
GaAs monolithic microwave integrated circuit trimming using laser-direct-written tungsten microstrip lines. C.L. Chen, J.G. Black, L.J. Mahoney, S.P. Doran, W.E. Courtney, D.J. Ehrlich and R.A. Murphy p402
Generation of a single-lobe radiation pattern from a phased-array laser using a near-contact variable phase-shift zone plate. S. Thaniyavarn and W. Dougherty p5

High-efficiency Nd-doped fibre lasers using direct-coated dielectric mirrors. M. Shimizu, H. Suda and M. Horiguchi p768
High-power CW operation of 780 nm T^3 laser diodes. A. Shima, T. Yamawaki, H. Saito, H. Matsubara, T. Murakami, K. Ohtaki, H. Kumabe and W. Susaki p672
High-power aging tests of 1·3 and 1·5 μm VIPS lasers. S. Oshiba and Y. Kawai p843
High-power operation of long-cavity phase-locked laser arrays. T. Aoyagi, S. Hinata, K. Shigihara, Y. Seiwa, K. Ikeda and W. Susaki p1396
High-speed all-optical gate switching experiment in a Fabry–Perot semiconductor laser amplifier. K. Inoue p921
High-speed, polyimide-based semi-insulating planar buried heterostructures. J.E. Bowers, U. Koren, B.I. Miller, C. Soccolich and W.Y. Jan p1263
Laser interferometer using a dual interference method. K.H. Yang, L. Chen and S.Y. Zhang p699
Laser recrystallised SOI with periodical seeding filled by selective epitaxial growth. J.L. Regolini, D. Dutartre, D. Bensahel, L. Karapiperis, G. Garry and D. Dieumegard p493
Linewidth enhancement for DFB lasers due to longitudinal field dependence in the laser cavity. J. Wang, N. Schunk and K. Petermann p715
Linewidth enhancement in quantum-well lasers. L.D. Westbrook and M.J. Adams p1223
Linewidth reduction by coupled phase-shift distributed-feedback lasers. T. Kimura and A. Sugimura p1014
Linewidth reduction in DFB laser by detuning effect. S. Ogita, M. Yano, H. Ishikawa and H. Imai p393
Local beam deflector integrated in a diode laser cavity. S. Mukai, M. Watanabe, H. Itoh and H. Yajima p361
Low-threshold CW operation of an erbium-doped fibre laser pumped at 807 nm wavelength. C.A. Millar, I.D. Miller, B.J. Ainslie, S.P. Craig and J.R. Armitage p865
Measuring modulus and phase of chirp/modulated power ratio. O. Doyle p133
Monolithically integrated thermoelectrically tunable distributed Bragg reflector laser. T. Cella, N.K. Dutta, A.B. Piccirilli and R.L. Brown p1031
Narrow-linewidth laser with a prism grating/GRIN rod lens combination serving as external cavity. J. Wittmann and G. Gaukel p524
Neodymium-doped fluoro-zirconate fibre laser. M.C. Brierley and P.W. France p815
New GaAlAs-GaAs surface-emitting laser diodes with lateral pumping structure. Y.-H. Wu, M. Ogura, M. Werner and S. Wang p123
New high-resolution positive and negative photoresist method for λ/4-shifted DFB lasers. M. Okai, S. Tsuji, M. Hirao and H. Matsumura p370
Nonuniform phased arrays of diode lasers for fundamental supermode operation. E. Kapon p879
Novel fabrication method of quarter-wave-shifted gratings using ECR-CVD SiN_x films. H. Sugimoto, Y. Abe, T. Matsui and H. Ogata p1260
Properties of quarter-wave-shifted DFB lasers in the presence of a taper. L.D. Westbrook p518
Quasi-instantaneous (<20 ps) phase locking in single-lobe Y-coupled laser diode arrays. R.K. DeFreez, R.A. Elliott, K. Hartnett and D.F. Welch p589
SPICE simulation of laser diode modules. B. Wedding p383
Spectral, phase noise and phase modulation characteristics of AM sideband injection-locked semiconductor lasers. K. Kikuchi and C.E. Zah p437
Thermal model of laser diode arrays. W. Nakwaski p458
Tunable optical-wavelength conversion using a multielectrode distributed-feedback laser diode with a saturable absorber. H. Kawaguchi, K. Oe, H. Yasaka, K. Magari, M. Fukuda and Y. Itaya p1088
Tuning characteristics and inverter/inverted-output flip-flop operation of tandem-electrode laser diode. M. Yamaguchi and K. Kikuchi p120
Ultra-high-power quasi-CW monolithic laser diode arrays with high power conversion efficiency. G.L. Harnagel, P.S. Cross, C.R. Lennon, M. DeVito and D.R. Scifres p743

LEAST-SQUARES APPROXIMATION

Instabilities in numerical inversion of Laplace transforms using Taylor series approach. R. Unnikrishnan and A.V. Mathew p482
Performance of LMS algorithm as a function of input signal pole loci. G.J. Freij and B.M.G. Cheetham p474

LENSES

Linearising method for nonlinear properties in a liquid-crystal lens. T. Nose and S. Sato p878

LIFE TESTING

Aging characteristics of AlGaInP/GaInP visible-light lasers (λ_L = 678 nm). A. Gomyo, K. Kobayashi, S. Kawata, I. Hino and T. Suzuki p85
CW performance and life of 1·3 μm InGaAsP/InP lasers emitting at high facet power densities. R.F. Murison, A.J.N. Houghton, A.R. Goodwin, A.J. Collar and I.G.A. Davies p601

LIGHT-EMITTING DIODES

Fabrication and performance of an InP/InGaAsP monolithic 12 × 12-element matrixed LED array. L.A. Koszi, H. Temkin, B.H. Chin, S.G. Napholtz and B.P. Segner p284
Modulation frequency-shift technique for dispersion measurements in optical fibres using LEDs. L. Thevenaz and J.-P. Pellaux p1078
Novel high-speed LED transmitter for single-mode fibre and wideband loop transmission systems. G.-K. Chang, H.P. Leblanc and P.W. Shumate p1338
WDM experiment using 1300/1500 nm dual-wavelength LED for single-mode fibre transmission systems. G.-K. Chang, L.A. Reith, H.P. Leblanc and A.K. Chin p1267

LINEAR NETWORKS

Computer-aided noise analysis of linear multiport networks. G.I. Vasilescu p351

LINEAR SYSTEMS

Family of reduced-order models for linear multivariable systems. A.M. Eydgahi and H. Singh p1178
Linear third-order discrete system stability under parameter variations. K.S. Yeung and S.S. Wang p266
Relaxing the detectability condition for the algebraic Riccati equation. F. Tan, W.G. Vogt and M.H. Mickle p1139

LIQUID CRYSTALS

Low RI liquid crystals for integrated optics. I. Sage and D. Chaplin p1192

LIQUID-PHASE EPITAXY

Dynamic spectral linewidth in InGaAsP multiquantum-well lasers grown by liquid-phase epitaxy. Y. Sasai, J. Ohya, M. Ogura and T. Kajiwara p232

LITHOGRAPHY

Fabrication of first-order gratings for 1·5 μm DFB lasers by high-voltage electron-beam lithography. M.J. Fice, H. Ahmed and S. Clements p590

LOGIC AND LOGIC DESIGN

Absolute-type shaft encoder using shift register sequences. G.H. Tomlinson p398
BIST structure using multi-input shift register with initial value. A. Hławiczka p476
CMOS logic cell switching speed thermal characterisation. F.S. Shoucair p458
Elimination of errors in absolute position encoders using *m*-sequences. G.H. Tomlinson and E. Ball p1372
Fast and dense low-power multiple-valued I^2L circuit. Q.P. Chao and Z. Tang p968
High-speed GaAs 4 × 4-bit parallel multiplier using super capacitor FET logic. K.S. Lowe p425
Josephson vortex timing circuit. K. Aihara, K. Miyahara and K. Hohkawa p545
Multivalued dynamic circuits. J.L. Huertas, A. Barriga and G. Sánchez-Gómez p502
New clustering approach to chip floorplan using functional data. I. Harada and T. Adachi p900
New pseudorandom encoding technique for shaft encoders with any desired resolution. E.M. Petriu p507
Partitioning for pseudo-exhaustive testing is *NP*-complete. W. Song, K.C. Smith and W.M. Snelgrove p1060
Reconvergent fanout analysis and fault simulation complexity of combinational circuits. F. Maamari and J. Rajski p1131
Self: A self-timed systems design technique. C.H. Lau p269
Serial-data computation on twin pipelines. M.S. McGregor, S.G. Smith, P.B. Denyer and A.F. Murray p292
Serial/parallel automultiplier. S.G. Smith p413
Systematic design of D flip-flops using two state variables. S. Okugawa and N. Inoue p909

LOGIC CIRCUITS

Fast and dense low-power multiple-valued I^2L circuit. Q.P. Chao and Z. Tang p968
Graphical technique for crosstalk timing analysis. M. Odasso and F. Scapino p864
High-speed GaAs 4 × 4-bit parallel multiplier using super capacitor FET logic. K.S. Lowe p425
Josephson vortex timing circuit. K. Aihara, K. Miyahara and K. Hohkawa p545
Method for synthesis of MOSFET logic networks. S.G. Smith and M. Keightley p902
Multivalued dynamic circuits. J.L. Huertas, A. Barriga and G. Sánchez-Gómez p502

LOGIC DEVICES

3·0 ps switching operation in all-Nb Josephson logic gates. K. Kuroda, J. Nakano, M. Yuda and M. Ueki p163
Simple JCCD logic at 20 MHz. J. Hoekstra p246

LOSSES

New bending loss formula explaining bends on loss curve. S.B. Andreasen p1138

LUMINESCENCE

High-sensitivity sampling technique for luminescence time constant measurement. S. Loualiche and E. Pauty p1017
Nondiffusion and 1·54 μm luminescence of erbium implanted in InP. P.N. Favennec, H. L'Haridon, A. Le Corre, M. Salvi and M. Gauneau p684

MAGNETIC DEVICES

Mode charts of gyromagnetic planar ring resonators. J. Helszajn, W.T. Nisbet and J. Sharp p1290
Stress-relieved magnetoelastic amorphous metal DC magnetometer. M.D. Mermelstein, C. Askins and A. Dandridge p280

MAGNETO-OPTICAL EFFECTS

Fibre-optic magnetic sensor utilising metal-coated fibre. H. Okamura p834

MAGNETOSTRICTIVE DEVICES

Low-frequency, submicrogauss fibre-optic magnetometer. F. Bucholtz, A.M. Yurek, K.P. Koo and A. Dandridge p985
Stress-relieved magnetoelastic amorphous metal DC magnetometer. M.D. Mermelstein, C. Askins and A. Dandridge p280

MATHEMATICAL TECHNIQUES

Application of the simplex technique in motion estimation. B.S. Lee and J.W.R. Griffiths p903
Considerations on group delay fitting equations for dispersion-shifted fibres. Y. Miyajima, T. Kawata and Y. Negishi p1381
Efficient probabilistic algorithm for solving quadratic equations over finite fields. T. Itoh p869

MATRIX ALGEBRA

Instabilities in numerical inversion of Laplace transforms using Taylor series approach. R. Unnikrishnan and A.V. Mathew p482
Relaxing the detectability condition for the algebraic Riccati equation. F. Tan, W.G. Vogt and M.H. Mickle p1139

MEASUREMENT

17 ps rise-time measurement by photoemission sampling. A. Blacha, R. Clauberg, H.K. Seitz and H. Beha p249
Accuracy of Fabry–Perot method of semiconductor laser gain measurement. M.B. El Mashade and J. Arnaud p568
Analysis of an interferometric optical fibre detection technique applied to silicon vibrating sensors. M.V. Andres, M.J. Tudor and K.W.H. Foulds p774
Application of LFB acoustic microscope to film thickness measurements. J. Kushibiki and N. Chubachi p652
Bidirectional and two-channel transmission system measurements using a semiconductor-laser-amplifier repeater. H.J. Westlake and M.J. O'Mahony p649
Dual sinusoidal modulation scheme for directional laser Doppler velocimeter. J.E. Schrøder p114
Elimination of ambiguity in measurement of permittivity with short-circuited waveguide. K.H. Oh, C.K. Ong and B.T.G. Tan p1181
Fibre-optic magnetic sensor utilising metal-coated fibre. H. Okamura p834
Fizeau fringe interferometer for fibre outside diameter measurements. M.S. O'Sullivan and D.W. Gransden p666
Improved method for resonant-frequency perturbation measurements. D.V. Land p1166
Low-frequency, submicrogauss fibre-optic magnetometer. F. Bucholtz, A.M. Yurek, K.P. Koo and A. Dandridge p985
Novel method for ultrahigh-frequency electro-optic time-domain reflectometry. T. Jackson, J. Nees, R. Vallee and G. Mourou p1130
Optical sampling of GHz charge density modulation in silicon bipolar junction transistors. A. Black, C. Courville, G. Schultheis and H. Heinrich p783
Optically excited resonant beam pressure sensor. D. Uttamchandani, K.E.B. Thornton and B. Culshaw p1333
Optically excited resonant diaphragm pressure sensor. D. Uttamchandani, K.E.B. Thornton, J. Nixon and B. Culshaw p152
Prediction of error due to distance in measurement or calculation of electromagnetic backscatter from a cylindrical body. J.A.G. Malherbe and C.W.I. Pistorius p1310
Scanning the laser gain spectrum using distributed feedback and hydrostatic pressure. K.C. Heasman, A.R. Adams and R.G. Plumb p555
Shear-wave magnetometry using metallic glass ribbon. P.T. Squire and M.R.J. Gibbs p147
Sideband noise of a large phase carrier in interferometric sensors. K.P. Koo, F. Bucholtz and A. Dandridge p1062
Single-crystal two-layer fibres for visible and infra-red transmission. A.V. Vasiljev, E.M. Dianov, L.N. Dmitruk and V.G. Plotnichenko p117
Stress-relieved magnetoelastic amorphous metal DC magnetometer. M.D. Mermelstein, C. Askins and A. Dandridge p280
Surface plasmon microscopy. E. Yeatman and E.A. Ash p1091

MEMORIES

Garbage collection coprocessor system. K.-F. Wong p798
Static random-access memory based on self-aligned-gate (Al, Ga)As/n^+-GaAs superlattice modulation-doped FETs. D.K. Arch, J.K. Abrokwah, P.J. Vold, A.M. Fraasch, B.L. Grung and N.C. Cirillo p87

METAL-INSULATOR-SEMICONDUCTOR STRUCTURES AND DEVICES

Blue electroluminescence from ZnSe/Langmuir-Blodgett film MIS diodes. Y.L. Hua, M.C. Petty, G.G. Roberts, M.M. Ahmad, H.M. Yates, N.J. Maung and J.O. Williams p231

METAL-OXIDE-SEMICONDUCTOR STRUCTURES AND DEVICES

Anomalous oscillation in depletion-mode MOSFETs at low temperature. C. Carruthers and J. Mavor p178
CMOS circuits made in thin SIMOX films. J.P. Colinge and T.I. Kamins p1162 e1397
CMOS on local SOI using SIMOX technology. S. Matsumoto, T. Ohno and K. Izumi p576
CMOS/SIMOX devices having a radiation hardness of 2 Mrad(Si). T. Ohno, K. Izumi, M. Shimaya and N. Shiono p141
Characterisation of *N*-channel germanium MOSFET with gate insulator formed by high-pressure thermal oxidation. E.E. Crisman, J.I. Lee, P.J. Stiles and O.J. Gregory p8
Computer simulation of an induction heating power supply using power MOSFETs. D.W. Tebb and L. Hobson p293
Gate current in 0·75 μm *N*-channel MOSFETs with doubly diffused drain. R.K. Watts, L. Manchanda and R.L. Johnston p468
Low-noise operation of buried channel MOS transistors. C. Carruthers and J. Mavor p1173
MOSFET model continuous from weak to strong inversion. M.M. Abu-Zeid and G.G. de Jong p1299
New analytical expression for the drain current of short-channel MOS transistors in the triode region. S. Dimitrijev, D. Zupac and N. Stojadinović p862
Role of source N^+N^- structure in parasitic bipolar action of lightly doped short-channel MOSFETs. N.D. Janković p461
SOI MOSFET in weak inversion and weak accumulation. F. Balestra and J. Brini p211
Testing of complex gates. R. Rajsuman, A.P. Jayasumana and Y.K. Malaiya p813

MICROSCOPES AND MICROSCOPY

New mechanism for subsurface imaging in silicon. S.J. Sheard and M.G. Somekh p1134
Surface plasmon microscopy. E. Yeatman and E.A. Ash p1091

MICROSTRIP

10 GHz space power combiner with parasitic injection locking. R.J. Dinger, D.J. White and D.R. Bowling p397
Analysis of microstripline coupled to microstrip antenna. X.Z. Gao and K. Chang p694
Approach to modelling of microstrip-microslot applicator. R. Ledee, P. Pribetich, P. Kennis and M. Chive p829
Characteristics of inhomogeneous coupled cylindrical striplines. C.J. Reddy and M.D. Deshpande p821
Compact broadband microstrip antenna. C.K. Aanandan and K.G. Nair e306
Complete and rigorous analysis of electromagnetically coupled transverse microstrip dipole. P. Lepeltier, J.M. Floc'h and J. Citerne p822
Conformal mapping analysis of shielded striplines. J.R. Souza p637
Dielectrically shielded microstrip (DSM) lines. K. Chang and J. Klein p535
Directivity of linear microstrip arrays. J.P. Daniel p897
Dispersion characteristics of microstrip lines in the vicinity of a coplanar ground. J. Fang, X. Zhang and K.K. Mei p1142
Dual aperture-coupled microstrip antenna for dual or circular polarisation. A. Adrian and D.H. Schaubert p1226
Effect of curvature on characteristics of rectangular patch antenna. J.S. Dahele, R.J. Mitchell, K.M. Luk and K.F. Lee p748
Feed radiation effects in sequentially rotated microstrip patch arrays. P.S. Hall p877
GaAs monolithic microwave integrated circuit trimming using laser-direct-written tungsten microstrip lines. C.L. Chen, J.G. Black, L.J. Mahoney, S.P. Doran, W.E. Courtney, D.J. Ehrlich and R.A. Murphy p402
Increasing the bandwidth of a microstrip antenna by proximity coupling. D.M. Pozar and B. Kaufman p368
Microstrip log-periodic antenna array with endfire beam. P.S. Hall and A. Sparrow p912
Modelling microstrip step discontinuities by the transmission matrix. J.S. Hong and J.M. Shi p678
New simple feed network for an array module of four microstrip elements. M.L. Oberhart, Y.T. Lo and R.Q.H. Lee p436
Novel microstrip transformer for superconducting microelectronics. H.K. Olsson p1152
Open-cavity resonator as high-Q microstrip circuit element. K.D. Stephan, S.L. Young and S.C. Wong p1028 e1397
Probe compensation in thick microstrip patches. P.S. Hall p606
Radiation characteristics of microstrip arrays with parasitic elements. R.Q. Lee, R. Acosta and K.F. Lee p835
Resonant frequency of electrically thick rectangular microstrip antennas. R. Garg and S.A. Long p1149
Very broadband flat coupling hybrid ring. A.S. Wright and S.K. Judah p47
Wideband microstrip balanced mixer. R.S. Tahim, K. Chang and K.A. Hummer p767

MICROWAVE AMPLIFIERS

Measurement of flicker phase noise of 1·4 GHz MESFET amplifier at temperatures between 300 K and 1·26 K. M.D. Hürlimann and W.N. Hardy p283
Microwave amplifier based RF optical receivers. S.R. Cochran p1283
Monolithic 2–6 GHz limiting amplifier. R. Majidi-Ahy, M. Omori and E. Stoneham p910

MICROWAVE ANTENNAS

Interpretation of compact range measurements. R.C. Brown p263
Optical feed for a phased array microwave antenna. M. Tamburrini, M. Parent, L. Goldberg and D. Stillwell p680

MICROWAVE CIRCUITS AND SYSTEMS

10 GHz space power combiner with parasitic injection locking. R.J. Dinger, D.J. White and D.R. Bowling p397
1·3 μm 35 km fibre-optic microwave multicarrier transmission system for satellite earth stations. W.I. Way, M. Krain and R.S. Wolff p400
20 GHz frequency-divider silicon bipolar MMIC. I. Kipnis p1085
8·8 Gbit/s travelling-pulse word generator. N. Mulombe, J. Kahlert, W. Piscalar and G. Seehausen p703
Acetylene black: a single-layer microwave absorber. A. Kumar p184
Analysis of bilateral finline couplers. D. Mirshekar-Syahkal and B. Jia p577
Analysis of microstripline coupled to microstrip antenna. X.Z. Gao and K. Chang p694
Characteristics of inhomogeneous coupled cylindrical striplines. C.J. Reddy and M.D. Deshpande p821
Complete and rigorous analysis of electromagnetically coupled transverse microstrip dipole. P. Lepeltier, J.M. Floc'h and J. Citerne p822
Computer-aided noise analysis of linear multiport networks. G.I. Vasilescu p351
Dielectrically shielded microstrip (DSM) lines. K. Chang and J. Klein p535
Direct fibre-optic transmission of entire microwave satellite antenna signals. J.E. Bowers, A.C. Chipaloski, S. Boodaghians and J.W. Carlin p185
Dispersion characteristics of microstrip lines in the vicinity of a coplanar ground. J. Fang, X. Zhang and K.K. Mei p1142
Efficient calculation of partial derivatives in nonlinear conductances driven by periodic input signals. C. Camacho-Peñalosa, L. Mariscal-Rico and A. Alonso-Pardo p565
Electro-optic sampling measurement of coplanar waveguide (coupled slot line) modes. R. Majidi-Ahy, K.J. Weingarten, M. Riaziat, B.A. Auld and D.M. Bloom p1262
Experimental determination of finline post discontinuity parameters: application to stopband and lowpass filters. P. Saquet and A. Essebar p691
GaAs monolithic microwave integrated circuit trimming using laser-direct-written tungsten microstrip lines. C.L. Chen, J.G. Black, L.J. Mahoney, S.P. Doran, W.E. Courtney, D.J. Ehrlich and R.A. Murphy p402
High-efficiency quasimicrowave GaAs FET power amplifier. T. Nojima, S. Nishiki and K. Chiba p512
Modelling microstrip step discontinuities by the transmission matrix. J.S. Hong and J.M. Shi p678
Monolithic 2–6 GHz limiting amplifier. R. Majidi-Ahy, M. Omori and E. Stoneham p910
Novel contacting method for millimetre-wave mixers. K. Künzi and J. Broennimann p107
Novel feedline for linearly tapered slotline antenna (LTSA). N. Popović p1285
Numerical convergence in calculating the propagation constants by the transverse modal analysis technique. T.N. Chang p40
Open-cavity resonator as high-Q microstrip circuit element. K.D. Stephan, S.L. Young and S.C. Wong p1028 e1397
Simple method for analysing finlines with extremely narrow slotwidth and thick fins. Xu Shanjia p677
Wideband microstrip balanced mixer. R.S. Tahim, K. Chang and K.A. Hummer p767

MICROWAVE DEVICES AND COMPONENTS

Approach to modelling of microstrip-microslot applicator. R. Ledee, P. Pribetich, P. Kennis and M. Chive p829
Broadband continuously variable microwave phase shifter employing a distributed Schottky contact on silicon. V.M. Hietala, Y.R. Kwon and K.S. Champlin p675
Design of crystal oscillators with fundamental frequencies in the UHF and microwave regions. G. Gonzalez and B. Avanic p1379
Determination of coupling capacitance of underpasses, air bridges and crossings in MICs and MMICs. L. Wiemer and R.H. Jansen p344

Ferrite tunable metal insert filter. J. Uher, J. Bornemann and F. Arndt p804
Fully implanted GaAs millimetre-wave mixer diode using high energy implantation. P. Thompson, H. Dietrich, Y. Anand, V. Higgins and J. Hillson p725
GaAs monolithic Schottky junction pairs for W-band crossbar mixers. Y. Anand and A. Christou p727
Growth temperature dependence of low-noise MESFET in molecular-beam epitaxy. Y.C. Chou, C.T. Lee, C.D. Chen and K.C. Chu p7
High carrier rejection for a 3·7 to 4·2 GHz BPSK modulator. J. Larroque, J. Sombrin, L. Lapierre and J.F. Sautereau p305
Low-loss and lightweight on-board 20 GHz-band pill-box-type directional filter. I. Ohtomo and H. Kumazawa p582
Measurement of flicker phase noise of 1·4 GHz MESFET amplifier at temperatures between 300 K and 1·26 K. M.D. Hürlimann and W.N. Hardy p283
Measurements of high-T_c superconductivity in a microwave cavity. T.M.P. Percival, J.S. Thorn and R. Driver p1225
Microwave characterisation of 1 μm-gate $Al_{0.48}In_{0.52}As/Ga_{0.47}In_{0.53}As/InP$ MODFETs. L.F. Palmateer, P.J. Tasker, T. Itoh, A.S. Brown, G.W. Wicks and L.F. Eastman p53
Millimetre-wave performance of state-of-the-art MESFET, MODFET and PBT transistors. R.J. Trew and M.B. Steer p149
Novel 93 GHz injection-locked impatt oscillator. D.H. Evans and R.N. Bates p771
Novel microstrip transformer for superconducting microelectronics. H.K. Olsson p1152
Novel varactor-tuned millimetre-wave Gunn oscillator. R.N. Bates and S. Feeney p714
Observations on 2 and 7·5 GHz microwave links during dust storms. S.I. Ghobrial, M.A. Hemeidi and M.E. Tawfig p44
Optoelectronic millimetre-wave switching using a finline-on-silicon substrate. K. Uhde p1155
Refractory self-aligned gate technology for GaAs microwave FETs and MMICs. A.E. Geissberger, R.A. Sadler, E.L. Griffin, I.J. Bahl and M.L. Balzan p1073
Very broadband flat coupling hybrid ring. A.S. Wright and S.K. Judah p47

MICROWAVE FILTERS

Ferrite tunable metal insert filter. J. Uher, J. Bornemann and F. Arndt p804
Low-loss and lightweight on-board 20 GHz-band pill-box-type directional filter. I. Ohtomo and H. Kumazawa p582
Nonreciprocal effects in an azimuthally magnetised millimetre-wave solid-plasma circular guide. V.I. Miteva and K.P. Ivanov p118

MICROWAVE LINKS

Case study of line-of-sight microwave multipath propagation. K.H. Craig and G.R. Kennedy p483
Improved Prony algorithm to identify multipath components. W.H. Lau, J. Austin and E. Vilar p1059
Observations on 2 and 7·5 GHz microwave links during dust storms. S.I. Ghobrial, M.A. Hemeidi and M.E. Tawfig p44

MICROWAVE MEASUREMENT

Case study of line-of-sight microwave multipath propagation. K.H. Craig and G.R. Kennedy p483
Determination of coupling capacitance of underpasses, air bridges and crossings in MICs and MMICs. L. Wiemer and R.H. Jansen p344
Measurements of high-T_c superconductivity in a microwave cavity. T.M.P. Percival, J.S. Thorn and R. Driver p1225
Thermometry of impedances by correlation radiometry. P. Lauer, Y. Leroy, J.C. Van de Velde and A. Mamouni p1348

MICROWAVE OSCILLATORS

Design of crystal oscillators with fundamental frequencies in the UHF and microwave regions. G. Gonzalez and B. Avanic p1379
High-quality factors for a sapphire-loaded superconducting cavity resonator. S.K. Jones and D.G. Blair p817
Novel 93 GHz injection-locked impatt oscillator. D.H. Evans and R.N. Bates p771
Novel varactor-tuned millimetre-wave Gunn oscillator. R.N. Bates and S. Feeney p714

MICROWAVE RADIATION

Acetylene black: a single-layer microwave absorber. A. Kumar p184
Microwave energy scattered off building surfaces shows strong dependence on orientation of city blocks. A. Ranade and A.R. Noerpel p922

MICROWAVES

Acetylene black: a single-layer microwave absorber. A. Kumar p184

MIXERS

Fully implanted GaAs millimetre-wave mixer diode using high energy implantation. P. Thompson, H. Dietrich, Y. Anand, V. Higgins and J. Hillson p725
GaAs monolithic Schottky junction pairs for W-band crossbar mixers. Y. Anand and A. Christou p727
Novel contacting method for millimetre-wave mixers. K. Künzi and J. Broennimann p107
Novel optically pumped electronic mixer using a Mott diode structure. N.J. Gomes and A.J. Seeds p1084
Wideband microstrip balanced mixer. R.S. Tahim, K. Chang and K.A. Hummer p767

MOBILE RADIO SYSTEMS

Characterising the UHF factory radio channel. T.S. Rappaport and C.D. McGillem p1015
Combined space and adaptive correlation diversity in the CD900 system. W.H. Lam and R. Steele p496
Half-bit offset decision frequency detection of differentially encoded GMSK signals. K. Ohno and F. Adachi p1311
Outage probability calculations for a mobile radio system having multiple Rayleigh interferers. K.W. Sowerby and A.G. Williamson p600
Outage probability calculations for a mobile radio system having two log-normal interferers. K.W. Sowerby and A.G. Williamson p1345
Radiowave propagation into and within a building at 927 MHz. P.J. Barry and A.G. Williamson p248

MODEL ANALYSIS

Numerical convergence in calculating the propagation constants by the transverse modal analysis technique. T.N. Chang p40
State-space models using simplified Routh approximation method. G.V.K.R. Sastry and V. Krishnamurthy p1300

MODELLING

Equivalent circuit modelling and derivative characterisation of 1·3 μm injection lasers. D.E. Ackley p1354
General probability density function of packet service times for computer networks. M. Ilyas p31
MOSFET model continuous from weak to strong inversion. M.M. Abu-Zeid and G.G. de Jong p1299
Monte Carlo simulation of GaAs Schottky barrier behaviour. C.M. Maziar and M.S. Lundstrom p61
Temperature distribution on ceramic substrates. E. Boone, G. De Mey and L. Rottiers p26
Transmission-line model for two-port rectangular microstrip patches with ports at the nonradiating edges. A. Benalla and K.C. Gupta p882

MODULATION

1 Gbit/s automatic-power-control-free zero-bias modulation of very-low threshold MQW laser diodes. M. Nakamura, H. Furuyama and A. Kurobe p1352
Alignment of polarisation-maintaining fibres by temperature modulation. G.R. Walker and N.G. Walker p689
Embedding data in DSB-AM using zero-synchronous modulation. G.B. Lockhart, T. Bayes, A.A.A. Mehdi and Y.O. Al-Jalili p745
Formulas for direct frequency modulation response of two-electrode diode lasers: proposals for improvement. O. Nilsson, L. Gillner and E. Goobar p1371
Gigabit QPSK modulator. R. Trambarulo, M.V. Schneider and M.J. Gans p998
Half-bit offset decision frequency detection of differentially encoded GMSK signals. K. Ohno and F. Adachi p1311
Multichannel intermodulation distortion in high-speed GaInAsP lasers. P. Iannone and T.E. Darcie p1361
Optimised pulse-width modulation method of forced commutated cycloconvertor. D.-H. Shin, G.-H. Cho and S.-B. Park p760
SPICE simulation of laser diode modules. B. Wedding p983
Solving nonlinear equations of harmonic elimination PWM in power control. P. Enjeti and J.F. Lindsay p656

MODULATORS

Coded phase-reversal $LiNbO_3$ modulator with bandwidth greater than 20 GHz at 1·3 μm wavelength. R.L. Jungerman, C.A. Johnsen, D.W. Dolfi and M. Nazarathy p172
GaInAs/InP waveguide multiple-quantum-well optical modulator with 9 dB on/off ratio. K. Wakita, S. Nojima, K. Nakashima and Y. Kawaguchi p1067
Gigabit QPSK modulator. R. Trambarulo, M.V. Schneider and M.J. Gans p998
Guided-wave GaAs/AlGaAs FET optical modulator based on free-carrier-induced bleaching. J.H. Abeles, W.K. Chan, A. Kastalsky, J.P. Harbison, L.T. Florez and R. Bhat p1302
High carrier rejection for a 3·7 to 4·2 GHz BPSK modulator. J. Larroque, J. Sombrin, L. Lapierre and J.F. Sautereau p305
High-speed GaInAsP/InP buried-heterostructure optical intensity modulator with semi-insulating InP burying layers. H. Soda, K. Nakai, H. Ishikawa and H. Imai p1232
Integration of GaAs MESFET drivers with GaAs directional-coupler electro-optic modulators. J.H. Abeles, W.K. Chan, F.K. Shokoohi, R. Bhat and M.A. Koza p1037

MULTIPLEXERS AND MULTIPLEXING

Data clock jitter in supersampling multiplex transmission. R. Gangopadhyay and P. Cochrane p1203
Frequency stabilisation of FDM optical signals originating from different locations. B. Glance, J. Stone, P.J. Fitzgerald, K.J. Pollock, C.A. Burrus and L.W. Stulz p1243
Low-loss and lightweight on-board 20 GHz-band pill-box-type directional filter. I. Ohtomo and H. Kumazawa p582
Measured pulse-stuffing jitter in asynchronous DS-1/SONET multiplexing with and without stuff-threshold modulation circuit. W.D. Grover, T.E. Moore and J.E. McEachern p959
Multiplexing of interferometric sensors using phase-generated carrier techniques. A. Dandridge, A.B. Tveten, A.D. Kersey and A.M. Yurek p665 e867
Sampled optical time-division multiplexing of asynchronous data. P.J. Chidgey and D.W. Smith p1228
Two-channel system demonstration of differential frequency-deviation multiplexing. T.E. Darcie, C.A. Burrus, A.H. Gnauck, B.L. Kasper and J.R. Talman p1278

MULTIVARIABLE SYSTEMS

Family of reduced-order models for linear multivariable systems. A.M. Eydgahi and H. Singh p1178

NETWORKS AND NETWORK THEORY

150 km optical fibre transmission network experiment with 2 Gbit/s throughput. L.C. Blank, E.G. Bryant, A. Lord, J.M. Boggis and W.A. Stallard p977
Connection-based media access for multichannel local and metropolitan area networks. B.P. Mohanty and T.D. Todd p1237
Crossconnection of wavelength-division-multiplexed high-speed channels. H. Kobrinski p974
Demonstration of high capacity in the LAMBDANET architecture: a multiwavelength optical network. H. Kobrinski, R.M. Bulley, M.S. Goodman, M.P. Vecchi, C.A. Brackett, L. Curtis and J.L. Gimlett p824
Methods for the connection of signalling units to switching networks. A. Jajszczyk and W. Kabaciński p443
Passive optical local networks for telephony applications and beyond. J.R. Stern, J.W. Ballance, D.W. Faulkner, S. Hornung, D.B. Payne and K. Oakley p1255

NOISE

Avalanche noise associated with gate current of Si JFET. J.M. Peransin, D. Rigaud and R. Alabedra p970

Deterministic-chaotic variably coloured noise. R.H.T. Bates and A.R. Murch p995
Impact of 1/*f*-type FM noise on coherent optical communications. K. Kikuchi p885
Low-noise D-band impatt oscillators. J. Wenger and S. Huber p475
Measurement of flicker phase noise of 1·4 GHz MESFET amplifier at temperatures between 300 K and 1·26 K. M.D. Hürlimann and W.N. Hardy p283
Noise performance of Gbit/s tuned optical receivers. J.X. Kan, G. Jacobsen and E. Bødtker p434
Rician envelope estimation and confidence intervals in low signal/noise levels. B.G. Stewart and J.F.L. Simmons p832
Statistics of phase noise in single-mode semiconductor lasers: free-running, weak external feedback and injection-locking configurations. A. Mecozzi, S. Piazzolla, A. Sapia and P. Spano p1183

NOISE GENERATORS

Deterministic-chaotic variably coloured noise. R.H.T. Bates and A.R. Murch p995

NONLINEAR NETWORKS

Numerical technique for determining steady-state response of nonlinear circuits to multitone input signals. C. Camacho-Peñalosa p828

NONLINEAR OPTICS

All-optical switching in prism coupling to semiconductor-doped glass waveguides. G. Assanto, A. Gabel, C.T. Seaton, G.I. Stegeman, C.N. Ironside and T.J. Cullen p484
Efficiency frequency-doubling in a poled PVDF copolymer guest/host composite. J.R. Hill, P.L. Dunn, G.J. Davies, S.N. Oliver, P. Pantelis and J.D. Rush p700
Finite-element solution of arbitrarily nonlinear, graded-index slab waveguides. K. Hayata, M. Koshiba and M. Suzuki p429 e1397
Optical third-harmonic generation from poly(*p*-phenylenevinylene) thin films. T. Kaino, K.-I. Kubodera, S. Tomaru, T. Kurihara, S. Saito, T. Tsutsui and S. Tokito p1095
Optical third-harmonic generation from polydiacetylene thin films deposited by vacuum evaporation. S. Tomaru, K. Kubodera, S. Zembutsu, K. Takeda and M. Hasegawa p595
Polarisation state stabilisation in optically nonlinear birefringent fibres. A. Vatarescu p379
Resolution of moment equations in a nonlinear optical amplifier. S. Ruiz-Moreno, G. Junyent, J.R. Usandizaga and A. Calzada p15
Second-harmonic generation in single crystals of 2-(N,N-dimethylamino)-5-nitroacetanilide (DAN) at 1·3 μm. P.V. Kolinsky, R.J. Chad, R.J. Jones, S.R. Hall, P.A. Norman, D. Bloor and J.S. Obhi p791
Semiconductor-doped fibre waveguides exhibiting picosecond optical nonlinearity. B.J. Ainslie, H.P. Girdlestone and D. Cotter p405

NONLINEAR SYSTEMS

Efficient calculation of partial derivatives in nonlinear conductances driven by periodic input signals. C. Camacho-Peñalosa, L. Mariscal-Rico and A. Alonso-Pardo p565
Solving nonlinear equations of harmonic elimination PWM in power control. P. Enjeti and J.F. Lindsay p656

OPERATIONAL AMPLIFIERS

Design of a high-gain, single-stage operational amplifier for GaAs switched-capacitor filters. C. Toumazou and D.G. Haigh p752
Generation of new two-amplifier synthetic floating inductors. R. Senani p1202
Optical amplifier configurations with low polarisation sensitivity. G. Großkopf, R. Ludwig, R.G. Waarts and H.G. Weber p1387
Spike-free switched-capacitor circuits. H. Matsumoto and K. Watanabe p428
Switched-capacitor biquad with low influence of finite gains. J. Mulawka, A. Konczykowska and M. Bon p1198
Temperature compensation of OTA-based filters and amplifiers. H.S. Malvar and M. Luettgen p890

OPTICAL COMMUNICATION

100 Mbit/s PSK heterodyne experiment using a travelling-wave laser amplifier. R.C. Steele and I.W. Marshall p296
12·5 Gbit/s fibre-optic network using all-optical processing. P.R. Prucnal, D.J. Blumenthal and M.A. Santoro p629
150 km optical fibre transmission network experiment with 2 Gbit/s throughput. L.C. Blank, E.G. Bryant, A. Lord, J.M. Boggis and W.A. Stallard p977
16 × 8 space switch for 2·24 Gbit/s transmission. L. Rønn and P. Deichmann p236
16 Gbit/s fibre transmission experiment using optical time-division multiplexing. R.S. Tucker, G. Eisenstein, S.K. Korotky, L.L. Buhl, J.J. Veselka, G. Raybon, B.L. Kasper and R.C. Alferness p1270
1·2 Gbit/s optical DPSK heterodyne detection transmission system using monolithic external-cavity DFB LDs. S. Yamazaki, S. Murata, K. Komatsu, Y. Koizumi, S. Fujita and K. Emura p860
2 Gbit/s optical CPFSK heterodyne transmission through 200 km single-mode fibre. K. Iwashita and N. Takachio p341
2 Gbit/s timing recovery circuit using dielectric resonator filter. D.J. Millicker and R.D. Standley p738
5 GHz-spaced, eight-channel, guided-wave tunable multi/demultiplexer for optical FDM transmission systems. H. Toba, K. Oda, N. Takato and K. Nosu p788
5 Gbit/s transmission system experiment over 111 km of optical fibre. R. Heidemann, U. Scholz and B. Wedding p1030
60-channel FM video subcarrier multiplexed optical communication system. R. Olshansky and V.A. Lanzisera p1196
Amplifier-induced crosstalk in multichannel coherent lightwave systems. G.P. Agrawal p1175
Bandwidth of directional-coupler wavelength filters made of dissimilar optical fibres. O. Leminger and R. Zengerle p241
Bidirectional optical transmission using polarised light waves. Y. Sasaki, K. Tajima and I. Yokohama p692
Chirp-induced penalty in optical fibre systems. J.J. O'Reilly and H.J.A. Silva p992
Coherent lightwave transmission at 2 Gbit/s over 170 km of optical fibre using phase modulation. A.H. Gnauck, R.A. Linke, B.L. Kasper, K.J. Pollock, K.C. Reichmann, R. Valenzuela and R.C. Alferness p286
Coherent optical fibre system with Zeeman lasers. Wu Yizun, Tian Feng, Yang Xinwei and Yu Tong p49
Coherent transmission using an external waveguide Bragg reflector laser with direct frequency modulation. N.A. Olsson, B.H. Johnson, H.J. Lee, C.H. Henry, R.F. Kazarinov, D.A. Ackerman and P.J. Anthony p687
Coupling efficiency and sensitivity of an LED to a single-mode fibre. D.N. Christodoulides, L.A. Reith and M.A. Saifi e251
Crossconnection of wavelength-division-multiplexed high-speed channels. H. Kobrinski p974
Crosstalk penalty in a two-channel ASK heterodyne detection system with non-negligible laser linewidth. Y.K. Park, S.W. Granlund, C.Y. Kuo, M. Dixon, T.W. Cline, R.W. Smith, N.K. Dutta and G. Vannucci p1291
Demonstration of high capacity in the LAMBDANET architecture: a multiwavelength optical network. H. Kobrinski, R.M. Bulley, M.S. Goodman, M.P. Vecchi, C.A. Brackett, L. Curtis and J.L. Gimlett p824
Design parameters for a 1·3 μm connectorised low-cost laser package for subscriber loop using graded-index lenses. L.A. Reith and J.W. Mann p520
Diode-laser-pumped Nd^{3+}-doped fibre laser operating at 938 nm. L. Reekie, I.M. Jauncey, S.B. Poole and D.N. Payne p884
Duplex–diplex optical transmission in the 1300 nm and 1500 nm fibre windows: an installed system. A.R. Hunwicks and P.A. Rosher p542
Dynamic polarisation fluctuation characteristics of optical fibre submarine cable coupling under periodic variable tension. Y. Namihira, Y. Horiuchi and H. Wakabayashi p1201
Endless polarisation control using four fibre squeezers. N.G. Walker and G.R. Walker p290
Endless polarisation state matching control experiment using two controllers of finite control range. C.J. Mahon and G.D. Khoe p1234
Evaluation of crosstalk penalty in multichannel ASK heterodyne optical communication systems. G.P. Agrawal p906
FDM-FSK star network with a tunable optical filter demultiplexer. I.P. Kaminow, P.P. Iannone, J. Stone and L.W. Stulz p1102
Fabrication of twin-rectangular-cored fibre couplers. M. Green and T.J. Tate p593 e867
Fast frequency-tunable external-cavity laser. B. Glance, C.A. Burrus and L.W. Stulz p98
Four-port homodyne receiver for optical fibre communications comprising phase and polarisation diversities. T. Okoshi and Y.H. Cheng p377
Frequency stabilisation of FDM optical signals originating from different locations. B. Glance, J. Stone, P.J. Fitzgerald, K.J. Pollock, C.A. Burrus and L.W. Stulz p1243
Frequency stabilisation of FDM optical signals. B. Glance, P.J. Fitzgerald, K.J. Pollack, J. Stone, C.A. Burrus, G. Eisenstein and L.W. Stulz p750
GaAs/GaAlAs rib waveguide grating filters for $\lambda = 1{\cdot}5\ \mu m$. A. Yi-Yan, H. Carru, P. Correc, J.P. Chandouineau, L. Dugrand and M. Carre p622
GaInAs/InP waveguide multiple-quantum-well optical modulator with 9 dB on/off ratio. K. Wakita, S. Nojima, K. Nakashima and Y. Kawaguchi p1067
Gigabit optical transmitter GaAs MESFET IC. K. Utsumi, A. Tezuka, K. Nishii, K. Bando, K. Inoue and T. Onuma p374
Guided-wave multi/demultiplexers with compensation for centre wavelength shift by fabrication process fluctuations. K. Imoto, H. Sano and M. Miyazaki p735
Guided-wave multi/demultiplexers with high stopband rejection. K. Imoto, H. Sano, M. Miyazaki and Y. Takasaki p472
High-speed waveguide optical modulator made from GaSb/AlGaSb multiple quantum wells (MQWs). T.H. Wood, E.C. Carr, C.A. Burrus, R.S. Tucker, T.-H. Chiu and W.-T. Tsang p540
High-speed, polyimide-based semi-insulating planar buried heterostructures. J.E. Bowers, U. Koren, B.I. Miller, C. Soccolich and W.Y. Jan p1263
Higher-density single-mode optical fibre cables than 1 fibre/mm^2, containing hundreds of fibres. Y. Katsuyama, S. Hatano, K. Hogari and T. Kokubun p481
Impact of 1/*f*-type FM noise on coherent optical communications. K. Kikuchi p885
Impact of laser intensity noise on ASK two-port optical homodyne receivers. L.G. Kazovsky, A.F. Elrefaie, P. Meissner, R. Welter, P. Crespo, J. Gimlett and R.W. Smith p871
Improved design of tuned optical receivers. G. Jacobsen, J.X. Kan and I. Garrett p787
InGaAsP Y-branch grating demultiplexer. C. Cremer, G. Heise, R. März, H. Riechert and M. Schienle p321
InGaAsP carrier injection modulator integrated with DFB LD. M. Yamaguchi, K. Emura, M. Kitamura, I. Mito and K. Kobayashi p190
Interferometric conversion of laser phase noise to intensity noise by single-mode fibre-optic components. M.M. Choy, J.L. Gimlett, R. Welter, L.G. Kazovsky and N.K. Cheung p1151
Intermodulation distortion in optical amplifiers from carrier-density modulation. T.E. Darcie, R.M. Jopson and R.W. Tkach p1392
Linewidth reduction by coupled phase-shift distributed-feedback lasers. T. Kimura and A. Sugimura p1014
Low-noise 8 GHz PIN/FET optical receiver. J.L. Gimlett p281
Low-noise LD module with an optical isolator using a highly Bi-substituted garnet film. K. Matsuda, H. Minemoto, K. Toda, O. Kamada and S. Ishizuka p203
Low-noise erbium-doped fibre amplifier operating at 1·54 μm. R.J. Mears, L. Reekie, I.M. Jauncey and D.N. Payne p1026
Low-threshold GaAs/GaAlAs buried heterostructure laser with an ion-beam-etched quarter ring cavity. P. Sansonetti, H. Ribot, J. Brandon, L. Menigaux, L. Dugrand and N. Bouadma p485
Measurement of carrier-density mediated intermodulation distortion in an optical amplifier. R.M. Jopson, T.E. Darcie, K.T. Gayliard, R.T. Ku, R.E. Tench, T.C. Rice and N.A. Olsson p1394
Microwave amplifier based RF optical receivers. S.R. Cochran p1283
Miniature micromachined Fabry–Perot interferometers in silicon. S.R. Mallinson and J.H. Jerman p1041
Narrow-bandwidth optical waveguide transmission filters. K.O. Hill, D.C. Johnson, F. Bilodeau and S. Faucher p465
Narrow-linewidth laser with a prism grating/GRIN rod lens combination serving as external cavity. J. Wittmann and G. Gaukel p524
New design concept for a narrowband wavelength-selective optical tap and combiner. D.C. Johnson, K.O. Hill, F. Bilodeau and S. Faucher p668
New polarisation-insensitive detection technique for coherent optical fibre heterodyne communications. A.D. Kersey, A.M. Yurek, A. Dandridge and J.F. Weller p924
New proposal for a multigigabit/s clock recovery IC based on a standard silicon bipolar technology. Z. Wang and U. Langmann p454
Noise performance of Gbit/s tuned optical receivers. J.X. Kan, G. Jacobsen and E. Bødtker p434
Nonlinear distortion produced by an injection-locked laser. V. O'Byrne and J.J. O'Reilly p955
Novel all-electrical scheme for dynamic semiconductor laser-to-fibre coupling control. P.A. Andrekson and A. Alping p1275
Novel fibre break locator for optical duplex transmission systems. P. Cochrane, A.R. Hunwicks and P.A. Rosher p440

OTDR in a 147 km single-mode fibre in 1·55 μm wavelength region using an LD and GaInAs/InP APD at room temperature. Y. Namihira, Y. Horiuchi, H. Wakabayashi, T. Oshimi, K. Kitagawa and T. Ooka p1219
Observation of crosstalk due to four-wave mixing in a laser amplifier for FDM transmission. K. Inoue p1293
Observation of two-colour gain saturation in an optical amplifier. R.M. Jopson, K.L. Hall, G. Eisenstein, G. Raybon and M.S. Whalen p510
Optical FSK transmission system using a phase-diversity receiver. M.J. Pettitt, D. Remedios, A.W. Davis, A. Hadjifotiou and S. Wright p1075
Optical amplifier configurations with low polarisation sensitivity. G. Großkopf, R. Ludwig, R.G. Waarts and H.G. Weber p1387
Optical homodyne receiver with a six-port fibre coupler. T.D. Stephens and G. Nicholson p1106
Optical receiver with optical feedback. G.S. Forsberg p478 e663
Optical sampling with gain-switched, pulse-compressed, distributed feedback laser diodes. D.L. Franzen, Y. Yamabayashi and T. Kanada p289
Optical self-homodyne DPSK transmission at 1 and 2 Gbit/s over 86 km of fibre. R.C. Giles and K.C. Reichmann p1180
Optical time-division multiplexed transmission system experiment at 8 Gbit/s. G. Eisenstein, R.S. Tucker, S.K. Korotky, G. Raybon, J.J. Veselka, L.L. Buhl, A.H. Gnauck, B.L. Kasper and R.C. Alferness p1115
Optical-fibre Fabry–Perot frequency discriminator for communications applications. L.J. Cimini, J. Stone and L.L. Buhl p463
Optimal local oscillator power in PSK homodyne systems. R. Gross p124
Optimum control beam angle for a biased optical bistable device. R. Cush p619
Optoelectronic time division multiplexing. D.J. Albares, G.A. Garcia, C.T. Chang and R.E. Reedy p327
Passive optical local networks for telephony applications and beyond. J.R. Stern, J.W. Ballance, D.W. Faulkner, S. Hornung, D.B. Payne and K. Oakley p1255
Picosecond pulse response of a travelling-wave semiconductor laser amplifier. I.W. Marshall, D.M. Spirit and M.J. O'Mahony p818
Polarisation fluctuation in optical-fibre submarine cable under 8000 m deep sea environmental conditions. Y. Namihira, S. Ryu, K. Mochizuki, K. Furusawa and Y. Iwamoto p100 e306
Polarisation transformer on Ti : $LiNbO_3$ with reset-free optical operation for heterodyne/homodyne receivers. H. Heidrich, C.H. von Helmolt, D. Hoffmann, H.-J. Hensel and A. Kleinwächter p335
Polarisation-diversity receiver for coherent FSK communications. T.E. Darcie, B. Glance, K. Gayliard, J.R. Talman, B.L. Kasper and C.A. Burrus p1369
Polarisation-insensitive coherent receiver using a double balanced optical hybrid system. L.D. Tzeng, W.L. Emkey, C.A. Jack and C.A. Burrus p1195
Polarisation-insensitive heterodyne detection using polarisation scrambling. T.G. Hodgkinson, R.A. Harmon and D.W. Smith p513
Polarisation-insensitive operation of coherent FSK transmission system using polarisation diversity. S. Ryu, S. Yamamoto and K. Mochizuki p1382
Polarisation-insensitive optical heterodyne receiver for coherent FSK communications. D. Kreit and R.C. Youngquist p168
Power penalty due to jitter on optical communication systems. K. Schumacher and J.J. O'Reilly p718
Power penalty in bit error rate due to limited transmission bandwidth. T.M. Shen p927
Precise optical heterodyne beat frequency from laser diodes locked to atomic resonances. B. Villeneuve, N. Cyr and M. Tetu p1082
Preservation of polarisation orthogonality through a linear optical system. L.J. Cimini, I.M.I. Habbab, R.K. John and A.A.M. Saleh p1365
SPICE simulation of laser diode modules. B. Wedding p383
Sampled optical time-division multiplexing of asynchronous data. P.J. Chidgey and D.W. Smith p1228
Signal transmission with optical carriers in multimode range of single-mode fibres. R. Ries p71
Simple and effective frequency stabilisation for HeNe lasers at 1·52 μm. G. Fischer p206
Simulataneous amplification of wavelength-division-multiplexed signals by a highly efficient fibre Raman amplifier pumped by high-power semiconductor lasers. N. Edagawa, K. Mochizuki and Y. Iwamoto p196
Single-laser high-selectivity bidirectional transmission system for local-area-network applications. N.A. Olsson and L.L. Buhl p62
Spectral response measurements on polarisation splitting ratio of fused-taper single-mode fibre couplers. Y. Namihira, Y. Horiuchi and H. Wakabayashi p1204
Transformer-tuned front-ends for heterodyne optical receivers. J.X. Kan, I. Garrett and G. Jacobsen p785
Transmission at 1 Gbit/s over 7·4 km of single-mode fibre using an edge-emitting LED and PINFET receiver. M. Stern, D.J. Millicker, A.E. Elrefaie and K. Runge p386
Tunable fibre-extended-cavity laser. M.S. Whalen, K.L. Hall, D.M. Tennant, U. Koren and G. Raybon p313
Two-channel system demonstration of differential frequency-deviation multiplexing. T.E. Darcie, C.A. Burrus, A.H. Gnauck, B.L. Kasper and J.R. Talman p1278
WDM experiment using 1300/1500 nm dual-wavelength LED for single-mode fibre transmission systems. G.-K. Chang, L.A. Reith, H.P. Leblanc and A.K. Chin p1267

OPTICAL CONNECTORS & COUPLERS

All single-mode optical fibre wavelength-tunable WDM with very narrow pass/stopband separations. S.P. Shipley and A. El Fatatry p523
Behaviour of a novel cylindrical glass fibre optical coupler buried in KDP. K.D. Leaver, M. Green and H. Daniel p820
Birefringent-fibre polarisation splitters. K.S. Chiang p908
Coupling efficiency and sensitivity of an LED to a single-mode fibre. D.N. Christodoulides, L.A. Reith and M.A. Saifi e251
Demonstration of high capacity in the LAMBDANET architecture: a multiwavelength optical network. H. Kobrinski, R.M. Bulley, M.S. Goodman, M.P. Vecchi, C.A. Brackett, L. Curtis and J.L. Gimlett p824
Design criterion for low-loss optical coupler tapers. K.S. Chiang p112
Design parameters for a 1·3 μm connectorised low-cost laser package for subscriber loop using graded-index lenses. L.A. Reith and J.W. Mann p520
Determination of coupling coefficient of DFB lasers by a newly proposed method. Y. Hirayama, H. Okuda, H. Furuyama, J. Kinoshita and M. Nakamura p101
Effect of axial compressive force for connection stability in PC optic fibre connectors. R. Nagase, T. Shintaku and E. Sugita p103
Efficient photodiode-waveguide coupling for hybrid integrated optical circuits. M. Yamada, H. Terui, Y. Yamada, A. Himeno and M. Kobayashi p1056
FDM-FSK star network with a tunable optical filter demultiplexer. I.P. Kaminow, P.P. Iannone, J. Stone and L.W. Stulz p1102
Fabrication of twin-rectangular-cored fibre couplers. M. Green and T.J. Tate p593 e867
Fibre couplers composed of unequal cores. A.W. Snyder and A. Ankiewicz e251
Fused couplers: condition for insensitivity to external refractive index. X.H. Zheng and A.W. Snyder p182
Interferometric conversion of laser phase noise to intensity noise by single-mode fibre-optic components. M.M. Choy, J.L. Gimlett, R. Welter, L.G. Kazovsky and N.K. Cheung p1151
Light coupling from a semiconductor laser into a polarisation-maintaining single-mode fibre. W. Eisenhauer and H. Richter p201
New analysis of LED to single-mode fibre coupling. B. Hillerich e1397 e306
Novel all-electrical scheme for dynamic semiconductor laser-to-fibre coupling control. P.A. Andrekson and A. Alping p1275
Optical homodyne receiver with a six-port fibre coupler. T.D. Stephens and G. Nicholson p1106
Optical sampling with gain-switched, pulse-compressed, distributed feedback laser diodes. D.L. Franzen, Y. Yamabayashi and T. Kanada p289
Perturbation analysis of fused tapered single-mode fibre couplers. K.S. Chiang p717
Self-routing fibre-optic networks and switches using multitailed receiver/transmitter units. P.J. Severin p651
Single-mode fibre Y-junction beam-splitter. J.D. Minelly and C.D. Hussey p1087
Single-mode-fibre passive components made in the fused-head-end technique. P.J. Severin p449
Spectral response measurements on polarisation splitting ratio of fused-taper single-mode fibre couplers. Y. Namihira, Y. Horiuchi and H. Wakabayashi p1204
Switching characteristics of a piezoelectrical actuated evanescent-wave directional coupler. H. Berthou and L. Falco p469
Vector modes of six-port couplers. A.J. Stevenson and J.D. Love p1011

OPTICAL DETECTORS

Low-noise D-band impatt oscillators. J. Wenger and S. Huber p475
Synchronous single-photon counting using an Si avalanche photodiode at room temperature. K. Shimizu, M. Fujise and M. Nunokawa p1307

OPTICAL DISPERSION

Interferometric measurements of chromatic and polarisation mode dispersion in highly birefringent single-mode fibres. J.-P. von der Weid, L. Thevenaz and J.-P. Pellaux p151
Low-loss dispersion-shifted polarisation-maintaining fibres. Y. Sasaki, K. Tajima and S. Seikai p279
Mode dispersion for optical fibres of arbitrary cross-section. K.S. Chiang p160
Modulation frequency-shift technique for dispersion measurements in optical fibres using LEDs. L. Thevenaz and J.-P. Pellaux p1078

OPTICAL FIBRES

10 mW superfluorescent single-mode fibre source at 1060 nm. K. Liu, M. Digonnet, H.J. Shaw, B.J. Ainslie and S.P. Craig p1320
12·5 Gbit/s fibre-optic network using all-optical processing. P.R. Prucnal, D.J. Blumenthal and M.A. Santoro p629
16 Gbit/s fibre transmission experiment using optical time-division multiplexing. R.S. Tucker, G. Eisenstein, S.K. Korotky, L.L. Buhl, J.J. Veselka, G. Raybon, B.L. Kasper and R.C. Alferness p1270
1·3 μm 35 km fibre-optic microwave multicarrier transmission system for satellite earth stations. W.I. Way, M. Krain and R.S. Wolff p400
26 km-long polarisation-maintaining optical fibre. Y. Sasaki, K. Tajima and S. Seikai p127
2 Gbit/s optical CPFSK heterodyne transmission through 200 km single-mode fibre. K. Iwashita and N. Takachio p341
34 Mbit/s optical fibre transmission system experiment at a wavelength of 2·4 μm. R.A. Garnham, D.G. Cunningham and W.A. Stallard p1063
5 Gbit/s transmission system experiment over 111 km of optical fibre. R. Heidemann, U. Scholz and B. Wedding p1030
60-channel FM video subcarrier multiplexed optical communication system. R. Olshansky and V.A. Lanzisera p1196
Alignment of polarisation-maintaining fibres by temperature modulation. G.R. Walker and N.G. Walker p689
All single-mode optical fibre wavelength-tunable WDM with very narrow pass/stopband separations. S.P. Shipley and A. El Fatatry p523
Analysis of an interferometric optical fibre detection technique applied to silicon vibrating sensors. M.V. Andres, M.J. Tudor and K.W.H. Foulds p774
Azimuthal filtering technique for effective LP_{11} cutoff wavelength measurement in optical fibres. J.M. Blondy, A.M. Blanc, M. Clapeau and P. Facq p522
Behaviour of a novel cylindrical glass fibre optical coupler buried in KDP. K.D. Leaver, M. Green and H. Daniel p820
Bend losses of higher-order modes in dispersion-flattened multiple-clad optical fibres. H. Schwierz and E.-G. Neumann p1296
Birefringence and polarisation dispersion measurements in high-birefringence single-mode fibres. M. Monerie and F. Alard p198
Birefringence in stress-applied polarisation-maintaining optical fibres. Chen Zhihao and Yao Huihai p1081
Birefringent-fibre polarisation splitters. K.S. Chiang p908
Broadband correlators employing fibre-optic recirculating delay lines. P.V. Gatenby, D.L. Switzer and N. Green p1246
Characterisation of a fibre Raman oscillator using fibre grating reflectors. P.N. Kean, K. Smith, B.D. Sinclair, W. Sibbett, C.J. Rowe and D.C.J. Reid p1241
Chromatic dispersion measurement from Fourier transform of white-light interference patterns. P.L. Francois, F. Alard and M. Monerie p357
Considerations on group delay fitting equations for dispersion-shifted fibres. Y. Miyajima, T. Kawata and Y. Negishi p1381
Coupled mode theory. W. Streifer p315
Determination of nondiagonal component $n_{2\theta\perp}$ of nonlinear refractive index in polarisation-maintaining fibres utilising optical Kerr modulation scheme. T. Morioka and M. Saruwatari p1330
Diode-laser-pumped operation of an Er^{3+}-doped single-mode fibre laser. L. Reekie, I.M. Jauncey, S.B. Poole and D.N. Payne p1076
Direct fibre-optic transmission of entire microwave satellite antenna signals. J.E. Bowers, A.C. Chipaloski, S. Boodaghians and J.W. Carlin p185
Direct interferometric measurement of nonlinear refractive index of optical fibres by crossphase modulation. M. Monerie and Y. Durteste p961
Dispersion of pure GeO_2 glass core and F-doped GeO_2 glass cladding single-mode optical fibre. T. Hosaka, S. Sudo and K. Okamoto p24
Dynamic polarisation fluctuation characteristics of optical fibre submarine cable coupling under periodic variable tension. Y. Namihira, Y. Horiuchi and H. Wakabayashi p1201
Fabrication and characterisation of circularly birefringent helical fibres. R.D. Birch p50

Fabrication of twin-rectangular-cored fibre couplers. M. Green and T.J. Tate p593 e867
Femtosecond single-pass cascade Raman soliton generation at 1·5 μm. A.S. Gouveia-Neto, A.S.L. Gomes, J.R. Taylor, B.J. Ainslie and S.P. Craig p1034
Fibre couplers composed of unequal cores. A.W. Snyder and A. Ankiewicz e251
Fibre-optic magnetic sensor utilising metal-coated fibre. H. Okamura p834
Fields in a bent single-mode fibre. S.J. Garth p373
Fundamental error of recent coupled mode formulations. A.W. Snyder, A. Ankiewicz and A. Altintas p1097
Fused couplers: condition for insensitivity to external refractive index. X.H. Zheng and A.W. Snyder p182
General formalism for the study of nonlinear pulse propagation in optical fibres. A. Kumar and M.S. Sodha p275
Generation of short pulses from CW light by influence of crossphase modulation (CPM) in optical fibres. D. Schadt and B. Jaskorzynska p1090 e1211
High-efficiency Nd-doped fibre lasers using direct-coated dielectric mirrors. M. Shimizu, H. Suda and M. Horiguchi p768
Higher-density single-mode optical fibre cables than 1 fibre/mm^2, containing hundreds of fibres. Y. Katsuyama, S. Hatano, K. Hogari and T. Kokubun p481
Highly efficient linearly polarised Raman generation in a germania-core optical fibre. A.S. Davison and I.H. White p1343
Hybridised sol-gel process for optical fibres. J.B. MacChesney, D.W. Johnson, D.A. Fleming and F.W. Walz p1005
In-line optical fibre filters using dispersive materials. K. Morishita, M.S. Yataki and W.A. Gambling p319
Influence of impurities on loss increase in optical fibre. H. Hanafusa, Y. Hibino, H. Itoh and F. Yamamoto p10
Interferometric conversion of laser phase noise to intensity noise by single-mode fibre-optic components. M.M. Choy, J.L. Gimlett, R. Welter, L.G. Kazovsky and N.K. Cheung p1151
Interferometric measurements of chromatic and polarisation mode dispersion in highly birefringent single-mode fibres. J.-P. von der Weid, L. Thevenaz and J.-P. Pellaux p151
Kerr modulation of signals at 1·3 and 1·5 μm in polarisation-maintaining fibres pumped at 1·06 μm. K.C. Byron p1324
LED pulse distortion in single-mode fibres near the wavelength of zero dispersion. D.N. Christodoulides and M.A. Saifi e251
Low-frequency, submicrogauss fibre-optic magnetometer. F. Bucholtz, A.M. Yurek, K.P. Koo and A. Dandridge p985
Low-loss dispersion-shifted polarisation-maintaining fibres. Y. Sasaki, K. Tajima and S. Seikai p279
Low-noise erbium-doped fibre amplifier operating at 1·54 μm. R.J. Mears, L. Reekie, I.M. Jauncey and D.N. Payne p1026
Macrobends of bow-tie fibres with constant curvature. Chen Yijiang and Huang Hung-chia p159
Methods for fine-tuning the wavelength response of single-mode optical-fibre taper filters. A.C. Boucouvalas and G. Georgiou p410
Microbending losses of bow-tie and similar anisotropic fibres. Chen Yijiang and Huang Hung-chia p157
Mode dispersion for optical fibres of arbitrary cross-section. K.S. Chiang p160
Modulation frequency-shift technique for dispersion measurements in optical fibres using LEDs. L. Thevenaz and J.-P. Pellaux p1078
Monomode fibre polarisation scrambler. A.D. Kersey and A. Dandridge p634
Multiple-wave generation due to four-wave mixing in a single-mode fibre. H.H. Yaffe, R.G. Waarts, E. Lichtman and A.A. Friesem p42
Neodymium-doped fluoro-zirconate fibre laser. M.C. Brierley and P.W. France p815
New bending loss formula explaining bends on loss curve. S.B. Andreasen p1138
New polarisation-insensitive detection technique for coherent optical fibre heterodyne communications. A.D. Kersey, A.M. Yurek, A. Dandridge and J.F. Weller p924
Nitrogen-related absorption bands in optical fibres. J.W. Gilliland and D.R. Powers p144
Novel fibre break locator for optical duplex transmission systems. P. Cochrane, A.R. Hunwicks and P.A. Rosher p440
Novel trial field of single-mode graded-index fibres usable for non-Gaussian field distributions. K. Hayata, M. Koshiba and M. Suzuki e251
Novel type of fibre-optic ring resonator. E. Meissner p683
OTDR in a 147 km single-mode fibre in 1·55 μm wavelength region using an LD and GaInAs/InP APD at room temperature. Y. Namihira, Y. Horiuchi, H. Wakabayashi, T. Oshimi, K. Kitagawa and T. Ooka p1219
Optical frequency shifter using linearly birefringent monomode fibre. C.N. Pannell, R.P. Tatam, J.D.C. Jones and D.A. Jackson p847
Optical self-homodyne DPSK transmission at 1 and 2 Gbit/s over 86 km of fibre. R.C. Giles and K.C. Reichmann p1180
Optimum fibre parameters of low-loss single-mode optical fibres for use in 1·55 μm-wavelength region. Y. Namihira, Y. Horiuchi, M. Kuwazuru, M. Nunokawa and Y. Iwamoto p963
Pattern of radiation from dielectric tapers. X.H. Zheng and A.W. Snyder p1184
Perturbation analysis of fused tapered single-mode fibre couplers. K.S. Chiang p717
Pigtailed high-finesse tunable fibre Fabry–Perot interferometers with large, medium and small free spectral ranges. J. Stone and L.W. Stulz p781
Polarisation fluctuation of submarine-cabled single-mode optical fibres in ocean installation. Y. Namihira, S. Ryu, M. Kuwazuru, K. Mochizuki and Y. Iwamoto p343
Polarisation state stabilisation in optically nonlinear birefringent fibres. A. Vatarescu p379
Power spectral density of CMI-coded TV signal transmitted through fibre-optic heterodyne system. N. Malaviya and G. Jauhari p1072
Practical method of measuring reflection-induced power penalties in single-mode fibre transmission systems. W.C. Young, L. Curtis, N.K. Cheung, S.J. Wang and D.S. Burpee p56
Preferred approaches to the determination of optical fibre mode field diameter. S.C. Fleming p338
Radiation from single-mode helical fibres. J.D. Love and A.W. Snyder p1109
Reduction of high surge voltage on coiled optical fibre submarine cable. H. Sakaguchi and Y. Niiro p1124
Reflectively tapped optical fibre transversal filters. C.-E. Lee, R.A. Atkins and H.F. Taylor p596
Second-harmonic generation in an optical fibre by self-written $\chi^{(2)}$ grating. M.C. Farries, P.St.J. Russell, M.E. Fermann and D.N. Payne p322
Second-harmonic generation in single-mode optical fibres. F.P. Payne p1215
Signal transmission with optical carriers in multimode range of single-mode fibres. R. Ries p71
Simple explicit formula for calculating the LP_{11} mode cutoff frequency. Jiang Shijun p534
Simple method for detecting water penetration into optical fibre cables. A.A. Abramov, V.A. Bogatyrjov, M.M. Bubnov and E.M. Dianov p957
Simple technique for measurement of equalisation wavelength in single-mode optical fibres. A.C. Boucouvalas and S.C. Robertson p215
Simulataneous amplification of wavelength-division-multiplexed signals by a highly efficient fibre Raman amplifier pumped by high-power semiconductor lasers. N. Edagawa, K. Mochizuki and Y. Iwamoto p196
Single-mode fibre Y-junction beam-splitter. J.D. Minelly and C.D. Hussey p1087
Single-mode single-polarisation fibre using resonant absorbing effect. Zheng Xue-heng p14
Single-mode-fibre passive components made in the fused-head-end technique. P.J. Severin p449
Single-polarisation single-mode guidance in stress-induced birefringence fibres with lossy stress-applying sections. K.S. Chiang p506
Soliton propagation in the presence of source chirping and mutual interaction in single-mode optical fibres. C. Desem and P.L. Chu p260
Solution-doping technique for fabrication of rare-earth-doped optical fibres. J.E. Townsend, S.B. Poole and D.N. Payne p329
Spatial filtering method of oblique slit for measurement of refractive-index profile of optical-fibre preforms. P. Skok and M. Miler p859
Spectral attenuation measurement for fluoride glass single-mode fibres by Fourier transform techniques. Y. Ohishi and S. Sakaguchi p272
Spot size, adiabaticity and diffraction in tapered fibres. J.D. Love p993
Switching characteristics of a piezoelectrical actuated evanescent-wave directional coupler. H. Berthou and L. Falco p469
Tables of integrals: misprint in a convolution-type integral with Gauss-Laguerre functions. He-Ming Chen and W. Freude p966 e1211
Theory of twin-core optical fibre frequency shifter. P.L. Chu and A.W. Snyder p1101
Time-domain bandwidth measurements of step-index plastic optical fibres. J. Meier, W. Lieber, W. Heinlein, W. Groh, P. Herbrechtsmeier and J. Theis p1208
Tolerance requirements for the drawing ratio of single-mode fibres with arbitrary refractive-index profile. G. Trommer p79
Ultrafast optical multi/demultiplexer utilising optical Kerr effect in polarisation-maintaining single-mode fibres. T. Morioka, M. Saruwatari and A. Takada p453
Vector modes of six-port couplers. A.J. Stevenson and J.D. Love p1011
Wavelength dependence of a D-fibre optical switch. S.A. Cassidy and P. Yennadhiou p1385
Wholly synthesised fluorine-doped silica optical fibres by sol-gel method. T. Kitagawa, S. Shibata and M. Horiguchi p1295

OPTICAL FILTERS

Bandwidth of directional-coupler wavelength filters made of dissimilar optical fibres. O. Leminger and R. Zengerle p241
Electro-optically tunable, narrowband Ti:$LiNbO_3$ wavelength filter. F. Heismann, L.L. Buhl and R.C. Alferness p572
GaAs/GaAlAs rib waveguide grating filters for $\lambda = 1{\cdot}5\,\mu m$. A. Yi-Yan, H. Carru, P. Correc, J.P. Chandouineau, L. Dugrand and M. Carre p622
In-line optical fibre filters using dispersive materials. K. Morishita, M.S. Yataki and W.A. Gambling p319
Methods for fine-tuning the wavelength response of single-mode optical-fibre taper filters. A.C. Boucouvalas and G. Georgiou p410
Pigtailed high-finesse tunable fibre Fabry–Perot interferometers with large, medium and small free spectral ranges. J. Stone and L.W. Stulz p781
Reflectively tapped optical fibre transversal filters. C.-E. Lee, R.A. Atkins and H.F. Taylor p596

OPTICAL LOGIC

Bistable optical switching and logic elements in photochromic fulgides with single-wavelength illumination. R. Cush, C. Trundle, C.J.G. Kirkby and I. Bennion p419
Dynamic response of an integrated optoelectronic logic device. P. Wheatley, G. Parry, J.E. Midwinter, G. Hill, P. Mistry, M.A. Pate and J.S. Roberts p1249
High-contrast optoelectronic logic device using a waveguide multiple-quantum-well optical modulator. P.J. Bradley, P. Wheatley, G. Parry, J.E. Midwinter, P. Mistry and J.S. Roberts p213
Novel nonresonant optoelectronic logic device. P. Wheatley, P.J. Bradley, M. Whitehead, G. Parry, J.E. Midwinter, P. Mistry, M.A. Pate and J.S. Roberts p92
Optically bistable operation in InGaAs/InAlAs MQW laser diodes using resonant tunnelling effect. Y. Kawamura, K. Wakita, H. Asahi and K. Oe p719
Optimum control beam angle for a biased optical bistable device. R. Cush p619
Tuning characteristics and inverter/inverted-output flip-flop operation of tandem-electrode laser diode. M. Yamaguchi and K. Kikuchi p120

OPTICAL MEASUREMENT

1 THz-bandwidth prober for high-speed devices and integrated circuits. J.A. Valdmanis p1308
Birefringence and polarisation dispersion measurements in high-birefringence single-mode fibres. M. Monerie and F. Alard p198
Direct interferometric measurement of nonlinear refractive index of optical fibres by crossphase modulation. M. Monerie and Y. Durteste p961
Electro-optic sampling measurement of coplanar waveguide (coupled slot line) modes. R. Majidi-Ahy, K.J. Weingarten, M. Riaziat, B.A. Auld and D.M. Bloom p1262
High-sensitivity sampling technique for luminescence time constant measurement. S. Loualiche and E. Pauty p1017
Improved method of measuring loss and phase shifts in waveguide devices. I.D. Henning and P.M. Rodgers p1245
Index profiling of distributed-index lenses by a total reflection method. X. Zhu and K. Iga p626
Interferometric measurements of chromatic and polarisation mode dispersion in highly birefringent single-mode fibres. J.-P. von der Weid, L. Thevenaz and J.-P. Pellaux p151
Laser interferometer using a dual interference method. K.H. Yang, L. Chen and S.Y. Zhang p699
Low-frequency, submicrogauss fibre-optic magnetometer. F. Bucholtz, A.M. Yurek, K.P. Koo and A. Dandridge p985
Modulation frequency-shift technique for dispersion measurements in optical fibres using LEDs. L. Thevenaz and J.-P. Pellaux p1078
Optical sampling of GHz charge density modulation in silicon bipolar junction transistors. A. Black, C. Courville, G. Schultheis and H. Heinrich p783
Optical sampling with gain-switched, pulse-compressed, distributed feedback laser diodes. D.L. Franzen, Y. Yamabayashi and T. Kanada p289
Optically excited resonant diaphragm pressure sensor. D. Uttamchandani, K.E.B. Thornton, J. Nixon and B. Culshaw p152

Practical method of measuring reflection-induced power penalties in single-mode fibre transmission systems. W.C. Young, L. Curtis, N.K. Cheung, S.J. Wang and D.S. Burpee p56

Sideband noise of a large phase carrier in interferometric sensors. K.P. Koo, F. Bucholtz and A. Dandridge p1062

Spectral attenuation measurement for fluoride glass single-mode fibres by Fourier transform techniques. Y. Ohishi and S. Sakaguchi p272

Spectral response measurements on polarisation splitting ratio of fused-taper single-mode fibre couplers. Y. Namihira, Y. Horiuchi and H. Wakabayashi p1204

Synchronous single-photon counting using an Si avalanche photodiode at room temperature. K. Shimizu, M. Fujise and M. Nunokawa p1307

Time-domain bandwidth measurements of step-index plastic optical fibres. J. Meier, W. Lieber, W. Heinlein, W. Groh, P. Herbrechtsmeier and J. Theis p1208

OPTICAL MODULATION

16 Gbit/s direct modulation of an InGaAsP laser. A.H. Gnauck and J.E. Bowers p801

Chirp-induced penalty in optical fibre systems. J.J. O'Reilly and H.J.A. Silva p992

Coded phase-reversal $LiNbO_3$ modulator with bandwidth greater than 20 GHz at 1·3 μm wavelength. R.L. Jungerman, C.A. Johnsen, D.W. Dolfi and M. Nazarathy p172

Coherent transmission using an external waveguide Bragg reflector laser with direct frequency modulation. N.A. Olsson, B.H. Johnson, H.J. Lee, C.H. Henry, R.F. Kazarinov, D.A. Ackerman and P.J. Anthony p687

Determination of nondiagonal component n_{23i} of nonlinear refractive index in polarisation-maintaining fibres utilising optical Kerr modulation scheme. T. Morioka and M. Saruwatari p1330

Effect of residual doping on optimum structure of multiquantum-well optical modulators. D.J. Newson and A. Kurobe p439

Electroabsorption in GaAs quantum-well waveguides. N.K. Dutta and N.A. Olsson p853

GaInAsP buried channel EA modulator for 1·3 μm fibre links. S.C. Lin, X.L. Jing, M.K. Chin, L.M. Walpita, P.K.L. Yu and W.S.C. Chang p1257

GaInAs/InP waveguide multiple-quantum-well optical modulator with 9 dB on/off ratio. K. Wakita, S. Nojima, K. Nakashima and Y. Kawaguchi p1067

Generation of short pulses from CW light by influence of crossphase modulation (CPM) in optical fibres. D. Schadt and B. Jaskorzynska p1090 e1211

Guided-wave GaAs/AlGaAs FET optical modulator based on free-carrier-induced bleaching. J.H. Abeles, W.K. Chan, A. Kastalsky, J.P. Harbison, L.T. Florez and R. Bhat p1302

Heterodyne transmission of a 560 Mbit/s optical signal by means of polarisation shift keying. E. Dietrich, B. Enning, R. Gross and H. Knupke p421

High-contrast optoelectronic logic device using a waveguide multiple-quantum-well optical modulator. P.J. Bradley, P. Wheatley, G. Parry, J.E. Midwinter, P. Mistry and J.S. Roberts p213

High-frequency InGaAs/InP multiple-quantum-well buried-mesa electroabsorption optical modulator. U. Koren, B.I. Miller, R.S. Tucker, G. Eisenstein, I. Bar-Joseph, D.A.B. Miller and D.S. Chemla p621

High-speed 2 × 2 electrically driven spatial light modulator made with GaAs/AlGaAs multiple quantum wells (MQWs). T.H. Wood, E.C. Carr, C.A. Burrus, J.E. Henry, A.C. Gossard and J.H. English p916

High-speed GaInAsP/InP buried-heterostructure optical intensity modulator with semi-insulating InP burying layers. H. Soda, K. Nakai, H. Ishikawa and H. Imai p1232

High-speed modulation characteristics of a GaSb/AlGaAb multiquantum-well laser diode. H. Toba and K. Nosu p188

High-speed waveguide optical modulator made from GaSb/AlGaSb multiple quantum wells (MQWs). T.H. Wood, E.C. Carr, C.A. Burrus, R.S. Tucker, T.-H. Chiu and W.-T. Tsang p540

InGaAsP carrier injection modulator integrated with DFB LD. M. Yamaguchi, K. Emura, M. Kitamura, I. Mito and K. Kobayashi p190

Intermodulation distortion in optical amplifiers from carrier-density modulation. T.E. Darcie, R.M. Jopson and R.W. Tkach p1392

Kerr modulation of signals at 1·3 and 1·5 μm in polarisation-maintaining fibres pumped at 1·06 μm. K.C. Byron p1324

Low-voltage modulator and self-biased self-electro-optic-effect device. J.S. Weiner, A.C. Gossard, J.H. English, D.A.B. Miller, D.S. Chemla and C.A. Burrus p75

Measurement of carrier-density mediated intermodulation distortion in an optical amplifier. R.M. Jopson, T.E. Darcie, K.T. Gayliard, R.T. Ku, R.E. Tench, T.C. Rice and N.A. Olsson p1394

Optical-fibre Fabry–Perot frequency discriminator for communications applications. L.J. Cimini, J. Stone and L.L. Buhl p463

Quantum confined Stark shifts in MOVPE-grown GaAs–AlGaAs multiple quantum wells. M. Whitehead, G. Parry, J.S. Roberts, P. Mistry, P. Li Kam Wa and J.P.R. David p1048

OPTICAL MULTI/DEMULTIPLEXERS

16 Gbit/s fibre transmission experiment using optical time-division multiplexing. R.S. Tucker, G. Eisenstein, S.K. Korotky, L.L. Buhl, J.J. Veselka, G. Raybon, B.L. Kasper and R.C. Alferness p1270

5 GHz-spaced, eight-channel, guided-wave tunable multi/demultiplexer for optical FDM transmission systems. H. Toba, K. Oda, N. Takato and K. Nosu p788

All single-mode optical fibre wavelength-tunable WDM with very narrow pass/stopband separations. S.P. Shipley and A. El Fatatry p523

Crossconnection of wavelength-division-multiplexed high-speed channels. H. Kobrinski p974

Flat passband birefringent wavelength-division multiplexers. W.J. Carlsen and C.F. Buhrer p106

Frequency stabilisation of FDM optical signals. B. Glance, P.J. Fitzgerald, K.J. Pollack, J. Stone, C.A. Burrus, G. Eisenstein and L.W. Stulz p750

Guided-wave multi/demultiplexers with compensation for centre wavelength shift by fabrication process fluctuations. K. Imoto, H. Sano and M. Miyazaki p735

Guided-wave multi/demultiplexers with high stopband rejection. K. Imoto, H. Sano, M. Miyazaki and Y. Takasaki p472

High-performance guided-wave multi/demultiplexer based on novel design using embedded gradient-index waveguides in glass. M. Seki, R. Sugawara, Y. Hanada, E. Okuda, H. Wada and T. Yamasaki p948

InGaAsP Y-branch grating demultiplexer. C. Cremer, G. Heise, R. März, H. Riechert and M. Schienle p321

Low-insertion-loss, tunable wavelength multiplexer on lithium niobate. F. Rottmann and E. Voges p1007

Optical time-division multiplexing and demultiplexing in a multigigabit/second fibre transmission system. R.S. Tucker, G. Eisenstein, S.K. Korotky, U. Koren, G. Raybon, J.J. Veselka, L.L. Buhl, B.L. Kasper and R.C. Alferness p208

Sampled optical time-division multiplexing of asynchronous data. P.J. Chidgey and D.W. Smith p1228

Single-mode-fibre passive components made in the fused-head-end technique. P.J. Severin p449

Two-channel system demonstration of differential frequency-deviation multiplexing. T.E. Darcie, C.A. Burrus, A.H. Gnauck, B.L. Kasper and J.R. Talman p1278

Ultrafast optical multi/demultiplexer utilising optical Kerr effect in polarisation-maintaining single-mode fibres. T. Morioka, M. Saruwatari and A. Takada p453

WDM experiment using 1300/1500 nm dual-wavelength LED for single-mode fibre transmission systems. G.-K. Chang, L.A. Reith, H.P. Leblanc and A.K. Chin p1267

OPTICAL PROCESSING

12·5 Gbit/s fibre-optic network using all-optical processing. P.R. Prucnal, D.J. Blumenthal and M.A. Santoro p629

Frequency stabilisation of FDM optical signals originating from different locations. B. Glance, J. Stone, P.J. Fitzgerald, K.J. Pollock, C.A. Burrus and L.W. Stulz p1243

OPTICAL RECEIVERS

10 GHz optical receiver using a travelling-wave semiconductor laser preamplifier. I.W. Marshall and M.J. O'Mahony p1052

Bidirectional and two-channel transmission system measurements using a semiconductor-laser-amplifier repeater. H.J. Westlake and M.J. O'Mahony p649

Effect of the non-Lorentzian lineshape of semiconductor laser on a PSK coherent heterodyne optical receiver. S. Betti, G. De Marchis, E. Iannone and A. Martellucci p1366

Endless polarisation control using four fibre squeezers. N.G. Walker and G.R. Walker p290

Flicker noise effect on sensitivity of PIN-(GaAs)FET fibre-optic receiver. Moon-Soo Park, Jun-Am Hwang and Young-Yun Chun p631

Four-port homodyne receiver for optical fibre communications comprising phase and polarisation diversities. T. Okoshi and Y.H. Cheng p377

Impact of laser intensity noise on ASK two-port optical homodyne receivers. L.G. Kazovsky, A.F. Elrefaie, P. Meissner, R. Welter, P. Crespo, J. Gimlett and R.W. Smith p871

Improved design of tuned optical receivers. G. Jacobsen, J.X. Kan and I. Garrett p787

Long-wavelength PINFET receiver OEIC on a GaAs-on-InP heterostructure. A. Suzuki, T. Itoh, T. Terakado, K. Kasahara, K. Asano, Y. Inomoto, H. Ishihara, T. Torikai and S. Fujita p954

Low-noise 8 GHz PIN/FET optical receiver. J.L. Gimlett p281

Microwave amplifier based RF optical receivers. S.R. Cochran p1283

Noise performance of Gbit/s tuned optical receivers. J.X. Kan, G. Jacobsen and E. Bødtker p434

Optical FSK transmission system using a phase-diversity receiver. M.J. Pettitt, D. Remedios, A.W. Davis, A. Hadjifotiou and S. Wright p1075

Optical homodyne receiver with a six-port fibre coupler. T.D. Stephens and G. Nicholson p1106

Optical receiver with optical feedback. G.S. Forsberg p478 e663

Optimal local oscillator power in PSK homodyne systems. R. Gross p124

Polarisation transformer on Ti : $LiNbO_3$ with reset-free optical operation for heterodyne/homodyne receivers. H. Heidrich, C.H. von Helmolt, D. Hoffmann, H.-J. Hensel and A. Kleinwächter p335

Polarisation-diversity receiver for coherent FSK communications. T.E. Darcie, B. Glance, K. Gayliard, J.R. Talman, B.L. Kasper and C.A. Burrus p1369

Polarisation-insensitive coherent receiver using a double balanced optical hybrid system. L.D. Tzeng, W.L. Emkey, C.A. Jack and C.A. Burrus p1195

Polarisation-insensitive operation of coherent FSK transmission system using polarisation diversity. S. Ryu, S. Yamamoto and K. Mochizuki p1382

Polarisation-insensitive optical heterodyne receiver for coherent FSK communications. D. Kreit and R.C. Youngquist p168

Transformer-tuned front-ends for heterodyne optical receivers. J.X. Kan, I. Garrett and G. Jacobsen p785

OPTICAL SENSORS

Analysis of an interferometric optical fibre detection technique applied to silicon vibrating sensors. M.V. Andres, M.J. Tudor and K.W.H. Foulds p774

Dual sinusoidal modulation scheme for directional laser Doppler velocimeter. J.E. Schrøder p114

Fabrication of twin-rectangular-cored fibre couplers. M. Green and T.J. Tate p593 e867

High-efficiency Nd-doped fibre lasers using direct-coated dielectric mirrors. M. Shimizu, H. Suda and M. Horiguchi p768

Interferometric fibre-optic sensor using a short-coherence-length source. A.S. Gerges, F. Farahi, T.P. Newson, J.D.C. Jones and D.A. Jackson p1110

Multiplexing of interferometric sensors using phase-generated carrier techniques. A. Dandridge, A.B. Tveten, A.D. Kersey and A.M. Yurek p665 e867

Nonlinear vibrations and hysteresis of micromachined silicon resonators designed as frequency-out sensors. M.V. Andres, K.W.H. Foulds and M.J. Tudor p952

Optical frequency shifter using linearly birefringent monomode fibre. C.N. Pannell, R.P. Tatam, J.D.C. Jones and D.A. Jackson p847

Optically excited resonant beam pressure sensor. D. Uttamchandani, K.E.B. Thornton and B. Culshaw p1333

Optically excited resonant diaphragm pressure sensor. D. Uttamchandani, K.E.B. Thornton, J. Nixon and B. Culshaw p152

Sideband noise of a large phase carrier in interferometric sensors. K.P. Koo, F. Bucholtz and A. Dandridge p1062

OPTICAL SWITCHING

All-optical switching in prism coupling to semiconductor-doped glass waveguides. G. Assanto, A. Gabel, C.T. Seaton, G.I. Stegeman, C.N. Ironside and T.J. Cullen p484

Bistable optical switching and logic elements in photochromic fulgides with single-wavelength illumination. R. Cush, C. Trundle, C.J.G. Kirkby and I. Bennion p419

Geometrical design considerations for a tree-structured optical switch matrix. K. Habara and K. Kikuchi p376

High-speed all-optical gate switching experiment in a Fabry–Perot semiconductor laser amplifier. K. Inoue p921

Implementation of multistage space-switch interconnections via the perfect shuffle. C.J.G. Kirkby p971

Low-drive-voltage and low-loss polarisation-independent $LiNbO_3$ optical waveguide switches. M. Kondo, Y. Ohta, Y. Tanisawa, T. Aoyama and R. Ishikawa p1167
Monolithically integrated optical gate 2 × 2 matrix switch using GaAs/AlGaAs multiple quantum well structure. A. Ajisawa, M. Fujiwara, J. Shimizu, M. Sugimoto, M. Uchida and Y. Ohta p1121
Optically biased $LiNbO_3$ $\Delta\beta$ reversal directional coupler switch. H. Okayama, A. Matoba, R. Shibuya and T. Ishida p1145
Performance of an 8 × 8 $LiNbO_3$ switch matrix as a gigahertz self-routing switching node. D.J. Blumenthal, P.R. Prucnal, L. Thylen and P. Granestrand p1359
Polarisation switching in a single-frequency external-cavity semiconductor laser. T. Fujita, A. Schremer and C.L. Tang p803
Room-temperature 1·55 μm optical bistability in a GaInAs/AlInAs multiple-quantum-well etalon. H. Kawaguchi and Y. Kawamura p1013
Self-routing fibre-optic networks and switches using multitailed receiver/transmitter units. P.J. Severin p651
Single-mode guided-wave optical gate matrix switch using Mach–Zehnder interferometer gates. A. Himeno and M. Kobayashi p887
Switching characteristics of a piezoelectrical actuated evanescent-wave directional coupler. H. Berthou and L. Falco p469
Ti:$LiNbO_3$ intersecting waveguides. G.A. Bogert p72
Tunable optical-wavelength conversion using a multielectrode distributed-feedback laser diode with a saturable absorber. H. Kawaguchi, K. Oe, H. Yasaka, K. Magari, M. Fukuda and Y. Itaya p1088
Wavelength dependence of a D-fibre optical switch. S.A. Cassidy and P. Yennadhiou p1385

OPTICAL TRANSMISSION

12·5 Gbit/s fibre-optic network using all-optical processing. P.R. Prucnal, D.J. Blumenthal and M.A. Santoro p629
150 km optical fibre transmission network experiment with 2 Gbit/s throughput. L.C. Blank, E.G. Bryant, A. Lord, J.M. Boggis and W.A. Stallard p977
15 000 km fibre-optic transmission using a linear repeater. N.A. Olsson p659
16 Gbit/s fibre transmission experiment using optical time-division multiplexing. R.S. Tucker, G. Eisenstein, S.K. Korotky, L.L. Buhl, J.J. Veselka, G. Raybon, B.L. Kasper and R.C. Alferness p1270
1·2 Gbit/s optical DPSK heterodyne detection transmission system using monolithic external-cavity DFB LDs. S. Yamazaki, S. Murata, K. Komatsu, Y. Koizumi, S. Fujita and K. Emura p860
1·3 μm 35 km fibre-optic microwave multicarrier transmission system for satellite earth stations. W.I. Way, M. Krain and R.S. Wolff p400
1·55 μm narrow-linewidth multielectrode DFB laser for coherent FSK transmission. Y. Nakano, Y. Itaya, M. Fukuda, Y. Noguchi, H. Yasaka and K. Oe p826
2 Gbit/s and 600 Mbit/s single-mode fibre transmission experiments using a high-speed Zn-doped 1·3 μm edge-emitting LED. S. Fujita, J. Hayashi, Y. Isoda, T. Uji and M. Shikada p636
2 Gbit/s optical CPFSK heterodyne transmission through 200 km single-mode fibre. K. Iwashita and N. Takachio p341
34 Mbit/s optical fibre transmission system experiment at a wavelength of 2·4 μm. R.A. Garnham, D.G. Cunningham and W.A. Stallard p1063
5 GHz-spaced, eight-channel, guided-wave tunable multi/demultiplexer for optical FDM transmission systems. H. Toba, K. Oda, N. Takato and K. Nosu p788
5 Gbit/s transmission system experiment over 111 km of optical fibre. R. Heidemann, U. Scholz and B. Wedding p1030
Bidirectional and two-channel transmission system measurements using a semiconductor-laser-amplifier repeater. H.J. Westlake and M.J. O'Mahony p649
Bidirectional optical transmission using polarised light waves. Y. Sasaki, K. Tajima and I. Yokohama p692
Chromatic dispersion limitations in coherent optical fibre transmission systems. A.F. Elrefaie, R.E. Wagner, D.A. Atlas and D.G. Daut p756
Coherent lightwave transmission at 2 Gbit/s over 170 km of optical fibre using phase modulation. A.H. Gnauck, R.A. Linke, B.L. Kasper, K.J. Pollock, K.C. Reichmann, R. Valenzuela and R.C. Alferness p286
Coherent transmission using an external waveguide Bragg reflector laser with direct frequency modulation. N.A. Olsson, B.H. Johnson, H.J. Lee, C.H. Henry, R.F. Kazarinov, D.A. Ackerman and P.J. Anthony p687
Considerations on group delay fitting equations for dispersion-shifted fibres. Y. Miyajima, T. Kawata and Y. Negishi p1381
Direct fibre-optic transmission of entire microwave satellite antenna signals. J.E. Bowers, A.C. Chipaloski, S. Boodaghians and J.W. Carlin p185
Duplex–diplex optical transmission in the 1300 nm and 1500 nm fibre windows: an installed system. A.R. Hunwicks and P.A. Rosher p542
Error-correcting code for optical-fibre transmission systems. N. Yoshikai p97 d647
Gigabit optical transmitter GaAs MESFET IC. K. Utsumi, A. Tezuka, K. Nishii, K. Bando, K. Inoue and T. Onuma p374
Heterodyne transmission of a 560 Mbit/s optical signal by means of polarisation shift keying. E. Dietrich, B. Enning, R. Gross and H. Knupke p421
High-speed GaInAsP/InP buried-heterostructure optical intensity modulator with semi-insulating InP burying layers. H. Soda, K. Nakai, H. Ishikawa and H. Imai p1232
Narrow-linewidth laser with a prism grating/GRIN rod lens combination serving as external cavity. J. Wittmann and G. Gaukel p524
Novel all-electrical scheme for dynamic semiconductor laser-to-fibre coupling control. P.A. Andrekson and A. Alping p1275
Novel fibre break locator for optical duplex transmission systems. P. Cochrane, A.R. Hunwicks and P.A. Rosher p440
Novel high-speed LED transmitter for single-mode fibre and wideband loop transmission systems. G.-K. Chang, H.P. Leblanc and P.W. Shumate p1338
Novel type of fibre-optic ring resonator. E. Meissner p683
Observation of crosstalk due to four-wave mixing in a laser amplifier for FDM transmission. K. Inoue p1293
Optical CPFSK 2 Gbit/s 202 km transmission experiment using a narrow-linewidth multielectrode DFB LD. K. Iwashita, N. Takachio, Y. Nakano and N. Tsuzuki p1022
Optical FSK transmission system using a phase-diversity receiver. M.J. Pettitt, D. Remedios, A.W. Davis, A. Hadjifotiou and S. Wright p1075
Optical self-homodyne DPSK transmission at 1 and 2 Gbit/s over 86 km of fibre. R.C. Giles and K.C. Reichmann p1180
Optical time-division multiplexed transmission system experiment at 8 Gbit/s. G. Eisenstein, R.S. Tucker, S.K. Korotky, G. Raybon, J.J. Veselka, L.L. Buhl, A.H. Gnauck, B.L. Kasper and R.C. Alferness p1115
Over 720 GHz (5·8 nm) frequency tuning by a 1·5 μm DBR laser with phase and Bragg wavelength control regions. S. Murata, I. Mito and K. Kobayashi p403
Passive optical local networks for telephony applications and beyond. J.R. Stern, J.W. Ballance, D.W. Faulkner, S. Hornung, D.B. Payne and K. Oakley p1255
Power penalty in bit error rate due to limited transmission bandwidth. T.M. Shen p927
Power spectral density of CMI-coded TV signal transmitted through fibre-optic heterodyne system. N. Malaviya and G. Jauhari p1072
Practical method of measuring reflection-induced power penalties in single-mode fibre transmission systems. W.C. Young, L. Curtis, N.K. Cheung, S.J. Wang and D.S. Burpee p56
Signal transmission with optical carriers in multimode range of single-mode fibres. R. Ries p71
Single-laser high-selectivity bidirectional transmission system for local-area-network applications. N.A. Olsson and L.L. Buhl p62
Transmission at 1 Gbit/s over 7·4 km of single-mode fibre using an edge-emitting LED and PINFET receiver. M. Stern, D.J. Millicker, A.E. Elrefaie and K. Runge p386
Travelling-wave optical amplifier at 1·3 μm. G. Eisenstein, B.C. Johnson and G. Raybon p1020
WDM experiment using 1300/1500 nm dual-wavelength LED for single-mode fibre transmission systems. G.-K. Chang, L.A. Reith, H.P. Leblanc and A.K. Chin p1267

OPTICAL WAVEGUIDE COMPONENTS

GaInAsP buried channel EA modulator for 1·3 μm fibre links. S.C. Lin, X.L. Jing, M.K. Chin, L.M. Walpita, P.K.L. Yu and W.S.C. Chang p1257
Miniature integrated optical beam-splitter in AlGaAs/GaAs ridge waveguides. J.S. Osinski, C.E. Zah, R. Bhat, R.J. Contolini, E.D. Beebe, T.P. Lee, K.D. Cummings and L.R. Harriott p1156
Narrow-bandwidth optical waveguide transmission filters. K.O. Hill, D.C. Johnson, F. Bilodeau and S. Faucher p465
Wavelength dependence of a D-fibre optical switch. S.A. Cassidy and P. Yennadhiou p1385

OPTICAL WAVEGUIDES

All-optical switching in prism coupling to semiconductor-doped glass waveguides. G. Assanto, A. Gabel, C.T. Seaton, G.I. Stegeman, C.N. Ironside and T.J. Cullen p484
Analysis of a PIN photodiode with integrated waveguide. M.-C. Amann p895
Antiresonant reflecting optical waveguides for III-V integrated optics. T.L. Koch, U. Koren, G.D. Boyd, P.J. Corvini and M.A. Duguay p244
Bend losses in GaAs/AlGaAs optical waveguides. R.J. Deri, E. Kapon and L.M. Schiavone p845
Coupled mode theory. W. Streifer p315
Depolarisation in Ti : $LiNbO_3$ waveguides and its effect on circuit design. P.G. Suchoski, T.K. Findakly and F.J. Leonberger p1357
Electric-field-assisted proton-exchanged optical waveguides in lithium niobate. C.W. Pitt, G. Burbie and Tat Wan p987
Electro-optic effect in He^+-implanted optical waveguides in $LiNbO_3$. G.T. Reed and B.L. Weiss p424
Electroabsorption in GaAs quantum-well waveguides. N.K. Dutta and N.A. Olsson p853
Fabrication of low-loss titanium-diffused $LiNbO_3$ waveguides using a closed platinum crucible. A. Neyer and T. Pohlmann p1187
Fields in a bent single-mode fibre. S.J. Garth p373
Finite-element solution of arbitrarily nonlinear, graded-index slab waveguides. K. Hayata, M. Koshiba and M. Suzuki p429 e1397
Finite-element theory of nonlinear TM-polarised guided waves. K. Hayata, M. Nagai and M. Koshiba p1305
Growth and properties of an $LiNbO_3$ film on sapphire with an $LiNbO_3$ buffer layer. T. Nozawa p1321
Guided-wave GaAs/AlGaAs FET optical modulator based on free-carrier-induced bleaching. J.H. Abeles, W.K. Chan, A. Kastalsky, J.P. Harbison, L.T. Florez and R. Bhat p1302
Highly efficient InGaAs/InAlAs MQW waveguide phase shifter. K. Wakita, Y. Yoshikuni and Y. Kawamura p303
Improved method of measuring loss and phase shifts in waveguide devices. I.D. Henning and P.M. Rodgers p1245
Low-drive-voltage and low-loss polarisation-independent $LiNbO_3$ optical waveguide switches. M. Kondo, Y. Ohta, Y. Tanisawa, T. Aoyama and R. Ishikawa p1167
Low-insertion-loss channel waveguides in $LiNbO_3$ fabricated by proton exchange. J.J. Veselka and G.A. Bogert p265
Low-loss antiresonant reflecting optical waveguide on Si substrate in visible-wavelength region. Y. Kokubun, T. Baba, T. Sakaki and K. Iga e251
Low-loss optical stripe waveguides in $LiNbO_3$ formed by He^+ implantation. G.T. Reed and B.L. Weiss p792
Low-loss ridge optical waveguides in quaternary InGaAlAs/InP grown by MBE. P. Cinguino, F. Genova, S. Morasca, C. Rigo and A. Stano p235
Low-loss single-mode InP/InGaAsP waveguides grown by MOVPE. P.W.A. McIlroy, P.M. Rodgers, J.S. Singh, P.C. Spurdens and I.D. Henning p701
Monolithic integrated waveguide photodetector. S. Chandrasekhar, J.C. Campbell, A.G. Dentai and G.J. Qua p501
Narrow, high-NA GaAs/GaAlAs optical waveguides with losses below 0·7 ± 0·1 dB cm^{-1}. R.G. Walker, H.E. Shephard and R.R. Bradley p362
One-step field-assisted ion exchange for fabrication of buried multimode optical strip waveguides. B.G. Pantchev p1188
Optical damage resistance of ion-implanted $LiNbO_3$ waveguides. E. Glavas, P.D. Townsend, G. Droungas, M. Dorey, K.K. Wong and L. Allen p73
Reduction of bend losses in Ti : $LiNbO_3$ waveguides through MgO double diffusion. B. Schüppert p797
Refractive waveguide lenses: a new design. G.C. Righini and G. Molesini p302
Resistance of Ti : $LiNbO_3$ devices to ionising radiation. E.I. Drummond p1214 e1397
Semiconductor-doped fibre waveguides exhibiting picosecond optical nonlinearity. B.J. Ainslie, H.P. Girdlestone and D. Cotter p405
Single-mode guided-wave optical gate matrix switch using Mach–Zehnder interferometer gates. A. Himeno and M. Kobayashi p887
Stress-induced index change for K^+–Na^+ ion exchange in glass. J. Albert and G.L. Yip p737
Ti:$LiNbO_3$ intersecting waveguides. G.A. Bogert p72
Very low-loss GaInAs/InP optical waveguides for the 10·6 μm wavelength. D. Delacourt, M. Papuchon, M.A. di Forte-Poisson and M. Razeghi p451

OPTICS

1 THz-bandwidth prober for high-speed devices and integrated circuits. J.A. Valdmanis p1308

Brillouin scattering and phonon attenuation in halide glasses: stimulated Brillouin emission. J. Schroeder, L.G. Hwa, M.C. Shyong, G.A. Floudas, D.A. Thompson and M.G. Drexhage p1128
Characterisation of a fibre Raman oscillator using fibre grating reflectors. P.N. Kean, K. Smith, B.D. Sinclair, W. Sibbett, C.J. Rowe and D.C.J. Reid p1241
Coupled mode theory. W. Streifer p315
Densely spaced WDM coherent optical star network. B. Glance, K. Pollock, C.A. Burrus, B.L. Kasper, G. Eisenstein and L.W. Stulz p875
Efficiency frequency-doubling in a poled PVDF copolymer guest/host composite. J.R. Hill, P.L. Dunn, G.J. Davies, S.N. Oliver, P. Pantelis and J.D. Rush p700
Electroabsorption in GaAs quantum-well waveguides. N.K. Dutta and N.A. Olsson p853
Femtosecond single-pass cascade Raman soliton generation at 1·5 μm. A.S. Gouveia-Neto, A.S.L. Gomes, J.R. Taylor, B.J. Ainslie and S.P. Craig p1034
Finite-element theory of nonlinear TM-polarised guided waves. K. Hayata, M. Nagai and M. Koshiba p1305
Generation of short pulses from CW light by influence of crossphase modulation (CPM) in optical fibres. D. Schadt and B. Jaskorzynska p1090 e1211
High-sensitivity sampling technique for luminescence time constant measurement. S. Loualiche and E. Pauty p1017
Hybrid optical bistability based on increasing absorption in depletion layer of an Si Schottky SEED device. D. Jäger, F. Forsmann and H.-C. Zhai p490
Improved method of measuring loss and phase shifts in waveguide devices. I.D. Henning and P.M. Rodgers p1245
Index profiling of distributed-index lenses by a total reflection method. X. Zhu and K. Iga p626
Laser interferometer using a dual interference method. K.H. Yang, L. Chen and S.Y. Zhang p699
Linearising method for nonlinear properties in a liquid-crystal lens. T. Nose and S. Sato p878
Low-loss ridge optical waveguides in quaternary InGaAlAs/InP grown by MBE. P. Cinguino, F. Genova, S. Morasca, C. Rigo and A. Stano p235
Miniature micromachined Fabry–Perot interferometers in silicon. S.R. Mallinson and J.H. Jerman p1041
OTDR in a 147 km single-mode fibre in 1·55 μm wavelength region using an LD and GaInAs/InP APD at room temperature. Y. Namihira, Y. Horiuchi, H. Wakabayashi, T. Oshimi, K. Kitagawa and T. Ooka p1219
Optical damage resistance of ion-implanted $LiNbO_3$ waveguides. E. Glavas, P.D. Townsend, G. Droungas, M. Dorey, K.K. Wong and L. Allen p73
Optical feed for a phased array microwave antenna. M. Tamburrini, M. Parent, L. Goldberg and D. Stillwell p680
Optical frequency shifter using linearly birefringent monomode fibre. C.N. Pannell, J.D. Tatam, J.D.C. Jones and D.A. Jackson p847
Optically induced modulation in FM sideband injection-locked laser diodes. M. Tamburrini, L. Goldberg and J.F. Weller p1120
Performance of a channelled-substrate-planar high-power phase-locked array operating in the diffraction limit. B. Goldstein, N.W. Carlson, G.A. Evans, N.A. Dinkel and V.J. Masin p1136
Pigtailed high-finesse tunable fibre Fabry–Perot interferometers with large, medium and small free spectral ranges. J. Stone and L.W. Stulz p781
Proposal of an optical triggering scheme for bistable semiconductor lasers: combination with photoconductors. H.-F. Liu, Y. Hashimoto and T. Kamiya p532
Refractive waveguide lenses: a new design. G.C. Righini and G. Molesini p302
Resolution of moment equations in a nonlinear optical amplifier. S. Ruiz-Moreno, G. Junyent, J.R. Usandizaga and A. Calzada p15
Role of Petermann's *K*-factor in semiconductor laser oscillators—a further note. J. Arnaud p450
Second-harmonic generation in single crystals of 2-(N,N-dimethylamino)-5-nitroacetanilide (DAN) at 1·3 μm. P.V. Kolinsky, R.J. Chad, R.J. Jones, S.R. Hall, P.A. Norman, D. Bloor and J.S. Obhi p791
Second-harmonic generation in single-mode optical fibres. F.P. Payne p1215
Semiconductor-doped fibre waveguides exhibiting picosecond optical nonlinearity. B.J. Ainslie, H.P. Girdlestone and D. Cotter p405
Simple and effective frequency stabilisation for HeNe lasers at 1·52 μm. G. Fischer p206
Single-mode guided-wave optical gate matrix switch using Mach–Zehnder interferometer gates. A. Himeno and M. Kobayashi p887
Stable pulsations of semiconductor lasers by optoelectronic feedback with avalanche photodiodes. P. Paulus, R. Langenhorst and D. Jäger p471
Synchronous single-photon counting using an Si avalanche photodiode at room temperature. K. Shimizu, M. Fujise and M. Nunokawa p1307
Tunable single-mode output of a multimode laser in a tunable fibre grating external cavity. W.V. Sorin and S.A. Newton p390

OPTOELECTRONICS

110 GHz high-efficiency photodiodes fabricated from indium tin oxide/GaAs. D.G. Parker, P.G. Say, A.M. Hansom and W. Sibbett p527
Analysis of a PIN photodiode with integrated waveguide. M.-C. Amann p895
Design and realisation of high-gain 1·5 μm semiconductor TW optical amplifiers. P. Brosson, B. Fernier, J. Benoit, J.C. Simon and B. Landousies p254
Dynamic response of an integrated optoelectronic logic device. P. Wheatley, G. Parry, J.E. Midwinter, G. Hill, P. Mistry, M.A. Pate and J.S. Roberts p1249
Fabrication and performance of an InP/InGaAsP monolithic 12 × 12-element matrixed LED array. L.A. Koszi, H. Temkin, B.H. Chin, S.G. Napholtz and B.P. Segner p284
GaAs/AlGaAs ridge waveguide laser monolithically integrated with a photodetector using ion beam etching. N. Bouadma, S. Grosmaire and F. Brillouet p855
GaAs/AlGaAs rooftop reflector laser for optoelectronic integrated circuits. Chang-Joon Chae and Young-Se Kwon p1118
GaInAs PIN photodiodes grown on silicon substrates for 1·55 μm detection. P.D. Hodson, R.R. Bradley, J.R. Riffat, T.B. Joyce and R.H. Wallis p1094
Gigabit optical transmitter GaAs MESFET IC. K. Utsumi, A. Tezuka, K. Nishii, K. Bando, K. Inoue and T. Onuma p374
Guided-wave GaAs/AlGaAs FET optical modulator based on free-carrier-induced bleaching. J.H. Abeles, W.K. Chan, A. Kastalsky, J.P. Harbison, L.T. Florez and R. Bhat p1302
High-contrast optoelectronic logic device using a waveguide multiple-quantum-well optical modulator. P.J. Bradley, P. Wheatley, G. Parry, J.E. Midwinter, P. Mistry and J.S. Roberts p213
Huygens-type formula for curvature loss from dielectric waveguides in optoelectronics. P.C. Kendall, M.S. Stern and P.N. Robson p850
InGaAs/InP SAGM avalanche photodiodes incorporating a pseudoquaternary superlattice graded heterojunction grown by atmospheric-pressure MOCVD. A.J. Moseley, J. Urquhart, P.D. Hodson, J.R. Riffat and J.I. Davies p914
$In_{0.53}Ga_{0.47}As$ PIN photodiode grown by MOVPE on a semi-insulating InP substrate for monolithic integration. D. Wake, R.H. Walling, S.K. Sargood and I.D. Henning p415
Integration of GaAs MESFET drivers with GaAs directional-coupler electro-optic modulators. J.H. Abeles, W.K. Chan, F.K. Shokoohi, R. Bhat and M.A. Koza p1037
Local beam deflector integrated in a diode laser cavity. S. Mukai, M. Watanabe, H. Itoh and H. Yajima p361
Long-wavelength PINFET receiver OEIC on a GaAs-on-InP heterostructure. A. Suzuki, T. Itoh, T. Terakado, K. Kasahara, K. Asano, Y. Inomoto, H. Ishihara, T. Torikai and S. Fujita p954
Low-threshold GaAs/GaAlAs buried heterostructure laser with an ion-beam-etched quarter ring cavity. P. Sansonetti, H. Ribot, J. Brandon, L. Menigaux, L. Dugrand and N. Bouadma p485
Miniature integrated optical beam-splitter in AlGaAs/GaAs ridge waveguides. J.S. Osinski, C.E. Zah, R. Bhat, R.J. Contolini, E.D. Beebe, T.P. Lee, K.D. Cummings and L.R. Harriott p1156
Monolithic integrated waveguide photodetector. S. Chandrasekhar, J.C. Campbell, A.G. Dentai and G.J. Qua p501
Monolithic integration of a transverse-junction stripe laser and metal-semiconductor field-effect transistors on a semi-insulating GaAs substrate. J. Ohta, K. Kuroda, K. Mitsunaga, K. Kyuma, K. Hamanaka and T. Nakayama p509
Novel nonresonant optoelectronic logic device. P. Wheatley, P.J. Bradley, M. Whitehead, G. Parry, J.E. Midwinter, P. Mistry, M.A. Pate and J.S. Roberts p92
Novel optically pumped electronic mixer using a Mott diode structure. N.J. Gomes and A.J. Seeds p1084
Novel process for integration of optoelectronic devices using reactive ion etching without chlorinated gas. L. Henry, C. Vaudry and P. Granjoux p1253
Optically bistable operation in InGaAs/InAlAs MQW laser diodes using resonant tunnelling effect. Y. Kawamura, K. Wakita, H. Asahi and K. Oe p719
Optoelectronic millimetre-wave switching using a finline-on-silicon substrate. K. Uhde p1155
Optoelectronic time division multiplexing. D.J. Albares, G.A. Garcia, C.T. Chang and R.E. Reedy p327
Phase-shifted diffraction-grating fabrication using holographic wavefront reconstruction. Y. Ono, S. Takano, I. Mito and N. Nishida p57
Planar TJS lasers fabricated in semi-insulating GaAs substrates for optoelectronic integrated circuits. M. Ishii, K. Kamon, M. Shimazu, M. Mihara, H. Kumabe and K. Isshiki p179
Proposal of an optical triggering scheme for bistable semiconductor lasers: combination with photoconductors. H.-F. Liu, Y. Hashimoto and T. Kamiya p532
Simple and effective frequency stabilisation for HeNe lasers at 1·52 μm. G. Fischer p206
Stable pulsations of semiconductor lasers by optoelectronic feedback with avalanche photodiodes. P. Paulus, R. Langenhorst and D. Jäger p471
Transimpedance optical preamplifier with a very low input resistance. B. Wilson and I. Darwazeh p138
Waveguide-integrated PIN photodiode on InP. C. Bornholdt, W. Döldissen, F. Fiedler, R. Kaiser and W. Kowalsky p2
Wavelength dependence of optical oxidation of silicon. I.W. Boyd and F. Micheli p298 e480

OSCILLATORS

Chaos via a piecewise-linear switched-capacitor circuit. A. Rodriguez-Vazquez, A. Rueda, B. Perez-Verdu and J.L. Huertas p662
Characterisation of a fibre Raman oscillator using fibre grating reflectors. P.N. Kean, K. Smith, B.D. Sinclair, W. Sibbett, C.J. Rowe and D.C.J. Reid p1241
Current-mirror phase-shifter oscillator. S. Pookaiyaudom and K. Samootrut p21
Quasisinusoidal oscillators with cubic-type nonlinearity. C. Di Bello p20
Surface-acoustic-wave device incorporating conducting Langmuir–Blodgett films. B. Holcroft, G.G. Roberts, A. Barraud and J. Richard p446
Voltage-controlled bipolar-MOS (VCBM) ring oscillator. J.P. Colinge p1023

PN JUNCTIONS

Fully ion-implanted abrupt *pn* junction on semi-insulating InP. K.-W. Wang, C.L. Cheng and S.M. Zima p1040

PARALLEL PROCESSING

Design of PE structure of a parallel image processor. J. Owczarczyk p121
Fault-tolerant schemes for parallel architectures. M.J. Livesey and J. Owczarczyk p1206
Implementation of multistage space-switch interconnections via the perfect shuffle. C.J.G. Kirkby p971
Novel reconfigurable tree machine. N.N. Biswas and S. Srinivas p1144
Parallel merger. G.S. Liu p1069

PATTERN RECOGNITION

Approach to performance optimisation in frequency-weighted memory network pattern classifiers. M.C. Fairhurst and H.M.S. Abdel Wahab p1116

PERTURBATION THEORY

Fields in a bent single-mode fibre. S.J. Garth p373
Improved method for resonant-frequency perturbation measurements. D.V. Land p1166

PHASE COMPARATORS

Novel circuit design and implementation of adaptive phase comparators. J.C. Haartsen and R.C. Den Dulk p551

PHASE MODULATION

Coherent lightwave transmission at 2 Gbit/s over 170 km of optical fibre using phase modulation. A.H. Gnauck, R.A. Linke, B.L. Kasper, K.J. Pollock, K.C. Reichmann, R. Valenzuela and R.C. Alferness p286
Comparison of phase modulation of GaAs/AlGaAs double heterostructures. J. Faist, F.K. Reinhart and D. Martin p1391

Nonlinear transmission line for picosecond pulse compression and broadband phase modulation. M.J.W. Rodwell, D.M. Bloom and B.A. Auld p109
Wavelength dependence of high-performance AlGaAs/GaAs waveguide phase modulators. A. Alping, X.S. Wu and L.A. Coldren p93

PHASE SHIFTERS

Broadband continuously variable microwave phase shifter employing a distributed Schottky contact on silicon. V.M. Hietala, Y.R. Kwon and K.S. Champlin p675
Dielectric slab matched ferrite gyrator. J. Uher, F. Arndt and J. Bornemann p278
Highly efficient InGaAs/InAlAs MQW waveguide phase shifter. K. Wakita, Y. Yoshikuni and Y. Kawamura p303

PHASE-LOCKED LOOPS

Novel circuit design and implementation of adaptive phase comparators. J.C. Haartsen and R.C. Den Dulk p551
Self-correcting clock recovery circuit with improved jitter performance. D. Shin, M. Park and M. Lee p110

PHASE SHIFT KEYING

Gigabit QPSK modulator. R. Trambarulo, M.V. Schneider and M.J. Gans p998
Optical self-homodyne DPSK transmission at 1 and 2 Gbit/s over 86 km of fibre. R.C. Giles and K.C. Reichmann p1180

PHOTOCHROMISM

Bistable optical switching and logic elements in photochromic fulgides with single-wavelength illumination. R. Cush, C. Trundle, C.J.G. Kirkby and I. Bennion p419

PHOTOCONDUCTING DEVICES

Proposal of an optical triggering scheme for bistable semiconductor lasers: combination with photoconductors. H.-F. Liu, Y. Hashimoto and T. Kamiya p532

PHOTODETECTORS

GaAs/AlGaAs ridge waveguide laser monolithically integrated with a photodetector using ion beam etching. N. Bouadma, S. Grosmaire and F. Brillouet p855
Monolithic integrated waveguide photodetector. S. Chandrasekhar, J.C. Campbell, A.G. Dentai and G.J. Qua p501
Sensitivity improvement in low-temperature operation of a baseband photoreceiver containing a TEGFET. D. Ronarch, M. Guibert and L. Pophillat p222

PHOTODIODES

110 GHz high-efficiency photodiodes fabricated from indium tin oxide/GaAs. D.G. Parker, P.G. Say, A.M. Hansom and W. Sibbett p527
GaInAs PIN photodiodes grown on silicon substrates for 1·55 μm detection. P.D. Hodson, R.R. Bradley, J.R. Riffat, T.B. Joyce and R.H. Wallis p1094
High-speed, self-passivated InGaAs PIN photodiode for microwave fibre links. C. Fan, P.K.L. Yu and P.C. Chen p571
InGaAs PIN photodiodes grown on GaAs substrates by metal organic vapour phase epitaxy. A.G. Dentai, J.C. Campbell, C.H. Joyner and G.J. Qua p38
InGaAs/InP SAGM avalanche photodiodes incorporating a pseudoquaternary superlattice graded heterojunction grown by atmospheric-pressure MOCVD. A.J. Moseley, J. Urquhart, P.D. Hodson, J.R. Riffat and J.I. Davies p914
$In_{0.53}Ga_{0.47}As$ PIN photodiode grown by MOVPE on a semi-insulating InP substrate for monolithic integration. D. Wake, R.H. Walling, S.K. Sargood and I.D. Henning p415
Low-leakage InGaAs photodiodes grown on GaAs substrates using a graded strained-layer superlattice. P.D. Hodson, R.H. Wallis and J.I. Davies p273
Microwave amplifier based RF optical receivers. S.R. Cochran p1283
Near-ambient-temperature bipolar transistor in cadmium mercury telluride. T. Ashley, C.T. Elliott, A.M. White, G.J. Crimes and A.T. Harker p1280
Synchronous single-photon counting using an Si avalanche photodiode at room temperature. K. Shimizu, M. Fujise and M. Nunokawa p1307
Type conversion in $Cd_xHg_{1-x}Te$ by ion beam treatment. M.V. Blackman, D.E. Charlton, M.D. Jenner, D.R. Purdy, J.T.M. Wotherspoon, C.T. Elliott and A.M. White p978
Waveguide-integrated PIN photodiode on InP. C. Bornholdt, W. Döldissen, F. Fiedler, R. Kaiser and W. Kowalsky p2

PHOTOELECTRIC DEVICES

High-speed, self-passivated InGaAs PIN photodiode for microwave fibre links. C. Fan, P.K.L. Yu and P.C. Chen p571
InGaAs PIN photodiodes grown on GaAs substrates by metal organic vapour phase epitaxy. A.G. Dentai, J.C. Campbell, C.H. Joyner and G.J. Qua p38
Low-leakage InGaAs photodiodes grown on GaAs substrates using a graded strained-layer superlattice. P.D. Hodson, R.H. Wallis and J.I. Davies p273
Monolithic photoreceiver integrating GaInAs PIN/JFET with diffused junctions. J.C. Renaud, L. N'Guyen, M. Allovon, F. Heliot, F. Lugiez and A. Scavennec p1055
Monolithically integrated photoreceiver with large gain-bandwidth product. S.J. Wojtczuk, J.M. Ballantyne, Y.K. Chen and S. Wanuga p574

PHOTOLUMINESCENCE

High-sensitivity sampling technique for luminescence time constant measurement. S. Loualiche and E. Pauty p1017

PIEZOELECTRIC DEVICES AND MATERIALS

Electrothermally excited silicon beam mechanical resonators. M.B. Othman and A. Brunnschweiler p728
Lamb wave graphic tablet. E. Dieulesaint, D. Royer, A. Chaabi and B. Formery p982
New cut of a quartz resonator with a linear temperature/frequency characteristic. M. Borissov, L. Spassov, E. Yosiffov, A. Balabanova and E. Radeva p169
YAG resonator. E. Dieulesaint, D. Mazerolle and D. Royer p581

PLANAR ANTENNAS

Compact broadband microstrip antenna. C.K. Aanandan and K.G. Nair e306
Radiation pattern of a stripline excited rectangular aperture. Shi Wen-hong and Chen Jin-guang p187

PLASMA WAVES

Photothermal radiometric imaging of semiconductors. S.J. Sheard, R.K. Appel and M.G. Somekh p227

PLASMAS

Advances in electrical properties of plasma-grown oxides of silicon. S. Taylor, W. Eccleston and P. Watkinson p732
Effect of process parameters on plasma-enhanced chemical vapour deposition of tungsten. C.M.T. Hodson and J. Wood p733
High-rate deposition of amorphous hydrogenated silicon: effect of plasma excitation frequency. H. Curtins, N. Wyrsch and A.V. Shah p228
Hydrogen plasma etching of amorphous and microcrystalline silicon. R.C. van Oort, M.J. Geerts, J.C. van den Heuvel and J.W. Metselaar p967

POLARISATION

Alignment of polarisation-maintaining fibres by temperature modulation. G.R. Walker and N.G. Walker p689
Backscattering matrix of dielectric objects at 9·6 GHz. Y.M.M. Antar, L.E. Allan and A.R. Holt p996
Birefringence and polarisation dispersion measurements in high-birefringence single-mode fibres. M. Monerie and F. Alard p198
Dual aperture-coupled microstrip antenna for dual or circular polarisation. A. Adrian and D.H. Schaubert p1226
Dynamic polarisation fluctuation characteristics of optical fibre submarine cable coupling under periodic variable tension. Y. Namihira, Y. Horiuchi and H. Wakabayashi p1201
Endless polarisation control using four fibre squeezers. N.G. Walker and G.R. Walker p290
Endless polarisation state matching control experiment using two controllers of finite control range. C.J. Mahon and G.D. Khoe p1234
Heterodyne transmission of a 560 Mbit/s optical signal by means of polarisation shift keying. E. Dietrich, B. Enning, R. Gross and H. Knupke p421
Interferometric measurements of chromatic and polarisation mode dispersion in highly birefringent single-mode fibres. J.-P. von der Weid, L. Thevenaz and J.-P. Pellaux p151
Kerr modulation of signals at 1·3 and 1·5 μm in polarisation-maintaining fibres pumped at 1·06 μm. K.C. Byron p1324
Low-loss dispersion-shifted polarisation-maintaining fibres. Y. Sasaki, K. Tajima and S. Seikai p279
Macrobends of bow-tie fibres with constant curvature. Chen Yijiang and Huang Hung-chia p159
Microbending losses of bow-tie and similar anisotropic fibres. Chen Yijiang and Huang Hung-chia p157
Monomode fibre polarisation scrambler. A.D. Kersey and A. Dandridge p634
Optical amplifier configurations with low polarisation sensitivity. G. Großkopf, R. Ludwig, R.G. Waarts and H.G. Weber p1387
Polarisation fluctuation in optical-fibre submarine cable under 8000 m deep sea environmental conditions. Y. Namihira, S. Ryu, K. Mochizuki, K. Furusawa and Y. Iwamoto p100 e306
Polarisation fluctuation of submarine-cabled single-mode optical fibres in ocean installation. Y. Namihira, S. Ryu, M. Kuwazuru, K. Mochizuki and Y. Iwamoto p343
Polarisation fluctuations in a 147 km undersea lightwave cable during installation. C.D. Poole, N.S. Bergano, H.J. Schulte, R.E. Wagner, V.P. Nathu, J.M. Amon and R.L. Rosenberg p1113
Polarisation state stabilisation in optically nonlinear birefringent fibres. A. Vatarescu p379
Polarisation transformer on Ti : $LiNbO_3$ with reset-free optical operation for heterodyne/homodyne receivers. H. Heidrich, C.H. von Helmolt, D. Hoffmann, H.-J. Hensel and A. Kleinwächter p335
Polarisation-insensitive heterodyne detection using polarisation scrambling. T.G. Hodgkinson, R.A. Harmon and D.W. Smith p513
Preservation of polarisation orthogonality through a linear optical system. L.J. Cimini, I.M.I. Habbab, R.K. John and A.A.M. Saleh p1365
Realisation of integrated-optical absorbers for Ti : $LiNbO_3$. G. Stock p831
Single-mode single-polarisation fibre using resonant absorbing effect. Zheng Xue-heng p14
Single-polarisation single-mode guidance in stress-induced birefringence fibres with lossy stress-applying sections. K.S. Chiang p506
Spectral response measurements on polarisation splitting ratio of fused-taper single-mode fibre couplers. Y. Namihira, Y. Horiuchi and H. Wakabayashi p1204
Ti : $LiNbO_3$ three-waveguide polarisation splitter. G.A. Bogert p37

POLES AND ZEROS

Iterative method for obtaining the argument of the dominant complex pole-pair. S. Puthenpura and N.K. Sinha p674

POLYNOMIALS

Aryabhata algorithm for polynomials. S.C. Kak p838

POWER SEMICONDUCTOR DEVICES

Computer simulation of an induction heating power supply using power MOSFETs. D.W. Tebb and L. Hobson p293
Development of gate-lag effect on GaAs power MESFETs during aging. J.-M. Dumas, F. Garat and D. Lecrosnier p139

Electromigration effects in power MESFET rectifying and ohmic contacts. C. Canali, F. Chiussi, F. Fantini, L. Umena and M. Vanzi p364
Gold-based gate-sinking enhanced by inhomogeneities in power MESFETs. C. Canali, G. Donzelli, F. Fantini, M. Vanzi and A. Paccagnella p83
High-efficiency quasimicrowave GaAs FET power amplifier. T. Nojima, S. Nishiki and K. Chiba p512
High-performance GaAs power MESFET with AlGaAs buffer layer. B. Kim, M. Wurtele, H.D. Shih and H.Q. Tserng p1008
High-performance millimetre-wave GaAs power MESFET prepared by gas source molecular beam epitaxy. H.D. Shih, B. Kim and M. Wurtele p1141
Simple method for increasing current gain and voltage ratings of power transistors. A. Silard, F. Floru, C. Ştefan and G. Nani p1213

POWER-SUPPLY CIRCUITS

Computer simulation of an induction heating power supply using power MOSFETs. D.W. Tebb and L. Hobson p293
Voltage-fed transistorised induction heating power supply. S. Hinchliffe and L. Hobson p549

PRINTED CIRCUITS

Prediction of electromagnetic radiation of a multilayer board. V. Ungvichian and R. Perez-Rodriquez p721

PSEUDORANDOM SEQUENCES

Absolute-type shaft encoder using shift register sequences. G.H. Tomlinson p398
Elimination of errors in absolute position encoders using *m*-sequences. G.H. Tomlinson and E. Ball p1372
New pseudorandom encoding technique for shaft encoders with any desired resolution. E.M. Petriu p507

PULSE GENERATION

8·8 Gbit/s travelling-pulse word generator. N. Mulombe, J. Kahlert, W. Piscalar and G. Seehausen p703

PULSE-CODE MODULATION

Embedded ADPCM with noise spectral shaping for packet voice transmission. H.D. Kim and C.K. Un p239

***Q*-FACTORS**

High-quality factors for a sapphire-loaded superconducting cavity resonator. S.K. Jones and D.G. Blair p817

QUANTUM OPTICS

Electro-optic effects and electroabsorption in a GaAs/AlGaAs multiquantum-well heterostructure near the bandgap. M. Glick, D. Pavuna and F.K. Reinhart p1235
Exciton electroabsorption at room temperature in InGaAs/InP multiquantum-well structures grown by. A.J. Moseley, M.D. Scott, P.J. Williams, R.H. Wallis, J.I. Davies and J.R. Riffat p516
High-brightness, high-efficiency, single-quantum-well laser diode array. D.F. Welch, M. Cardinal, W. Streifer, D.R. Scifres and P.S. Cross p1240
Linewidth enhancement in quantum-well lasers. L.D. Westbrook and M.J. Adams p1223
Observations of room-temperature excitons in InGaP/InGaAlP MQW structures. H. Tanaka, Y. Kawamura and H. Asahi p166
Room-temperature 1·55 μm optical bistability in a GaInAs/AlInAs multiple-quantum-well etalon. H. Kawaguchi and Y. Kawamura p1013
Room-temperature CW operation of MBE-grown GaInAs/AlInAs MQW lasers in 1·5 μm range. Y. Matsushima, K. Utaka, K. Sakai and O. Takeuchi p1271
Self longitudinal-mode stabilisation in GaAs/(AlGa)As quantum-well lasers. B. Garrett, I.H. White and D.F.G. Gallagher p1193

QUARTZ OSCILLATORS

SAW quartz cuts with low stress and temperature sensitivity. E. Bigler, G. Theobald and D. Hauden p514

RADAR

Backscattering matrix of dielectric objects at 9·6 GHz. Y.M.M. Antar, L.E. Allan and A.R. Holt p996
Data-based matrix decomposition technique for high-resolution array processing of coherent signals. Gao Shi-wei and Bao Zheng p643
Objective measurement of receiver sensitivity. B.A. Wyndham and T.B. Nichols p1388
Optical feed for a phased array microwave antenna. M. Tamburrini, M. Parent, L. Goldberg and D. Stillwell p680
Robustness of a modified greatest-of CFAR detector. T. Bucciarelli and A. Nardone p128

RADAR RECEIVERS

Objective measurement of receiver sensitivity. B.A. Wyndham and T.B. Nichols p1388

RADIATION AND RADIATION EFFECTS

Influence of impurities on loss increase in optical fibre. H. Hanafusa, Y. Hibino, H. Itoh and F. Yamamoto p10
Resistance of Ti : $LiNbO_3$ devices to ionising radiation. E.I. Drummond p1214 e1397

RADIO LINKS

Automatic channel selection using template correlation. A.P. Jowett and M. Darnell p1209
Binary frame synchronisation sequences for packet radio. P.F. Driessen p1190
Combined space and adaptive correlation diversity in the CD900 system. W.H. Lam and R. Steele p496
Half-bit offset decision frequency detection of differentially encoded GMSK signals. K. Ohno and F. Adachi p1311

RADIOASTRONOMY

Low-noise SIS heterodyne receiver at 230 GHz. S.R. Davies, L.T. Little and C.T. Cunningham p946

RADIOCOMMUNICATION

Automatic channel selection using template correlation. A.P. Jowett and M. Darnell p1209
Rician envelope estimation and confidence intervals in low signal/noise levels. B.G. Stewart and J.F.L. Simmons p832

RADIOMETERS

Photothermal radiometric imaging of semiconductors. S.J. Sheard, R.K. Appel and M.G. Somekh p227

RADIOWAVE PROPAGATION

Analytical investigation of LOS multipath propagation. H.M. Rashwan, A.K. Aboul-Saoud and H.N. Kheirallah p746
Base station multicoupler design for UK cellular radio systems. S. Kazeminejad, D.P. Howson and G. Hamer p812
Case study of line-of-sight microwave multipath propagation. K.H. Craig and G.R. Kennedy p483
Characterising the UHF factory radio channel. T.S. Rappaport and C.D. McGillem p1015
Generation of a wide circularly polarised wave from a conical-helix antenna. H. Nakano, M. Sato and J. Yamauchi p387
Influence of raypath parameters on digital radio outage. Y. Serizawa and S. Takeshita p1353
M-profile ray tracing technique for multipath propagation. H.N. Kheirallah, H.M. Rashwan and A.K. Aboul-Saoud p82
Microwave energy scattered off building surfaces shows strong dependence on orientation of city blocks. A. Ranade and A.R. Noerpel p922
Outage probability calculations for a mobile radio system having multiple Rayleigh interferers. K.W. Sowerby and A.G. Williamson p600
Outage probability calculations for a mobile radio system having two log-normal interferers. K.W. Sowerby and A.G. Williamson p1345
Radiowave propagation into and within a building at 927 MHz. P.J. Barry and A.G. Williamson p248

RECEIVERS

Efficient digital receiver structure for trellis-coded signals transmitted through channels with intersymbol interference. K. Wesolowski p1265
Low-noise SIS heterodyne receiver at 230 GHz. S.R. Davies, L.T. Little and C.T. Cunningham p946

RECURSIVE FILTERS

New systolic array for realising second-order recursive digital filters. H.K. Kwan p442
Systolic arrays for recursive digital filtering. W. Luk and G. Jones p1174

REFLECTOR ANTENNAS

Aspheric double mirror systems. S. Cornbleet p199
Effect of support strut diffraction on reflector surface profile assessment. P. Kerbyson, A.P. Anderson and J.C. Bennett p146
Offset dual-reflector multiple-beam antennas using circularly symmetric main reflectors. S.G. Hay p888
Polarisation discrimination in shaped beam applications. R.C. Brown, P.J.B. Clarricoats and H. Zhou p238
Subreflector shaping to improve multiple-beam performance of a Cassegrain antenna. S.G. Hay p789

REFRACTIVE INDEX PROFILES

Spatial filtering method of oblique slit for measurement of refractive-index profile of optical-fibre preforms. P. Skok and M. Miler p859

RELIABILITY

Electromigration effects in power MESFET rectifying and ohmic contacts. C. Canali, F. Chiussi, F. Fantini, L. Umena and M. Vanzi p364
High-power aging tests of 1·3 and 1·5 μm VIPS lasers. S. Oshiba and Y. Kawai p843

RESISTORS

New tungsten silicide thin-film resistor technology applied to GaAs integrated circuits. D.A. Allan, M.J. Gilbert and P.J. O'Sullivan p1216

RESONANCE

Resonant tunnelling gate field-effect transistor. F. Capasso, S. Sen, F. Beltram and A.Y. Cho p225

RESONATORS

Electrothermally excited silicon beam mechanical resonators. M.B. Othman and A. Brunnschweiler p728

Field patterns of TM_0 modes in a shielded dielectric resonator. D. Kajfez and J. Lebaric p944
High-quality factors for a sapphire-loaded superconducting cavity resonator. S.K. Jones and D.G. Blair p817
Mode charts of gyromagnetic planar ring resonators. J. Helszajn, W.T. Nisbet and J. Sharp p1290
New cut of a quartz resonator with a linear temperature/frequency characteristic. M. Borissov, L. Spassov, E. Yosiffov, A. Balabanova and E. Radeva p169
Nonlinear vibrations and hysteresis of micromachined silicon resonators designed as frequency-out sensors. M.V. Andres, K.W.H. Foulds and M.J. Tudor p952
Novel type of fibre-optic ring resonator. E. Meissner p683
Open-cavity resonator as high-Q microstrip circuit element. K.D. Stephan, S.L. Young and S.C. Wong p1028 e1397
Resonant coupled stub in nonradiative dielectric waveguide. J.A.G. Malherbe and J.C. Olivier p749
Theoretical radiation resistance of an isolated slot ring resonator. G. Dubost p928
YAG resonator. E. Dieulesaint, D. Mazerolle and D. Royer p581

SAMPLE-AND-HOLD CIRCUITS

Optically strobed sample-and-hold circuit. C. McConaghy p234

SATELLITE LINKS

1·3 μm 35 km fibre-optic microwave multicarrier transmission system for satellite earth stations. W.I. Way, M. Krain and R.S. Wolff p400
Channel reallocatable onboard baseband switch. S. Suzuki, M. Yabusaki, T. Arita and F. Ishino p487
Direct fibre-optic transmission of entire microwave satellite antenna signals. J.E. Bowers, A.C. Chipaloski, S. Boodaghians and J.W. Carlin p185
Variable-data-rate systems applicable to fading satellite channels. A.P. Gallois and A.M. Böck p766

SATELLITE RELAY SYSTEMS

Channel reallocatable onboard baseband switch. S. Suzuki, M. Yabusaki, T. Arita and F. Ishino p487

SCANNING ANTENNAS

Offset dual-reflector multiple-beam antennas using circularly symmetric main reflectors. S.G. Hay p888
Subreflector shaping to improve multiple-beam performance of a Cassegrain antenna. S.G. Hay p789

SCATTERING

Backscattering matrix of dielectric objects at 9·6 GHz. Y.M.M. Antar, L.E. Allan and A.R. Holt p996
Brillouin scattering and phonon attenuation in halide glasses: stimulated Brillouin emission. J. Schroeder, L.G. Hwa, M.C. Shyong, G.A. Floudas, D.A. Thompson and M.G. Drexhage p1128
Efficient choice of basis functions in moment method analysis of frequency-selective surfaces. R. Orta, R. Tascone and R. Zich p586
Electromagnetic scattering by inhomogeneous dielectric cylinders. C.G. Migliora and M.B.F. Chaves p795
High-frequency scattering of a Hermite-Gaussian beam mode by a perfectly conducting cylinder. M. Yokota, T. Kudou and O. Fukumitsu p174
Low backscattered TM-polarised strip gratings. K.A. Jose, C.K. Aanandan and K.G. Nair p905
Microwave energy scattered off building surfaces shows strong dependence on orientation of city blocks. A. Ranade and A.R. Noerpel p922
Multiple-wave generation due to four-wave mixing in a single-mode fibre. H.H. Yaffe, R.G. Waarts, E. Lichtman and A.A. Friesem p42
Novel microwave projection imaging for determination of internal structure. K.I. Schultz and D.L. Jaggard p267
Reflector-backed perfectly blazed strip gratings simulate corrugated reflector effects. K.A. Jose and K.G. Nair p86
Scattering of arbitrarily polarised, arbitrarily directed incident plane waves by frequency-selective surfaces. M.J. Archer p660

SCHOTTKY-BARRIER DEVICES

Enhanced Schottky barrier heights on n-type $Ga_{0.47}In_{0.53}As$ by Be implantation. G. Fernholz, R. Westphalen, W. Lange and H. Beneking p722

SEMICONDUCTOR DEVICES AND MATERIALS

1·3 μm InGaAsP/InP distributed-feedback p-substrate partially inverted buried-heterostructure laser diode. A. Takemoto, Y. Sakakibara, Y. Nakajima, M. Fujiwara, S. Kakimoto, H. Namizaki and W. Susaki p546
20 GHz dynamic frequency divider with GaAs advanced SAINT and air-bridge technology. K. Osafune, T. Enoki, M. Muraguchi and K. Ohwada p300
Advances in electrical properties of plasma-grown oxides of silicon. S. Taylor, W. Eccleston and P. Watkinson p732
AlGaAs/GaAs bipolar transistors with a modulation-doped superlattice emitter. J.F. Palmier, A. Sibille, J.C. Harmand and J. Dangla p936
$Al_{0.45}Ga_{0.55}As$/GaAs HEMTs grown by MOVPE exhibiting high transconductance. A.L. Powell, P. Mistry, J.S. Roberts and P.I. Rockett p528
Anomalous oscillation in depletion-mode MOSFETs at low temperature. C. Carruthers and J. Mavor p178
Application of AlGaAs/GaAs HBTs for wideband direct-coupled amplifiers. Y. Yamauchi and T. Ishibashi p156
Avalanche noise associated with gate current of Si JFET. J.M. Peransin, D. Rigaud and R. Alabedra p970
Bend losses in GaAs/AlGaAs optical waveguides. R.J. Deri, E. Kapon and L.M. Schiavone p845
Blue electroluminescence from ZnSe/Langmuir-Blodgett film MIS diodes. Y.L. Hua, M.C. Petty, G.G. Roberts, M.M. Ahmad, H.M. Yates, N.J. Maung and J.O. Williams p231
Bonding silicon wafer to silicon nitride with spin-on glass as adhesive. A. Yamada, T. Kawasaki and M. Kawashima p314
Broadband continuously variable microwave phase shifter employing a distributed Schottky contact on silicon. V.M. Hietala, Y.R. Kwon and K.S. Champlin p675
CMOS circuits made in thin SIMOX films. J.P. Colinge and T.I. Kamins p1162 e1397
CMOS on local SOI using SIMOX technology. S. Matsumoto, T. Ohno and K. Izumi p576
CMOS/SIMOX devices having a radiation hardness of 2 Mrad(Si). T. Ohno, K. Izumi, M. Shimaya and N. Shiono p141
Characterisation of N-channel germanium MOSFET with gate insulator formed by high-pressure thermal oxidation. E.E. Crisman, J.I. Lee, P.J. Stiles and O.J. Gregory p8
Comparison of RF and microwave oxidation systems for the growth of thin oxides at low temperatures. S. Taylor, K.J. Barlow, W. Eccleston and A. Kiermasz p309
Comparison of phase modulation of GaAs/AlGaAs double heterostructures. J. Faist, F.K. Reinhart and D. Martin p1391
Complementary silicon MESFET technology. K.E. Bohlin, P.A. Tove, U. Magnusson and J. Tiren p205
Computer simulation of an induction heating power supply using power MOSFETs. D.W. Tebb and L. Hobson p293
Cooling characteristics of diamond-shaped interrupted cooling fin for high-power LSI devices. T. Kishimoto and S. Sasaki p456
DC and microwave characteristics of an $In_{0.53}Ga_{0.47}As/In_{0.52}Al_{0.48}As$ modulation-doped quasi-MISFET. K.S. Seo, P.K. Bhattacharya and K.R. Gleason p259
Development of gate-lag effect on GaAs power MESFETs during aging. J.-M. Dumas, F. Garat and D. Lecrosnier p139
Double-heterojunction bipolar transistors in InP/GaInAs grown by metal organic chemical vapour deposition. P.A. Houston, C. Blaauw, A. Margittai, M.N. Svilans, N. Puetz, D.J. Day, F.R. Shepherd and A.J. Springthorpe p931
Dual-gate silicon permeable-base transistors built on LPVPE-grown material. A. Gruhle, L. Vescan and H. Beneking p447
Dynamic response of an integrated optoelectronic logic device. P. Wheatley, G. Parry, J.E. Midwinter, G. Hill, P. Mistry, M.A. Pate and J.S. Roberts p1249
Effect of photochemical etching on interface state density of $Ga_{0.47}In_{0.53}As$ metal/insulator/semiconductor diodes. A. Aoki, S. Miyoshi and J. Shirafuji p891
Effect of process parameters on plasma-enhanced chemical vapour deposition of tungsten. C.M.T. Hodson and J. Wood p733
Effect of residual doping on optimum structure of multiquantum-well optical modulators. D.J. Newson and A. Kurobe p439
Electro-optic effects and electroabsorption in a GaAs/AlGaAs multiquantum-well heterostructure near the bandgap. M. Glick, D. Pavuna and F.K. Reinhart p1235
Electromigration effects in power MESFET rectifying and ohmic contacts. C. Canali, F. Chiussi, F. Fantini, L. Umena and M. Vanzi p364
Electron transport of (Al, Ga)Sb/InAs heterojunctions prepared by molecular beam epitaxy. T.H. Chiu, W.T. Tsang and A.F.J. Levi p917
Enhanced Schottky barrier heights on n-type $Ga_{0.47}In_{0.53}As$ by Be implantation. G. Fernholz, R. Westphalen, W. Lange and H. Beneking p722
Epitaxial, thermodynamically stabilised metal/III-V compound semiconductor interface: NiGa on GaAs (001). A. Guivarc'h, R. Guerin and M. Secoue p1004
Exciton electroabsorption at room temperature in InGaAs/InP multiquantum-well structures grown by. A.J. Moseley, M.D. Scott, P.J. Williams, R.H. Wallis, J.I. Davies and J.R. Riffat p516
Explicit formulation of delays in CMOS VLSI. D. Auvergne, D. Deschacht and M. Robert p741
Extremely high-quality GaInAs/AlInAs single quantum wells grown by molecular beam epitaxy. E.G. Scott, S.T. Davey and G.J. Davies p761
Fabrication and performance of an InP/InGaAsP monolithic 12 × 12-element matrixed LED array. L.A. Koszi, H. Temkin, R.H. Chin, S.G. Napholtz and B.P. Segner p284
Fabrication of a new type of field-effect transistor using neutralisation of shallow donors by atomic hydrogen in n-GaAs (Si). E. Constant, N. Caglio, J. Chevallier and J.C. Pesant p841
Fast and dense low-power multiple-valued I^2L circuit. Q.P. Chao and Z. Tang p968
Fully ion-implanted abrupt pn junction on semi-insulating InP. K.-W. Wang, C.L. Cheng and S.M. Zima p1040
GaAs lateral bipolar transistor with field-separated carriers. D. Ueda, H. Takagi, G. Kano and I. Teramoto p899
GaAs/GaAlAs rib waveguide grating filters for $\lambda = 1{\cdot}5\,\mu$m. A. Yi-Yan, H. Carru, P. Correc, J.P. Chandouineau, L. Dugrand and M. Carre p622
GaInAs junction FET fully dry etched by metal organic reactive ion etching technique. D. Lecrosnier, L. Henry, A. Le Corre and C. Vaudry p1254
Gate current in 0·75 μm N-channel MOSFETs with doubly diffused drain. R.K. Watts, L. Manchanda and R.L. Johnston p468
Gate-oxide integrity of silicon-on-insulator transistors. T.I. Kamins p175
Growth temperature dependence of low-noise MESFET in molecular-beam epitaxy. Y.C. Chou, C.T. Lee, C.D. Chen and K.C. Chu p7
Heterostructure complementary technology. J.G. Simmons and G.W. Taylor p380
High-frequency InGaAs/InP multiple-quantum-well buried-mesa electroabsorption optical modulator. U. Koren, B.I. Miller, R.S. Tucker, G. Eisenstein, I. Bar-Joseph, D.A.B. Miller and D.S. Chemla p621
High-performance GaAs power MESFET with AlGaAs buffer layer. B. Kim, M. Wurtele, H.D. Shih and H.Q. Tserng p1008
High-performance WN-gate MISFETs fabricated from MOVPE wafers. M. Wolny, T. Aguila, P. Deconinck, D. Moroni and J.P. Andre p1127
High-performance millimetre-wave GaAs power MESFET prepared by gas source molecular beam epitaxy. H.D. Shih, B. Kim and M. Wurtele p1141
High-pressure thermal oxidation of gallium arsenide at 250°C. K.N. Bhat and N. Basu p1329
High-rate deposition of amorphous hydrogenated silicon: effect of plasma excitation frequency. H. Curtins, N. Wyrsch and A.V. Shah p228
High-speed 2 × 2 electrically driven spatial light modulator made with GaAs/AlGaAs multiple quantum wells (MQWs). T.H. Wood, E.C. Carr, C.A. Burrus, J.E. Henry, A.C. Gossard and J.H. English p916
High-speed GaAs 4 × 4-bit parallel multiplier using super capacitor FET logic. K.S. Lowe p425
High-speed GaInAsP/InP buried-heterostructure optical intensity modulator with semi-insulating InP burying layers. H. Soda, K. Nakai, H. Ishikawa and H. Imai p1232
High-speed waveguide optical modulator made from GaSb/AlGaSb multiple quantum wells (MQWs). T.H. Wood, E.C. Carr, C.A. Burrus, R.S. Tucker, T.-H. Chiu and W.-T. Tsang p540
High-temperature metallisation systems for transient annealing of GaAs. D.V. Morgan, H. Thomas, W.T. Anderson, P. Thompson, A. Christou and D.J. Diskett p1154

High-transconductance AlInAs/GaInAs HIFETs grown by MOCVD. M. Kamada, T. Kobayashi, H. Ishikawa, Y. Mori, K. Kaneko and C Kojima p297
Hot electron degradation in the source of asymmetrical LDD structures. B.S. Doyle, M. Bourcerie, P. Leclaire, A. Boudou and P. Dars p1356
Hydrogen plasma etching of amorphous and microcrystalline silicon. R.C. van Oort, M.J. Geerts, J.C. van den Heuvel and J.W. Metselaar p967
Impedance switching effects in GaAs/AlAs barrier structures. A.C. Campbell, V.P. Kesan, G.E. Crook, C.M. Maziar, D.P. Neikirk and B.G. Streetman p926
Improved AlGaAs/GaAs HBT performance by InGaAs emitter cap layer. K. Nagata, O. Nakajima, T. Nittono, H. Ito and T. Ishibashi p566
Improved negative feedback technique to reduce drain conductance of GaAs MESFETs for precision analogue ICs. W.S. Lee and J. Mun p705
InGaAs/InP SAGM avalanche photodiodes incorporating a pseudoquaternary superlattice graded heterojunction grown by atmospheric-pressure MOCVD. A.J. Moseley, J. Urquhart, P.D. Hodson, J.R. Riffat and J.I. Davies p914
InP/GaInAs heterojunction bipolar transistors with improved electrical characteristics grown on strained buffer layers. N. Emeis and H. Beneking p295
Increased carrier lifetimes in epitaxial silicon layers on buried silicon nitride produced by ion implantation. W. Skorupa, U. Kreissig, E. Hensel and H. Bartsch d579
Indium phosphide and quaternary doping superlattices grown by liquid-phase epitaxy. P.D. Greene, A.D. Prins, D.J. Dunstan and A.R. Adams p324
Inner-stripe AlGaAs/GaAs laser diode by single-step molecular beam epitaxy. K. Imanaka, H. Imamoto, F. Sato, M. Asai and M. Shimura p209
Ion-implanted *P*-channel GaAs MESFET using Schottky barrier height tailoring. S.M. Baier, G.Y. Lee, H.K. Chung, B.J. Fure and N.C. Cirillo p223
Langmuir-Blodgett deposited cadmium gate inverted InP-GaInAs modulation-doped field-effect transistors. W.K. Chan, H.M. Cox, J.H. Abeles and S.P. Kelty p1346
Laser recrystallised SOI with periodical seeding filled by selective epitaxial growth. J.L. Regolini, D. Dutartre, D. Bensahel, L. Karapiperis, G. Garry and D. Dieumegard p493
Lateral protrusions of ohmic contacts to AlGaAs/GaAs MODFET material. A. Ezis, A.K. Rai and D.W. Langer p113
Low-leakage InGaAs photodiodes grown on GaAs substrates using a graded strained-layer superlattice. P.D. Hodson, R.H. Wallis and J.I. Davies p273
Low-noise D-band impatt oscillators. J. Wenger and S. Huber p475
Low-noise operation of buried channel MOS transistors. C. Carruthers and J. Mavor p1173
Low-temperature process for high-mobility polysilicon TFTs. B. Loisel, Y. Chouan, N. Pedrono and P. Joubert p288
MBE-grown AlGaAs/GaAs HBTs on InP substrate. H. Ito and T. Ishibashi p394
MOCVD-grown AlGaAs/GaAs HBTs with epitaxially embedded p^+ layers in extrinsic base. K. Taira, H. Kawai and K. Kaneko p989
MOSFET model continuous from weak to strong inversion. M.M. Abu-Zeid and G.G. de Jong p1299
Model for the switching voltage of MISS devices based on an analogy with the thyristor. W.K. Choi, A.E. Owen, J.J. Delima and S.M. Gage p1
Molecular-beam-epitaxial growth of GaAs on high-temperature hydrogen-annealed (100) silicon. T.P. Humphreys, K. Das, S.M. Bedair, J.J. Wortman, N. Parikh, W.K. Chu, N. El-Masry and J.C.L. Tarn p1079
Molybdenum germanide ohmic contact to *n*-GaAs. K. Daoud-Ketata, C. Dubon-Chevallier, C. Besombes, J.F. Bresse and P. Henoc p17
Monte Carlo simulation of GaAs Schottky barrier behaviour. C.M. Maziar and M.S. Lundstrom p61
Narrow pulse measurement of drain characteristics of GaAs MESFETs. T.M. Barton, C.M. Snowden, J.R. Richardson and P.H. Ladbrooke p686
Near-ambient-temperature bipolar transistor in cadmium mercury telluride. T. Ashley, C.T. Elliott, A.M. White, G.J. Crimes and A.T. Harker p1280
Negative differential resistance at room temperature from resonant tunnelling in GaInAs/InP double-barrier heterostructures. M. Razeghi, A. Tardella, R.A. Davies, A.P. Long, M.J. Kelly, E. Britton, C. Boothroyd and W.M. Stobbs p116
New analytical expression for the drain current of short-channel MOS transistors in the triode region. S. Dimitrijev, D. Župac and N. Stojadinović p862
New analytical solution for a current/voltage characteristic of space-charge-limited currents with a nonlinear velocity-field relationship. G.S. Gildenblat and S.S. Cohen e251
New interpretation of structure of thermally grown silicon dioxide. I.W. Boyd p411
New mechanism for subsurface imaging in silicon. S.J. Sheard and M.G. Somekh p1134
New structure of three-terminal GaAs p^+-n^--$\delta(p^+)$-n^--n^+ switching device prepared by molecular beam epitaxy. Y.H. Wang, K.F. Yarn, C.Y. Chang and M.S. Jame p873
Noise in epitaxial silicon bulk unipolar diodes. C. Werres, L. Vescan and H. Beneking p613
Nondiffusion and 1·54 μm luminescence of erbium implanted in InP. P.N. Favennec, H. L'Haridon, A. Le Corre, M. Salvi and M. Gauneau p684
Nonreciprocal effects in an azimuthally magnetised millimetre-wave solid-plasma circular guide. V.I. Miteva and K.P. Ivanov p118
Novel process for emitter-base-collector self-aligned heterojunction bipolar transistor using a pattern-inversion method. S. Tanaka, M. Madihian, H. Toyoshima, N. Hayama and K. Honjo p567
Novel process for integration of optoelectronic devices using reactive ion etching without chlorinated gas. L. Henry, C. Vaudry and P. Granjoux p1253
Novel vertical Hall cells in standard bipolar technology. K. Maenaka, T. Ohgusu, M. Ishida and T. Nakamura p1104
OMCVD-grown InP/GaInAs heterojunction bipolar transistors. J.R. Hayes, R. Bhat, H. Schumacher and M. Koza p1298
Observations of room-temperature excitons in InGaP/InGaAlP MQW structures. H. Tanaka, Y. Kawamura and H. Asahi p166
Out-diffusion and reactivation of Zn in InP substrates. H. Jung and P. Marschall p1010
Photoelectrochemical laser interference etching for fabrication of 235 nm diffraction gratings on *n*-InP. L. Bäcklin p657
Photothermal radiometric imaging of semiconductors. S.J. Sheard, R.K. Appel and M.G. Somekh p227
Pressure dependence of threshold current and carrier lifetime in 1·55 μm GaInAsP lasers. K.C. Heasman, A.R. Adams, P.D. Greene and G.D. Henshall p492
Quantum confined Stark shifts in MOVPE-grown GaAs–AlGaAs multiple quantum wells. M. Whitehead, G. Parry, J.S. Roberts, P. Mistry, P. Li Kam Wa and J.P.R. David p1048
Reactive ion etching of GaAs using a mixture of methane and hydrogen. R. Cheung, S. Thoms, S.P. Beamont, G. Doughty, V. Law and C.D.W. Wilkinson p857
Refractory self-aligned gate technology for GaAs microwave FETs and MMICs. A.E. Geissberger, R.A. Sadler, E.L. Griffin, I.J. Bahl and M.L. Balzan p1073
Resonant tunnelling condition in a one-dimensional rectangular double-barrier structure. H. Yamamoto p161
Resonant tunnelling electron spectroscopy. F. Capasso, S. Sen, A.Y. Cho and A.L. Hutchinson p28
Resonant tunnelling gate field-effect transistor. F. Capasso, S. Sen, F. Beltram and A.Y. Cho p225
Resonant-tunnelling hot-electron transistor (RHET) using a GaInAs/(AlGa)InAs heterostructure. K. Imamura, S. Muto, H. Ohnishi, T. Fujii and N. Yokoyama p870
Role of source N^+N^- structure in parasitic bipolar action of lightly doped short-channel MOSFETs. N.D. Janković p461
Room-temperature 1·55 μm optical bistability in a GaInAs/AlInAs multiple-quantum-well etalon. H. Kawaguchi and Y. Kawamura p1013
Room-temperature operation of $Ga_{0.47}In_{0.53}As/Al_{0.48}In_{0.52}As$ resonant tunnelling diodes. S. Sen, F. Capasso, A.L. Hutchinson and A.Y. Cho p1229
SOI MOSFET in weak inversion and weak accumulation. F. Balestra and J. Brini p211
SOI by wafer bonding with spin-on glass as adhesive. A. Yamada, T. Kawasaki and M. Kawashima p39
Selective formation of ohmic contacts to *n*-GaAs. Y. Yamane, Y. Takahashi, H. Ishii and M. Hirayama p382
Selectively implanted buried oxide (SIBO) process for VLSI applications. P. Ratnam p1316
Self-aligned AlGaAs/GaAs HBT with InGaAs emitter cap layer. K. Nagata, O. Nakajima, T. Nittono, H. Ito and T. Ishibashi p64
Self-aligned GaAs gate heterojunction SISFET. M. Chen, W.J. Schaff, P.J. Tasker and L.F. Eastman p105
Self-aligned Si MESFETs fabricated in thin silicon-on-insulator films. D.P. Vu and A. Sono p354
Self-aligned diffusion technique for *n*-InP JFETs. C. Fan and P.K.L. Yu p981
Simple method for increasing current gain and voltage ratings of power transistors. A. Silard, F. Floru, C. Ştefan and G. Nani p1213
Simple method for measuring hot-electron temperature in GaAs. Jiang Xiaosong, Yu Li-sheng, Wang Shu-min and Liu Hong-xun p55
Slope angle influence on silicon doping in AlGaAs/GaAs MBE-grown on stepped surface of (100) GaAs substrate. H. Nobuhara, O. Wada and T. Fujii p35
Space-charge-influenced avalanche-breakdown characteristics: an improved approximation. J.-F. Luy, G. Baur and E. Kasper p638
Static 7 GHz Frequency divider IC based on a 2 μm Si bipolar technology. P. Weger, L. Treitinger, R. Reimann and H.-M. Rein p192
Tailoring the *I*/*V* characteristics of a superlattice tunnel diode. R.A. Davies, M.J. Kelly and T.M. Kerr p90
Testing of complex gates. R. Rajsuman, A.P. Jayasumana and Y.K. Malaiya p813
Transconductance dependence on gate length for GaAs gate SISFETs. M. Chen, W.J. Schaff, P.J. Tasker and L.F. Eastman p800
Transimpedance optical preamplifier with a very low input resistance. B. Wilson and I. Darwazeh p138
Type conversion in $Cd_xHg_{1-x}Te$ by ion beam treatment. M.V. Blackman, D.E. Charlton, M.D. Jenner, D.R. Purdy, J.T.M. Wotherspoon, C.T. Elliott and A.M. White p978
Uniformity of threshold voltage for MESFETs fabricated on VGF GaAs substrates. C.L. Reynolds, W.C. Gibson and J.E. Clemans p1222
Using oxide sidewall taper to improve breakdown voltage in planar junction of DMOS devices by a simple process. C.Y. Lu, P.C. Riffe, N.S. Tsai, R.E. Ahrens and M.A. Banak p407
Very high-transconductance heterojunction field-effect transistor (HFET). G.W. Taylor, M.S. Lebby, T.Y. Chang, R.N. Gnall, N. Sauer, B. Tell and J.G. Simmons p77
Very high-transconductance short-channel GaAs MESFETs with $Ga_{0.3}Al_{0.7}As$ buffer layer. K.Y. Lee, M. Al-Mudares, S.P. Beaumont, C.D.W. Wilkinson, J. Frost and C.R. Stanley p11
Very low-noise HEMTs using a 0·2 μm T-gate. W.L. Jones, S.K. Ageno and T.Y. Sato p844
Voltage-controlled bipolar-MOS (VCBM) ring oscillator. J.P. Colinge p1023
Wavelength dependence of high-performance AlGaAs/GaAs waveguide phase modulators. A. Alping, X.S. Wu and L.A. Coldren p93
p-type modulation-doped AlGaAs/GaAs heterostructures grown by atmospheric-pressure metal organic vapour phase epitaxy (MOVPE). J.S. Roberts, J. Woodhead, P. Mistry, K.C. Singh and C.M. Sotomayor-Torres p605

SEMICONDUCTOR DOPING

CMOS on local SOI using SIMOX technology. S. Matsumoto, T. Ohno and K. Izumi p576

SEMICONDUCTOR JUNCTIONS

Epitaxial, thermodynamically stabilised metal/III-V compound semiconductor interface: NiGa on GaAs (001). A. Guivarc'h, R. Guerin and M. Secoue p1004

SEMICONDUCTOR LASERS

0°-phase-shift, single-lobe operation from wide-waveguide interferometric (WWI) phase-locked arrays of InGaAsP/InP ($\lambda = 1{\cdot}3\,\mu$m) diode lasers. D. Botez, T. Pham and D. Tran p416
16 Gbit/s direct modulation of an InGaAsP laser. A.H. Gnauck and J.E. Bowers p801
1·55 μm narrow-linewidth multielectrode DFB laser for coherent FSK transmission. Y. Nakano, Y. Itaya, M. Fukuda, Y. Noguchi, H. Yasaka and K. Oe p826
1·55 μm wavelength tunable FBH-DBR laser. Y. Kotaki, M. Matsuda, M. Yano, H. Ishikawa and H. Imai p325
1 Gbit/s automatic-power-control-free zero-bias modulation of very-low threshold MQW laser diodes. M. Nakamura, H. Furuyama and A. Kurobe p1352
24 h frequency stabilisation of an SLM external-cavity semiconductor laser. Zhou Bingkun, Zhang Hanyi, Wu Yuanxiang, Zhou Jianying, Li Jian and Pan Zhenwu p194
300 mW operation of a surface-emitting phase-locked array of diode lasers. J. Puretz, R.K. DeFreez, R.A. Elliott, J. Orloff and T.L. Paoli p130
370 mW, 1·06 μm, CW TEM_{00} output from an Nd : YAG laser rod end-pumped by a monolithic diode array. J. Berger, D.F. Welch, D.R. Scifres, W. Streifer and P.S. Cross p669
450 Hz relative frequency stability in an AlGaAs diode laser. Y.C. Chung and T.M. Shay p1044

5·2 dB noise figure in a 1·5 μm InGaAsP travelling-wave laser amplifier. T. Mukai and T. Saitoh p216
Accuracy of Fabry–Perot method of semiconductor laser gain measurement. M.B. El Mashade and J. Arnaud p568
Aging characteristics of AlGaInP/GaInP visible-light lasers (λ_L = 678 nm). A. Gomyo, K. Kobayashi, S. Kawata, I. Hino and T. Suzuki p85
AlGaAs/GaAs visible distributed feedback laser operating at 770 nm. Y. Nakano, Y. Luo and K. Tada p1342
Amplifier-induced crosstalk in multichannel coherent lightwave systems. G.P. Agrawal p1175
Analysis of the stability of the highest-order supermode in semiconductor laser arrays. G.H.B. Thompson and J.E.A. Whiteaway p444
Analysis of threshold current density in 2·2 μm GaInAsSb/GaAlAsSb/GaSb DH lasers. P. Brosson, J. Benoit, A. Joullie and B. Sermage p417
Broadband 1·5 μm GaInAsP travelling-wave laser amplifier with high-saturation output power. T. Saitoh and T. Mukai p218
Buried-heterostructure diode lasers with *in-situ*-grown self-aligned GaAs mask for Zn diffusion. S. Mukai, M. Itoh, M. Watanabe, H. Itoh and H. Yajima p755
CW diode-pumped Tm^{3+}, Ho^{3+}:YAG 2·1 μm room-temperature laser. G.J. Kintz, L. Esterowitz and R. Allen p616
CW performance and life of 1·3 μm InGaAsP/InP lasers emitting at high facet power densities. R.F. Murison, A.J.N. Houghton, A.R. Goodwin, A.J. Collar and I.G.A. Davies p601
Coherent transmission using an external waveguide Bragg reflector laser with direct frequency modulation. N.A. Olsson, B.H. Johnson, H.J. Lee, C.H. Henry, R.F. Kazarinov, D.A. Ackerman and P.J. Anthony p687
Coupled-mode analysis of a periodic array of diode lasers. J.Z. Wilcox, J.J. Yang and M. Jansen p69
DFB ridge waveguide lasers at $\lambda = 1{\cdot}5\,\mu m$ with first-order gratings fabricated using electron beam lithography. C.J. Armistead, B.R. Butler, S.J. Clements, A.J. Collar, D.J. Moule, S.A. Wheeler, M.J. Fice and H. Ahmed p592
Dependence of spectral linewidth of DFB lasers on facet reflectivity. S. Ogita, M. Hirano, H. Soda, M. Yano, H. Ishikawa and H. Imai p347
Design for single-mode asymmetric quarter-wavelength-shifted DFB laser with high differential efficiency. H. Soda, H. Ishikawa and H. Imai p598
Determination of coupling coefficient of DFB lasers by a newly proposed method. Y. Hirayama, H. Okuda, H. Furuyama, J. Kinoshita and M. Nakamura p101
Direct supermode analysis of phase-locked diode laser arrays. K. Hayata and M. Koshiba p935
Distributed-feedback, surface-emitting laser diode with lateral double heterostructure. M. Ogura and S. Mukai p758
Dynamic spectral linewidth in InGaAsP multiquantum-well lasers grown by liquid-phase epitaxy. Y. Sasai, J. Ohya, M. Ogura and T. Kajiwara p232
Effect of facet coatings on far fields of semiconductor lasers. T. Ohtoshi p570
Effect of the non-Lorentzian lineshape of semiconductor laser on a PSK coherent heterodyne optical receiver. S. Betti, G. De Marchis, E. Iannone and A. Martellucci p1366
Entirely VPE-grown 1·5 μm DFB lasers with low threshold currents. T. Nishibe, M. Funamizu, H. Okuda, H. Furuyama, Y. Hirayama, M. Nakamura and M. Iwamoto p34
Equivalent circuit modelling and derivative characterisation of 1·3 μm injection lasers. D.E. Ackley p1354
Fabrication and performance of 1·5 μm GaInAsP travelling-wave laser amplifiers with angled facets. C.E. Zah, J.S. Osinski, C. Caneau, S.G. Menocal, L.A. Reith, J. Salzman, F.K. Shokoohi and T.P. Lee p990
Fabrication of first-order gratings for 1·5 μm DFB lasers by high-voltage electron-beam lithography. M.J. Fice, H. Ahmed and S. Clements p590
Fast frequency-tunable external-cavity laser. B. Glance, C.A. Burrus and L.W. Stulz p98
Formulas for direct frequency modulation response of two-electrode diode lasers: proposals for improvement. O. Nilsson, L. Gillner and E. Goobar p1371
Frequency modulation and spectral characteristics for a 1·5 μm phase-tunable DFB laser. S. Murata, I. Mito and K. Kobayashi p12
Frequency stabilisation of a modulated semiconductor laser. H. Tsuchida and Y. Mitsuhashi p1147
GaAs/AlGaAs ridge waveguide laser monolithically integrated with a photodetector using ion beam etching. N. Bouadma, S. Grosmaire and F. Brillouet p855
GaAs/AlGaAs rooftop reflector laser for optoelectronic integrated circuits. Chang-Joon Chae and Young-Se Kwon p1118
GaInAsP/InP unstable resonator lasers. H. Wang, Y.Y. Liu, M. Mittelstein, T.R. Chen and A. Yariv p949
Gain saturation dependence on signal wavelength in a travelling-wave semiconductor laser amplifier. K. Inoue, T. Mukai and T. Saitoh p328
Gain, polarisation sensitivity and saturation power of 1·5 μm near-travelling-wave semiconductor laser amplifier. J.C. Simon, B. Landousies, Y. Bossis, P. Doussiere, B. Fernier and D. Padioleau p332
High-brightness, high-efficiency, single-quantum-well laser diode array. D.F. Welch, M. Cardinal, W. Streifer, D.R. Scifres and P.S. Cross p1240
High-power CW operation of 780 nm T^3 laser diodes. A. Shima, T. Yamawaki, H. Saito, H. Matsubara, T. Murakami, K. Ohtaki, H. Kumabe and W. Susaki p672
High-power aging tests of 1·3 and 1·5 μm VIPS lasers. S. Oshiba and Y. Kawai p843
High-power etched-facet lasers. P. Tihanyi, D.K. Wagner, H.J. Vollmer, A.J. Roza, C.M. Harding, R.J. Davis and E.D. Wolf p772
High-power operation of a transverse-mode stabilised AlGaInP visible light (λ_L = 683 nm) semiconductor laser. H. Fujii, K. Kobayashi, S. Kawata, A. Gomyo, I. Hino, H. Hotta and T. Suzuki p938
High-power, wide-bandwidth, 1·55 μm-wavelength GaInAsP/InP distributed feedback laser. K. Kihara, K. Kamite, H. Sudo, T. Tanahashi, T. Kusunoki, S. Isozumi, H. Ishikawa and H. Imai p941
High-speed all-optical gate switching experiment in a Fabry–Perot semiconductor laser amplifier. K. Inoue p921
High-speed modulation characteristics of a GaSb/AlGaAb multiquantum-well laser diode. H. Toba and K. Nosu p188
High-speed, polyimide-based semi-insulating planar buried heterostructures. J.E. Bowers, U. Koren, B.I. Miller, C. Soccolich and W.Y. Jan p1263
Impact of 1/*f*-type FM noise on coherent optical communications. K. Kikuchi p885
InGaAsP buried heterostructure laser with 22 GHz bandwidth and high modulation efficiency. R. Olshansky, W. Powazinik, P. Hill, V. Lanzisera and R.B. Lauer p839
Inner-stripe AlGaAs/GaAs laser diode by single-step molecular beam epitaxy. K. Imanaka, H. Imamoto, F. Sato, M. Asai and M. Shimura p209
Interferometric conversion of laser phase noise to intensity noise by single-mode fibre-optic components. M.M. Choy, J.L. Gimlett, R. Welter, L.G. Kazovsky and N.K. Cheung p1151
Interferometric method for preventing mode-hopping in tunable external-cavity semiconductor lasers. M. Ohtsu, K.-Y. Liou, E.C. Burrows, C.A. Burrus and G. Eisenstein p1111
Kerr modulation of signals at 1·3 and 1·5 μm in polarisation-maintaining fibres pumped at 1·06 μm. K.C. Byron p1324
Linewidth and FM characteristics of a distributed feedback laser monolithically integrated with a tunable external cavity. T.P. Lee, S.G. Menocal, S. Sakano, A. Valster and S. Tsuji p153
Linewidth enhancement for DFB lasers due to longitudinal field dependence in the laser cavity. J. Wang, N. Schunk and K. Petermann p715
Linewidth enhancement in quantum-well lasers. L.D. Westbrook and M.J. Adams p1223
Linewidth reduction by coupled phase-shift distributed-feedback lasers. T. Kimura and A. Sugimura p1014
Linewidth reduction in DFB laser by detuning effect. S. Ogita, M. Yano, H. Ishikawa and H. Imai p393
Local beam deflector integrated in a diode laser cavity. S. Mukai, M. Watanabe, H. Itoh and H. Yajima p361
Low-drive-current, high-efficiency AlGaAs/GaAs SQW laser. H. Nobuhara, T. Fujii and O. Wada p645
Low-threshold GaAs/GaAlAs buried heterostructure laser with an ion-beam-etched quarter ring cavity. P. Sansonetti, H. Ribot, J. Brandon, L. Menigaux, L. Dugrand and N. Bouadma p485
Low-threshold operation of 1·5 μm buried-heterostructure DFB lasers grown entirely by low-pressure MOVPE. Y. Itaya, M. Oishi, M. Nakao, K. Sato, Y. Kondo and Y. Imamura p193
Low-threshold, high-power zero-order lateral-mode DQW-SCH metal-clad ridge waveguide (AlGa)As/GaAs lasers. B. Garrett and R.W. Glew p371
MOVPE studies for the development of GaInAsP/InP lasers with semi-insulating InP blocking layers. P. Speier, K. Wünstel and F.J. Tegude p1363
Measurement of effective index and dispersion in an index-guided surface-emitting distributed Bragg reflector laser. N.W. Carlson, G.A. Evans, J.M. Hammer and C.C. Neil p355
Microcavity GaAlAs/GaAs surface-emitting laser with I_{th} = 6 mA. K. Iga, S. Kinoshita and F. Koyama p134
Monolithically integrated thermoelectrically tunable distributed Bragg reflector laser. T. Cella, N.K. Dutta, A.B. Piccirilli and R.L. Brown p1031
Multichannel intermodulation distortion in high-speed GaInAsP lasers. P. Iannone and T.E. Darcie p1361
New GaAlAs-GaAs surface-emitting laser diodes with lateral pumping structure. Y.-H. Wu, M. Ogura, M. Werner and S. Wang p123
New high-resolution positive and negative photoresist method for λ/4-shifted DFB lasers. M. Okai, S. Tsuji, M. Hirao and H. Matsumura p370
Novel fabrication method of quarter-wave-shifted gratings using ECR-CVD SiN_x films. H. Sugimoto, Y. Abe, T. Matsui and H. Ogata p1260
Observation of crosstalk due to four-wave mixing in a laser amplifier for FDM transmission. K. Inoue p1293
Optical frequency scanning of a stabilised and linewidth-reduced multielectrode DFB laser using current feedback. H. Yasaka, Y. Yoshikuni, G. Motosugi and K. Oe p984
Optical frequency stabilisation and linewidth reduction of a multielectrode DFB laser with current feedback. H. Yasaka, Y. Yoshikuni, Y. Nakano and K. Oe p1161
Optically bistable operation in InGaAs/InAlAs MQW laser diodes using resonant tunnelling effect. Y. Kawamura, K. Wakita, H. Asahi and K. Oe p719
Performance characteristics of high-brightness, CW, diode laser arrays. D.F. Welch, M. DeVito, M. Cardinal, M. Abraham, H. Kung, G. Harnagel, P. Cross, D. Scifres and W. Streifer p892
Performance of a GaAlAs laser diode used for multichannel video transmission employing multiplexed UHF subcarriers. S.J. Chua, P.S. Kooi and M.S. Leong p366
Picosecond pulse response of a travelling-wave semiconductor laser amplifier. I.W. Marshall, D.M. Spirit and M.J. O'Mahony p818
Planar TJS lasers fabricated in semi-insulating GaAs substrates for optoelectronic integrated circuits. M. Ishii, K. Kamon, M. Shimazu, M. Mihara, H. Kumabe and K. Isshiki p179
Polarisation switching in a single-frequency external-cavity semiconductor laser. T. Fujita, A. Schremer and C.L. Tang p803
Power penalty in bit error rate due to limited transmission bandwidth. T.M. Shen p927
Pressure dependence of threshold current and carrier lifetime in 1·55 μm GaInAsP lasers. K.C. Heasman, A.R. Adams, P.D. Greene and G.D. Henshall p492
Properties of quarter-wave-shifted DFB lasers in the presence of a taper. L.D. Westbrook p518
Proposal of an optical triggering scheme for bistable semiconductor lasers: combination with photoconductors. H.-F. Liu, Y. Hashimoto and T. Kamiya p532
Relationship between linewidth and chirp reductions in gain-detuned composite-cavity semiconductor lasers. P. Gallion and G. Debarge p1375
Role of Petermann's *K*-factor in semiconductor laser oscillators—a further note. J. Arnaud p450
Room-temperature CW operation of MBE-grown GaInAs/AlInAs MQW lasers in 1·5 μm range. Y. Matsushima, K. Utaka, K. Sakai and O. Takeuchi p1271
Room-temperature continuous-wave operation of a 640 nm AlGaInP visible-light semiconductor laser. S. Kawata, H. Fujii, K. Kobayashi, A. Gomyo, I. Hino and T. Suzuki p1327
Scanning the laser gain spectrum using distributed feedback and hydrostatic pressure. K.C. Heasman, A.R. Adams and R.G. Plumb p555
Self longitudinal-mode stabilisation in GaAs/(AlGa)As quantum-well lasers. B. Garrett, I.H. White and D.F.G. Gallagher p1193
Signal gain saturation in two-channel common amplification using a 1·5 μm InGaAsP travelling-wave laser amplifier. T. Mukai, K. Inoue and T. Saitoh p396
Simultaneous amplification of wavelength-division-multiplexed signals by a highly efficient fibre Raman amplifier pumped by high-power semiconductor lasers. N. Edagawa, K. Mochizuki and Y. Iwamoto p196
Single-lobe 'Y' coupled laser diode arrays. D.F. Welch, P.S. Cross, D.R. Scifres and W. Streifer p270
Spectral behaviour of aged 1·55 μm λ/4-shifted DFB lasers. S. Akiba, Y. Matsushima, M. Usami and K. Utaka p316
Spectral, phase noise and phase modulation characteristics of AM sideband injection-locked semiconductor lasers. K. Kikuchi and C.E. Zah p437
Stabilisation of oscillation frequency of an AlGaAs/GaAs ridge waveguide distributed feedback laser. M. Kameya, S. Tai, K. Kojima, K. Kyuma, K. Hamanaka and T. Nakayama p245
Stable pulsations of semiconductor lasers by optoelectronic feedback with avalanche photodiodes. P. Paulus, R. Langenhorst and D. Jäger p471
Statistics of phase noise in single-mode semiconductor lasers: free-running, weak external feedback and injection-locking configurations. A. Mecozzi, S. Piazzolla, A. Sapia and P. Spano p1183
Thermal model of laser diode arrays. W. Nakwaski p458
Transverse junction buried heterostructure (TJ-BH) AlGaAs diode laser. Y.

Suzuki, S. Mukai, H. Yajima and T. Sato p384
Tunable optical-wavelength conversion using a multielectrode distributed-feedback laser diode with a saturable absorber. H. Kawaguchi, K. Oe, H. Yasaka, K. Magari, M. Fukuda and Y. Itaya p1088
Tuning characteristics and inverter/inverted-output flip-flop operation of tandem-electrode laser diode. M. Yamaguchi and K. Kikuchi p120
Validity of κL evaluation by stopband method for $\lambda/4$ DFB lasers with low reflecting facets. J. Kinoshita p499
Very low threshold current densities (under 100 A/cm^2) in AlGaAs/GaAs single-quantum-well GRINSCH lasers grown by molecular beam epitaxy. H.Z. Chen, A. Ghaffari, H. Morkoç and A. Yariv p1334
Very low-threshold 1·53 μm DFB lasers by VPE transport. B. Broberg, S. Nilsson and T. Tanbun-Ek p624
Wide temperature range of stable single-mode operation in weakly coupled asymmetric mirror reflectivity DFB lasers. H. Soda, K. Kihara, M. Furutsu, M. Matsuda, H. Seki, S. Ogita, H. Ishikawa and H. Imai p724
Wide-bandwidth and high-power 1·3 μm InGaAsP buried crescent lasers with semi-insulating Fe-doped InP current blocking layers. C.E. Zah, J.S. Osinski, S.G. Menocal, N. Tabatabaie, T.P. Lee, A.G. Dentai and C.A. Burrus p52
1/4-shifted AlGaAs/GaAs DFB lasers with double window structures. S. Hirata, K. Tamamura and C. Kojima p627

SEMICONDUCTORS

Photothermal radiometric imaging of semiconductors. S.J. Sheard, R.K. Appel and M.G. Somekh p227

SENSITIVITY

Flicker noise effect on sensitivity of PIN-(GaAs)FET fibre-optic receiver. Moon-Soo Park, Jun-Am Hwang and Young-Yun Chun p631

SEQUENTIAL CIRCUITS AND MACHINES

Absolute-type shaft encoder using shift register sequences. G.H. Tomlinson p398
Elimination of errors in absolute position encoders using *m*-sequences. G.H. Tomlinson and E. Ball p1372
New pseudorandom encoding technique for shaft encoders with any desired resolution. E.M. Petriu p507

SHIFT REGISTERS

Absolute-type shaft encoder using shift register sequences. G.H. Tomlinson p398
BIST structure using multi-input shift register with initial value. A. Hławiczka p476

SIGNAL GENERATORS

Zero-crossing estimation in signal generation of narrowband digital angle-modulated signals. K.S. Chung p697

SIGNAL PROCESSING

3 μm VLSI processing element using the Cordic algorithm. G.J. Vaudin and G.R. Nudd p1164
8·8 Gbit/s travelling-pulse word generator. N. Mulombe, J. Kahlert, W. Piscalar and G. Seehausen p703
Alternative to split-radix Hartley transform. R.N. Bracewell p1148
Automatic formant estimation algorithm based on pointwise analysis. X.D. Huang, G. Duncan and M.A. Jack p807
Broadband correlators employing fibre-optic recirculating delay lines. P.V. Gatenby, D.L. Switzer and N. Green p1246
Comparative study of time efficiency of several algorithms for discrete W transform and discrete Hartley transform. Z. Wang and Y. Wang p219
Complexity reduction in fully vector quantised stochastic coders. P.G. Hammett p253
Crosscorrelation pitch extraction method. S.T. Jovičić and P.Ž. Randjelović p1317
Data-based matrix decomposition technique for high-resolution array processing of coherent signals. Gao Shi-wei and Bao Zheng p643
Efficient technique for scale-space imaging of planar objects. D.T. Nguyen and D.-Y. Xu p1326
Fast computation of discrete Hartley transform via Walsh–Hadamard transform. Chau-Yun Hsu and Ja-Ling Wu p466
Fast search techniques for use in vector quantisation and related pattern matching applications. H.A. Kaouri, J.V. McCanny and W. Millar p311
Fault detection in RNS systolic arrays. M. Taheri, G.A. Jullien and W.C. Miller p165
Formant labelling using pole-focused spectra. X.D. Huang, M.A. Jack and G. Duncan p1047
GMSK frequency detection using decision feedback equalisation. K. Ohno and F. Adachi p1350
Globally optimising formant tracker using generalised centroids. A. Crowe and M.A. Jack p1019
Improper decimation of *m*-sequences. Shi Wen-hong and Chen Jin-guang p210
Improved postfiltering technique for block quantisation of speech. H.A. Kaouri and J.V. McCanny p1288
Improving the performance of nonplanar systolic architectures through increased fan-out. A. El-Amawy p765
Low-loss three-phase frequency conversion using a TDM-PWM technique. S.A.I. Sid Ahmed and P.S. Excell p126
Modified bit-level systolic inner product/convolver architecture with increased throughput. R.A. Evans and R. Eames p460
New classes of complementary signals. B. Bartosiński and R. Zielonko p433 e867
New configuration of echo canceller adaptable during double talk. J. Chao and S. Tsujii p1314
Reference template adaptation in speaker-independent isolated word speech recognition. F.R. McInnes and M.A. Jack p1304
Rician envelope estimation and confidence intervals in low signal/noise levels. B.G. Stewart and J.F.L. Simmons p832
Serial-data computation on twin pipelines. M.S. McGregor, S.G. Smith, P.B. Denyer and A.F. Murray p292
Simple adaptive algorithm for rejection of interference. Y.-H. Choi and J.-W. Ra p1038
Vector quantisation for minimum residual energy in pitch prediction of speech. A. Lowry and S.Q.A.M.A. Hossain p999

SILICON

Advances in electrical properties of plasma-grown oxides of silicon. S. Taylor, W. Eccleston and P. Watkinson p732
CMOS circuits made in thin SIMOX films. J.P. Colinge and T.I. Kamins p1162 e1397
Electrothermally excited silicon beam mechanical resonators. M.B. Othman and A. Brunnschweiler p728
High-rate deposition of amorphous hydrogenated silicon: effect of plasma excitation frequency. H. Curtins, N. Wyrsch and A.V. Shah p228
Hydrogen plasma etching of amorphous and microcrystalline silicon. R.C. van Oort, M.J. Geerts, J.C. van den Heuvel and J.W. Metselaar p967
Molecular-beam-epitaxial growth of GaAs on high-temperature hydrogen-annealed (100) silicon. T.P. Humphreys, K. Das, S.M. Bedair, J.J. Wortman, N. Parikh, W.K. Chu, N. El-Masry and J.C.L. Tarn p1079
New mechanism for subsurface imaging in silicon. S.J. Sheard and M.G. Somekh p1134
SOI MOSFET in weak inversion and weak accumulation. F. Balestra and J. Brini p211
Selectively implanted buried oxide (SIBO) process for VLSI applications. P. Ratnam p1316

SIMULATION

Computer simulation of SC circuits using NAP. S. Osowski p547 e763

SPACE COMMUNICATION LINKS

Novel contacting method for millimetre-wave mixers. K. Künzi and J. Broennimann p107

SPECTRAL ANALYSIS

Alternative to split-radix Hartley transform. R.N. Bracewell p1148

SPECTROSCOPY

Resonant tunnelling electron spectroscopy. F. Capasso, S. Sen, A.Y. Cho and A.L. Hutchinson p28

SPEECH PROCESSING

Adaptive LSP filter. B.M.G. Cheetham p89
Automatic formant estimation algorithm based on pointwise analysis. X.D. Huang, G. Duncan and M.A. Jack p807
Complexity reduction in fully vector quantised stochastic coders. P.G. Hammett p253
Crosscorrelation pitch extraction method. S.T. Jovičić and P.Ž. Randjelović p1317
Formant labelling using pole-focused spectra. X.D. Huang, M.A. Jack and G. Duncan p1047
Globally optimising formant tracker using generalised centroids. A. Crowe and M.A. Jack p1019
Improved postfiltering technique for block quantisation of speech. H.A. Kaouri and J.V. McCanny p1288
New configuration of echo canceller adaptable during double talk. J. Chao and S. Tsujii p1314
Reference template adaptation in speaker-independent isolated word speech recognition. F.R. McInnes and M.A. Jack p1304
Vector quantisation for minimum residual energy in pitch prediction of speech. A. Lowry and S.Q.A.M.A. Hossain p999
Vector-quantised transform coder for speech coding at 9·6 kbit/s and below. A. Kondoz and B.G. Evans p1286

SPEECH RECOGNITION

Automatic formant estimation algorithm based on pointwise analysis. X.D. Huang, G. Duncan and M.A. Jack p807
Formant labelling using pole-focused spectra. X.D. Huang, M.A. Jack and G. Duncan p1047
Homomorphic vector quantisation. R. Vích p561
Reference template adaptation in speaker-independent isolated word speech recognition. F.R. McInnes and M.A. Jack p1304

STABILITY

24 h frequency stabilisation of an SLM external-cavity semiconductor laser. Zhou Bingkun, Zhang Hanyi, Wu Yuanxiang, Zhou Jianying, Li Jian and Pan Zhenwu p194
Experiment on 1500 nm stabilised Zeeman laser. Wu Yizun, Guan Kejian, Yu Tong and Tian Feng p318
Extended power method and stability of linear discrete-time systems. S. Puthenpura and N.K. Sinha p4
Linear third-order discrete system stability under parameter variations. K.S. Yeung and S.S. Wang p266

STATISTICS

Comparison of two statistical tests for keystream sequences. M. Kimberley p365

STRIPLINES AND STRIPLINE COMPONENTS

Characteristics of inhomogeneous coupled cylindrical striplines. C.J. Reddy and M.D. Deshpande p821
Dielectrically shielded microstrip (DSM) lines. K. Chang and J. Klein p535
Radiation pattern of a stripline excited rectangular aperture. Shi Wen-hong and Chen Jin-guang p187

SUPERCONDUCTING DEVICES

High-quality factors for a sapphire-loaded superconducting cavity resonator. S.K. Jones and D.G. Blair p817
Low-noise SIS heterodyne receiver at 230 GHz. S.R. Davies, L.T. Little and C.T. Cunningham p946
Measurements of high-T_c superconductivity in a microwave cavity. T.M.P. Percival, J.S. Thorn and R. Driver p1225
Novel microstrip transformer for superconducting microelectronics. H.K. Olsson p1152

SUPERCONDUCTORS

Measurements of high-T_c superconductivity in a microwave cavity. T.M.P. Percival, J.S. Thorn and R. Driver p1225

SURFACE ACOUSTIC WAVES

Narrow-aperture SAW filter with both transducers finger-length-weighted. C.D. Blake p1248
SAW quartz cuts with low stress and temperature sensitivity. E. Bigler, G. Theobald and D. Hauden p514
Surface-acoustic-wave device incorporating conducting Langmuir–Blodgett films. B. Holcroft, G.G. Roberts, A. Barraud and J. Richard p446

SURFACE PHENOMENA

Surface plasmon microscopy. E. Yeatman and E.A. Ash p1091

SURFACE-ACOUSTIC-WAVE DEVICES

Narrow-aperture SAW filter with both transducers finger-length-weighted. C.D. Blake p1248
Surface-acoustic-wave device incorporating conducting Langmuir–Blodgett films. B. Holcroft, G.G. Roberts, A. Barraud and J. Richard p446

SWITCHED-CAPACITOR FILTERS

Clocking schemes for switched-capacitor FIR decimators. A.K. Betts, J.T. Taylor and D.G. Haigh p1323
Stray-free first-order circuit for correction of sample-and-hold amplitude distortion in switched-capacitor filters. J.T. Taylor and D.G. Haigh p177
Switched-capacitor biquad with low influence of finite gains. J. Mulawka, A. Konczykowska and M. Bon p1198

SWITCHED-CAPACITOR NETWORKS

8-bit micropower algorithmic A/D convertor. V. Valencic, P. Deval and F. Krummenacher p932
Chaos via a piecewise-linear switched-capacitor circuit. A. Rodriguez-Vazquez, A. Rueda, B. Perez-Verdu and J.L. Huertas p662
Compact formulation for exact analysis of nonideal SC circuits. M. Sanz and A. Puerta p554
Computer simulation of SC circuits using NAP. S. Osowski p547 e763
Spike-free switched-capacitor circuits. H. Matsumoto and K. Watanabe p428
Switched-capacitor neutral networks. Y.P. Tsividis and D. Anastassiou p958

SWITCHES

Channel reallocatable onboard baseband switch. S. Suzuki, M. Yabusaki, T. Arita and F. Ishino p487
Tester architecture for a time-division switch. A. Jajszczyk and J. Tyszer p1064

SWITCHING AND SWITCHING CIRCUITS

16 × 8 space switch for 2·24 Gbit/s transmission. L. Rønn and P. Deichmann p236
3·0 ps switching operation in all-Nb Josephson logic gates. K. Kuroda, J. Nakano, M. Yuda and M. Ueki p163
CMOS logic cell switching speed thermal characterisation. F.S. Shoucair p458
Channel reallocatable onboard baseband switch. S. Suzuki, M. Yabusaki, T. Arita and F. Ishino p487
Impedance switching effects in GaAs/AlAs barrier structures. A.C. Campbell, V.P. Kesan, G.E. Crook, C.M. Maziar, D.P. Neikirk and B.G. Streetman p926
Implementation of multistage space-switch interconnections via the perfect shuffle. C.J.G. Kirkby p971
Methods for the connection of signalling units to switching networks. A. Jajszczyk and W. Kabaciński p443
Optoelectronic millimetre-wave switching using a finline-on-silicon substrate. K. Uhde p1155
Switch reduction for bidirectional telephone systems. C. Mitchell and P. Wild p346
Tester architecture for a time-division switch. A. Jajszczyk and J. Tyszer p1064

SYNCHRONISATION

Binary frame synchronisation sequences for packet radio. P.F. Driessen p1190
New postdetection processing technique for frame synchronisers. L.-K. Shark, R.J. Simpson and T.J. Terrell p1337

SYSTEM THEORY

Biased model reduction by simplified Routh approximation method. G.V.K.R. Sastry and V. Krishnamurthy p1045
Self: A self-timed systems design technique. C.H. Lau p269
State-space models using simplified Routh approximation method. G.V.K.R. Sastry and V. Krishnamurthy p1300

TELECOMMUNICATION

Automatic channel selection using template correlation. A.P. Jowett and M. Darnell p1209
Connection-based media access for multichannel local and metropolitan area networks. B.P. Mohanty and T.D. Todd p1237
Data clock jitter in supersampling multiplex transmission. R. Gangopadhyay and P. Cochrane p1203
Data sequence coding for low jitter timing recovery. E.V. Jones and S. Zhu p337
Differential phase error in pulse-width-modulated TV transmission systems. B. Wilson and Z. Ghassemlooy p1133 e1397
Improved scheduling of traffic for a high-speed slotted ring. J.O. Limb and S. Kandiyoor p806
Laser power sharing in the subscriber loop. H. Kobrinski and S.S. Cheng p943
Measured pulse-stuffing jitter in asynchronous DS-1/SONET multiplexing with and without stuff-threshold modulation circuit. W.D. Grover, T.E. Moore and J.E. McEachern p959
Method for analytic subscriber traffic data acquisition in telephone networks. D. Lymberopoulos and G. Kokkinakis p1057
Narrowband digital voice communications over a meteor burst channel. J.R. Herman, C.C. Duggan, W.I. Thompson, R.A. Costa and D.M. DeLuca p59 e480
New postdetection processing technique for frame synchronisers. L.-K. Shark, R.J. Simpson and T.J. Terrell p1337
Performance of a GaAlAs laser diode used for multichannel video transmission employing multiplexed UHF subcarriers. S.J. Chua, P.S. Kooi and M.S. Leong p366
Variable-data-rate systems applicable to fading satellite channels. A.P. Gallois and A.M. Böck p766

TELEPHONE SWITCHING EQUIPMENT

Methods for the connection of signalling units to switching networks. A. Jajszczyk and W. Kabaciński p443
Switch reduction for bidirectional telephone systems. C. Mitchell and P. Wild p346

TELEPHONY

Passive optical local networks for telephony applications and beyond. J.R. Stern, J.W. Ballance, D.W. Faulkner, S. Hornung, D.B. Payne and K. Oakley p1255

TELEVISION

Differential phase error in pulse-width-modulated TV transmission systems. B. Wilson and Z. Ghassemlooy p1133 e1397
Nonlinear interpolation of TV image sequences. R. Glavina, S. Cucchi and G.L. Sicuranza p778
Performance of a GaAlAs laser diode used for multichannel video transmission employing multiplexed UHF subcarriers. S.J. Chua, P.S. Kooi and M.S. Leong p366
Power spectral density of CMI-coded TV signal transmitted through fibre-optic heterodyne system. N. Malaviya and G. Jauhari p1072

THIN-FILM DEVICES

Low-temperature process for high-mobility polysilicon TFTs. B. Loisel, Y. Chouan, N. Pedrono and P. Joubert p288
New tungsten silicide thin-film resistor technology applied to GaAs integrated circuits. D.A. Allan, M.J. Gilbert and P.J. O'Sullivan p1216
Nonlinear thermal effects in thin-film conductors on insulating substrates. D. de Cogan and M. Henini p552
Optical third-harmonic generation from polydiacetylene thin films deposited by vacuum evaporation. S. Tomaru, K. Kubodera, S. Zembutsu, K. Takeda and M. Hasegawa p595

THYRISTORS

Model for the switching voltage of MISS devices based on an analogy with the thyristor. W.K. Choi, A.E. Owen, J.J. Delima and S.M. Gage p1

TIME-DOMAIN REFLECTOMETRY

OTDR in a 147 km single-mode fibre in 1·55 μm wavelength region using an LD and GaInAs/InP APD at room temperature. Y. Namihira, Y. Horiuchi, H. Wakabayashi, T. Oshimi, K. Kitagawa and T. Ooka p1219

TIMING CIRCUITS

2 Gbit/s timing recovery circuit using dielectric resonator filter. D.J. Millicker and R.D. Standley p738

TRANSDUCERS

Bulk-acoustic-wave transducer consisting of intergidital electrodes on a grooved surface of $LiNbO_3$. K. Nakamura and H. Shimizu p74
Narrow-aperture SAW filter with both transducers finger-length-weighted. C.D. Blake p1248

TRANSFER FUNCTIONS

Constrained l_2 suboptimal model reduction. P. Vilbe and L.C. Calvez p1340
Family of reduced-order models for linear multivariable systems. A.M. Eydgahi and H. Singh p1178
Matrix approach for the coefficients of maximally flat FIR filter transfer functions expressed in powers of cos w. L.R. Rajagopal and S.C. Dutta Roy p391
Transfer function matrix. H. Seraji p256

TRANSFORMS

Alternative to split-radix Hartley transform. R.N. Bracewell p1148
Block-diagonal structure of Walsh–Hadamard/discrete cosine transform. Chau-Yun Hsu and Ja-Ling Wu p1123 e1397
Comparative study of time efficiency of several algorithms for discrete W transform and discrete Hartley transform. Z. Wang and Y. Wang p219
DC coefficient restoration by cosine and sine transforms. W.K. Cham p349
Fast computation of discrete Hartley transform via Walsh–Hadamard transform. Chau-Yun Hsu and Ja-Ling Wu p466
Simple method to determine microwave phase. P.H. Wu and Qian Min p1050

TRANSISTORS

AlGaAs/GaAs bipolar transistors with a modulation-doped superlattice emitter. J.F. Palmier, A. Sibille, J.C. Harmand and J. Dangla p936
$Al_{0.45}Ga_{0.55}As$/GaAs HEMTs grown by MOVPE exhibiting high transconductance. A.L. Powell, P. Mistry, J.S. Roberts and P.I. Rockett p528
Application of AlGaAs/GaAs HBTs for wideband direct-coupled amplifiers. Y. Yamauchi and T. Ishibashi p156
Double-heterojunction bipolar transistors in InP/GaInAs grown by metal organic chemical vapour deposition. P.A. Houston, C. Blaauw, A. Margittai, M.N. Svilans, N. Puetz, D.J. Day, F.R. Shepherd and A.J. Springthorpe p931
Dual-gate silicon permeable-base transistors built on LPVPE-grown material. A. Gruhle, L. Vescan and H. Beneking p447
GaAs lateral bipolar transistor with field-separated carriers. D. Ueda, H. Takagi, G. Kano and I. Teramoto p899
InP/GaInAs heterojunction bipolar transistors with improved electrical characteristics grown on strained buffer layers. N. Emeis and H. Beneking p295
Low-noise operation of buried channel MOS transistors. C. Carruthers and J. Mavor p1173
Low-temperature process for high-mobility polysilicon TFTs. B. Loisel, Y. Chouan, N. Pedrono and P. Joubert p288
MBE-grown AlGaAs/GaAs HBTs on InP substrate. H. Ito and T. Ishibashi p394
MOCVD-grown AlGaAs/GaAs HBTs with epitaxially embedded p^+ layers in extrinsic base. K. Taira, H. Kawai and K. Kaneko p989
Millimetre-wave performance of state-of-the-art MESFET, MODFET and PBT transistors. R.J. Trew and M.B. Steer p149
Near-ambient-temperature bipolar transistor in cadmium mercury telluride. T. Ashley, C.T. Elliott, A.M. White, G.J. Crimes and A.T. Harker p1280

New analytical expression for the drain current of short-channel MOS transistors in the triode region. S. Dimitrijev, D. Župac and N. Stojadinović p862
OMCVD-grown InP/GaInAs heterojunction bipolar transistors. J.R. Hayes, R. Bhat, H. Schumacher and M. Koza p1298
Simple method for increasing current gain and voltage ratings of power transistors. A. Silard, F. Floru, C. Ştefan and G. Nani p1213
Very low-noise HEMTs using a 0·2 μm T-gate. W.L. Jones, S.K. Ageno and T.Y. Sato p844

TRANSMISSION LINES

Analysis of a narrow slit in a parallel-plate transmission line: *E*-polarisation case. Young Ki Cho p1105 e1397
Characteristic impedance of stripline. B. Nauwelaers and A. Van De Capelle p930
Nonlinear transmission line for picosecond pulse compression and broadband phase modulation. M.J.W. Rodwell, D.M. Bloom and B.A. Auld p109
Nonreciprocal effects in an azimuthally magnetised millimetre-wave solid-plasma circular guide. V.I. Miteva and K.P. Ivanov p118
Single-mode operation of coplanar waveguides. M. Riaziat, I.J. Feng, R. Majidi-Ahy and B.A. Auld p1281
Transmission-line model for two-port rectangular microstrip patches with ports at the nonradiating edges. A. Benalla and K.C. Gupta p882

TREES

Content-addressable memories for storing and processing recursively subdivided images and trees. J.V. Oldfield, R.D. Williams and N.E. Wiseman p262

TUNING

Independent tuning of quality factor and unity-gain frequency in a transconductance-capacitance integrator. Z. Czarnul and Y. Tsividis d913

TUNNEL DIODES

Tailoring the *I/V* characteristics of a superlattice tunnel diode. R.A. Davies, M.J. Kelly and T.M. Kerr p90

TUNNELLING

Negative differential resistance at room temperature from resonant tunnelling in GaInAs/InP double-barrier heterostructures. M. Razeghi, A. Tardella, R.A. Davies, A.P. Long, M.J. Kelly, E. Britton, C. Boothroyd and W.M. Stobbs p116
Resonant tunnelling condition in a one-dimensional rectangular double-barrier structure. H. Yamamoto p161
Resonant tunnelling gate field-effect transistor. F. Capasso, S. Sen, F. Beltram and A.Y. Cho p225
Room-temperature operation of $Ga_{0.47}In_{0.53}As/Al_{0.48}In_{0.52}As$ resonant tunnelling diodes. S. Sen, F. Capasso, A.L. Hutchinson and A.Y. Cho p1229

ULTRASONIC DEVICES

New dynamic focusing scheme for ultrasound scanners. Y.G. Kim and S.B. Park p181

ULTRASONICS

Bulk waves radiated from an interdigital metallic transducer deposited on an anisotropic substrate. Y.W. Zhang and M. Planat p68
New dynamic focusing scheme for ultrasound scanners. Y.G. Kim and S.B. Park p181
Perturbation analysis of fibre acoustic modes. A. Safaai-Jazi, C.K. Jen and G.W. Farnell p350

VAPOUR DEPOSITION

Double-heterojunction bipolar transistors in InP/GaInAs grown by metal organic chemical vapour deposition. P.A. Houston, C. Blaauw, A. Margittai, M.N. Svilans, N. Puetz, D.J. Day, F.R. Shepherd and A.J. Springthorpe p931
Effect of process parameters on plasma-enhanced chemical vapour deposition of tungsten. C.M.T. Hodson and J. Wood p733
Low-threshold operation of 1·5 μm buried-heterostructure DFB lasers grown entirely by low-pressure MOVPE. Y. Itaya, M. Oishi, M. Nakao, K. Sato, Y. Kondo and Y. Imamura p193
MOCVD-grown AlGaAs/GaAs HBTs with epitaxially embedded p^+ layers in extrinsic base. K. Taira, H. Kawai and K. Kaneko p989

VARACTORS

Novel varactor-tuned millimetre-wave Gunn oscillator. R.N. Bates and S. Feeney p714

VIDEO

60-channel FM video subcarrier multiplexed optical communication system. R. Olshansky and V.A. Lanzisera p1196
Demonstration of high capacity in the LAMBDANET architecture: a multiwavelength optical network. H. Kobrinski, R.M. Bulley, M.S. Goodman, M.P. Vecchi, C.A. Brackett, L. Curtis and J.L. Gimlett p824
Performance of a GaAlAs laser diode used for multichannel video transmission employing multiplexed UHF subcarriers. S.J. Chua, P.S. Kooi and M.S. Leong p366

WAVE PROPAGATION

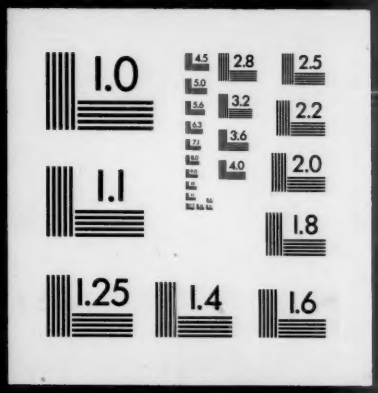
Effect of facet coatings on far fields of semiconductor lasers. T. Ohtoshi p570

WAVEGUIDE COMPONENTS

Ferrite tunable metal insert filter. J. Uher, J. Bornemann and F. Arndt p804
Wavelength dependence of high-performance AlGaAs/GaAs waveguide phase modulators. A. Alping, X.S. Wu and L.A. Coldren p93

WAVEGUIDES

Accuracy of method of moments and weighted index method. D.A. Roberts and M.S. Stern p784
Analysis of a narrow slit in a parallel-plate transmission line: *E*-polarisation case. Young Ki Cho p1105 e1397
Bias-variable characteristics of coupled coplanar waveguide on GaAs substrate. H. Baudrand, M. Kaddour and M. Ahmadpanah p171
Calculation of the radiation losses of groove-guide *E*-plane bends. J. Meißner p65
Electro-optic sampling measurement of coplanar waveguide (coupled slot line) modes. R. Majidi-Ahy, K.J. Weingarten, M. Riaziat, B.A. Auld and D.M. Bloom p1262
Elimination of ambiguity in measurement of permittivity with short-circuited waveguide. K.H. Oh, C.K. Ong and B.T.G. Tan p1181
Fields in a bent single-mode fibre. S.J. Garth p373
Finite-element solution of arbitrarily nonlinear, graded-index slab waveguides. K. Hayata, M. Koshiba and M. Suzuki p429 e1397
Guided-wave acousto-optic interaction on proton-exchanged lithium tantalate. J.F. Duffy, S.M. Al-Shukri and R.M. De La Rue p849
Gunn diode oscillator constructed in nonradiative dielectric waveguide. J.A.G. Malherbe and M.C. Wijnbeek p1368
Huygens-type formula for curvature loss from dielectric waveguides in optoelectronics. P.C. Kendall, M.S. Stern and P.N. Robson p850
Mutual coupling in finite coplanar rectangular waveguide arrays. T.S. Bird p1199
New accurate and simple equivalent circuit for circular *E*-plane bends in rectangular waveguide. P.L. Carle p531
New technique for analysing planar waveguides with finite metallisation thickness. K. Wu and P. Saguet e251
Novel finite-element formulation without any spurious solutions for dielectric waveguides. K. Hayata, M. Koshiba, M. Eguchi and M. Suzuki e251
Single-mode operation of coplanar waveguides. M. Riaziat, I.J. Feng, R. Majidi-Ahy and B.A. Auld p1281
Six-port reflectometer. S.P. Yeo and A.L. Ang p1160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1.1
1.25
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1.6
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